Rethinking Memory System Design
Robustness, Energy, Performance

Onur Mutlu

omutlu@gmail.com

https://people.inf.ethz.ch/omutlu

July 3, 2018

IOLTS Keynote Talk

SAFARI

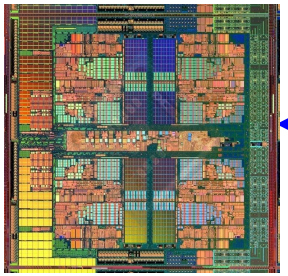
ETH zürich

Carnegie Mellon

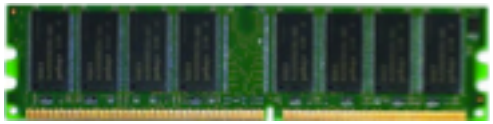
Current Research Focus Areas

***Research Focus:* Computer architecture, HW/SW, security, bioinformatics**

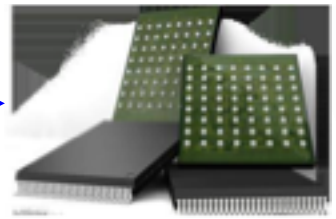
- ***Memory and storage (DRAM, flash, emerging), interconnects***
- ***Heterogeneous & parallel systems, GPUs, systems for data analytics***
- ***System/architecture interaction, new execution models, new interfaces***
- ***Hardware security, energy efficiency, fault tolerance, performance***
- ***Genome sequence analysis & assembly algorithms and architectures***
- ***Biologically inspired systems & system design for bio/medicine***



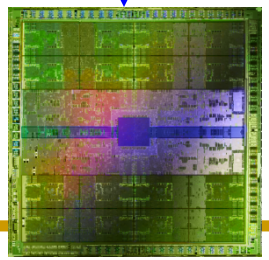
Heterogeneous Processors and Accelerators



Hybrid Main Memory



Persistent Memory/Storage



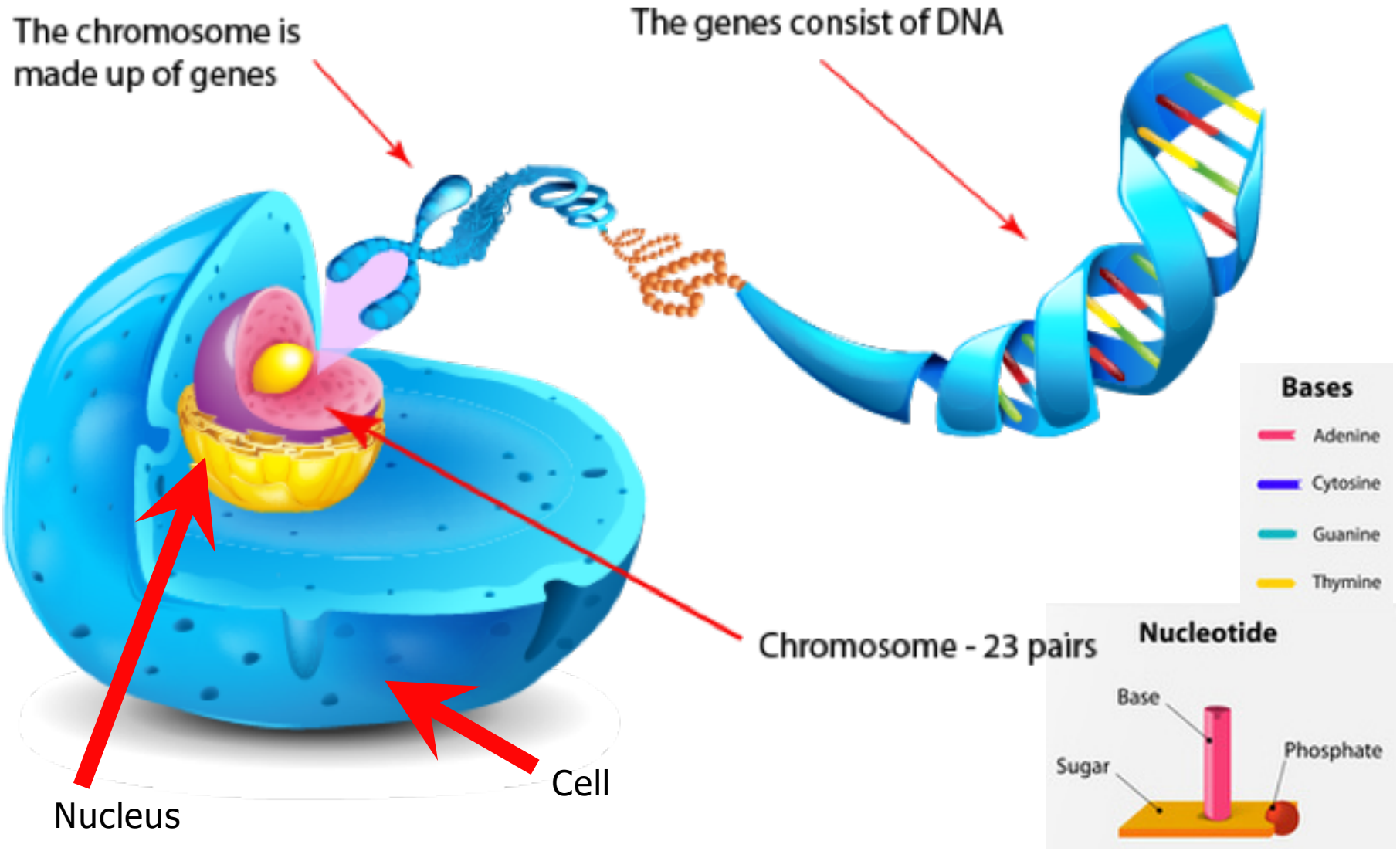
Graphics and Vision Processing

Broad research spanning apps, systems, logic with architecture at the center

Our Dream

- An embedded device that performs complex genome analysis in real time

What Is a Genome Made Of?



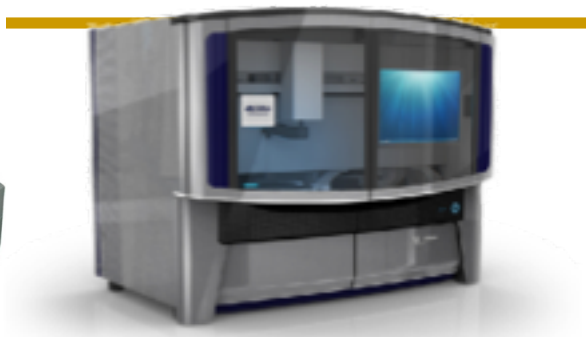
DNA Sequencing

- Goal:
  - Find the complete sequence of A, C, G, T's in DNA.
- Challenge:
  - There is no machine that takes long DNA as an input, and gives the complete sequence as output
  - All sequencing machines chop DNA into pieces and identify relatively small pieces (but not how they fit together)

Untangling Yarn Balls & DNA Sequencing

Genome Sequencers

Roche/454



AB SOLiD

Illumina MiSeq

Complete Genomics

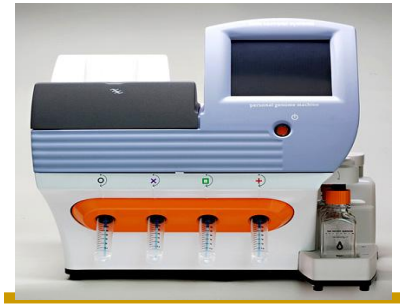
Oxford Nanopore MinION

Illumina HiSeq2000

Pacific Biosciences RS

Oxford Nanopore GridION

Illumina NovaSeq 6000

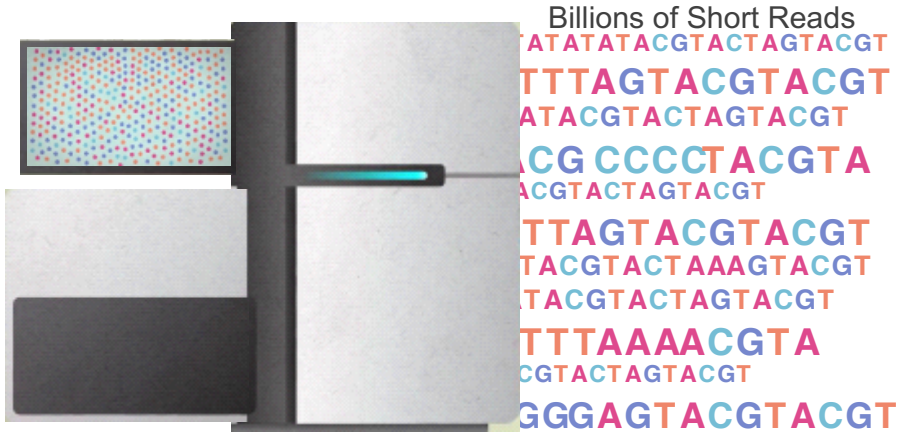


Ion Torrent PGM

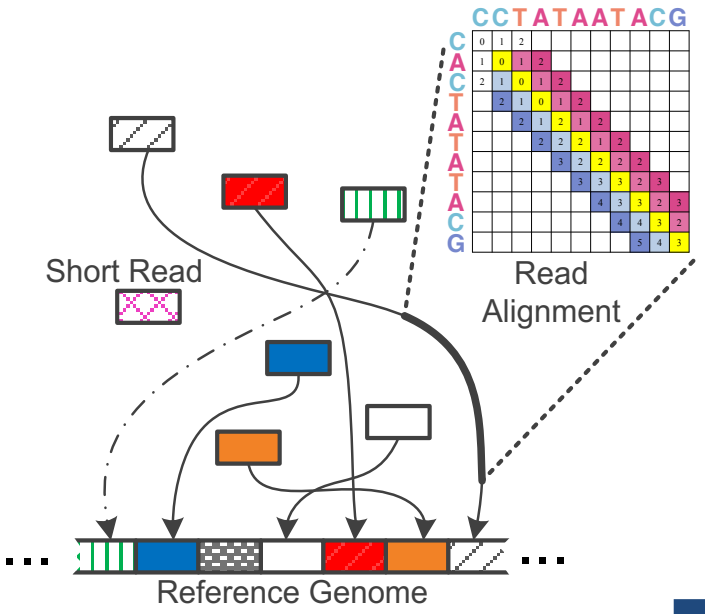
Ion Torrent Proton

SAFARI

… and more! All produce data with different properties.

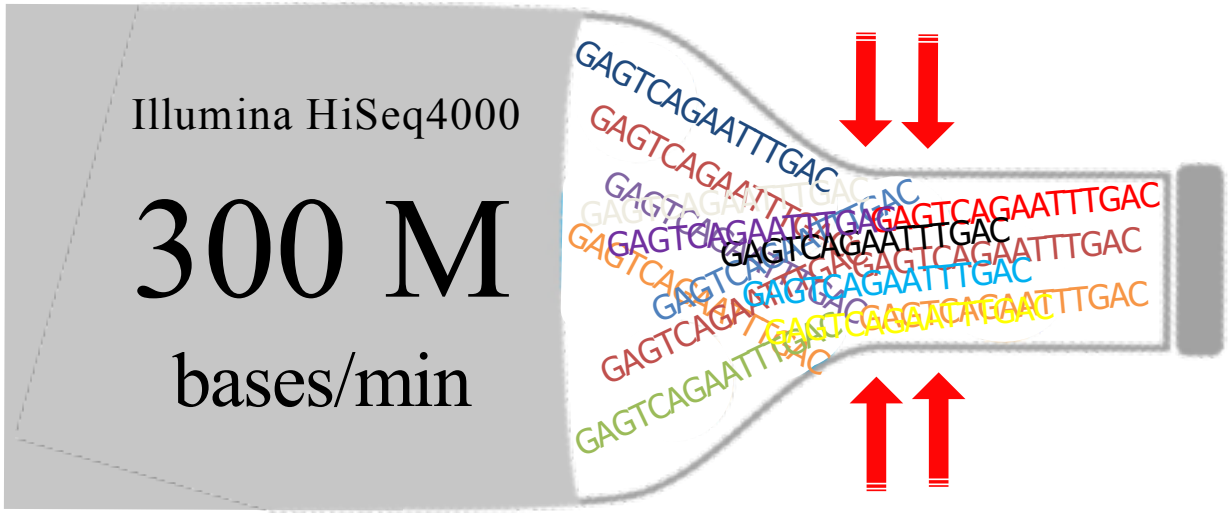


1 Sequencing



Read Mapping 2

Bottlenecked in Mapping!!



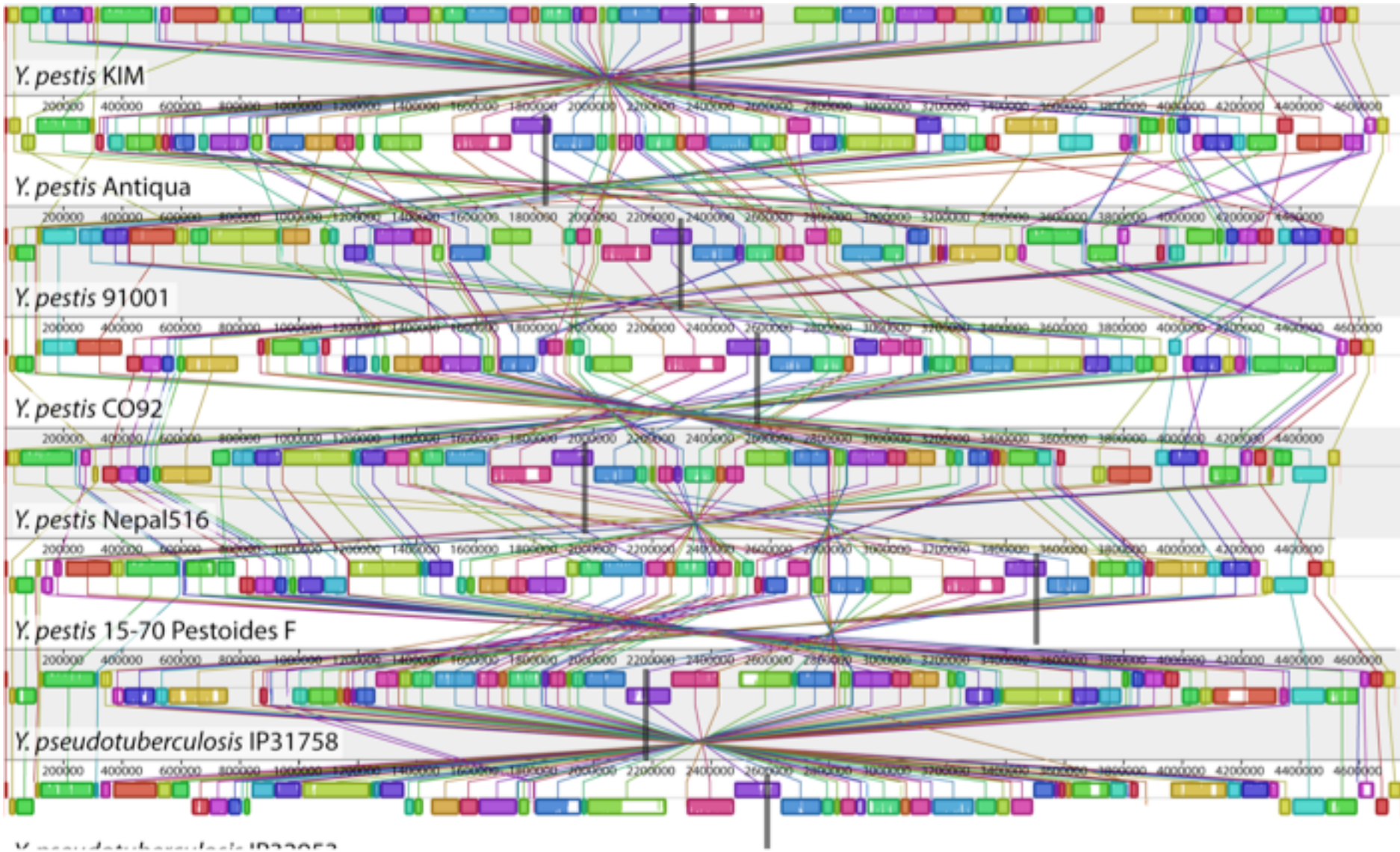
on average

2 M

bases/min

(0.6%)

Genome Sequence Alignment: Example



Source: By Aaron E. Darling, István Miklós, Mark A. Ragan - Figure 1 from Darling AE, Miklós I, Ragan MA (2008). "Dynamics of Genome Rearrangement in Bacterial Populations". PLOS Genetics. DOI:10.1371/journal.pgen.1000128., CC BY 2.5, https://commons.wikimedia.org/w/index.php?curid=30550950

Hash Table Based Read Mappers

- + Guaranteed to find *all* mappings → sensitive
- + Can tolerate up to *e* errors

nature genetics

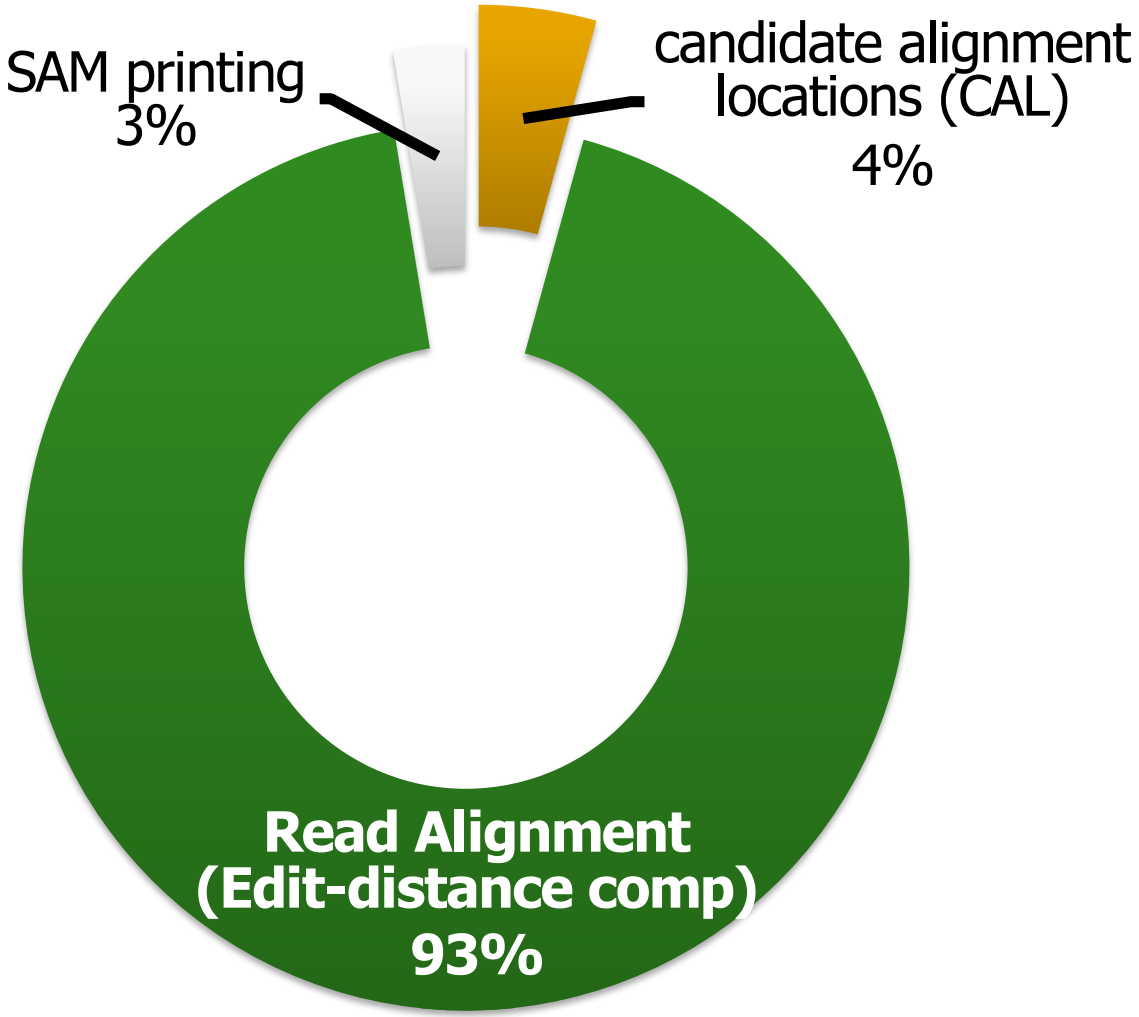
http://mrfast.sourceforge.net/

Personalized copy number and segmental duplication maps using next-generation sequencing

Can Alkan[1,2], Jeffrey M Kidd[1], Tomas Marques-Bonet[1,3], Gozde Aksay[1], Francesca Antonacci[1], Fereydoun Hormozdiari[4], Jacob O Kitzman[1], Carl Baker[1], Maika Malig[1], Onur Mutlu[5], S Cenk Sahinalp[4], Richard A Gibbs[6] & Evan E Eichler[1,2]

Alkan+, **"Personalized copy number and segmental duplication maps using next-generation sequencing"**, Nature Genetics 2009.

Read Mapping Execution Time Breakdown



Idea

Filter fast before you align

Minimize costly
"approximate string comparisons"

Our First Filter: Pure Software Approach

- Download source code and try for yourself
  - Download link to FastHASH

Xin *et al. BMC Genomics* 2013, **14**(Suppl 1):S13
http://www.biomedcentral.com/1471-2164/14/S1/S13

BMC Genomics

PROCEEDINGS Open Access

Accelerating read mapping with FastHASH

Hongyi Xin[1], Donghyuk Lee[1], Farhad Hormozdiari[2], Samihan Yedkar[1], Onur Mutlu[1*], Can Alkan[3*]

From The Eleventh Asia Pacific Bioinformatics Conference (APBC 2013)
Vancouver, Canada. 21-24 January 2013

Shifted Hamming Distance: SIMD Acceleration

Bioinformatics, 31(10), 2015, 1553–1560
doi: 10.1093/bioinformatics/btu856
Advance Access Publication Date: 10 January 2015
Original Paper

Sequence analysis

Shifted Hamming distance: a fast and accurate SIMD-friendly filter to accelerate alignment verification in read mapping

Hongyi Xin[1,*], John Greth[2], John Emmons[2], Gennady Pekhimenko[1], Carl Kingsford[3], Can Alkan[4,*] and Onur Mutlu[2,*]

Xin+, **"Shifted Hamming Distance: A Fast and Accurate SIMD-friendly Filter to Accelerate Alignment Verification in Read Mapping", Bioinformatics 2015.**

An Example Solution: GateKeeper

1 **High throughput DNA sequencing (HTS) technologies**

2 **Read Pre-Alignment Filtering**
Fast & Low False Positive Rate

3 **Read Alignment**
Slow & Zero False Positives

FPGA-Based Alignment Filtering

- Mohammed Alser, Hasan Hassan, Hongyi Xin, Oguz Ergin, Onur Mutlu, and Can Alkan

  "GateKeeper: A New Hardware Architecture for Accelerating Pre-Alignment in DNA Short Read Mapping" ***Bioinformatics***, [published online, May 31], 2017.
  [Source Code]
  [Online link at Bioinformatics Journal]

GateKeeper: a new hardware architecture for accelerating pre-alignment in DNA short read mapping

Mohammed Alser ✉, Hasan Hassan, Hongyi Xin, Oğuz Ergin, Onur Mutlu ✉, Can Alkan ✉

Bioinformatics, Volume 33, Issue 21, 1 November 2017, Pages 3355–3363,
https://doi.org/10.1093/bioinformatics/btx342

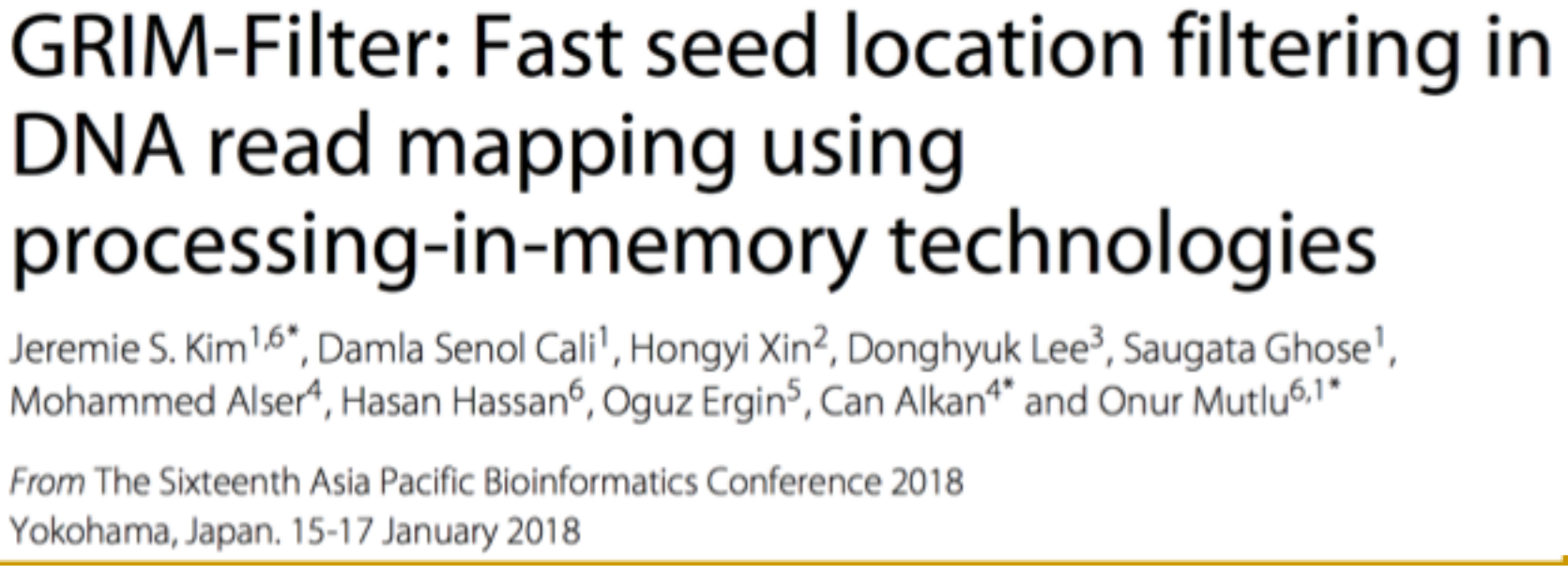
Published: 31 May 2017 **Article history** ▾

DNA Read Mapping & Filtering

- Problem: **Heavily bottlenecked by Data Movement**
- GateKeeper FPGA performance limited by DRAM bandwidth [Alser+, Bioinformatics 2017]
- Ditto for SHD on SIMD [Xin+, Bioinformatics 2015]
- Solution: Processing-in-memory can alleviate the bottleneck
- However, we need to design mapping & filtering algorithms to fit processing-in-memory

In-Memory DNA Sequence Analysis

- Jeremie S. Kim, Damla Senol Cali, Hongyi Xin, Donghyuk Lee, Saugata Ghose, Mohammed Alser, Hasan Hassan, Oguz Ergin, Can Alkan, and Onur Mutlu, **"GRIM-Filter: Fast Seed Location Filtering in DNA Read Mapping Using Processing-in-Memory Technologies"**
  BMC Genomics, 2018.
  *Proceedings of the 16th Asia Pacific Bioinformatics Conference (**APBC**)*, Yokohama, Japan, January 2018.
  arxiv.org Version (pdf)



GRIM-Filter: Fast seed location filtering in DNA read mapping using processing-in-memory technologies

Jeremie S. Kim[1,6*], Damla Senol Cali[1], Hongyi Xin[2], Donghyuk Lee[3], Saugata Ghose[1], Mohammed Alser[4], Hasan Hassan[6], Oguz Ergin[5], Can Alkan[4*] and Onur Mutlu[6,1*]

From The Sixteenth Asia Pacific Bioinformatics Conference 2018
Yokohama, Japan. 15-17 January 2018

New Genome Sequencing Technologies

Nanopore sequencing technology and tools for genome assembly: computational analysis of the current state, bottlenecks and future directions

Damla Senol Cali ✉, Jeremie S Kim, Saugata Ghose, Can Alkan, Onur Mutlu

Briefings in Bioinformatics, bby017, https://doi.org/10.1093/bib/bby017
Published: 02 April 2018 **Article history** ▾

Oxford Nanopore MinION

Senol Cali+, "**Nanopore Sequencing Technology and Tools for Genome Assembly: Computational Analysis of the Current State, Bottlenecks and Future Directions**," Briefings in Bioinformatics, 2018.

[Preliminary arxiv.org version]

Nanopore Genome Assembly Pipeline

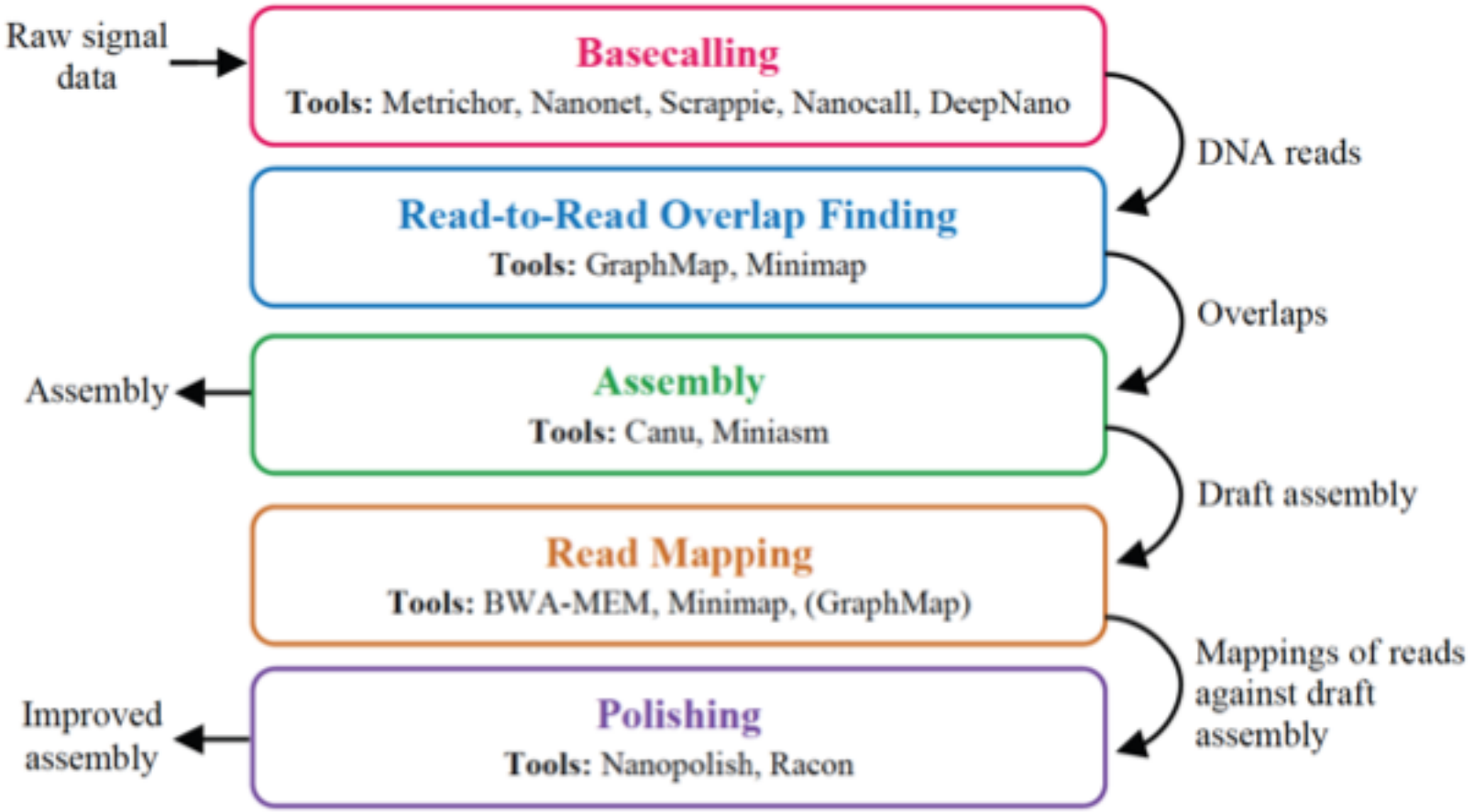


Figure 1. The analyzed genome assembly pipeline using nanopore sequence data, with its five steps and the associated tools for each step.

Senol Cali+, "**Nanopore Sequencing Technology and Tools for Genome Assembly,**" Briefings in Bioinformatics, 2018.

More on Genome Analysis: Another Talk

Accelerating Genome Analysis

A Primer on an Ongoing Journey

Onur Mutlu
omutlu@gmail.com
https://people.inf.ethz.ch/omutlu

May 21, 2018

HiCOMB-17 Keynote Talk

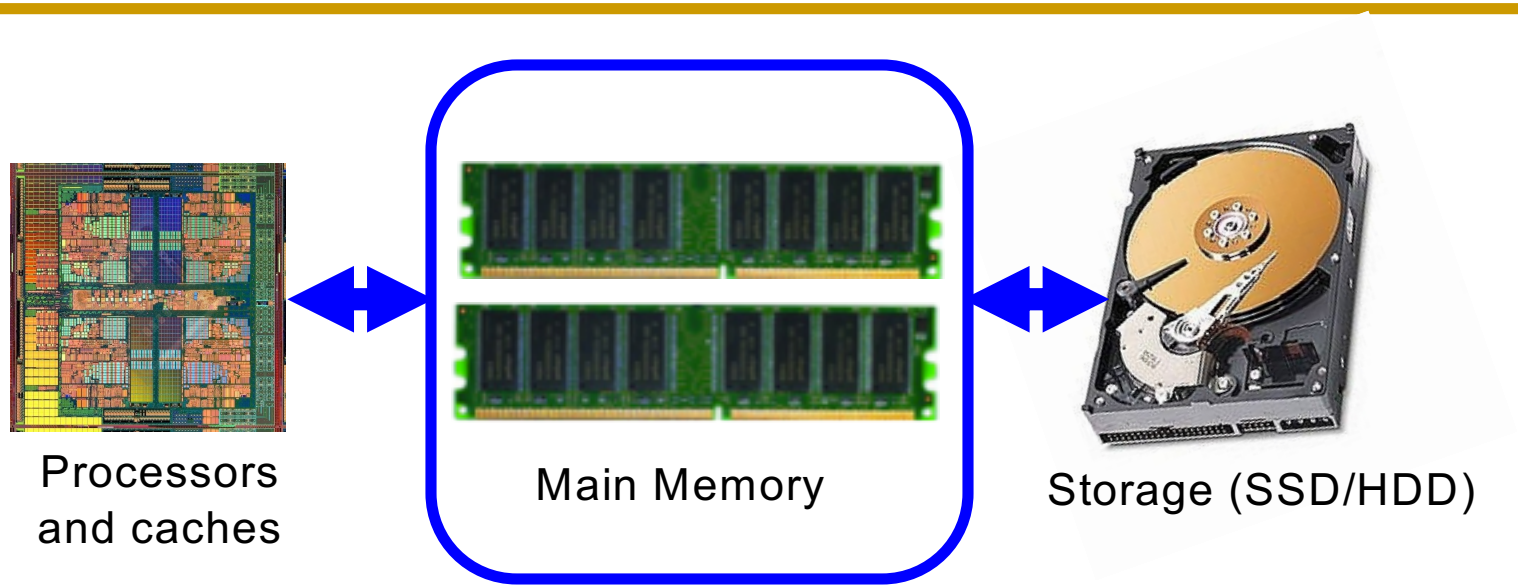
ETH zürich

Four Key Directions

- Fundamentally Secure/Reliable/Safe Architectures
- Fundamentally Energy-Efficient Architectures
  - Memory-centric (Data-centric) Architectures
- Fundamentally Low-Latency Architectures
- Architectures for Genomics, Medicine, Health

Memory & Storage

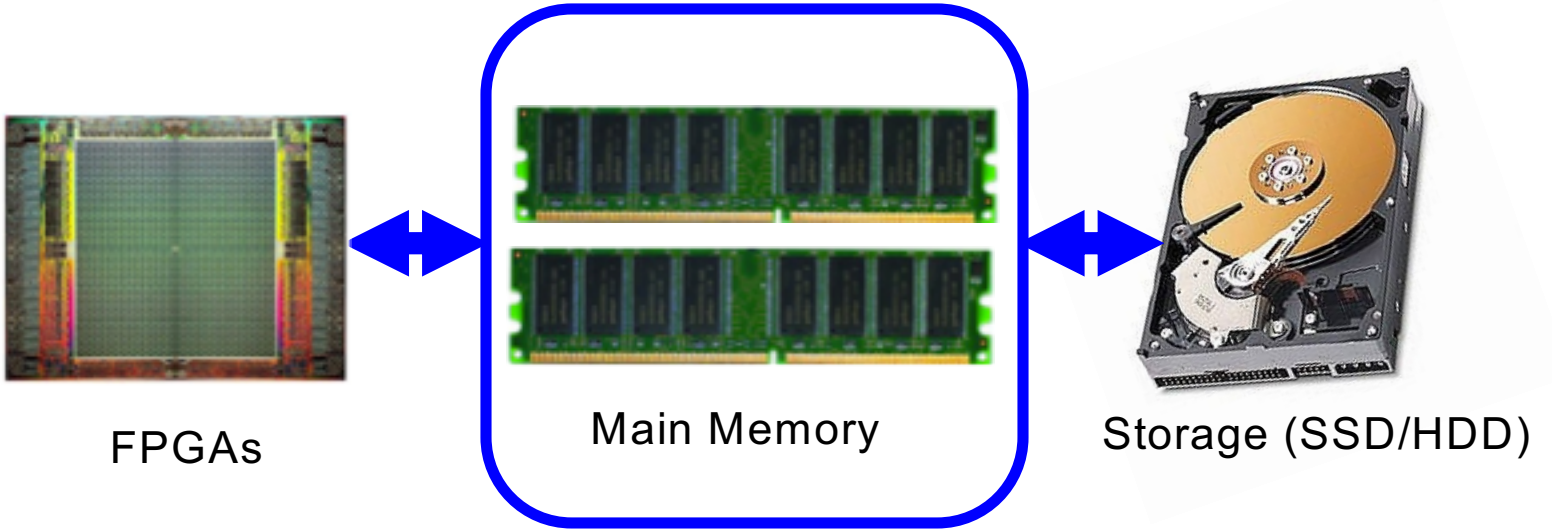
The Main Memory System



- Main memory is a critical component of all computing systems: server, mobile, embedded, desktop, sensor

- Main memory system must scale (in *size*, *technology*, *efficiency*, *cost*, and *management algorithms*) to maintain performance growth and technology scaling benefits

The Main Memory System



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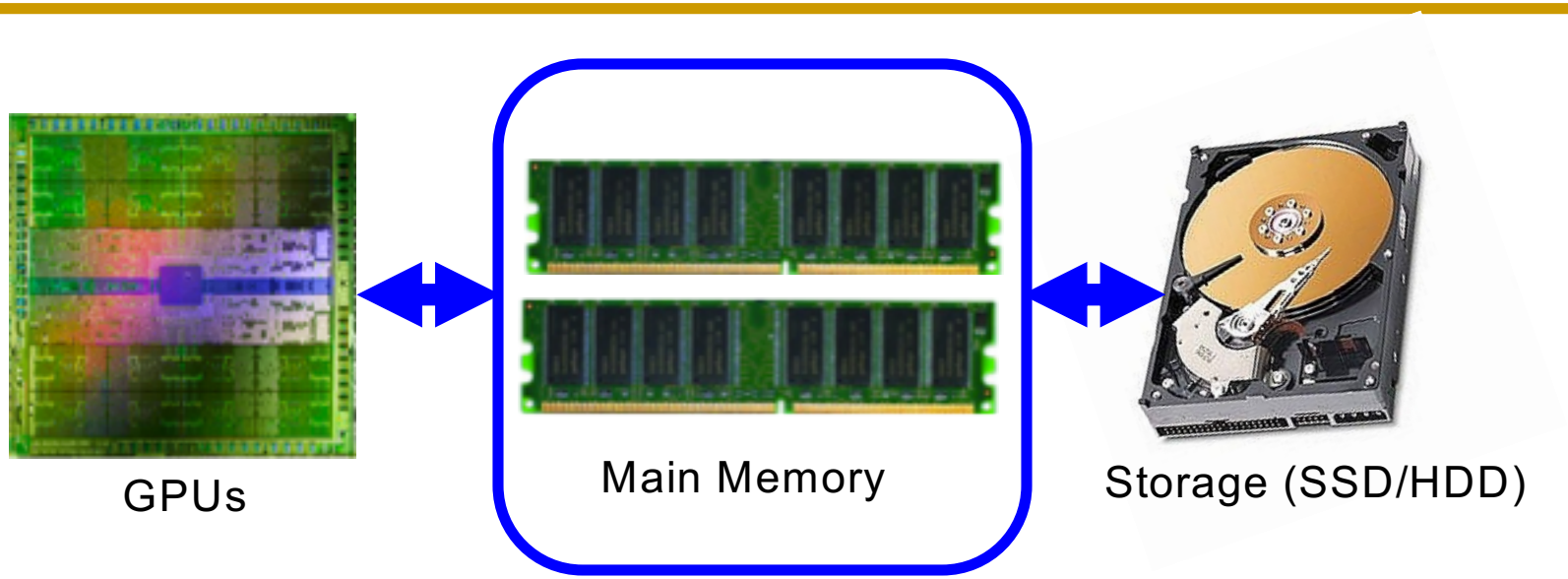

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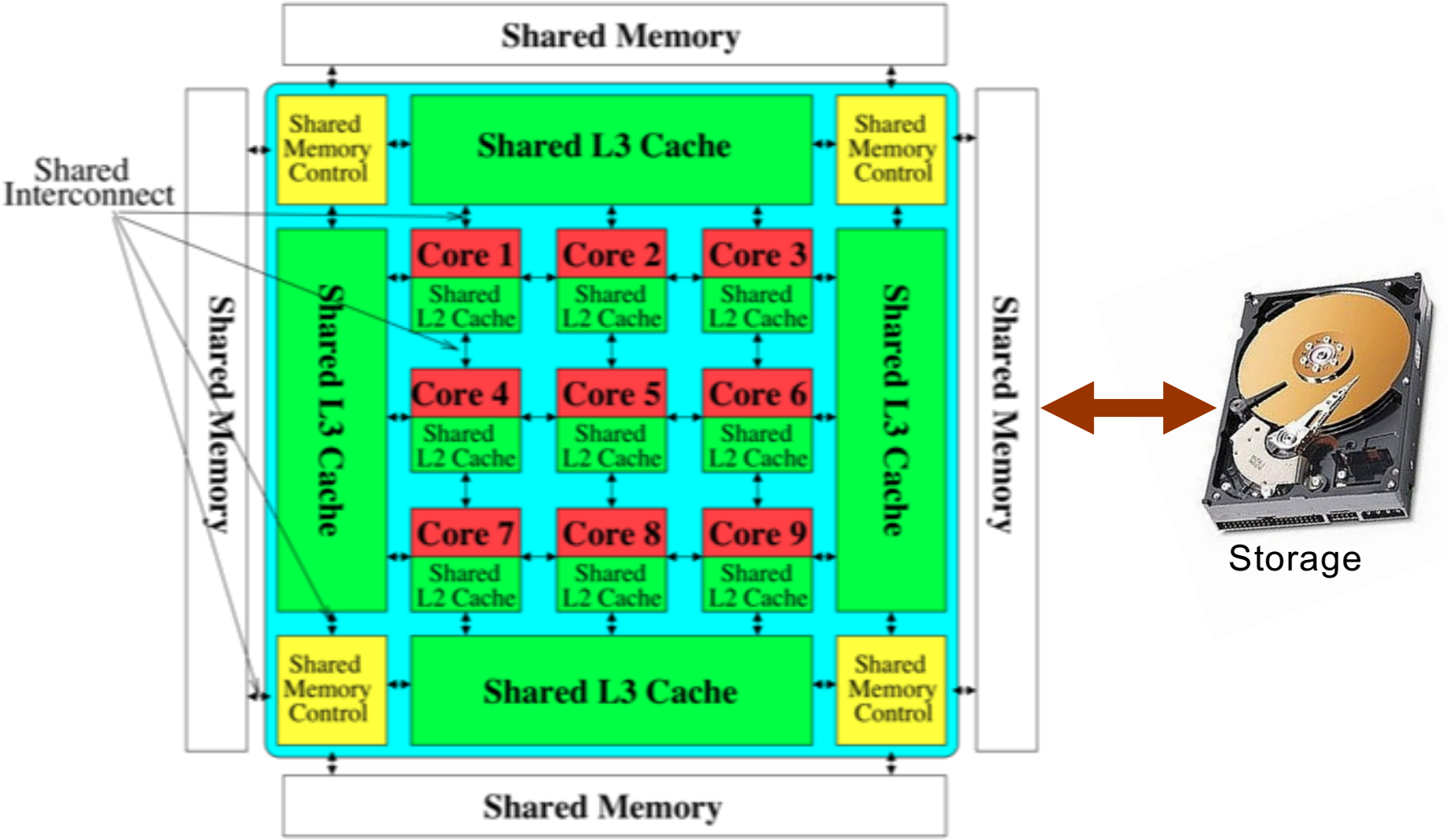
- Main memory system must scale (in *size*, *technology*, *efficiency*, *cost*, and *management algorithms*) to maintain performance growth and technology scaling benefits

Memory System: A *Shared Resource* View



Most of the system is dedicated to storing and moving data

State of the Main Memory System

- Recent technology, architecture, and application trends
  - lead to new requirements
  - exacerbate old requirements
- DRAM and memory controllers, as we know them today, are (will be) unlikely to satisfy all requirements
- Some emerging non-volatile memory technologies (e.g., PCM) enable new opportunities: memory+storage merging
- We need to rethink the main memory system
  - to fix DRAM issues and enable emerging technologies
  - to satisfy all requirements

Agenda

- Major Trends Affecting Main Memory
- Key Challenges and Solution Directions
  - Robustness: Reliability and Security
  - Low Latency/Energy and Latency/Energy/Reliability Tradeoffs
  - Energy and Performance: In-Memory Computation
- Concluding Remarks
- Summary

Major Trends Affecting Main Memory (I)

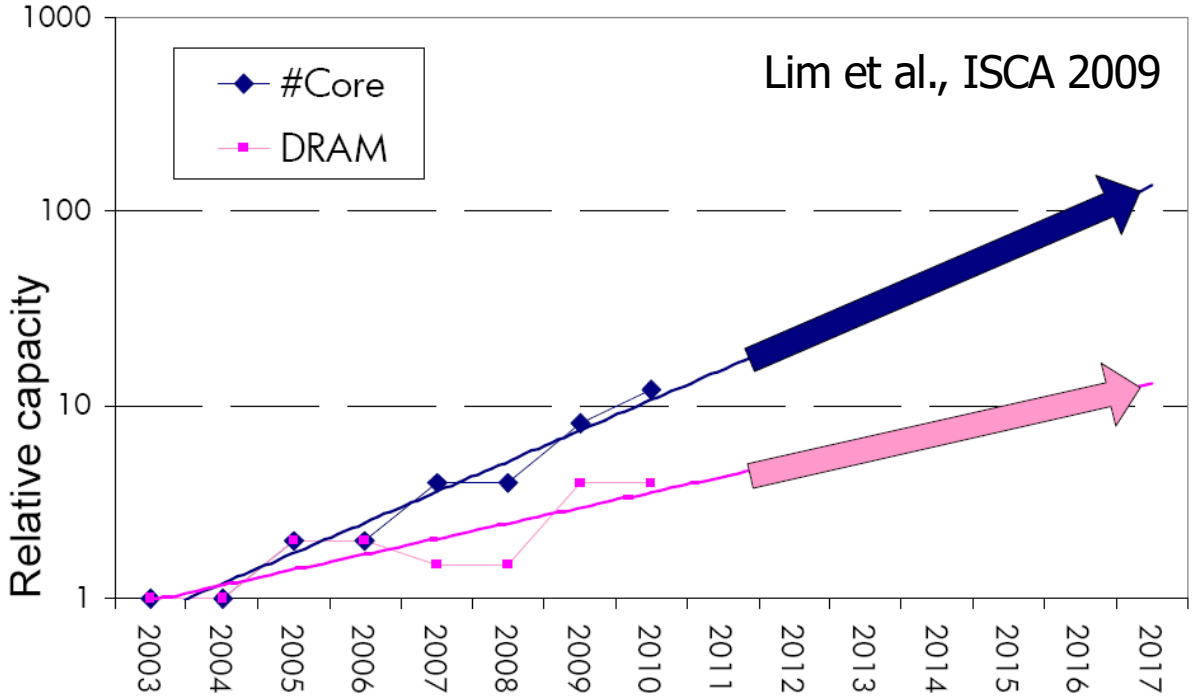
- Need for main memory capacity, bandwidth, QoS increasing
- Main memory energy/power is a key system design concern
- DRAM technology scaling is ending

Major Trends Affecting Main Memory (II)

- Need for main memory capacity, bandwidth, QoS increasing
  - Multi-core: increasing number of cores/agents
  - Data-intensive applications: increasing demand/hunger for data
  - Consolidation: cloud computing, GPUs, mobile, heterogeneity
- Main memory energy/power is a key system design concern
- DRAM technology scaling is ending

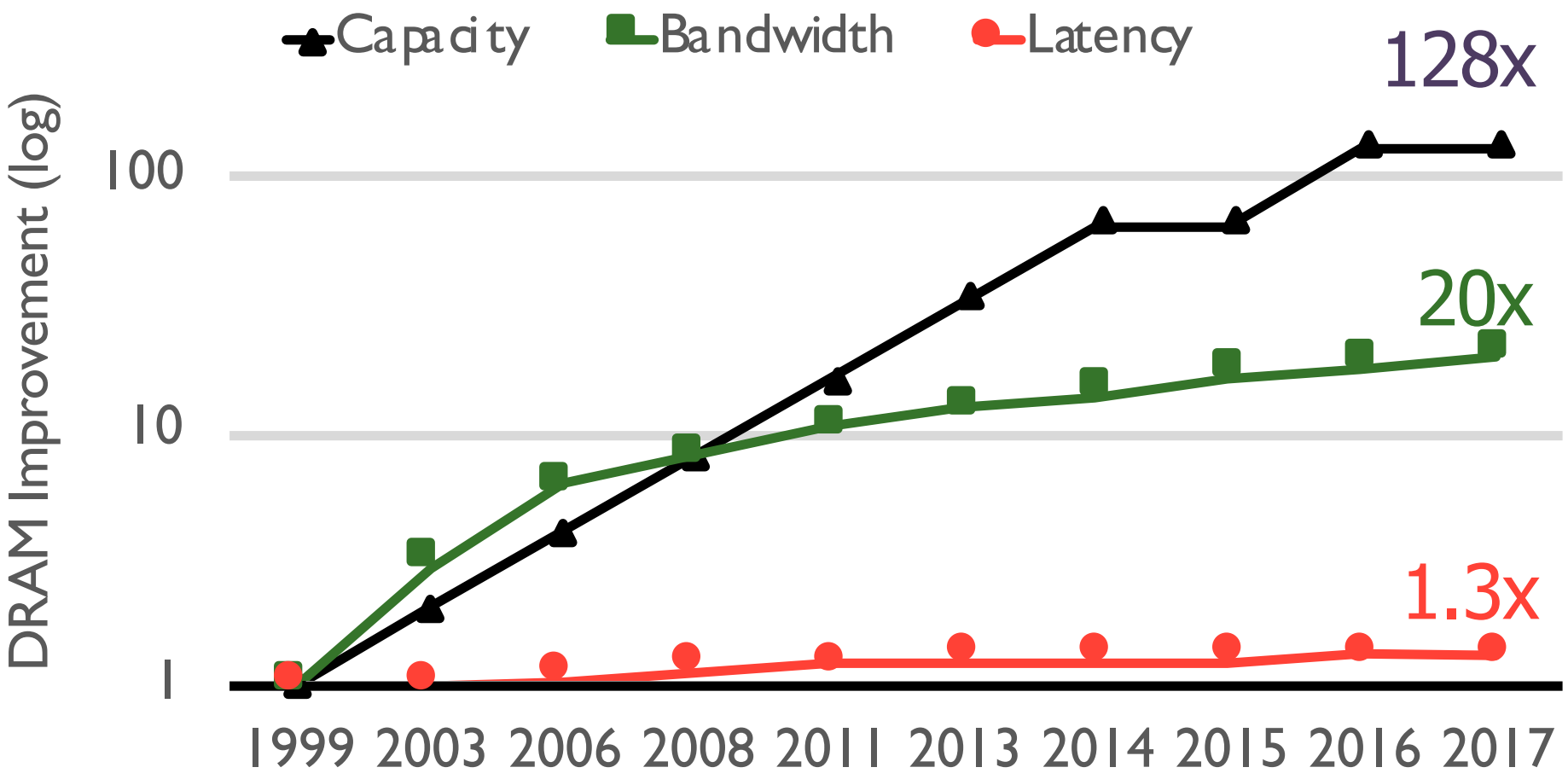
Example: The Memory Capacity Gap

Core count doubling ~ every 2 years
DRAM DIMM capacity doubling ~ every 3 years



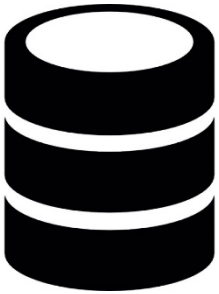
- *Memory capacity per core* expected to drop by 30% every two years
- Trends worse for *memory bandwidth per core*!

DRAM Capacity, Bandwidth, Latency Trends



Memory latency remains almost constant

DRAM Latency Is Critical for Performance



In-memory Databases

[Mao+, EuroSys'12;
Clapp+ (**Intel**), IISWC'15]

Graph/Tree Processing

[Xu+, IISWC'12; Umuroglu+, FPL'15]

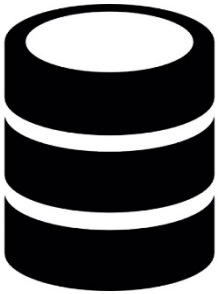
In-Memory Data Analytics

[Clapp+ (**Intel**), IISWC'15;
Awan+, BDCloud'15]

Datacenter Workloads

[Kanev+ (**Google**), ISCA'15]

DRAM Latency Is Critical for Performance



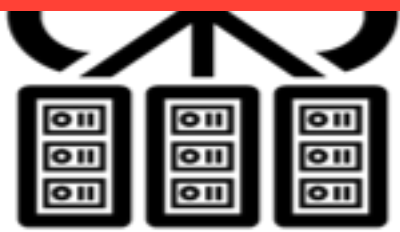
In-memory Databases

Graph/Tree Processing

Long memory latency → performance bottleneck

In-Memory Data Analytics

[Clapp+ (**Intel**), IISWC'15; Awan+, BDCloud'15]



Datacenter Workloads

[Kanev+ (**Google**), ISCA'15]

Major Trends Affecting Main Memory (III)

- Need for main memory capacity, bandwidth, QoS increasing

- Main memory energy/power is a key system design concern
  - ~40-50% energy spent in off-chip memory hierarchy [Lefurgy, IEEE Computer'03] >40% power in DRAM [Ware, HPCA'10][Paul,ISCA'15]
  - DRAM consumes power even when not used (periodic refresh)

- DRAM technology scaling is ending

Major Trends Affecting Main Memory (IV)

- Need for main memory capacity, bandwidth, QoS increasing

- Main memory energy/power is a key system design concern

- DRAM technology scaling is ending
  - ITRS projects DRAM will not scale easily below X nm
  - Scaling has provided many benefits:
    - higher capacity (density), lower cost, lower energy

Major Trends Affecting Main Memory (V)

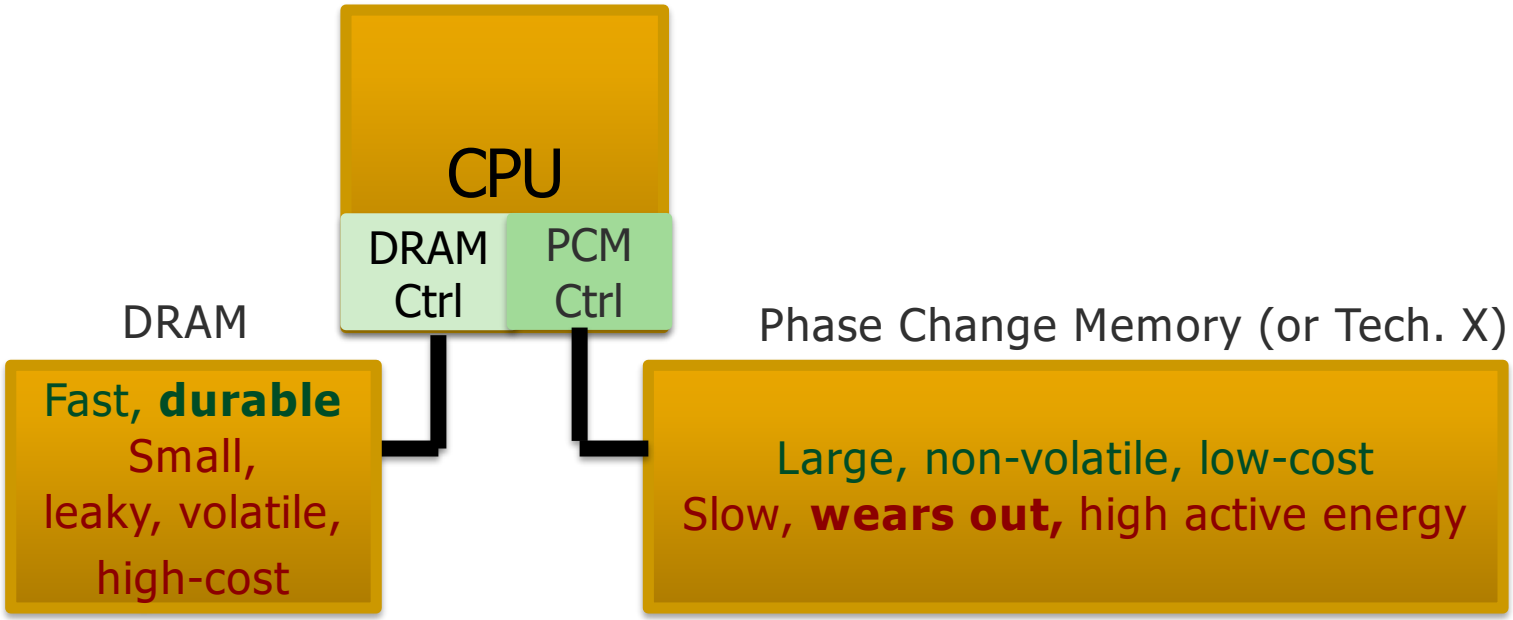
- DRAM scaling has already become increasingly difficult
  - Increasing cell leakage current, reduced cell reliability, increasing manufacturing difficulties [Kim+ ISCA 2014], [Liu+ ISCA 2013], [Mutlu IMW 2013], [Mutlu DATE 2017]
  - **Difficult to significantly improve capacity, energy**
- **Emerging memory technologies** are promising

Major Trends Affecting Main Memory (V)

- DRAM scaling has already become increasingly difficult
  - Increasing cell leakage current, reduced cell reliability, increasing manufacturing difficulties [Kim+ ISCA 2014], [Liu+ ISCA 2013], [Mutlu IMW 2013], [Mutlu DATE 2017]
  - **Difficult to significantly improve capacity, energy**
- **Emerging memory technologies** are promising

3D-Stacked DRAM	higher bandwidth	smaller capacity
Reduced-Latency DRAM (e.g., RL/TL-DRAM, FLY-RAM)	lower latency	higher cost
Low-Power DRAM (e.g., LPDDR3, LPDDR4, Voltron)	lower power	higher latency higher cost
Non-Volatile Memory (NVM) (e.g., PCM, STTRAM, ReRAM, 3D Xpoint)	larger capacity	higher latency higher dynamic power lower endurance

Major Trend: Hybrid Main Memory



Hardware/software manage data allocation and movement
to achieve the best of multiple technologies

Meza+, "Enabling Efficient and Scalable Hybrid Memories," IEEE Comp. Arch. Letters, 2012.
Yoon+, "Row Buffer Locality Aware Caching Policies for Hybrid Memories," ICCD 2012 Best Paper Award.

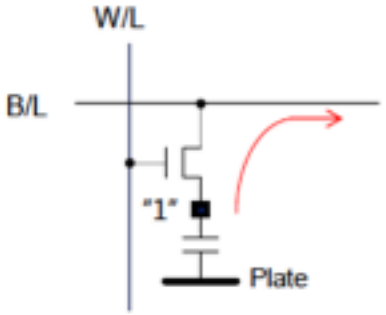
One Foreshadowing

Main Memory Needs Intelligent Controllers

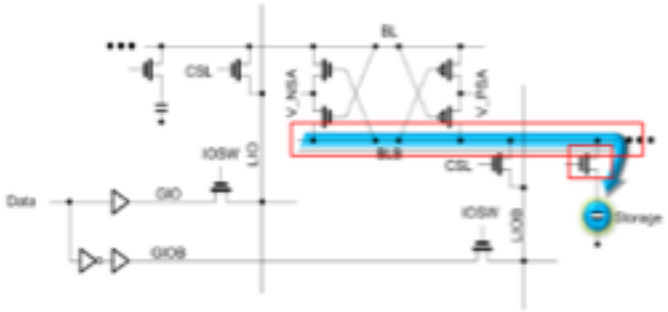
Industry Is Writing Papers About It, Too

DRAM Process Scaling Challenges

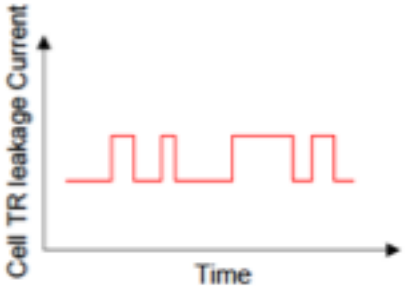
- **Refresh**
  - Difficult to build high-aspect ratio cell capacitors decreasing cell capacitance
  - Leakage current of cell access transistors increasing
- **tWR**
  - Contact resistance between the cell capacitor and access transistor increasing
  - On-current of the cell access transistor decreasing
  - Bit-line resistance increasing
- **VRT**
  - Occurring more frequently with cell capacitance decreasing



Refresh



tWR



VRT

Call for Intelligent Memory Controllers

DRAM Process Scaling Challenges

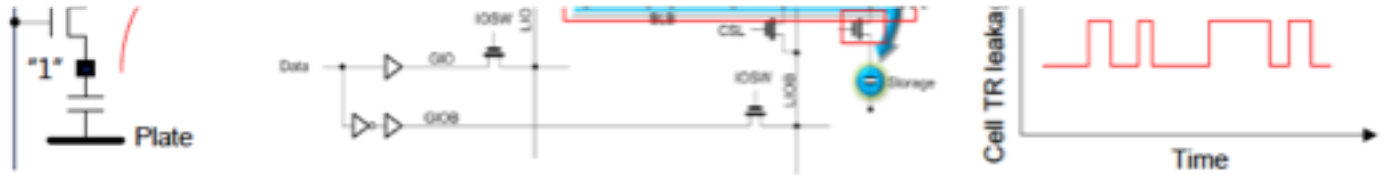
- **Refresh**
  - Difficult to build high-aspect ratio cell capacitors decreasing cell capacitance

THE MEMORY FORUM 2014

Co-Architecting Controllers and DRAM to Enhance DRAM Process Scaling

Uksong Kang, Hak-soo Yu, Churoo Park, *Hongzhong Zheng,
**John Halbert, **Kuljit Bains, SeongJin Jang, and Joo Sun Choi

*Samsung Electronics, Hwasung, Korea / *Samsung Electronics, San Jose / **Intel*



Refresh **tWR** **VRT**

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  - Low Latency/Energy and Latency/Energy/Reliability Tradeoffs
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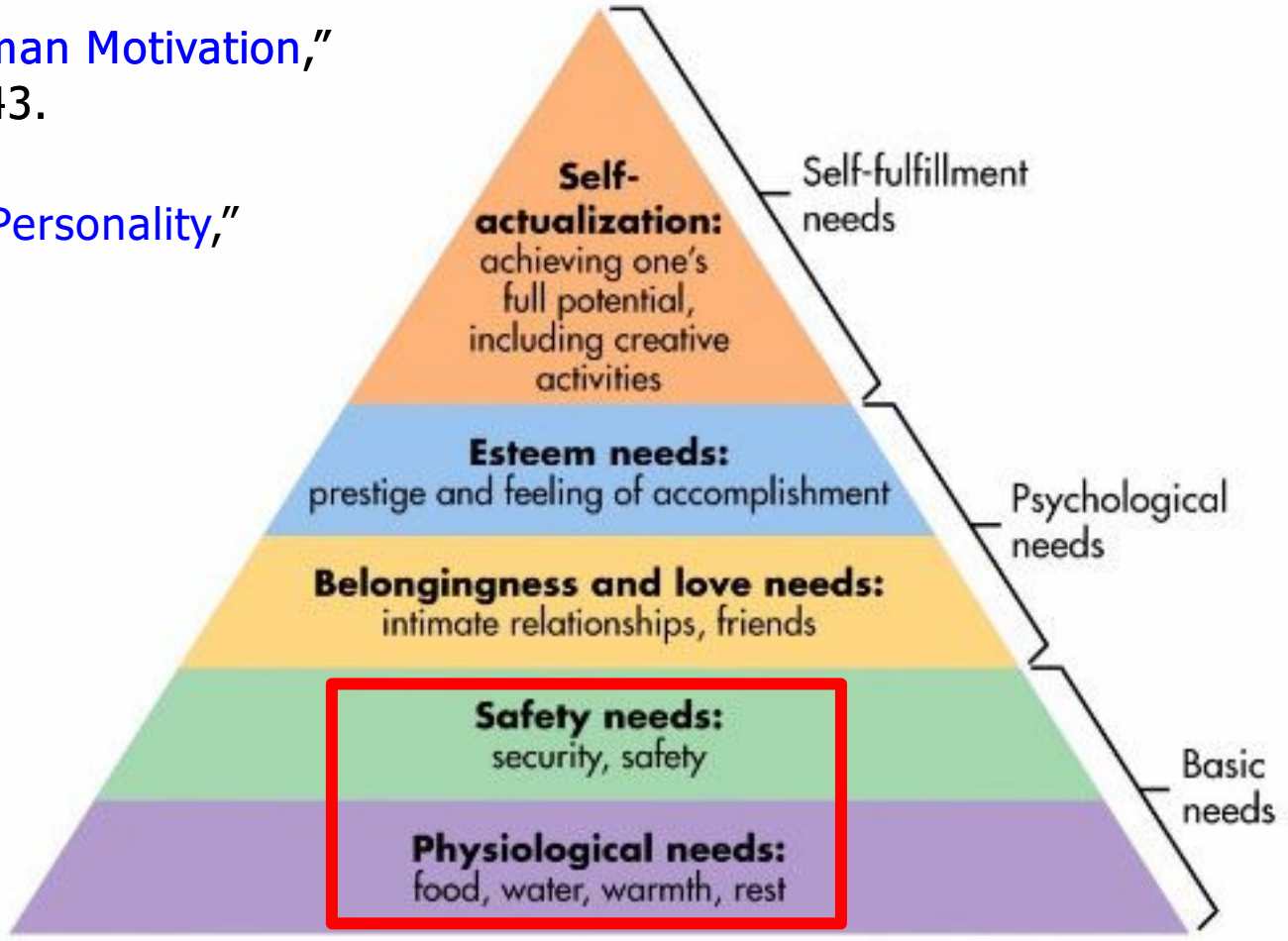
Four Key Issues in Future Platforms

- Fundamentally Secure/Reliable/Safe Architectures
- Fundamentally Energy-Efficient Architectures
  - Memory-centric (Data-centric) Architectures
- Fundamentally Low-Latency Architectures
- Architectures for Genomics, Medicine, Health

Maslow's (Human) Hierarchy of Needs

Maslow, "A Theory of Human Motivation," Psychological Review, 1943.

Maslow, "Motivation and Personality," Book, 1954-1970.



- We need to start with reliability and security…

Source: https://www.simplypsychology.org/maslow.html

How Reliable/Secure/Safe is This Bridge?

Source: http://www.technologystudent.com/struct1/tacom1.png

Collapse of the "Galloping Gertie"

Source: AP

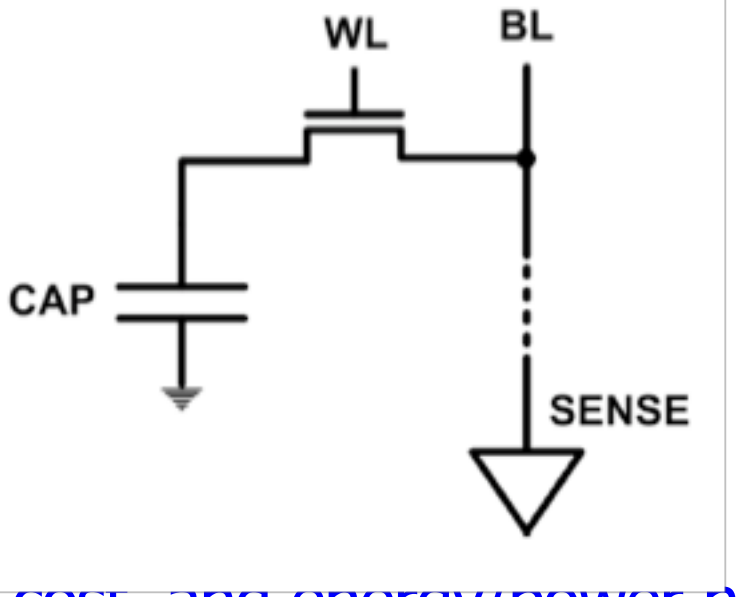
How Secure Are These People?

Security is about preventing unforeseen consequences

Source: https://s-media-cache-ak0.pinimg.com/originals/48/09/54/4809543a9c7700246a0cf8acdae27abf.jpg

The DRAM Scaling Problem

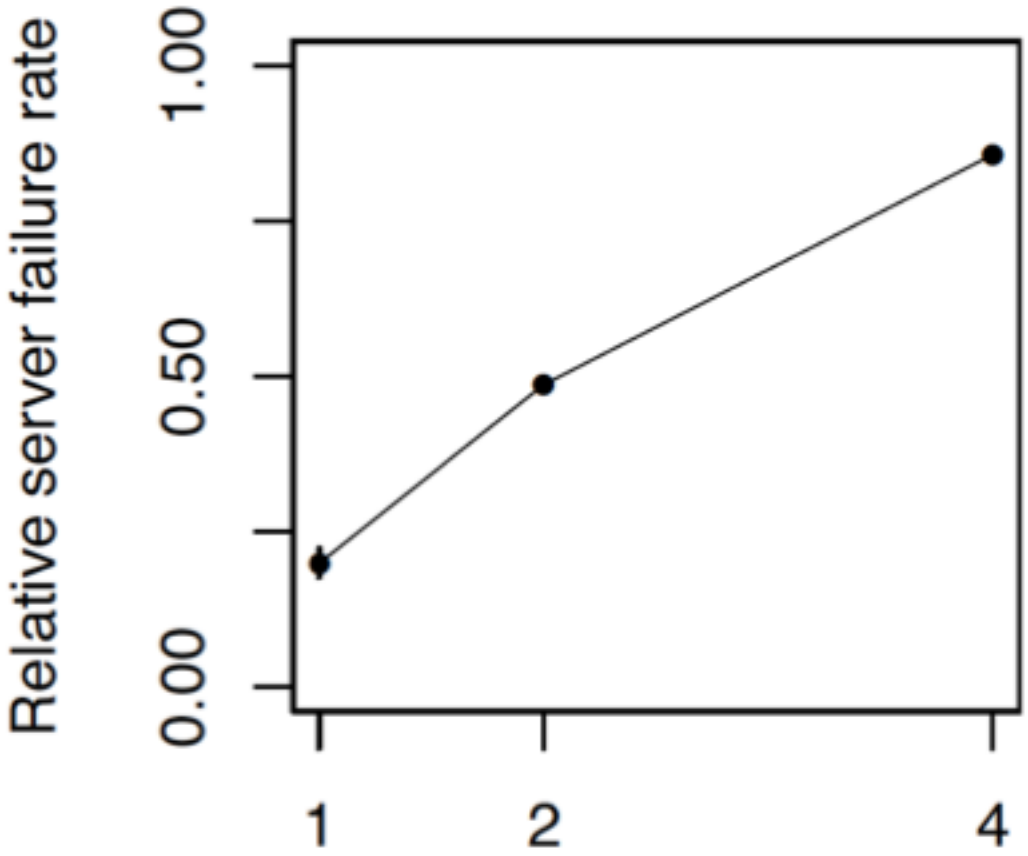
- DRAM stores charge in a capacitor (charge-based memory)
  - Capacitor must be large enough for reliable sensing
  - Access transistor should be large enough for low leakage and high retention time
  - Scaling beyond 40-35nm (2013) is challenging [ITRS, 2009]



- DRAM capacity, cost, and energy/power hard to scale

As Memory Scales, It Becomes Unreliable

- Data from all of Facebook's servers worldwide
- Meza+, "Revisiting Memory Errors in Large-Scale Production Data Centers," DSN'15.

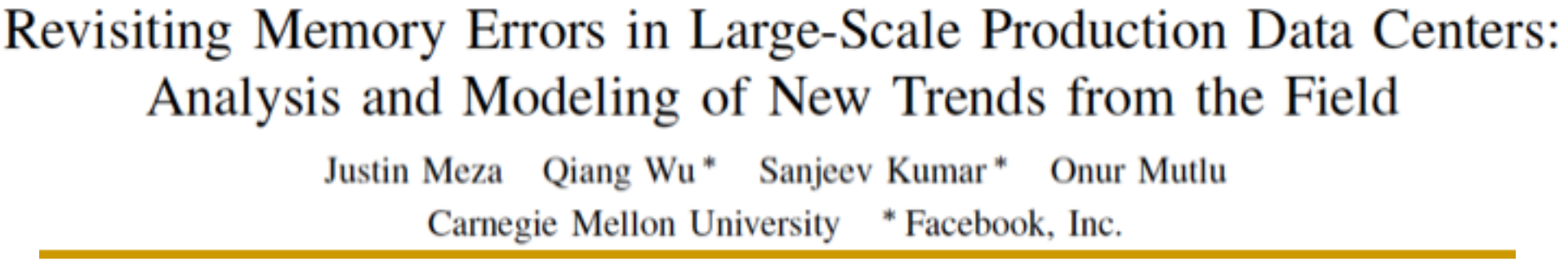


Intuition: quadratic increase in capacity

Large-Scale Failure Analysis of DRAM Chips

- Analysis and modeling of memory errors found in all of Facebook's server fleet

- Justin Meza, Qiang Wu, Sanjeev Kumar, and Onur Mutlu, **"Revisiting Memory Errors in Large-Scale Production Data Centers: Analysis and Modeling of New Trends from the Field"** *Proceedings of the 45th Annual IEEE/IFIP International Conference on Dependable Systems and Networks* (***DSN***), Rio de Janeiro, Brazil, June 2015.
  [Slides (pptx) (pdf)] [DRAM Error Model]


Revisiting Memory Errors in Large-Scale Production Data Centers: Analysis and Modeling of New Trends from the Field

Justin Meza Qiang Wu * Sanjeev Kumar * Onur Mutlu

Carnegie Mellon University * Facebook, Inc.

Infrastructures to Understand Such Issues

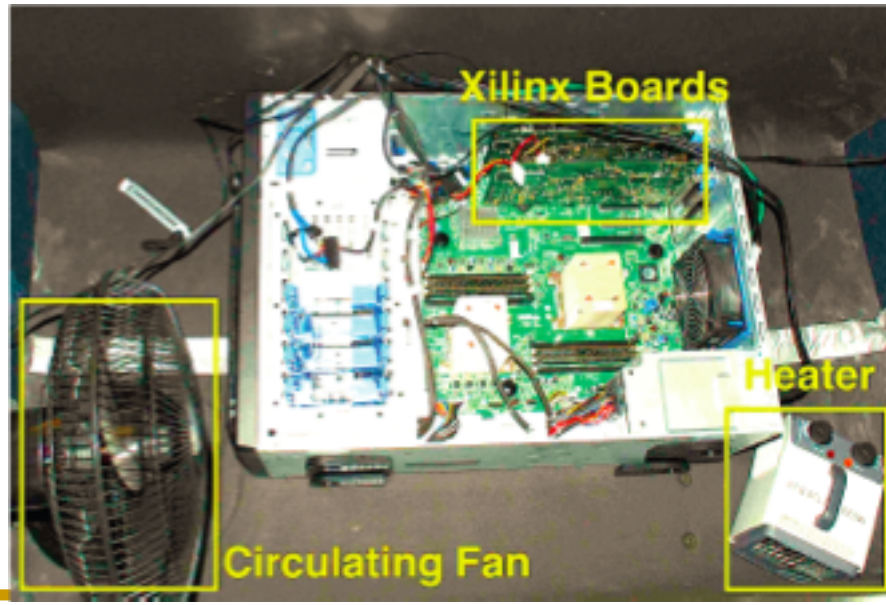
An Experimental Study of Data Retention Behavior in Modern DRAM Devices: Implications for Retention Time Profiling Mechanisms (Liu et al., ISCA 2013)

The Efficacy of Error Mitigation Techniques for DRAM Retention Failures: A Comparative Experimental Study (Khan et al., SIGMETRICS 2014)

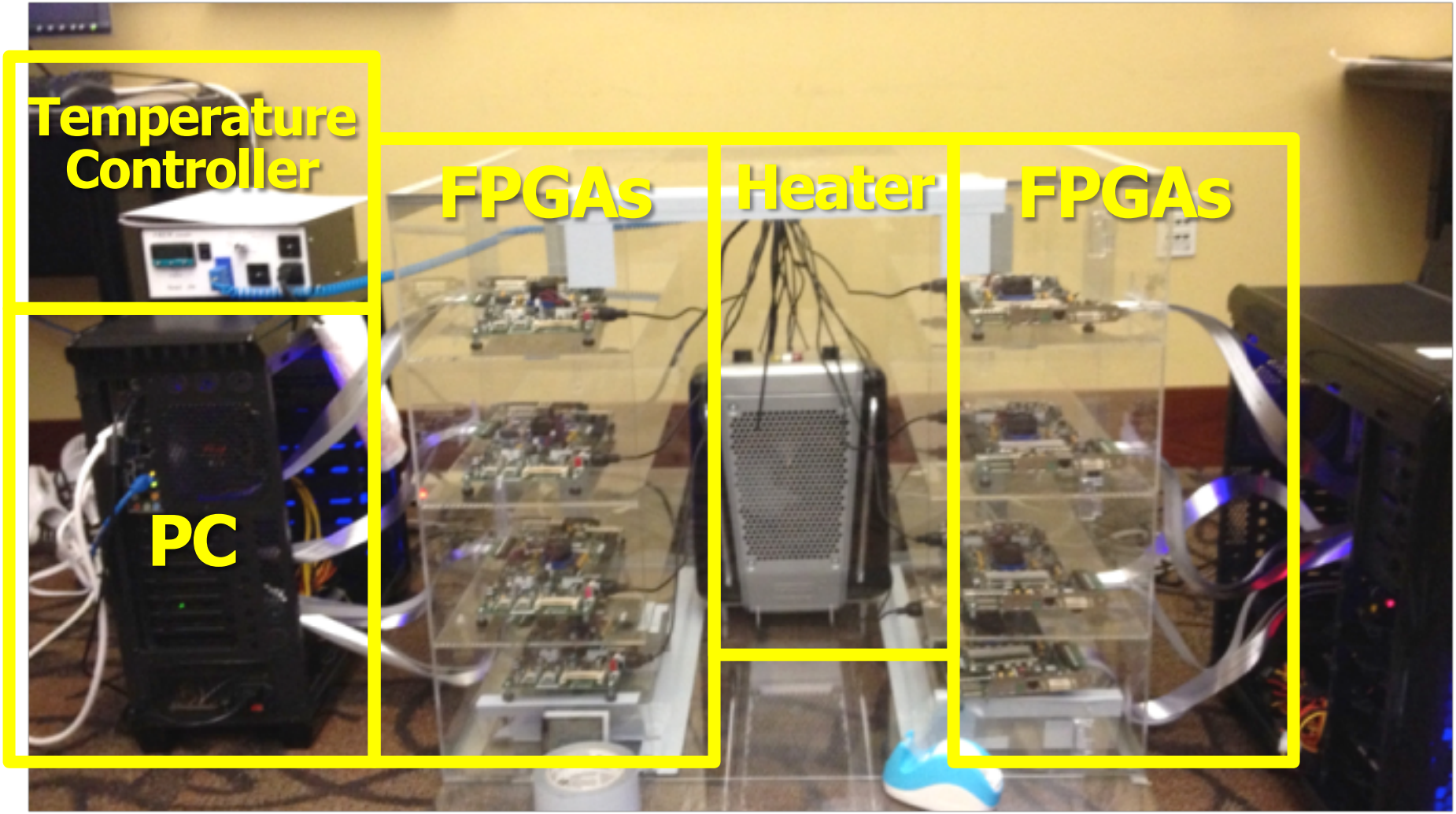
Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors (Kim et al., ISCA 2014)

Adaptive-Latency DRAM: Optimizing DRAM Timing for the Common-Case (Lee et al., HPCA 2015)

AVATAR: A Variable-Retention-Time (VRT) Aware Refresh for DRAM Systems (Qureshi et al., DSN 2015)



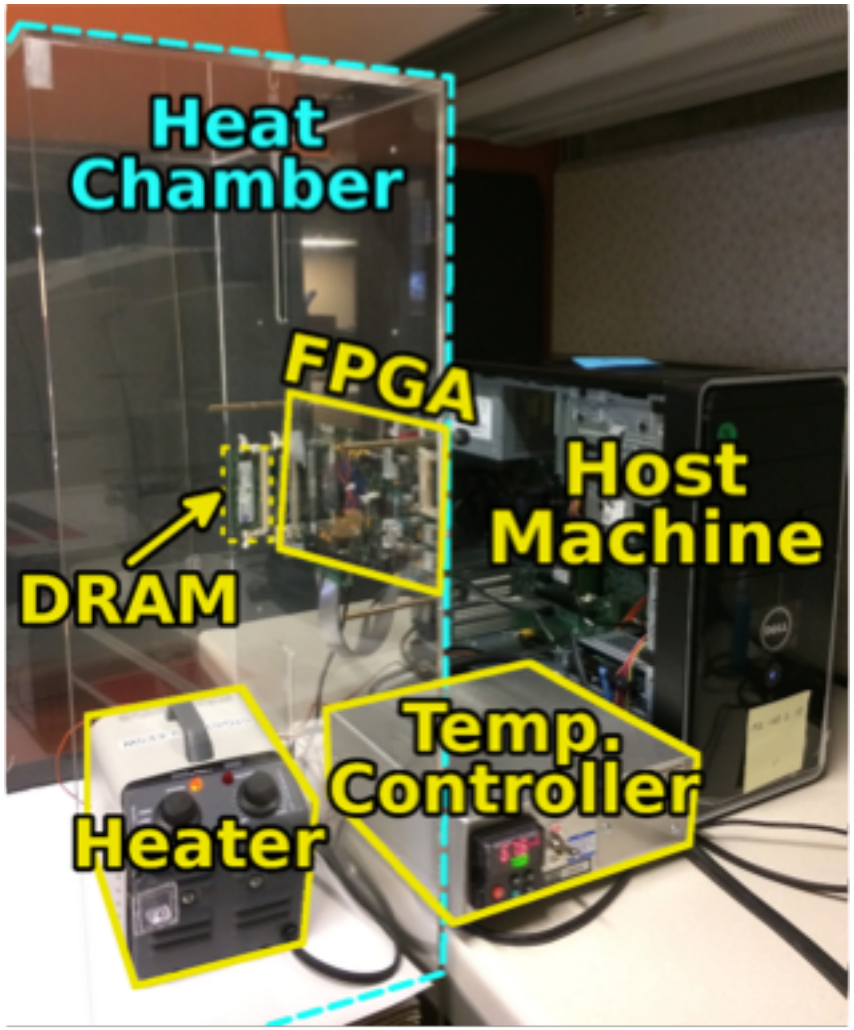
Infrastructures to Understand Such Issues



Kim+, "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors," ISCA 2014.

SoftMC: Open Source DRAM Infrastructure

- Hasan Hassan et al., "**SoftMC: A Flexible and Practical Open-Source Infrastructure for Enabling Experimental DRAM Studies**," HPCA 2017.



- **Flexible**
- **Easy to Use (C++ API)**
- **Open-source**

  github.com/CMU-SAFARI/SoftMC

SoftMC

- https://github.com/CMU-SAFARI/SoftMC

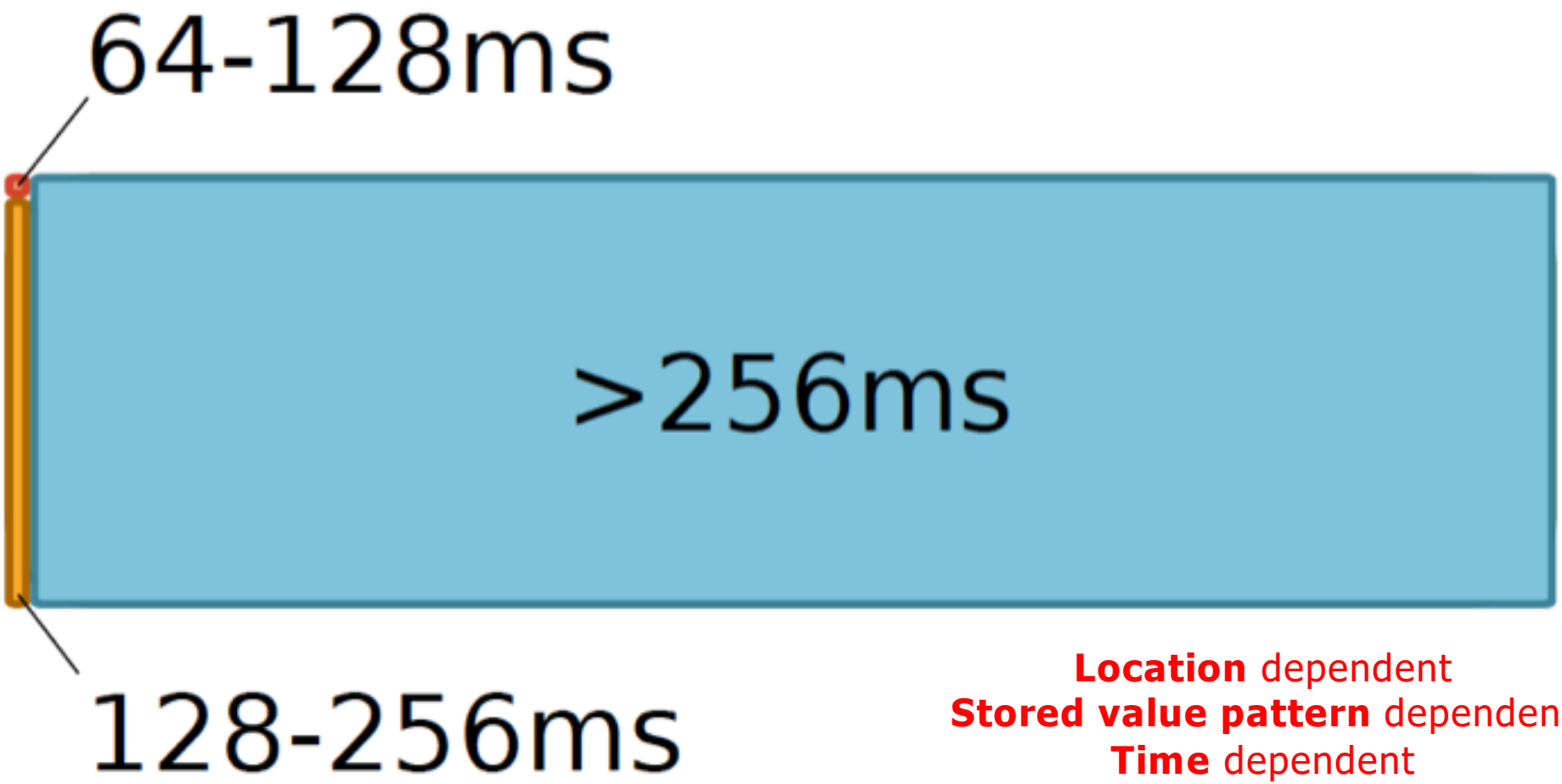
SoftMC: A Flexible and Practical Open-Source Infrastructure for Enabling Experimental DRAM Studies

Hasan Hassan[1,2,3] Nandita Vijaykumar[3] Samira Khan[4,3] Saugata Ghose[3] Kevin Chang[3]
Gennady Pekhimenko[5,3] Donghyuk Lee[6,3] Oguz Ergin[2] Onur Mutlu[1,3]

[1]*ETH Zürich* [2]*TOBB University of Economics & Technology* [3]*Carnegie Mellon University*
[4]*University of Virginia* [5]*Microsoft Research* [6]*NVIDIA Research*

Data Retention in Memory [Liu et al., ISCA 2013]

- Retention Time Profile of DRAM looks like this:



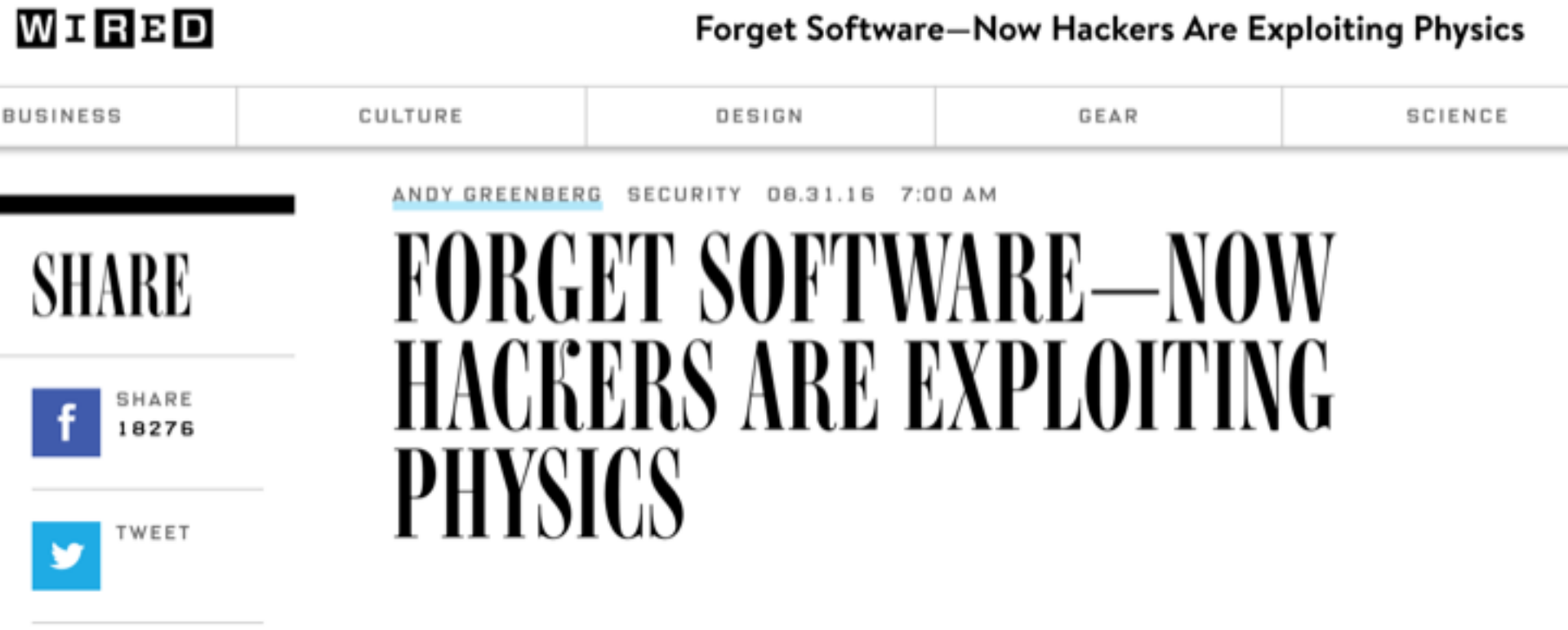
Location dependent
Stored value pattern dependent
Time dependent

A Curious Discovery [Kim et al., ISCA 2014]

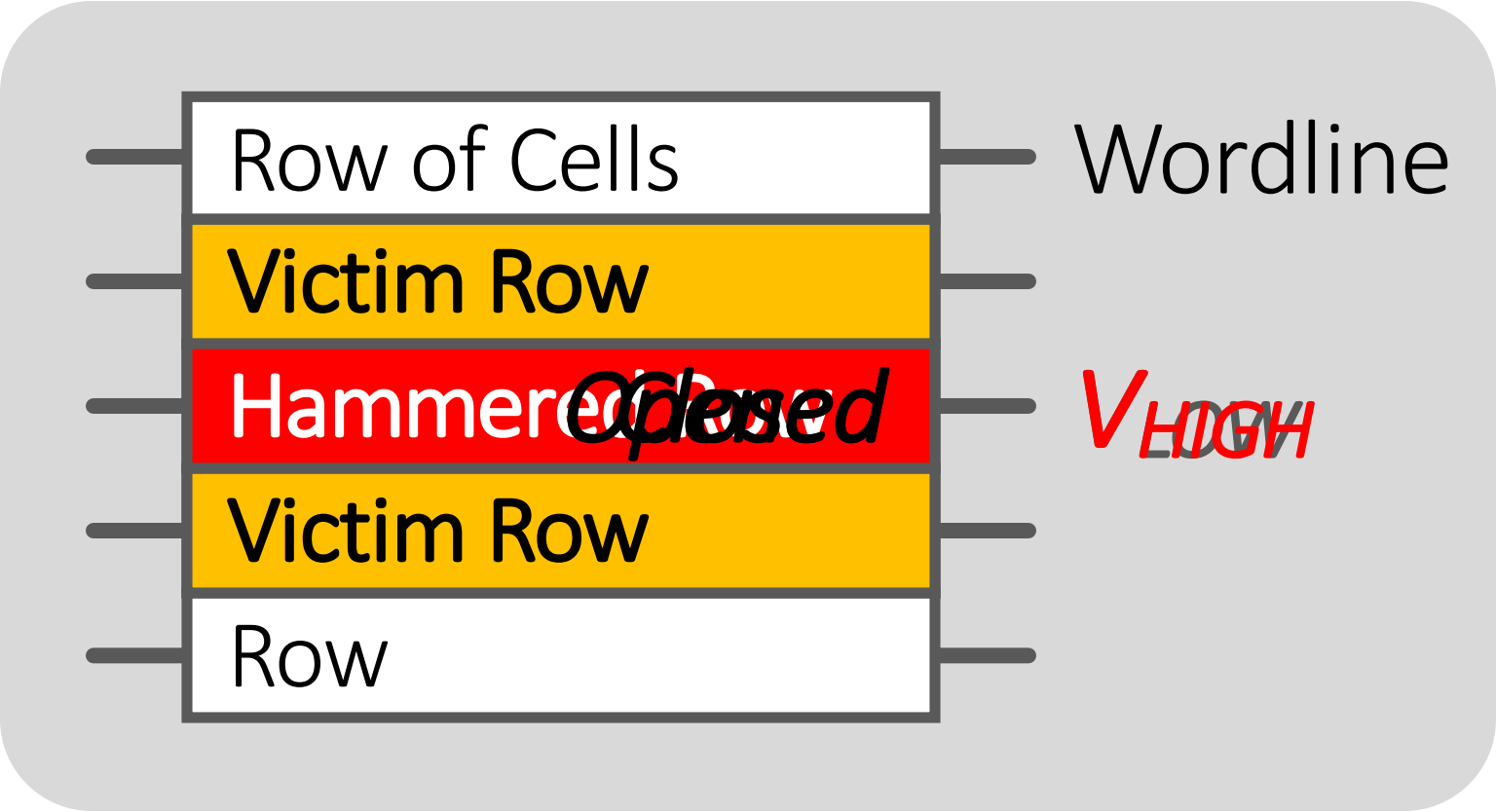
One can
predictably induce errors
in most DRAM memory chips

DRAM RowHammer

A simple hardware failure mechanism can create a widespread system security vulnerability



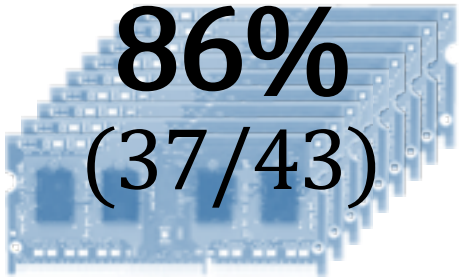
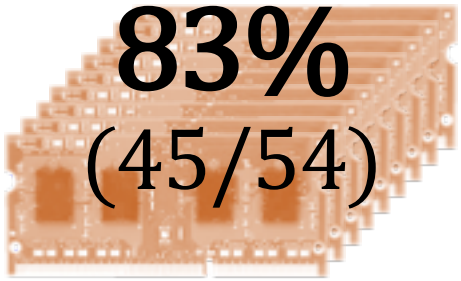
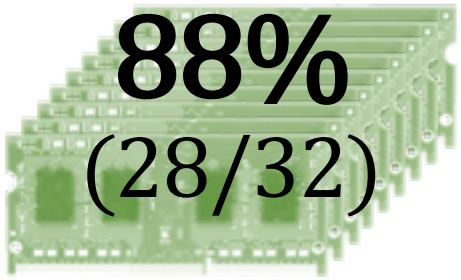
Modern DRAM is Prone to Disturbance Errors



Repeatedly reading a row enough times (before memory gets refreshed) induces **disturbance errors** in **adjacent rows** in **most real DRAM chips you can buy today**

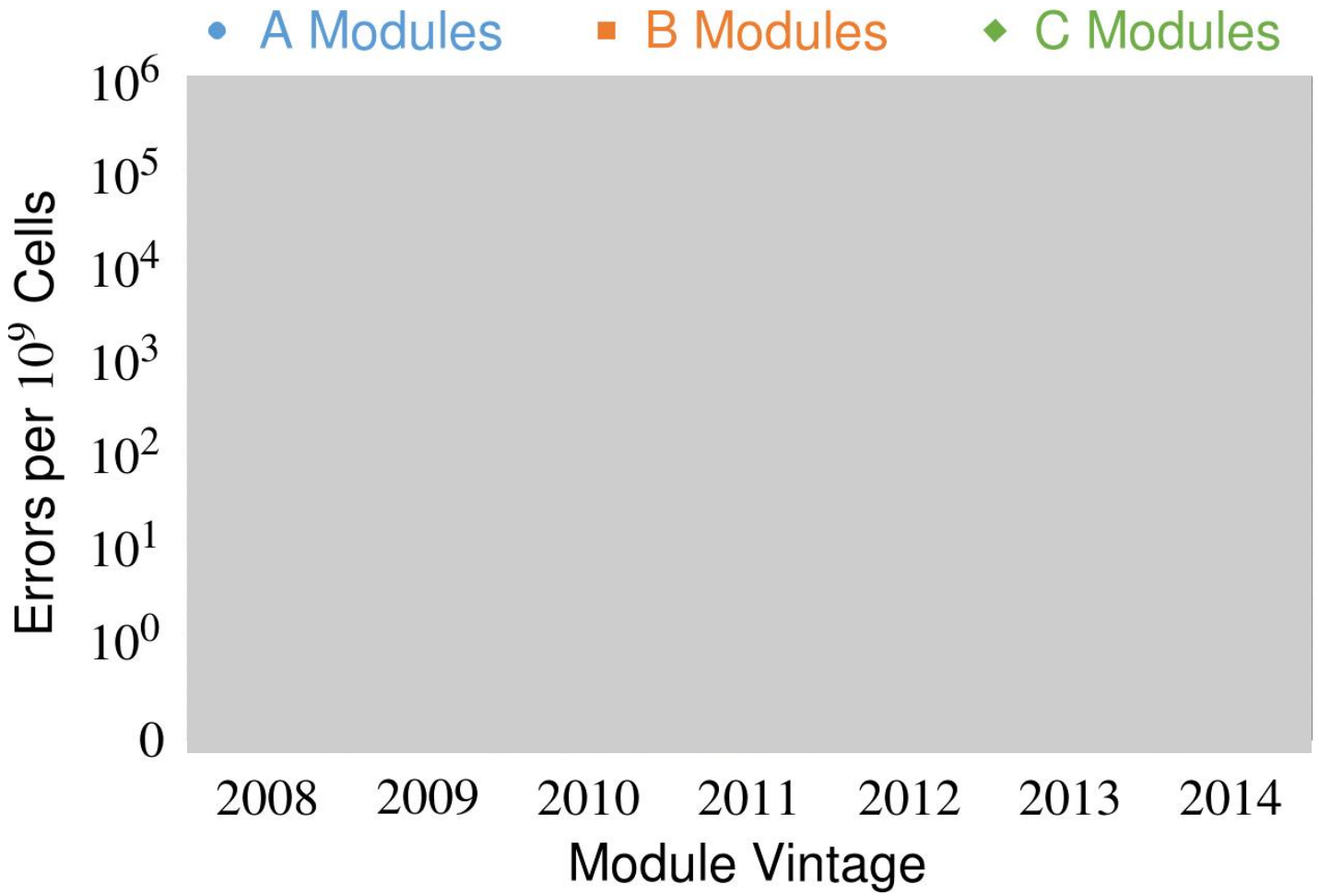
Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors, (Kim et al., ISCA 2014)

Most DRAM Modules Are Vulnerable

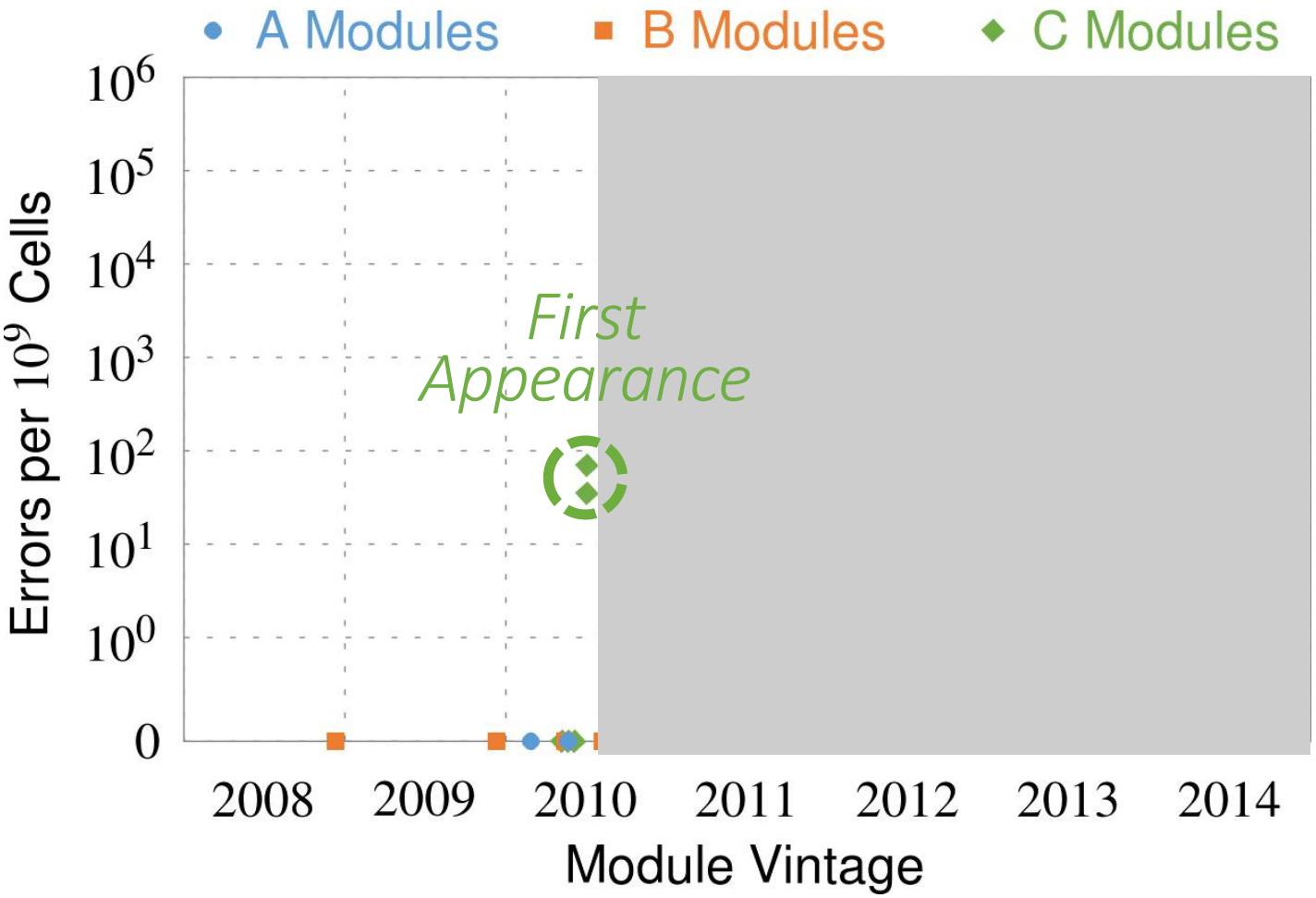
A company	B company	C company
		
86% (37/43)	**83%** (45/54)	**88%** (28/32)
Up to **1.0×10^7** errors	Up to **2.7×10^6** errors	Up to **3.3×10^5** errors

Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors, (Kim et al., ISCA 2014)

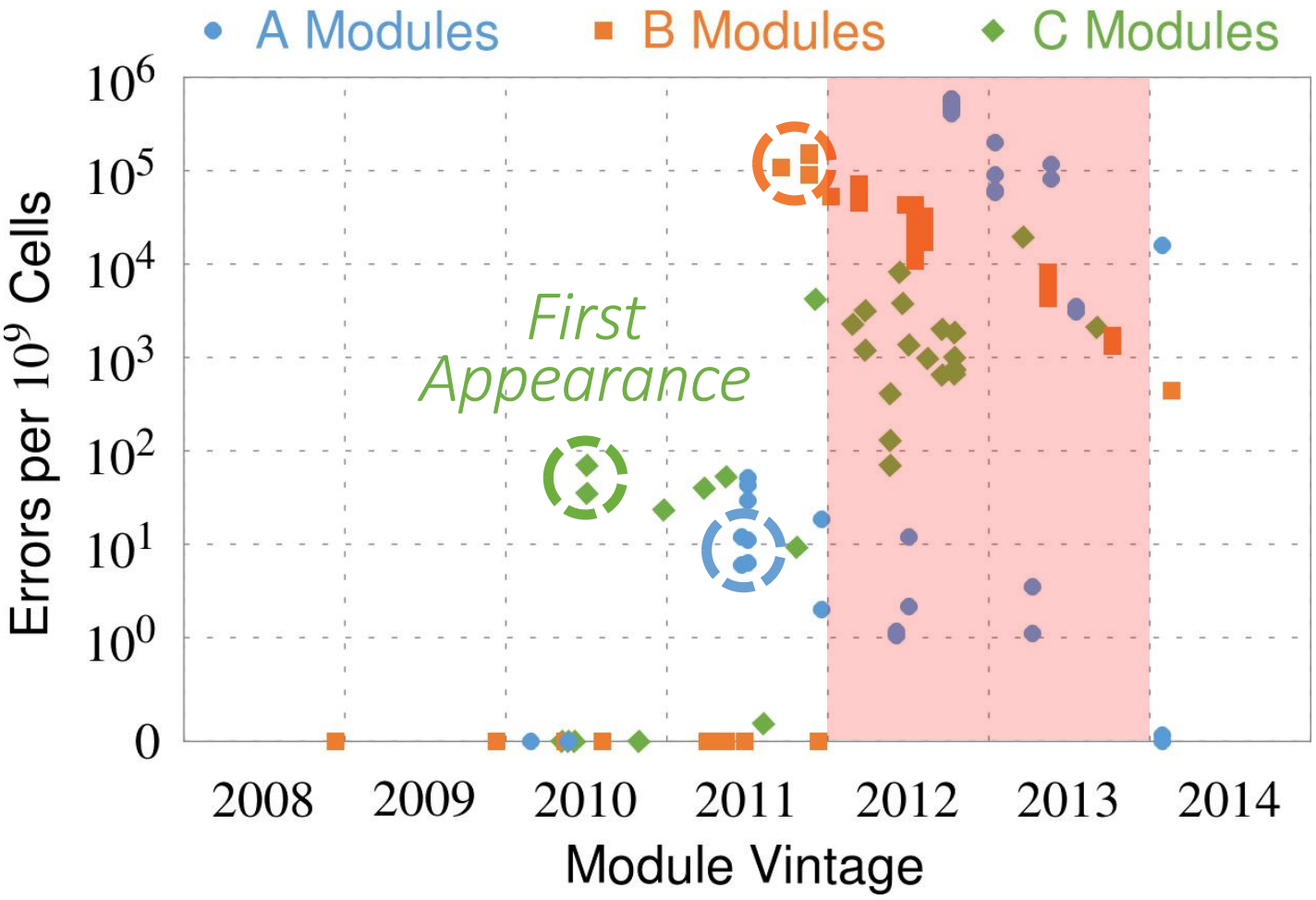
Recent DRAM Is More Vulnerable



Recent DRAM Is More Vulnerable

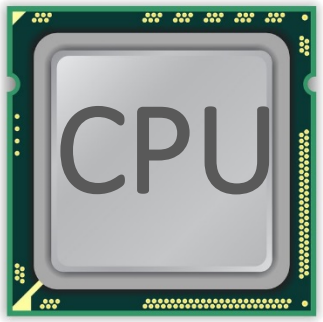


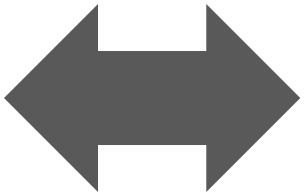
Recent DRAM Is More Vulnerable

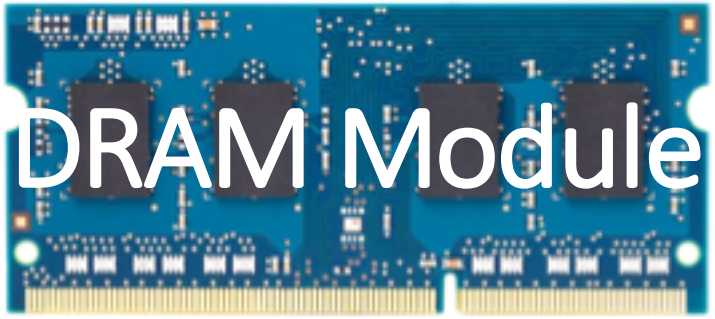


All modules from 2012–2013 are vulnerable

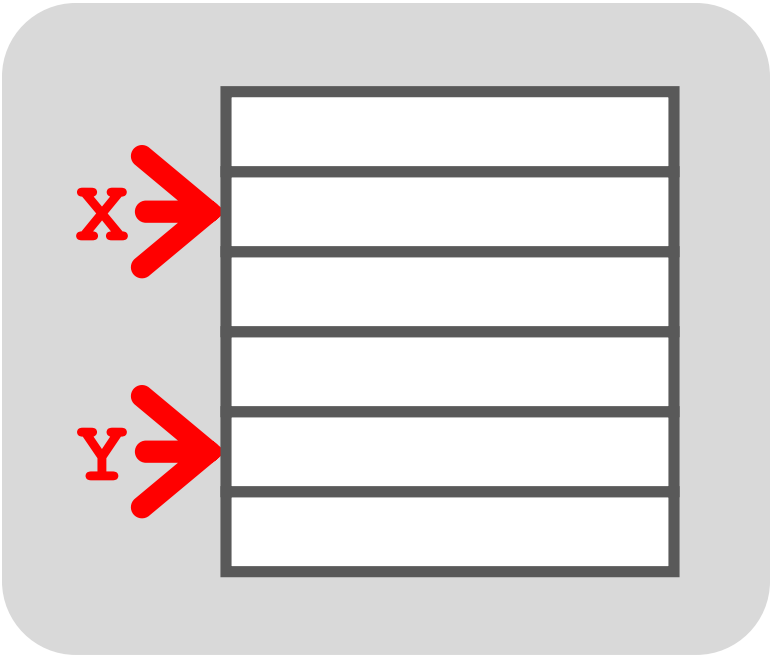
A Simple Program Can Induce Many Errors





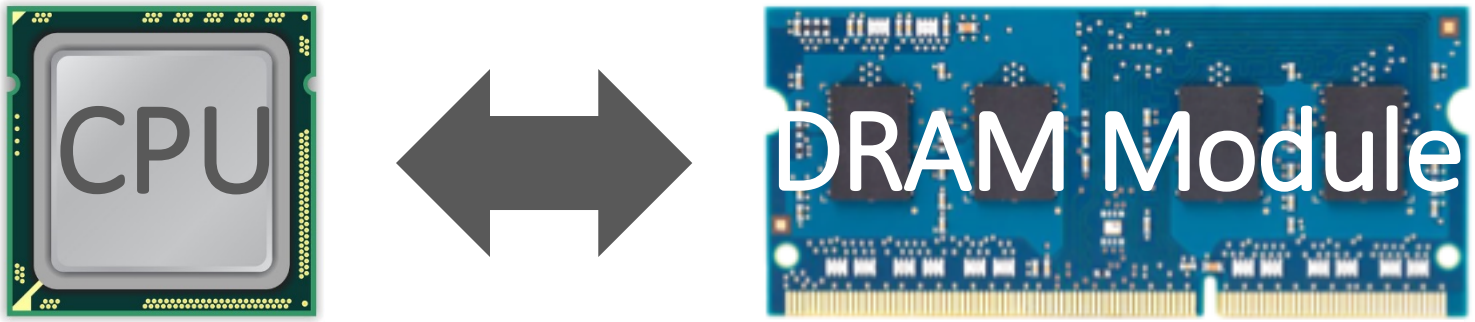



```
loop:
  mov (X), %eax
  mov (Y), %ebx
  clflush (X)
  clflush (Y)
  mfence
  jmp loop
```



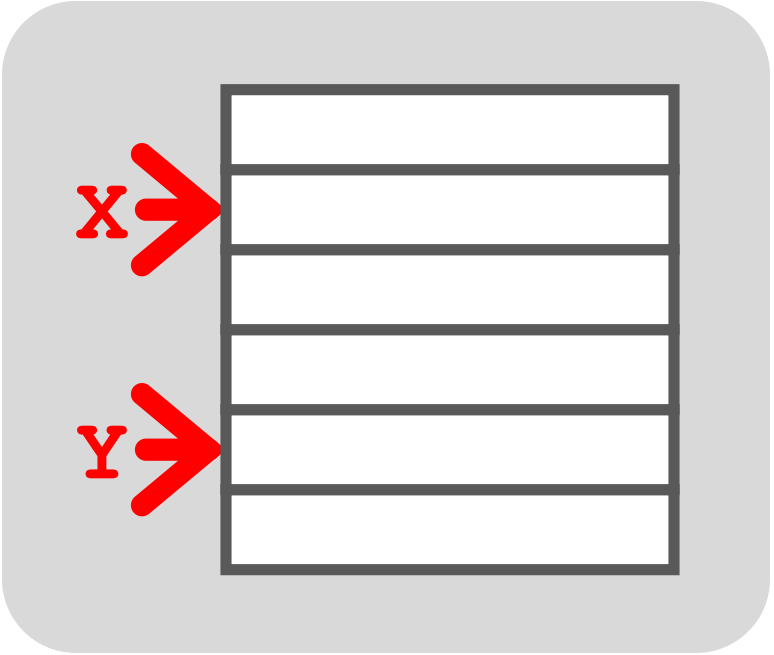
Download from: https://github.com/CMU-SAFARI/rowhammer

A Simple Program Can Induce Many Errors



1. Avoid ***cache hits***
   – Flush **X** from cache

2. Avoid ***row hits*** to **X**
   – Read **Y** in another row



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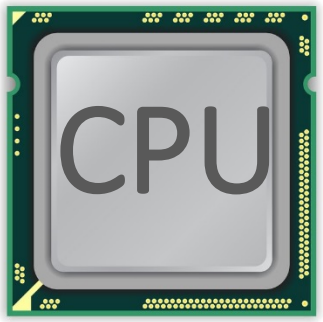
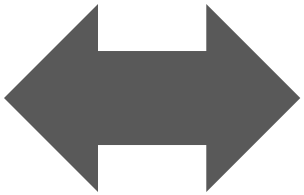
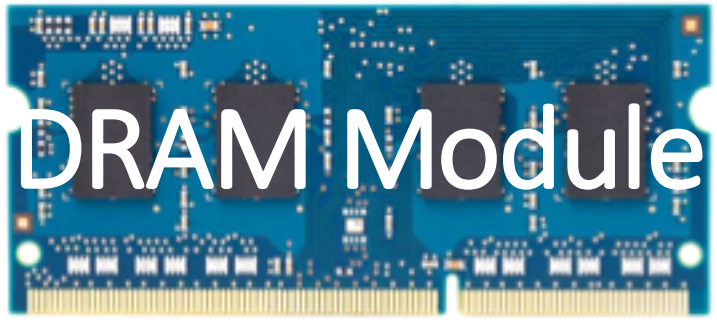
A Simple Program Can Induce Many Errors





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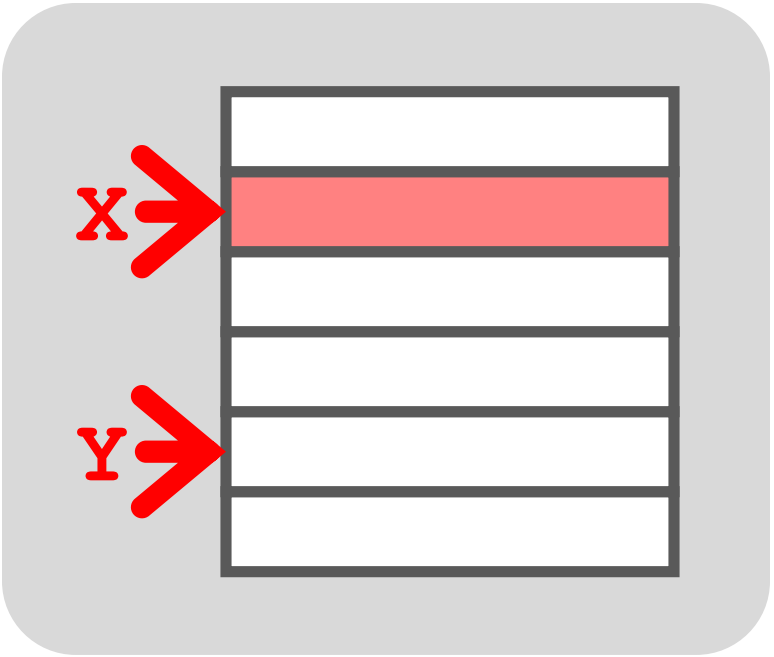
   clflush (X)
   clflush (Y)
   mfence
   jmp loop
```



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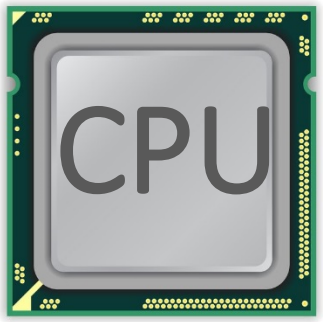

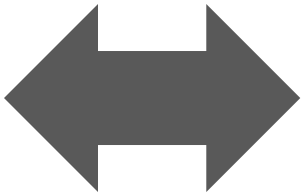

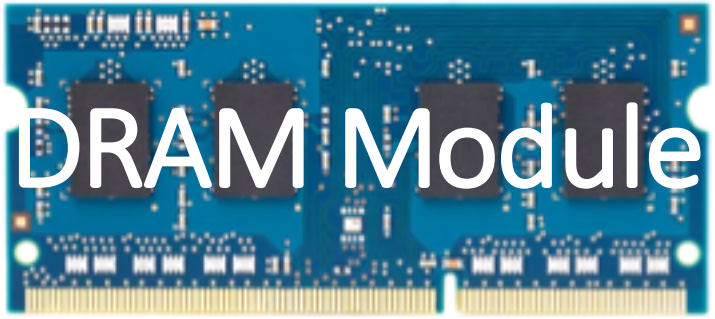


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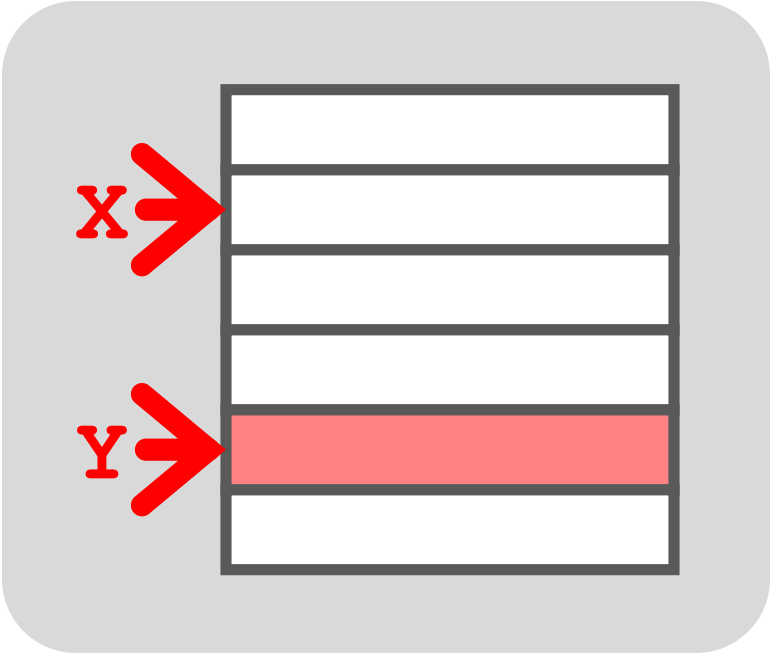

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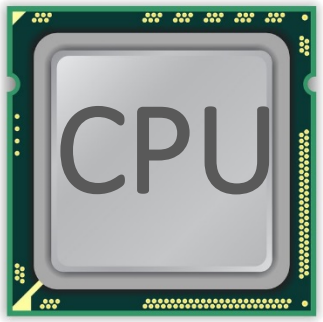

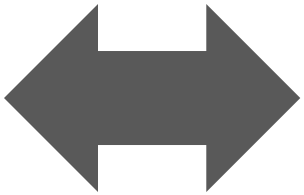

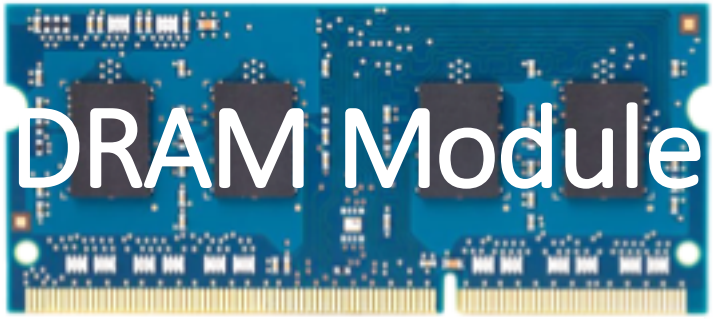


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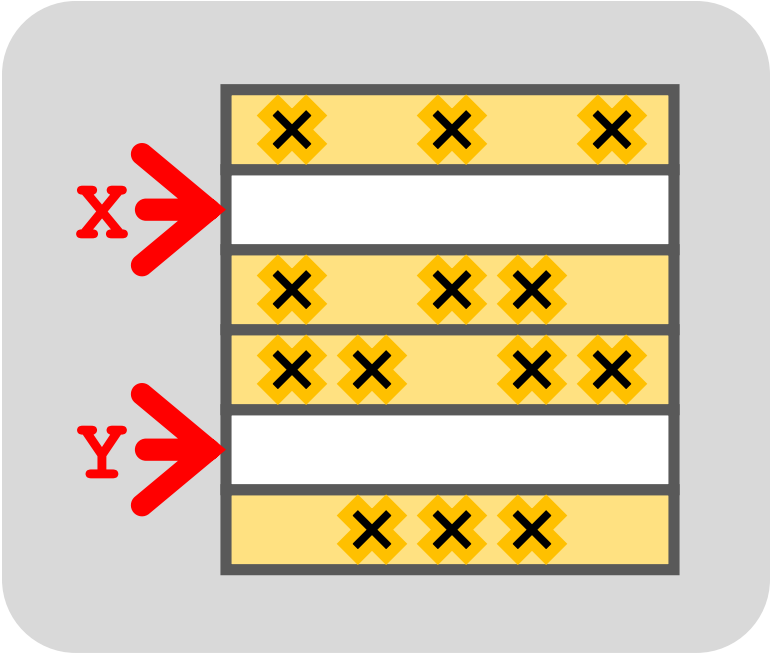


Download from: https://github.com/CMU-SAFARI/rowhammer

Observed Errors in Real Systems

CPU Architecture	Errors	Access-Rate
Intel Haswell (2013)	22.9K	12.3M/sec
Intel Ivy Bridge (2012)	20.7K	11.7M/sec
Intel Sandy Bridge (2011)	16.1K	11.6M/sec
AMD Piledriver (2012)	59	6.1M/sec

A real reliability & security issue

Kim+, "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors," ISCA 2014.

One Can Take Over an Otherwise-Secure System

Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors

Abstract. Memory isolation is a key property of a reliable and secure computing system — an access to one memory address should not have unintended side effects on data stored in other addresses. However, as DRAM process technology

Project Zero

Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors (Kim et al., ISCA 2014)

News and updates from the Project Zero team at Google

Exploiting the DRAM rowhammer bug to gain kernel privileges (Seaborn, 2015)

Monday, March 9, 2015

Exploiting the DRAM rowhammer bug to gain kernel privileges

RowHammer Security Attack Example

- "Rowhammer" is a problem with some recent DRAM devices in which repeatedly accessing a row of memory can cause bit flips in adjacent rows (Kim et al., ISCA 2014).
  - Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors (Kim et al., ISCA 2014)
- We tested a selection of laptops and found that a subset of them exhibited the problem.
- We built two working privilege escalation exploits that use this effect.
  - Exploiting the DRAM rowhammer bug to gain kernel privileges (Seaborn+, 2015)
- One exploit uses rowhammer-induced bit flips to gain kernel privileges on x86-64 Linux when run as an unprivileged userland process.
- When run on a machine vulnerable to the rowhammer problem, the process was able to induce bit flips in page table entries (PTEs).
- It was able to use this to gain write access to its own page table, and hence gain read-write access to all of physical memory.

Exploiting the DRAM rowhammer bug to gain kernel privileges (Seaborn & Dullien, 2015)

Security Implications

Security Implications

It's like breaking into an apartment by repeatedly slamming a neighbor's door until the vibrations open the door you were after

Selected Readings on RowHammer (I)

- Our first detailed study: Rowhammer analysis and solutions (June 2014)
  - Yoongu Kim, Ross Daly, Jeremie Kim, Chris Fallin, Ji Hye Lee, Donghyuk Lee, Chris Wilkerson, Konrad Lai, and Onur Mutlu,
    "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors"
    *Proceedings of the 41st International Symposium on Computer Architecture (**ISCA**)*, Minneapolis, MN, June 2014. [Slides (pptx) (pdf)] [Lightning Session Slides (pptx) (pdf)] [Source Code and Data]

- Our Source Code to Induce Errors in Modern DRAM Chips (June 2014)
  - https://github.com/CMU-SAFARI/rowhammer

- Google Project Zero's Attack to Take Over a System (March 2015)
  - Exploiting the DRAM rowhammer bug to gain kernel privileges (Seaborn+, 2015)
  - https://github.com/google/rowhammer-test
  - **Double-sided Rowhammer**

Selected Readings on RowHammer (II)

- Remote RowHammer Attacks via JavaScript (July 2015)
  - http://arxiv.org/abs/1507.06955
  - https://github.com/IAIK/rowhammerjs
  - Gruss et al., DIMVA 2016.
  - **CLFLUSH-free Rowhammer**
  - "A fully automated attack that requires nothing but a website with JavaScript to **trigger faults on remote hardware**."
  - "We can gain unrestricted access to systems of website visitors."

- ANVIL: Software-Based Protection Against Next-Generation Rowhammer Attacks (March 2016)
  - http://dl.acm.org/citation.cfm?doid=2872362.2872390
  - Aweke et al., ASPLOS 2016
  - **CLFLUSH-free Rowhammer**
  - Software based monitoring for rowhammer detection

Selected Readings on RowHammer (III)

- Dedup Est Machina: Memory Deduplication as an Advanced Exploitation Vector (May 2016)
  - https://www.ieee-security.org/TC/SP2016/papers/0824a987.pdf
  - Bosman et al., IEEE S&P 2016.
  - Exploits Rowhammer and Memory Deduplication to overtake a browser
  - "We report on the **first reliable remote exploit for the Rowhammer vulnerability** running entirely in Microsoft Edge."
  - "[an attacker] … can reliably "own" a system with all defenses up, even if the software is entirely free of bugs."

Selected Readings on RowHammer (IV)

- Flip Feng Shui: Hammering a Needle in the Software Stack (August 2016)
  - https://www.usenix.org/system/files/conference/usenixsecurity16/sec16_paper_razavi.pdf
  - Razavi et al., USENIX Security 2016.
  - Combines memory deduplication and RowHammer
  - "**A malicious VM can gain unauthorized access to a co-hosted VM running OpenSSH**."
  - Breaks OpenSSH public key authentication

- Drammer: Deterministic Rowhammer Attacks on Mobile Platforms (October 2016)
  - http://dl.acm.org/citation.cfm?id=2976749.2978406
  - Van Der Veen et al., CCS 2016
  - **Can take over an ARM-based Android system deterministically**
  - Exploits predictable physical memory allocator behavior
    - Can deterministically place security-sensitive data (e.g., page table) in an attacker-chosen, vulnerable location in memory

Selected Readings on RowHammer (V)

- Grand Pwning Unit: Accelerating Microarchitectural Attacks with the GPU (May 2018)
  - https://www.vusec.net/wp-content/uploads/2018/05/glitch.pdf
  - Frigo et al., IEEE S&P 2018.
  - The first end-to-end remote Rowhammer exploit on mobile platforms that use our GPU-based primitives in orchestration to **compromise browsers on mobile devices in under two minutes**.

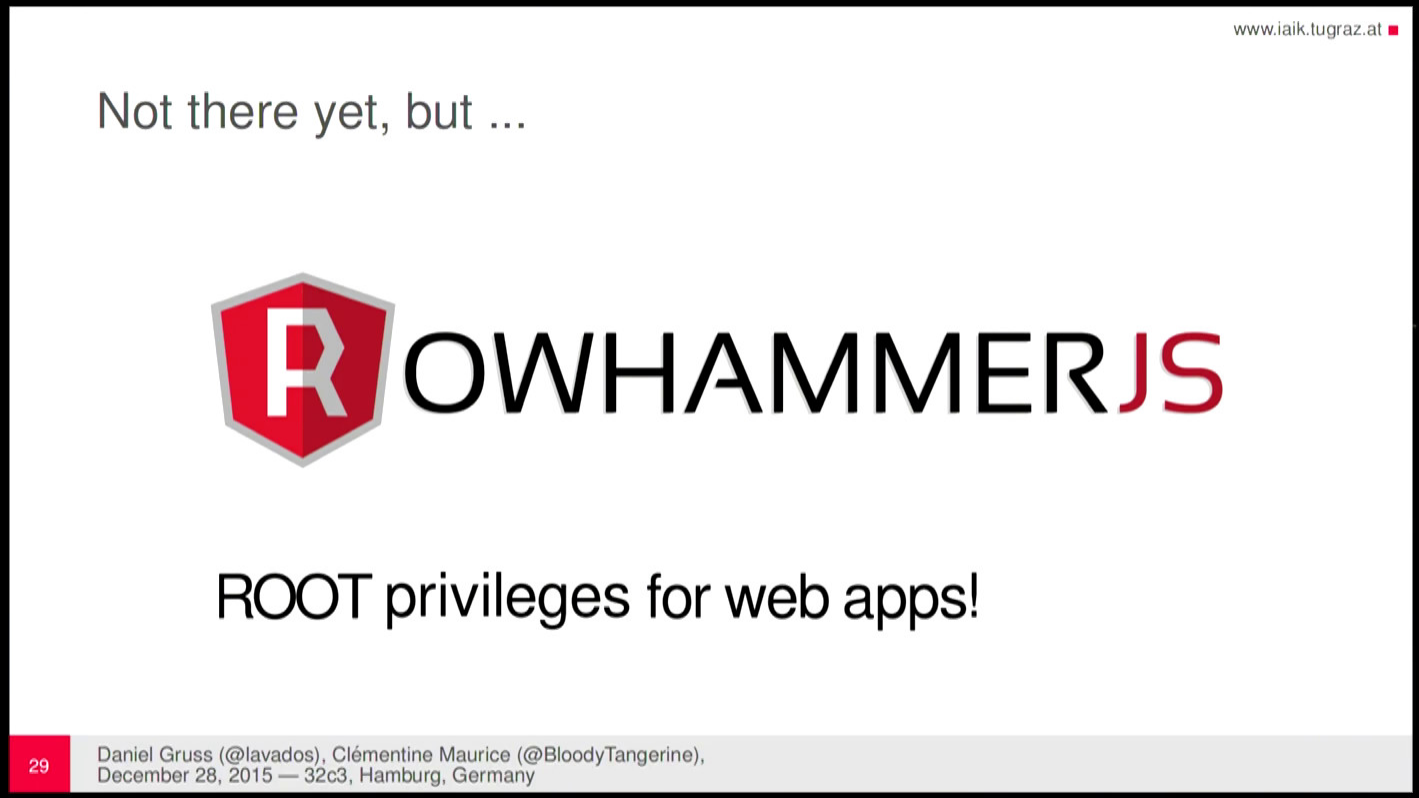
- Throwhammer: Rowhammer Attacks over the Network and Defenses (July 2018)
  - https://www.cs.vu.nl/~herbertb/download/papers/throwhammer_atc18.pdf
  - Tatar et al., USENIX ATC 2018.
  - "[We] show that **an attacker can trigger and exploit Rowhammer bit flips directly from a remote machine by only sending network packets**."

Selected Readings on RowHammer (VI)

- Nethammer: Inducing Rowhammer Faults through Network Requests (July 2018)
  - https://arxiv.org/pdf/1805.04956.pdf
  - Lipp et al., arxiv.org 2018.
  - "Nethammer is the first truly **remote Rowhammer attack**, without a single attacker-controlled line of code on the targeted system."

More Security Implications (I)

"We can gain unrestricted access to systems of website visitors."



Rowhammer.js: A Remote Software-Induced Fault Attack in JavaScript (DIMVA'16)

Source: https://lab.dsst.io/32c3-slides/7197.html

More Security Implications (II)

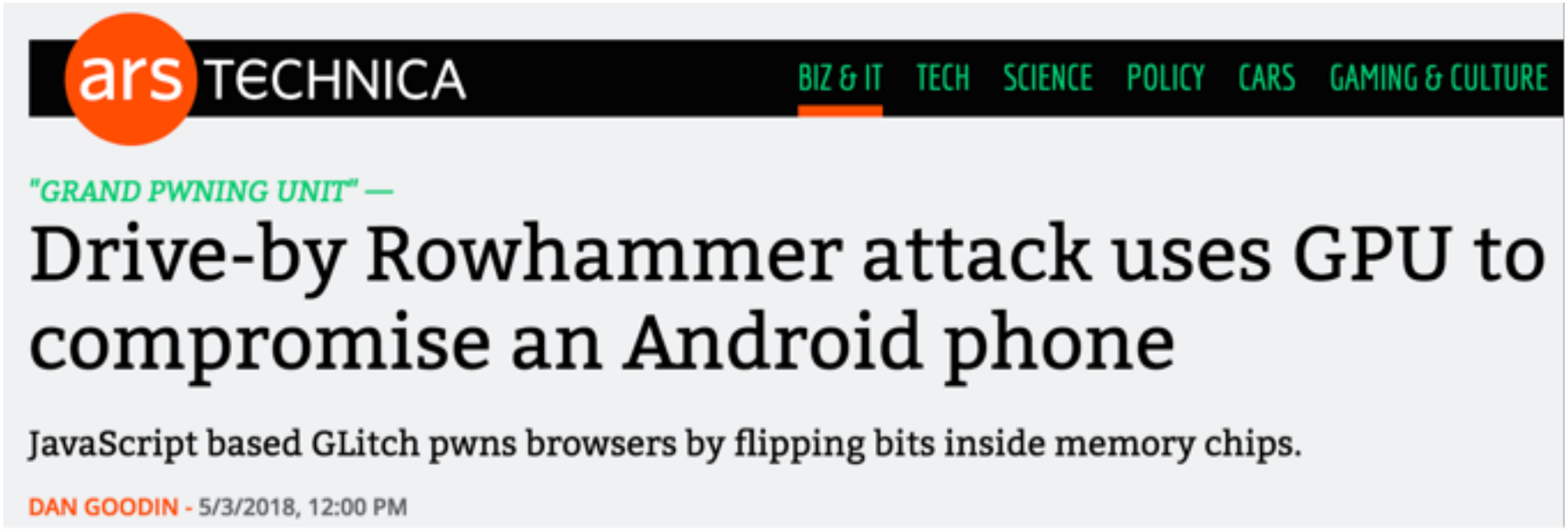
"Can gain control of a smart phone deterministically"

Drammer: Deterministic Rowhammer Attacks on Mobile Platforms, CCS'16

Source: https://fossbytes.com/drammer-rowhammer-attack-android-root-devices/

More Security Implications (III)

- Using an integrated GPU in a mobile system to remotely escalate privilege via the WebGL interface



Grand Pwning Unit: Accelerating Microarchitectural Attacks with the GPU

Pietro Frigo
Vrije Universiteit
Amsterdam
p.frigo@vu.nl

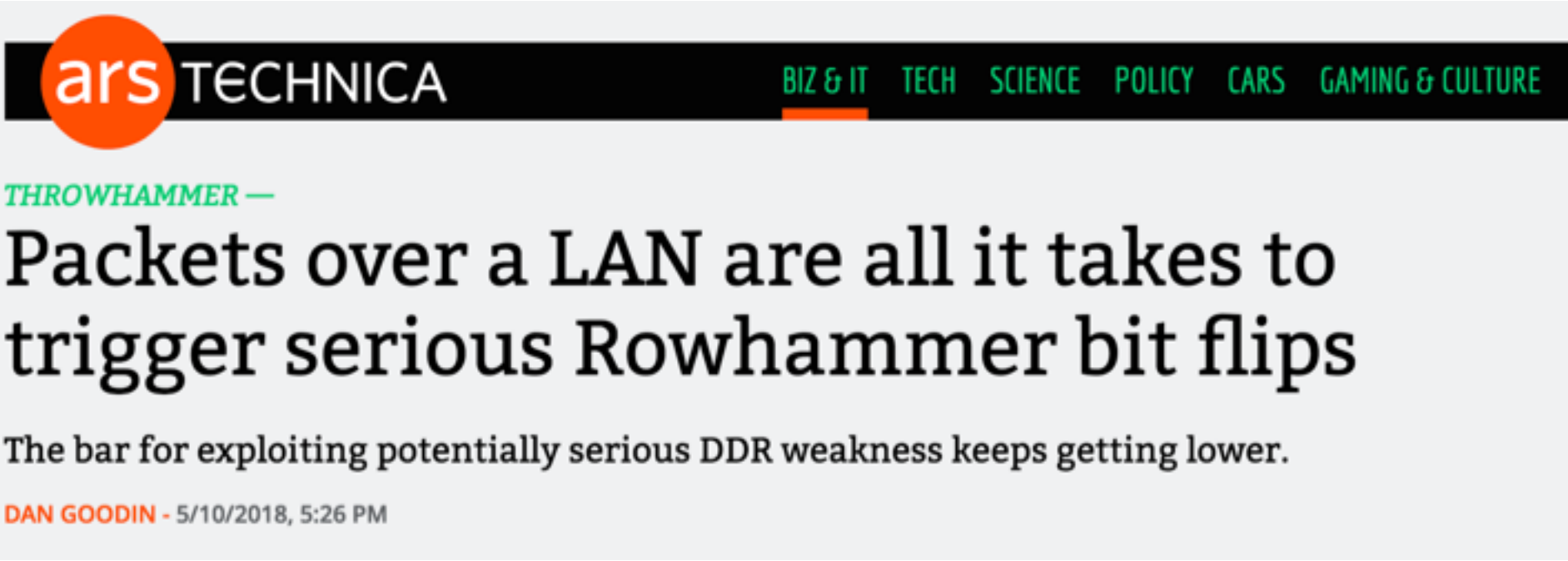
Cristiano Giuffrida
Vrije Universiteit
Amsterdam
giuffrida@cs.vu.nl

Herbert Bos
Vrije Universiteit
Amsterdam
herbertb@cs.vu.nl

Kaveh Razavi
Vrije Universiteit
Amsterdam
kaveh@cs.vu.nl

More Security Implications (IV)

- Rowhammer over RDMA (I)



ars TECHNICA

BIZ & IT TECH SCIENCE POLICY CARS GAMING & CULTURE

THROWHAMMER —

Packets over a LAN are all it takes to trigger serious Rowhammer bit flips

The bar for exploiting potentially serious DDR weakness keeps getting lower.

DAN GOODIN - 5/10/2018, 5:26 PM

Throwhammer: Rowhammer Attacks over the Network and Defenses

Andrei Tatar
VU Amsterdam

Radhesh Krishnan
VU Amsterdam

Elias Athanasopoulos
University of Cyprus

Cristiano Giuffrida
VU Amsterdam

Herbert Bos
VU Amsterdam

Kaveh Razavi
VU Amsterdam

More Security Implications (V)

- Rowhammer over RDMA (II)

The Hacker News™
Security in a serious way

Nethammer—Exploiting DRAM Rowhammer Bug Through Network Requests

Nethammer:
Inducing Rowhammer Faults through Network Requests

Moritz Lipp
Graz University of Technology

Misiker Tadesse Aga
University of Michigan

Michael Schwarz
Graz University of Technology

Daniel Gruss
Graz University of Technology

Clémentine Maurice
Univ Rennes, CNRS, IRISA

Lukas Raab
Graz University of Technology

Lukas Lamster
Graz University of Technology

More Security Implications?

Some Potential Solutions

- Make better DRAM chips — Cost
- Refresh frequently — Power, Performance
- Sophisticated ECC — Cost, Power
- Access counters — Cost, Power, Complexity

Apple's Patch for RowHammer

- https://support.apple.com/en-gb/HT204934

Available for: OS X Mountain Lion v10.8.5, OS X Mavericks v10.9.5

Impact: A malicious application may induce memory corruption to escalate privileges

Description: A disturbance error, also known as Rowhammer, exists with some DDR3 RAM that could have led to memory corruption. This issue was mitigated by increasing memory refresh rates.

CVE-ID

CVE-2015-3693 : Mark Seaborn and Thomas Dullien of Google, working from original research by Yoongu Kim et al (2014)

HP, Lenovo, and other vendors released similar patches

Our Solution to RowHammer

- **PARA:** *Probabilistic Adjacent Row Activation*
- Key Idea
  - After closing a row, we activate (i.e., refresh) one of its neighbors with a low probability: $p = 0.005$
- Reliability Guarantee
  - When $p=0.005$, errors in one year: 9.4×10^{-14}
  - By adjusting the value of p, we can vary the strength of protection against errors

Advantages of PARA

- *PARA refreshes rows infrequently*
  - Low power
  - Low performance-overhead
    - Average slowdown: 0.20% (for 29 benchmarks)
    - Maximum slowdown: 0.75%
- *PARA is stateless*
  - Low cost
  - Low complexity

- *PARA is an effective and low-overhead solution to prevent disturbance errors*

Requirements for PARA

- If implemented in DRAM chip
  - Enough slack in timing parameters
  - Plenty of slack today:
    - Lee et al., "**Adaptive-Latency DRAM: Optimizing DRAM Timing for the Common Case**," HPCA 2015.
    - Chang et al., "**Understanding Latency Variation in Modern DRAM Chips**," SIGMETRICS 2016.
    - Lee et al., "**Design-Induced Latency Variation in Modern DRAM Chips**," SIGMETRICS 2017.
    - Chang et al., "**Understanding Reduced-Voltage Operation in Modern DRAM Devices**," SIGMETRICS 2017.
    - Ghose et al., "**What Your DRAM Power Models Are Not Telling You: Lessons from a Detailed Experimental Study**," SIGMETRICS 2018.

- If implemented in memory controller
  - Better coordination between memory controller and DRAM
  - Memory controller should know which rows are physically adjacent

More on RowHammer Analysis

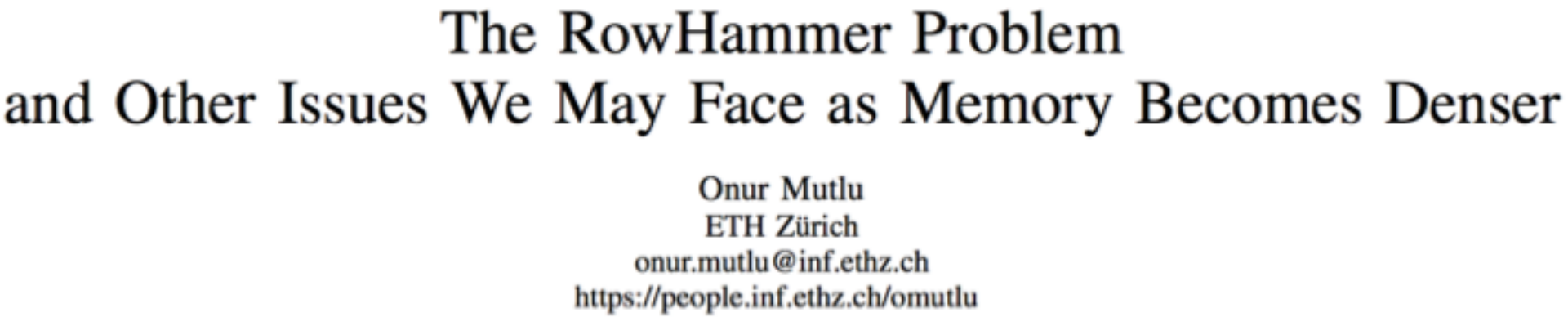
- Yoongu Kim, Ross Daly, Jeremie Kim, Chris Fallin, Ji Hye Lee, Donghyuk Lee, Chris Wilkerson, Konrad Lai, and Onur Mutlu,
  "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors"
  *Proceedings of the 41st International Symposium on Computer Architecture (**ISCA**)*, Minneapolis, MN, June 2014.
  [Slides (pptx) (pdf)] [Lightning Session Slides (pptx) (pdf)] [Source Code and Data]

Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors

Yoongu Kim[1] Ross Daly* Jeremie Kim[1] Chris Fallin* Ji Hye Lee[1]
Donghyuk Lee[1] Chris Wilkerson[2] Konrad Lai Onur Mutlu[1]
[1]Carnegie Mellon University [2]Intel Labs

Future of Memory Reliability/Security

- Onur Mutlu,
  "The RowHammer Problem and Other Issues We May Face as Memory Becomes Denser"
  *Invited Paper in Proceedings of the Design, Automation, and Test in Europe Conference (**DATE**)*, Lausanne, Switzerland, March 2017.
  [Slides (pptx) (pdf)]

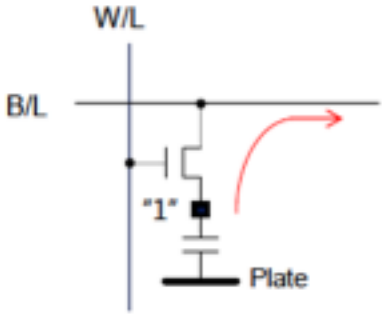

The RowHammer Problem
and Other Issues We May Face as Memory Becomes Denser

Onur Mutlu
ETH Zürich
onur.mutlu@inf.ethz.ch
https://people.inf.ethz.ch/omutlu

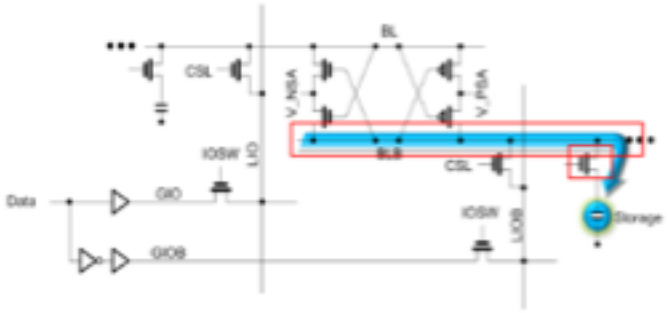
Industry Is Writing Papers About It, Too

DRAM Process Scaling Challenges

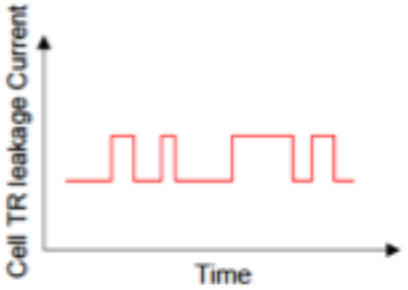
- **Refresh**
  - Difficult to build high-aspect ratio cell capacitors decreasing cell capacitance
  - Leakage current of cell access transistors increasing
- **tWR**
  - Contact resistance between the cell capacitor and access transistor increasing
  - On-current of the cell access transistor decreasing
  - Bit-line resistance increasing
- **VRT**
  - Occurring more frequently with cell capacitance decreasing



Refresh



tWR



VRT

Call for Intelligent Memory Controllers

DRAM Process Scaling Challenges

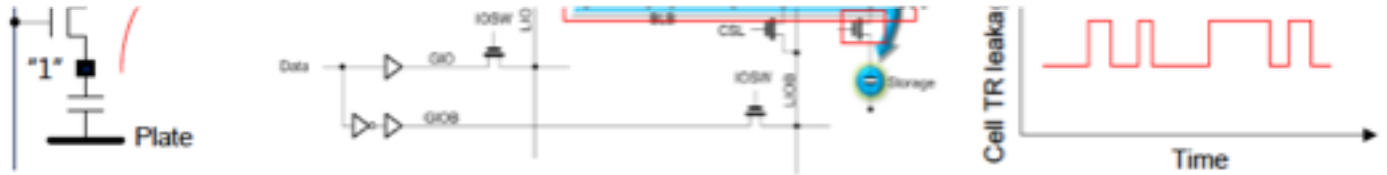
- **Refresh**
  - Difficult to build high-aspect ratio cell capacitors decreasing cell capacitance

THE MEMORY FORUM 2014

Co-Architecting Controllers and DRAM to Enhance DRAM Process Scaling

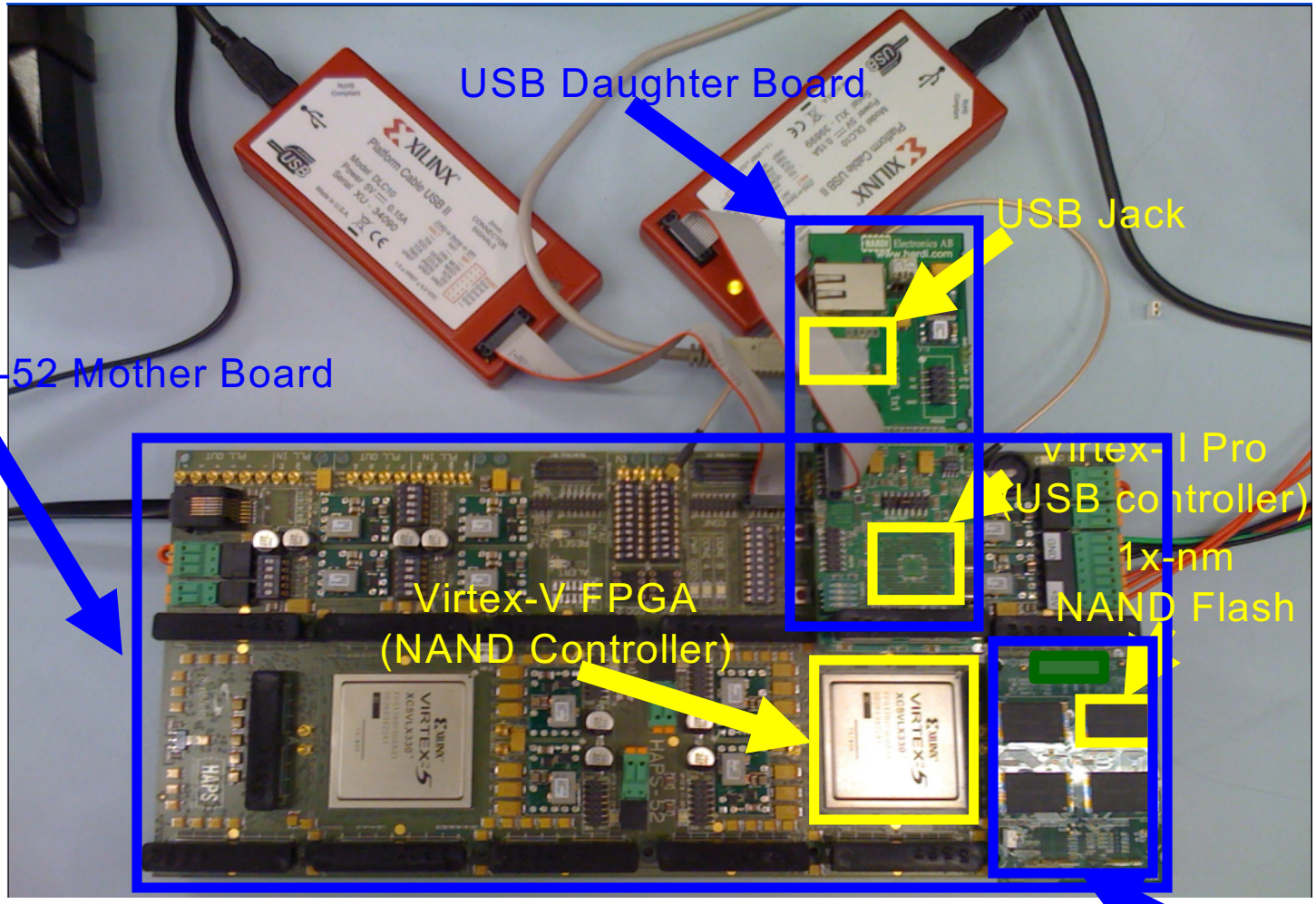
Uksong Kang, Hak-soo Yu, Churoo Park, *Hongzhong Zheng,
**John Halbert, **Kuljit Bains, SeongJin Jang, and Joo Sun Choi

*Samsung Electronics, Hwasung, Korea / *Samsung Electronics, San Jose / **Intel*



Refresh **tWR** **VRT**

Aside: Intelligent Controller for NAND Flash



[DATE 2012, ICCD 2012, DATE 2013, ITJ 2013, ICCD 2013, SIGMETRICS 2014, HPCA 2015, DSN 2015, MSST 2015, JSAC 2016, HPCA 2017, DFRWS 2017, PIEEE 2017, HPCA 2018, SIGMETRICS 2018]

Cai+, "Error Characterization, Mitigation, and Recovery in Flash Memory Based Solid State Drives," Proc. IEEE 2017.

Aside: Intelligent Controller for NAND Flash

Proceedings of the IEEE, Sept. 2017

Error Characterization, Mitigation, and Recovery in Flash-Memory-Based Solid-State Drives

This paper reviews the most recent advances in solid-state drive (SSD) error characterization, mitigation, and data recovery techniques to improve both SSD's reliability and lifetime.

By Yu Cai, Saugata Ghose, Erich F. Haratsch, Yixin Luo, and Onur Mutlu

https://arxiv.org/pdf/1706.08642

A Key Takeaway

Main Memory Needs Intelligent Controllers

Solution Direction: Principled Designs

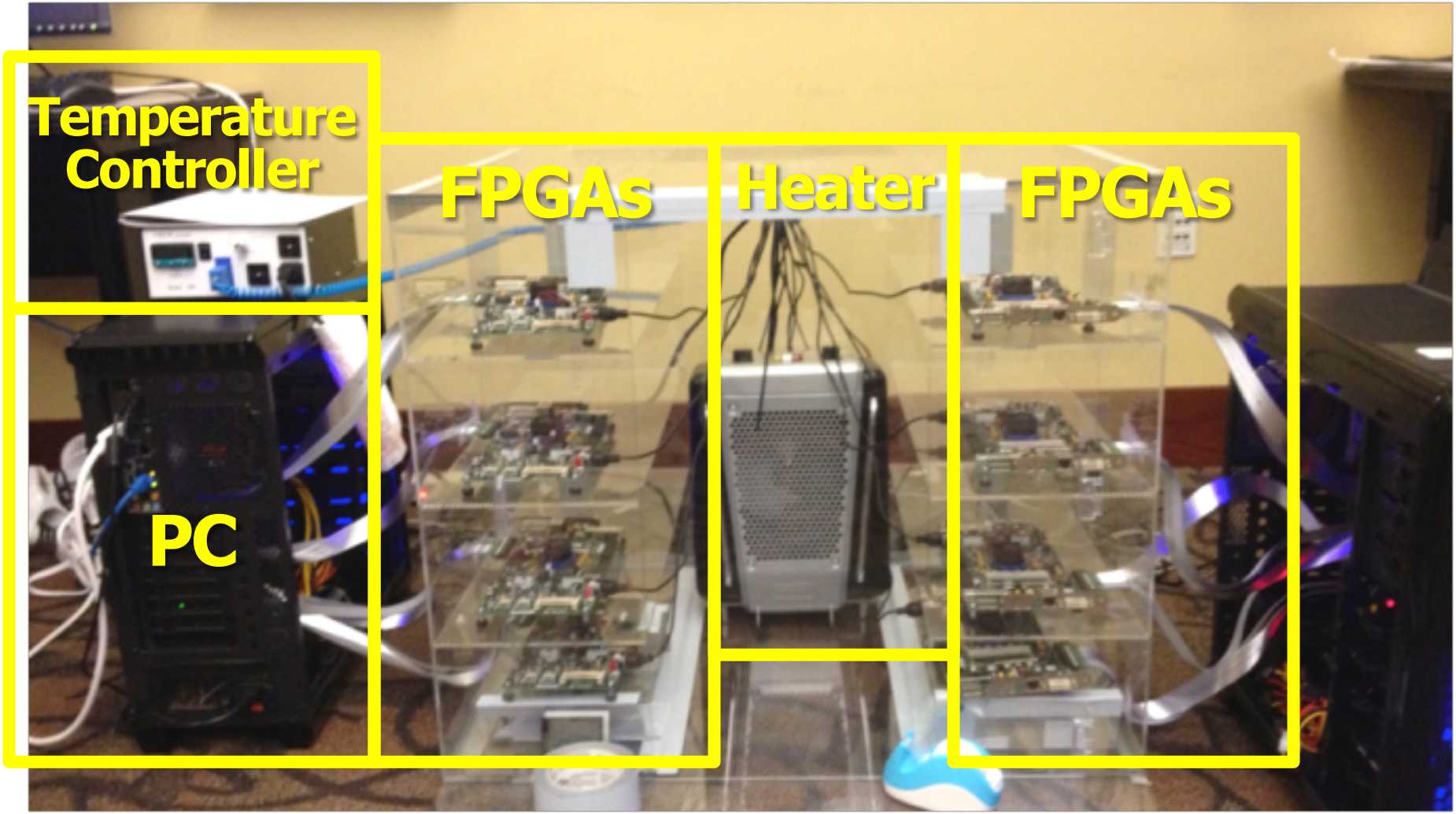
Design fundamentally secure computing architectures

Predict and prevent such safety issues

Architecting for Security

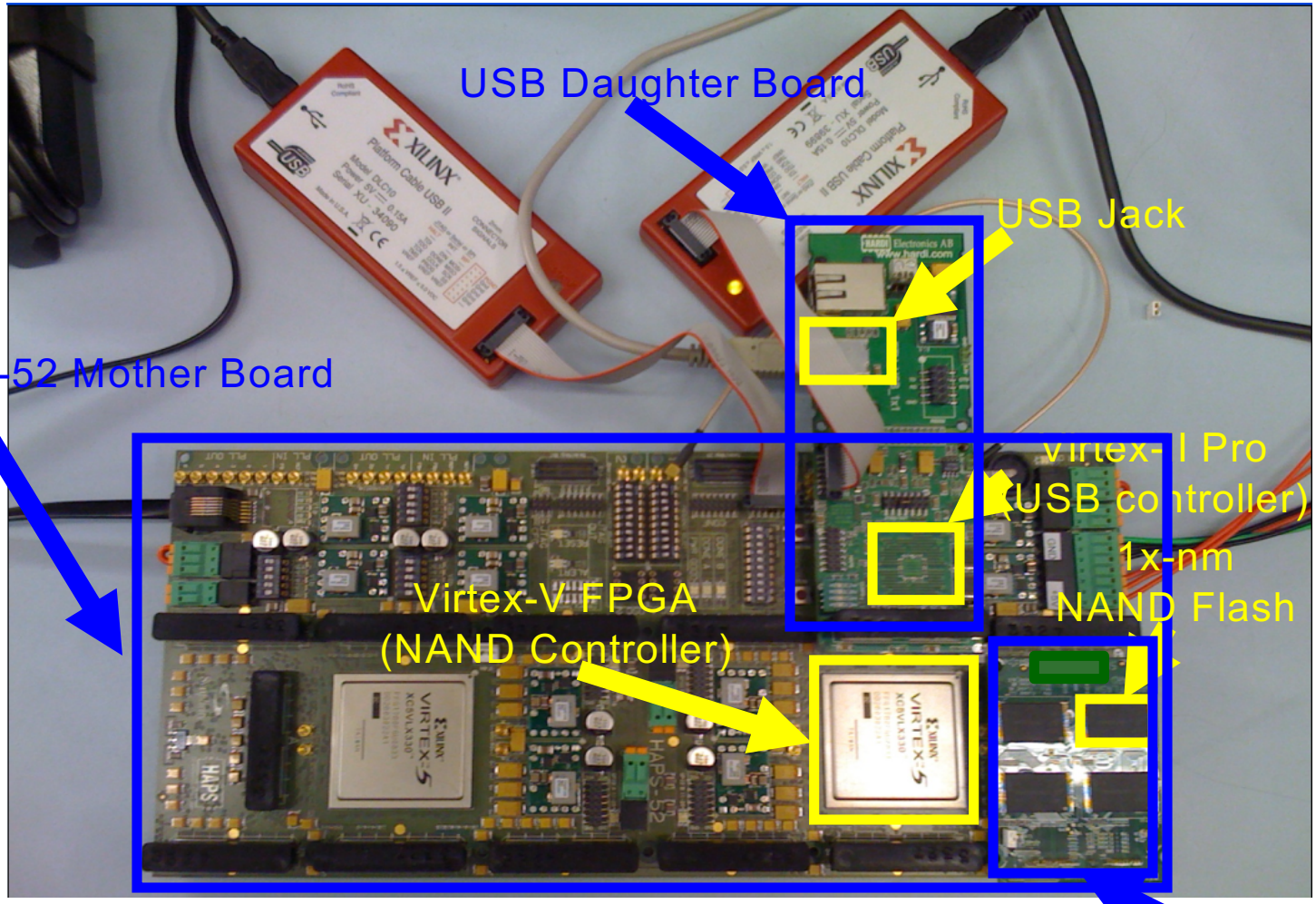
- **Understand**: Methods for vulnerability modeling & discovery
  - Modeling and prediction based on real (device) data and analysis
  - Understanding vulnerabilities
  - Developing reliable metrics
- **Architect**: Principled architectures with security as key concern
  - Good partitioning of duties across the stack
  - Cannot give up performance and efficiency
  - Patch-ability in the field
- **Design & Test**: Principled design, automation, (online) testing
  - Design for security
  - High coverage and good interaction with system reliability methods

Understand and Model with Experiments (DRAM)



Kim+, "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors," ISCA 2014.

Understand and Model with Experiments (Flash)



[DATE 2012, ICCD 2012, DATE 2013, ITJ 2013, ICCD 2013, SIGMETRICS 2014, HPCA 2015, DSN 2015, MSST 2015, JSAC 2016, HPCA 2017, DFRWS 2017, PIEEE'17, HPCA'18]

Cai+, "Error Characterization, Mitigation, and Recovery in Flash Memory Based Solid State Drives," Proc. IEEE 2017.

Understanding Flash Memory Reliability

Proceedings of the IEEE, Sept. 2017

Error Characterization, Mitigation, and Recovery in Flash-Memory-Based Solid-State Drives

This paper reviews the most recent advances in solid-state drive (SSD) error characterization, mitigation, and data recovery techniques to improve both SSD's reliability and lifetime.

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https://arxiv.org/pdf/1706.08642

Understanding Flash Memory Reliability

- Justin Meza, Qiang Wu, Sanjeev Kumar, and Onur Mutlu,
  "A Large-Scale Study of Flash Memory Errors in the Field"
  Proceedings of the ACM International Conference on Measurement and Modeling of Computer Systems (***SIGMETRICS***), Portland, OR, June 2015.
  [Slides (pptx) (pdf)] [Coverage at ZDNet] [Coverage on The Register] [Coverage on TechSpot] [Coverage on The Tech Report]

A Large-Scale Study of Flash Memory Failures in the Field

Justin Meza
Carnegie Mellon University
meza@cmu.edu

Qiang Wu
Facebook, Inc.
qwu@fb.com

Sanjeev Kumar
Facebook, Inc.
skumar@fb.com

Onur Mutlu
Carnegie Mellon University
onur@cmu.edu

NAND Flash Vulnerabilities [HPCA'17]

HPCA, Feb. 2017

Vulnerabilities in MLC NAND Flash Memory Programming: Experimental Analysis, Exploits, and Mitigation Techniques

Yu Cai[†] Saugata Ghose[†] Yixin Luo[‡†] Ken Mai[†] Onur Mutlu[§†] Erich F. Haratsch[‡]
[†]*Carnegie Mellon University* [‡]*Seagate Technology* [§]*ETH Zürich*

Modern NAND flash memory chips provide high density by storing two bits of data in each flash cell, called a multi-level cell *(MLC). An MLC partitions the threshold voltage range of a flash cell into four* voltage states. *When a flash cell is programmed, a high voltage is applied to the cell. Due to parasitic capacitance coupling between flash cells that are physically close to each other, flash cell programming can lead to* cell-to-cell program interference, *which introduces errors into* neighboring *flash cells. In order to reduce the impact of cell-to-cell interference on the reliability of MLC NAND flash memory, flash manufacturers adopt a* two-step programming method, *which programs the MLC in two separate steps. First, the flash memory partially programs the least significant bit of the MLC to some intermediate threshold voltage. Second, it programs the most significant bit to bring the MLC up to its full voltage state.*

In this paper, we demonstrate that two-step programming exposes new reliability and security vulnerabilities. We expe-

belongs to a different flash memory *page* (the unit of data programmed and read at the same time), which we refer to, respectively, as the least significant bit (LSB) page and the most significant bit (MSB) page [5].

A flash cell is programmed by applying a large voltage on the control gate of the transistor, which triggers charge transfer into the floating gate, thereby increasing the threshold voltage. To precisely control the threshold voltage of the cell, the flash memory uses *incremental step pulse programming* (ISPP) [12, 21, 25, 41]. ISPP applies multiple short pulses of the programming voltage to the control gate, in order to increase the cell threshold voltage by some small voltage amount (V_{step}) after each step. Initial MLC designs programmed the threshold voltage in *one shot*, issuing all of the pulses back-to-back to program *both* bits of data at the same time. However, as flash memory scales down, the distance between neighboring flash cells decreases, which

https://people.inf.ethz.ch/omutlu/pub/flash-memory-programming-vulnerabilities_hpca17.pdf

3D NAND Flash Reliability I [HPCA'18]

- Yixin Luo, Saugata Ghose, Yu Cai, Erich F. Haratsch, and Onur Mutlu, **"HeatWatch: Improving 3D NAND Flash Memory Device Reliability by Exploiting Self-Recovery and Temperature-Awareness"**
  *Proceedings of the 24th International Symposium on High-Performance Computer Architecture (**HPCA**)*, Vienna, Austria, February 2018.
  [Lightning Talk Video]
  [Slides (pptx) (pdf)] [Lightning Session Slides (pptx) (pdf)]

HeatWatch: Improving 3D NAND Flash Memory Device Reliability by Exploiting Self-Recovery and Temperature Awareness

Yixin Luo[†] Saugata Ghose[†] Yu Cai[‡] Erich F. Haratsch[‡] Onur Mutlu[§†]
[†]*Carnegie Mellon University* [‡]*Seagate Technology* [§]*ETH Zürich*

3D NAND Flash Reliability II [SIGMETRICS'18]

- Yixin Luo, Saugata Ghose, Yu Cai, Erich F. Haratsch, and Onur Mutlu, **"Improving 3D NAND Flash Memory Lifetime by Tolerating Early Retention Loss and Process Variation"**
  *Proceedings of the ACM International Conference on Measurement and Modeling of Computer Systems (**SIGMETRICS**)*, Irvine, CA, USA, June 2018.
  [Abstract]

Improving 3D NAND Flash Memory Lifetime by Tolerating Early Retention Loss and Process Variation

Yixin Luo[†] Saugata Ghose[†] Yu Cai[†] Erich F. Haratsch[‡] Onur Mutlu[§†]
[†]Carnegie Mellon University [‡]Seagate Technology [§]ETH Zürich

Another Talk: NAND Flash Memory Robustness

- Yu Cai, Saugata Ghose, Erich F. Haratsch, Yixin Luo, and Onur Mutlu, **"Error Characterization, Mitigation, and Recovery in Flash Memory Based Solid State Drives"**

  to appear in Proceedings of the IEEE, 2017.

Cai+, "Error Patterns in MLC NAND Flash Memory: Measurement, Characterization, and Analysis," DATE 2012.

Cai+, "Flash Correct-and-Refresh: Retention-Aware Error Management for Increased Flash Memory Lifetime," ICCD 2012.

Cai+, "Threshold Voltage Distribution in MLC NAND Flash Memory: Characterization, Analysis and Modeling," DATE 2013.

Cai+, "Error Analysis and Retention-Aware Error Management for NAND Flash Memory," Intel Technology Journal 2013.

Cai+, "Program Interference in MLC NAND Flash Memory: Characterization, Modeling, and Mitigation," ICCD 2013.

Cai+, "Neighbor-Cell Assisted Error Correction for MLC NAND Flash Memories," SIGMETRICS 2014.

Cai+,"Data Retention in MLC NAND Flash Memory: Characterization, Optimization and Recovery," HPCA 2015.

Cai+, "Read Disturb Errors in MLC NAND Flash Memory: Characterization and Mitigation," DSN 2015.

Luo+, "WARM: Improving NAND Flash Memory Lifetime with Write-hotness Aware Retention Management," MSST 2015.

Meza+, "A Large-Scale Study of Flash Memory Errors in the Field," SIGMETRICS 2015.

Luo+, "Enabling Accurate and Practical Online Flash Channel Modeling for Modern MLC NAND Flash Memory," IEEE JSAC 2016.

Cai+, "Vulnerabilities in MLC NAND Flash Memory Programming: Experimental Analysis, Exploits, and Mitigation Techniques," HPCA 2017.

Fukami+, "Improving the Reliability of Chip-Off Forensic Analysis of NAND Flash Memory Devices," DFRWS EU 2017.

Luo+, "HeatWatch: Improving 3D NAND Flash Memory Device Reliability by Exploiting Self-Recovery and Temperature-Awareness," HPCA 2018.

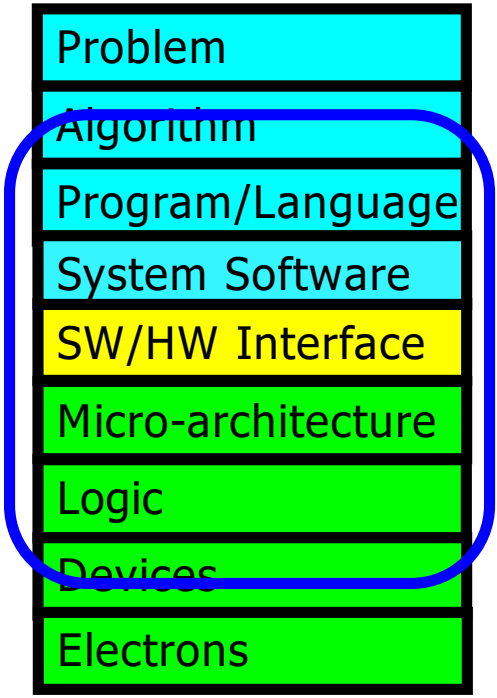
Luo+, "Improving 3D NAND Flash Memory Lifetime by Tolerating Early Retention Loss and Process Variation," SIGMETRICS 2018.

Cai+, "Error Characterization, Mitigation, and Recovery in Flash Memory Based Solid State Drives," Proc. IEEE 2017.

There are Two Other Solution Directions

- **New Technologies:** Replace or (more likely) augment DRAM with a different technology
  - Non-volatile memories

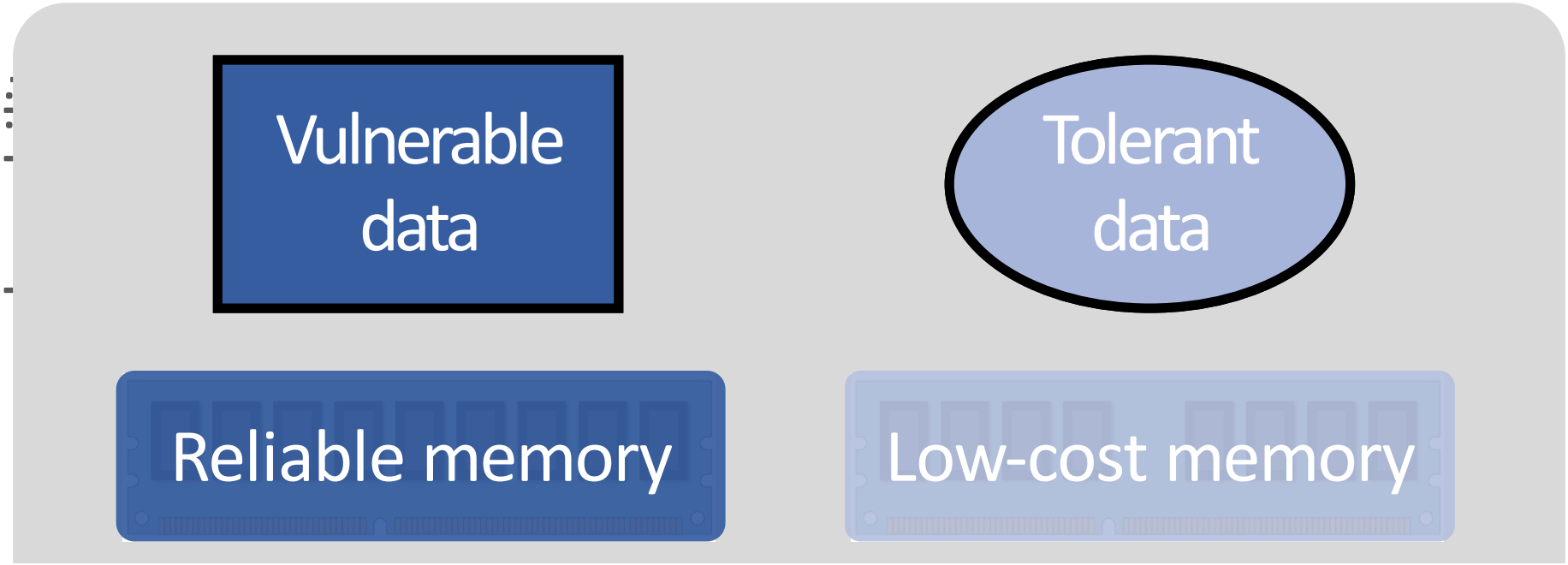
- **Embracing Un-reliability:**
  Design memories with different reliability and store data intelligently across them



- ...

Fundamental solutions to security require co-design across the hierarchy

Exploiting Memory Error Tolerance with Hybrid Memory Systems



On Microsoft's Web Search workload

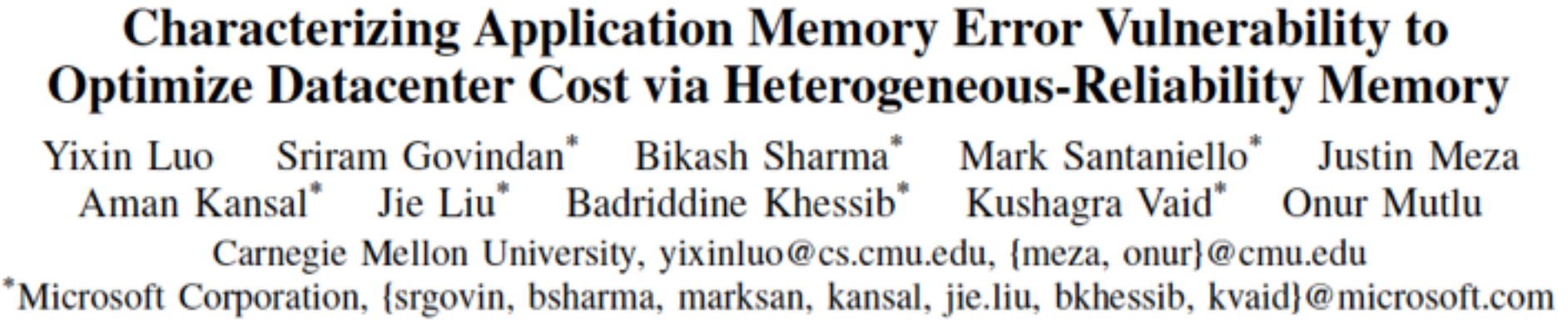
Reduces server hardware cost by 4.7 %

Achieves single server availability target of 99.90 %

Heterogeneous-**R**eliability **M**emory [DSN 2014]

More on Heterogeneous-Reliability Memory

- Yixin Luo, Sriram Govindan, Bikash Sharma, Mark Santaniello, Justin Meza, Aman Kansal, Jie Liu, Badriddine Khessib, Kushagra Vaid, and Onur Mutlu, **"Characterizing Application Memory Error Vulnerability to Optimize Data Center Cost via Heterogeneous-Reliability Memory"** *Proceedings of the 44th Annual IEEE/IFIP International Conference on Dependable Systems and Networks (**DSN**)*, Atlanta, GA, June 2014. [Summary] [Slides (pptx) (pdf)] [Coverage on ZDNet]



Characterizing Application Memory Error Vulnerability to Optimize Datacenter Cost via Heterogeneous-Reliability Memory

Yixin Luo Sriram Govindan* Bikash Sharma* Mark Santaniello* Justin Meza
Aman Kansal* Jie Liu* Badriddine Khessib* Kushagra Vaid* Onur Mutlu

Carnegie Mellon University, yixinluo@cs.cmu.edu, {meza, onur}@cmu.edu
*Microsoft Corporation, {srgovin, bsharma, marksan, kansal, jie.liu, bkhessib, kvaid}@microsoft.com

Summary: Memory Reliability and Security

- Memory reliability is reducing
- Reliability issues open up security vulnerabilities
  - Very hard to defend against
- Rowhammer is an example
  - Its implications on system security research are tremendous & exciting

- **Good news: We have a lot more to do.**
- Understand: Solid methodologies for failure modeling and discovery
  - Modeling based on real device data – small scale and large scale
- Architect: Principled co-architecting of system and memory
  - Good partitioning of duties across the stack
- Design & Test: Principled electronic design, automation, testing
  - High coverage and good interaction with system reliability methods

Challenge and Opportunity for Future

Fundamentally

Secure, Reliable, Safe

Computing Architectures

One Important Takeaway

Main Memory Needs Intelligent Controllers

Four Key Issues in Future Platforms

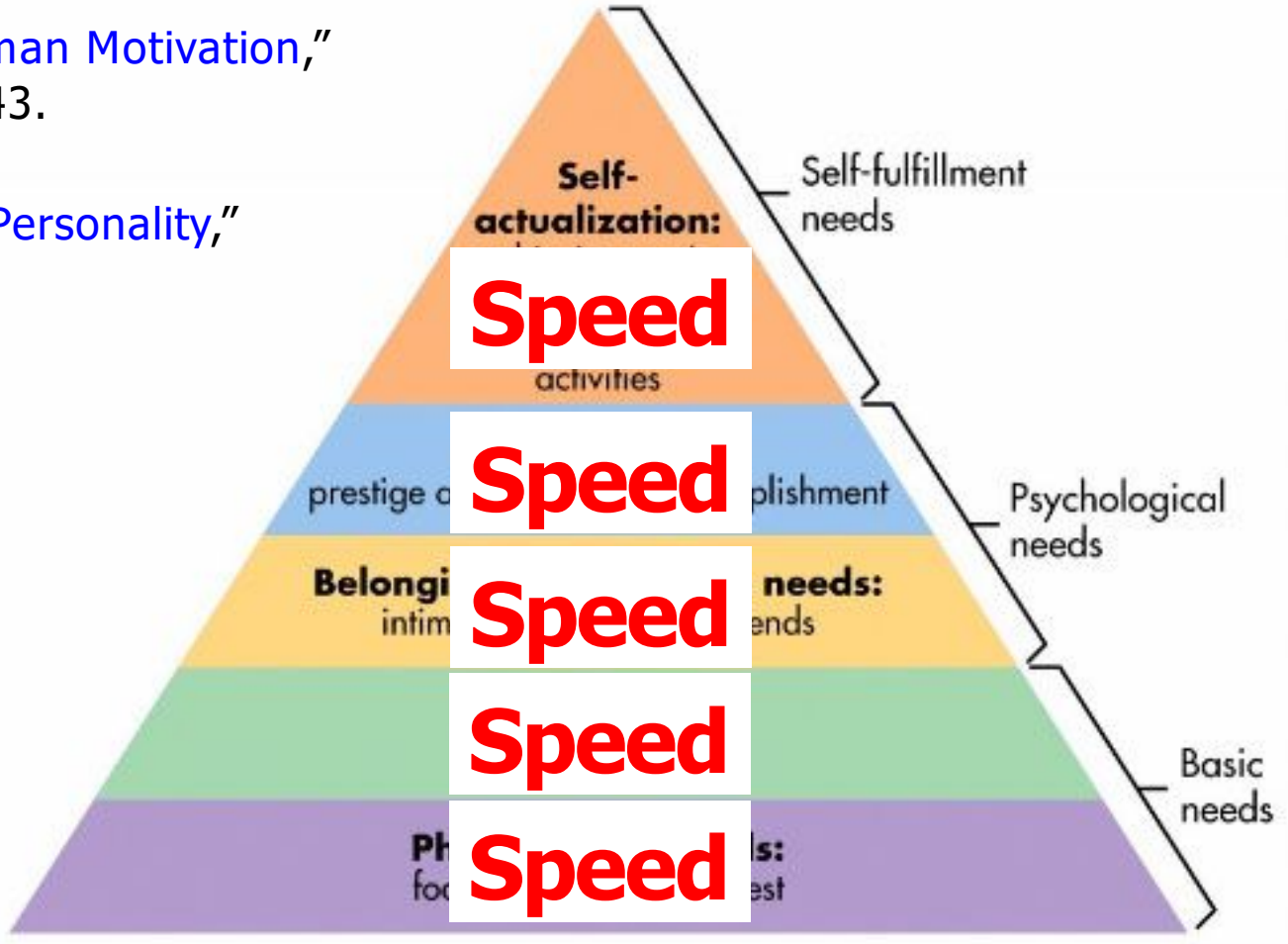
- Fundamentally Secure/Reliable/Safe Architectures
- Fundamentally Energy-Efficient Architectures
  - Memory-centric (Data-centric) Architectures
- Fundamentally Low-Latency Architectures
- Architectures for Genomics, Medicine, Health

Source: http://spectrum.ieee.org/image/MjYzMzAyMg.jpeg

Maslow's Hierarchy of Needs, A Third Time

Maslow, "A Theory of Human Motivation," Psychological Review, 1943.

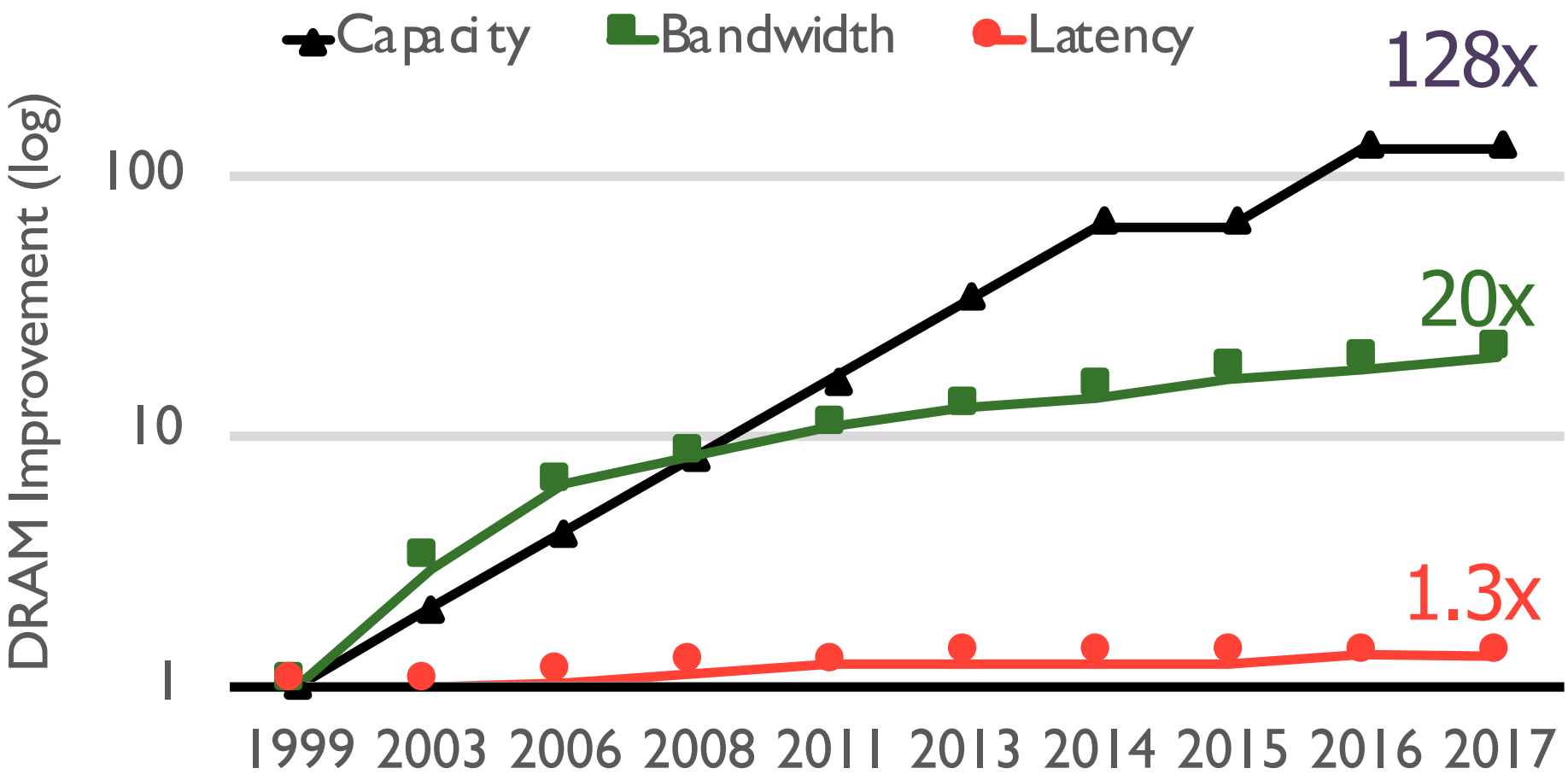
Maslow, "Motivation and Personality," Book, 1954-1970.



Source: https://www.simplypsychology.org/maslow.html

Reducing Memory Latency

Main Memory Latency Lags Behind



Memory latency remains almost constant

A Closer Look …

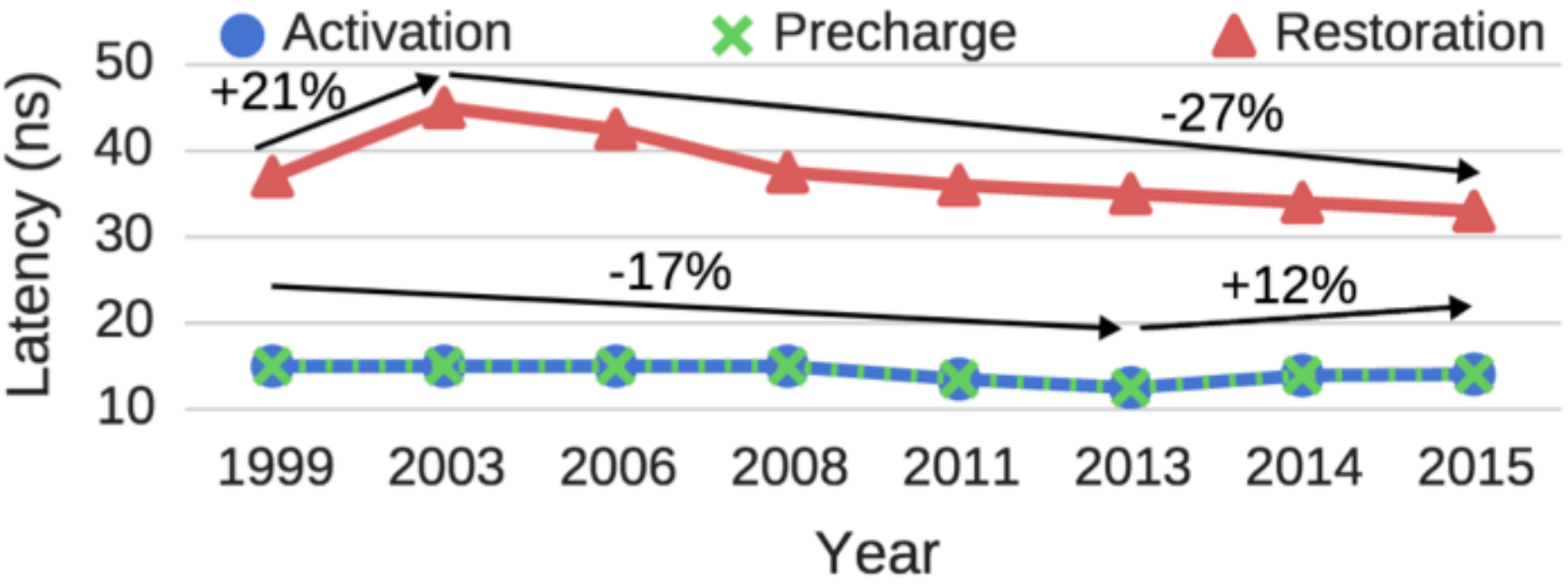
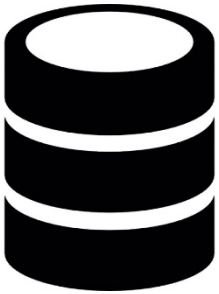


Figure 1: DRAM latency trends over time [20, 21, 23, 51].

Chang+, "**Understanding Latency Variation in Modern DRAM Chips: Experimental Characterization, Analysis, and Optimization**," SIGMETRICS 2016.

DRAM Latency Is Critical for Performance



In-memory Databases

[Mao+, EuroSys'12;
Clapp+ (**Intel**), IISWC'15]

Graph/Tree Processing

[Xu+, IISWC'12; Umuroglu+, FPL'15]

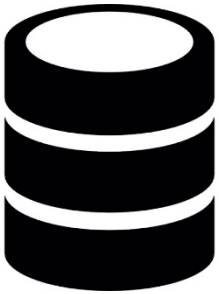
In-Memory Data Analytics

[Clapp+ (**Intel**), IISWC'15;
Awan+, BDCloud'15]

Datacenter Workloads

[Kanev+ (**Google**), ISCA'15]

DRAM Latency Is Critical for Performance



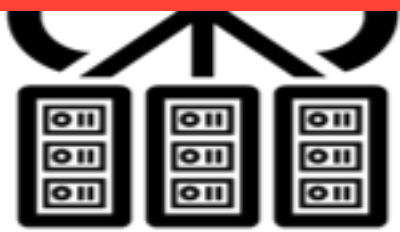
In-memory Databases

Graph/Tree Processing

Long memory latency → performance bottleneck

In-Memory Data Analytics

[Clapp+ (**Intel**), IISWC'15; Awan+, BDCloud'15]



Datacenter Workloads

[Kanev+ (**Google**), ISCA'15]

Two Major Sources of Latency Inefficiency

- Modern DRAM is **not** designed for low latency
  - Main focus is cost-per-bit (capacity)
- Modern DRAM latency is determined by **worst case** conditions and **worst case** devices
  - Much of memory latency is unnecessary

Our Goal: Reduce Memory Latency at the Source of the Problem

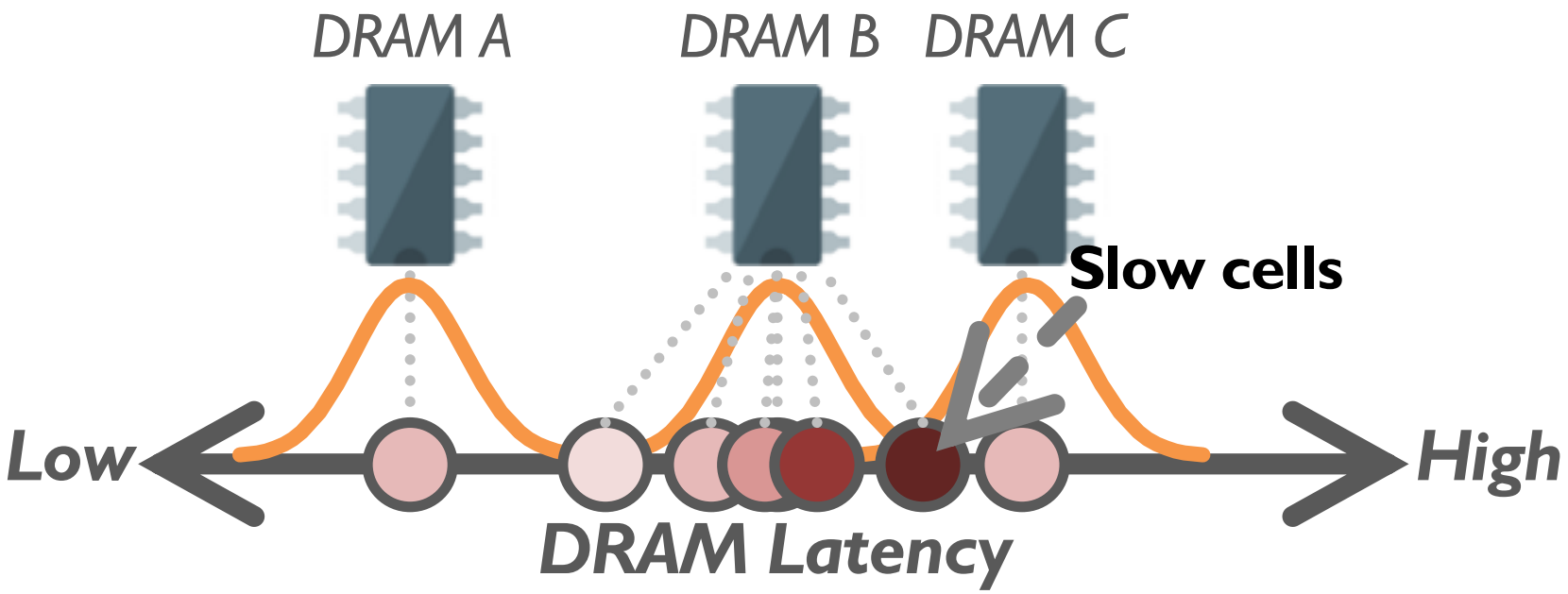
Why the Long Memory Latency?

- Reason 1: Design of DRAM Micro-architecture
  - Goal: Maximize capacity/area, not minimize latency

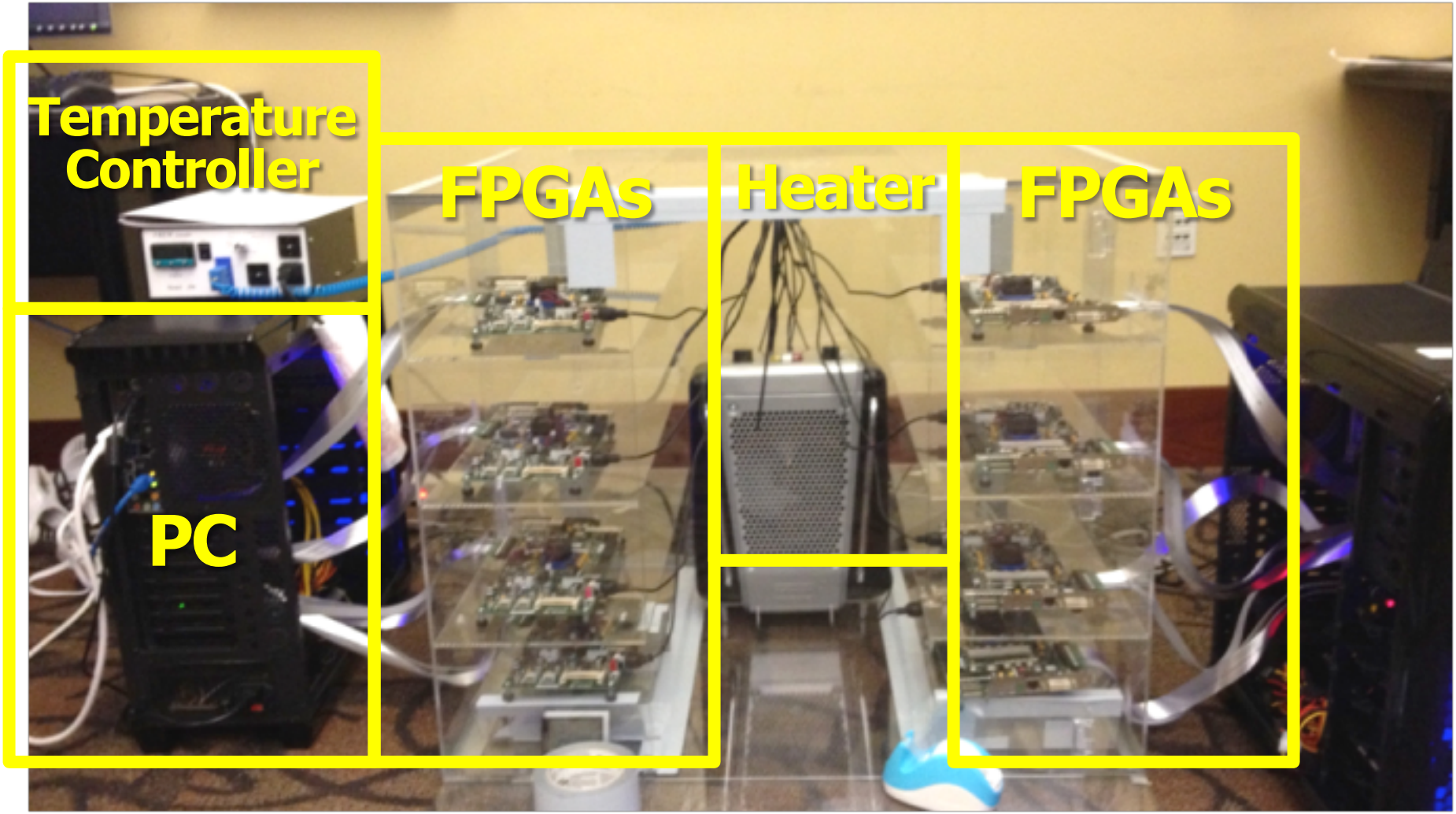
- Reason 2: "One size fits all" approach to latency specification
  - Same latency parameters for all temperatures
  - Same latency parameters for all DRAM chips (e.g., rows)
  - Same latency parameters for all parts of a DRAM chip
  - Same latency parameters for all supply voltage levels
  - Same latency parameters for all application data
  - …

Latency Variation in Memory Chips

Heterogeneous manufacturing & operating conditions → latency variation in timing parameters



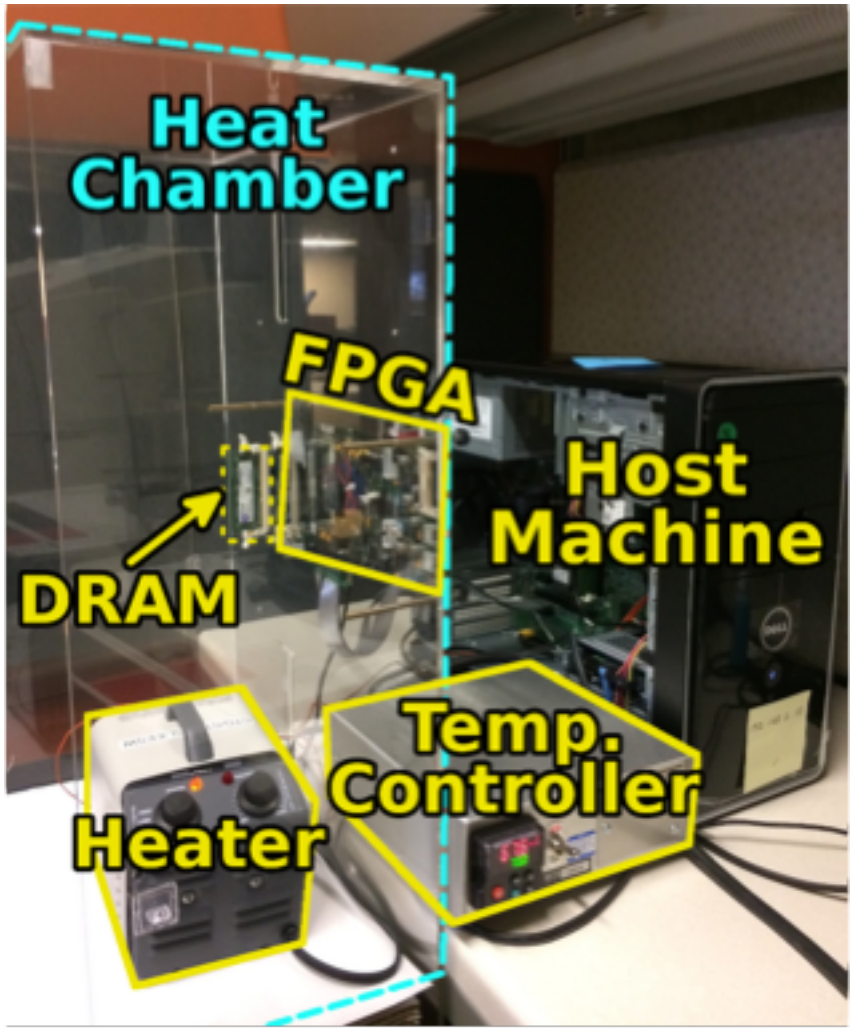
DRAM Characterization Infrastructure



Kim+, "Flipping Bits in Memory Without Accessing Them: An Experimental Study of DRAM Disturbance Errors," ISCA 2014.

DRAM Characterization Infrastructure

- Hasan Hassan et al., **SoftMC: A Flexible and Practical Open-Source Infrastructure for Enabling Experimental DRAM Studies**, HPCA 2017.



- **Flexible**
- **Easy to Use (C++ API)**
- **Open-source**

  github.com/CMU-SAFARI/SoftMC

SoftMC: Open Source DRAM Infrastructure

- https://github.com/CMU-SAFARI/SoftMC

SoftMC: A Flexible and Practical Open-Source Infrastructure for Enabling Experimental DRAM Studies

Hasan Hassan[1,2,3] Nandita Vijaykumar[3] Samira Khan[4,3] Saugata Ghose[3] Kevin Chang[3]
Gennady Pekhimenko[5,3] Donghyuk Lee[6,3] Oguz Ergin[2] Onur Mutlu[1,3]

[1]*ETH Zürich* [2]*TOBB University of Economics & Technology* [3]*Carnegie Mellon University*
[4]*University of Virginia* [5]*Microsoft Research* [6]*NVIDIA Research*

Tackling the Fixed Latency Mindset

- Reliable operation latency is actually very heterogeneous
  - Across temperatures, chips, parts of a chip, voltage levels, …
- Idea: Dynamically find out and use the lowest latency one can reliably access a memory location with
  - Adaptive-Latency DRAM [HPCA 2015]
  - Flexible-Latency DRAM [SIGMETRICS 2016]
  - Design-Induced Variation-Aware DRAM [SIGMETRICS 2017]
  - Voltron [SIGMETRICS 2017]
  - DRAM Latency PUF [HPCA 2018]
  - …
- We would like to find sources of latency heterogeneity and exploit them to minimize latency

Adaptive-Latency DRAM

- *Key idea*
  - **Optimize DRAM timing parameters online**

- *Two components*
  - DRAM manufacturer provides multiple sets of reliable DRAM timing parameters at different temperatures for each DIMM
  - System monitors DRAM temperature & uses appropriate DRAM timing parameters

Lee+, "Adaptive-Latency DRAM: Optimizing DRAM Timing for the Common-Case," HPCA 2015.

Latency Reduction Summary of 115 DIMMs

- *Latency reduction for read & write (55°C)*
  - *Read Latency:* ***32.7%***
  - *Write Latency:* ***55.1%***
- *Latency reduction for each timing parameter (55°C)*
  - *Sensing:* ***17.3%***
  - *Restore:* ***37.3%*** *(read),* ***54.8%*** *(write)*
  - *Precharge:* ***35.2%***

Lee+, "Adaptive-Latency DRAM: Optimizing DRAM Timing for the Common-Case," HPCA 2015.

AL-DRAM: Real System Evaluation

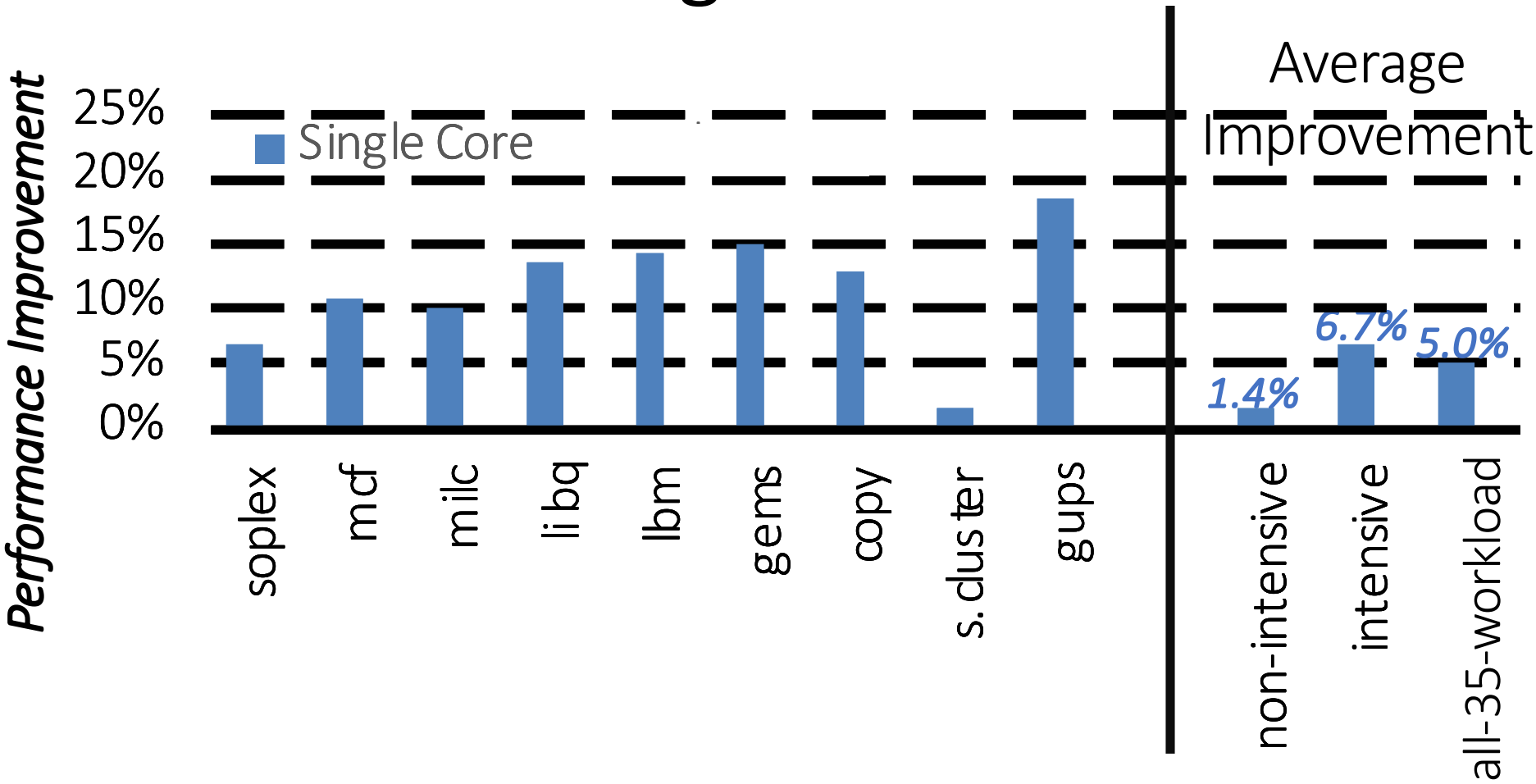
- *System*
  - *CPU: AMD 4386 (8 Cores, 3.1GHz, 8MB LLC)*

D18F2x200_dct[0]_mp[1:0] DDR3 DRAM Timing 0

Reset: 0F05_0505h. See 2.9.3 [DCT Configuration Registers].

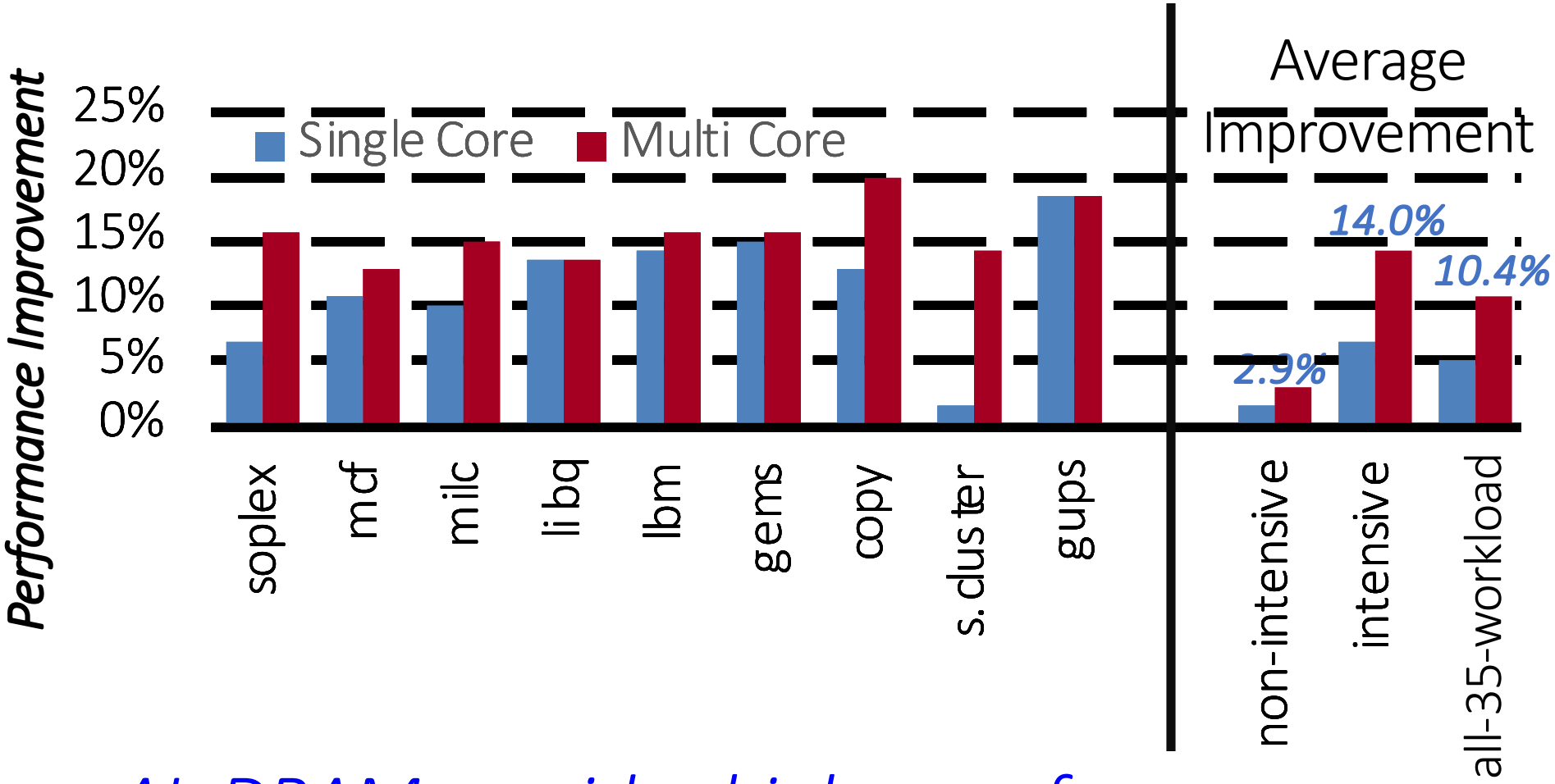
Bits	Description
31:30	Reserved.
29:24	**Tras: row active strobe**. Read-write. BIOS: See 2.9.7.5 [SPD ROM-Based Configuration]. Specifies the minimum time in memory clock cycles from an activate command to a precharge command, both to the same chip select bank. Bits — Description 07h-00h — Reserved 2Ah-08h — <Tras> clocks 3Fh-2Bh — Reserved
23:21	Reserved.
20:16	**Trp: row precharge time**. Read-write. BIOS: See 2.9.7.5 [SPD ROM-Based Configuration]. Specifies the minimum time in memory clock cycles from a precharge command to an activate command or auto refresh command, both to the same bank.

AL-DRAM: Single-Core Evaluation



AL-DRAM ***improves single-core performance*** *on a real system*

AL-DRAM: Multi-Core Evaluation



AL-DRAM provides higher performance on

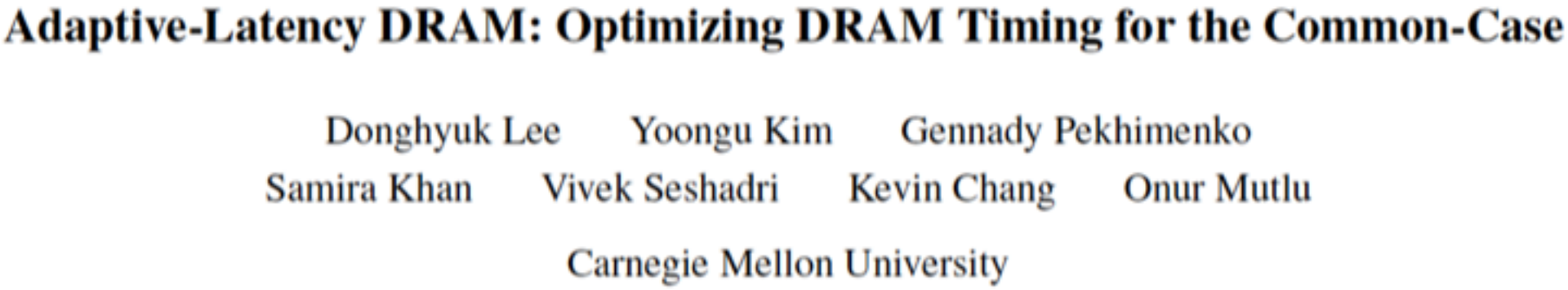
multi-programmed & multi-threaded workloads

Reducing Latency Also Reduces Energy

- AL-DRAM reduces DRAM power consumption by 5.8%
- Major reason: reduction in row activation time

More on Adaptive-Latency DRAM

- Donghyuk Lee, Yoongu Kim, Gennady Pekhimenko, Samira Khan, Vivek Seshadri, Kevin Chang, and Onur Mutlu,
  "Adaptive-Latency DRAM: Optimizing DRAM Timing for the Common-Case"
  *Proceedings of the 21st International Symposium on High-Performance Computer Architecture (**HPCA**)*, Bay Area, CA, February 2015.
  [Slides (pptx) (pdf)] [Full data sets]


Adaptive-Latency DRAM: Optimizing DRAM Timing for the Common-Case

Donghyuk Lee Yoongu Kim Gennady Pekhimenko
Samira Khan Vivek Seshadri Kevin Chang Onur Mutlu

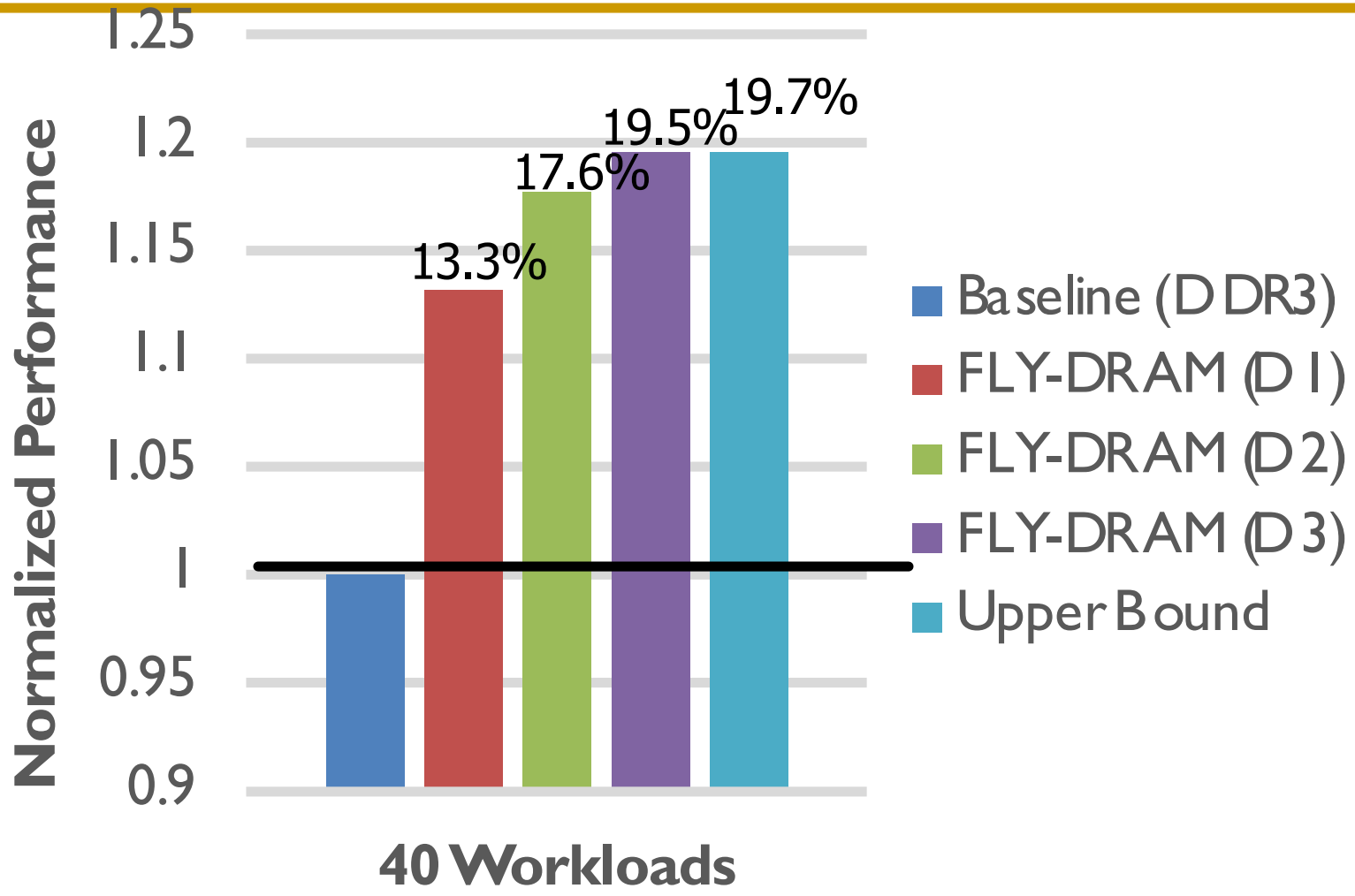
Carnegie Mellon University

Heterogeneous Latency within A Chip

- **Observation:** DRAM timing errors (slow DRAM cells) are concentrated on certain regions
- **Flexible-LatencY (FLY) DRAM**
  - A software-transparent design that reduces latency
- **Key idea**:
  1) Divide memory into regions of different latencies
  2) *Memory controller:* Use lower latency for regions without slow cells; higher latency for other regions

Chang+, "**Understanding Latency Variation in Modern DRAM Chips: Experimental Characterization, Analysis, and Optimization**," SIGMETRICS 2016.

Heterogeneous Latency within A Chip

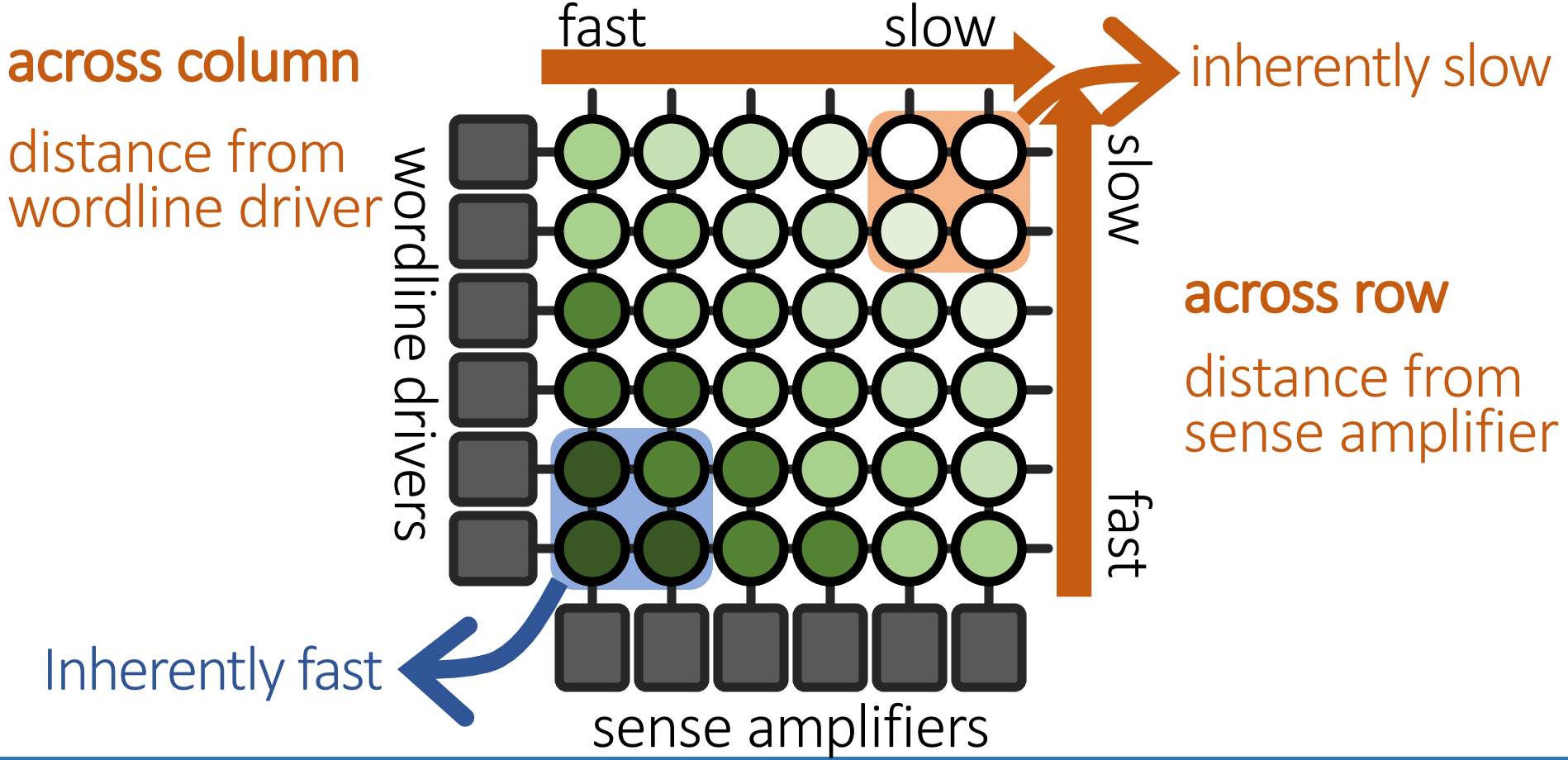


Chang+, "**Understanding Latency Variation in Modern DRAM Chips: Experimental Characterization, Analysis, and Optimization**," SIGMETRICS 2016.

Analysis of Latency Variation in DRAM Chips

- Kevin Chang, Abhijith Kashyap, Hasan Hassan, Samira Khan, Kevin Hsieh, Donghyuk Lee, Saugata Ghose, Gennady Pekhimenko, Tianshi Li, and Onur Mutlu,
  "Understanding Latency Variation in Modern DRAM Chips: Experimental Characterization, Analysis, and Optimization"
  Proceedings of the ACM International Conference on Measurement and Modeling of Computer Systems (***SIGMETRICS***), Antibes Juan-Les-Pins, France, June 2016.
  [Slides (pptx) (pdf)]
  [Source Code]

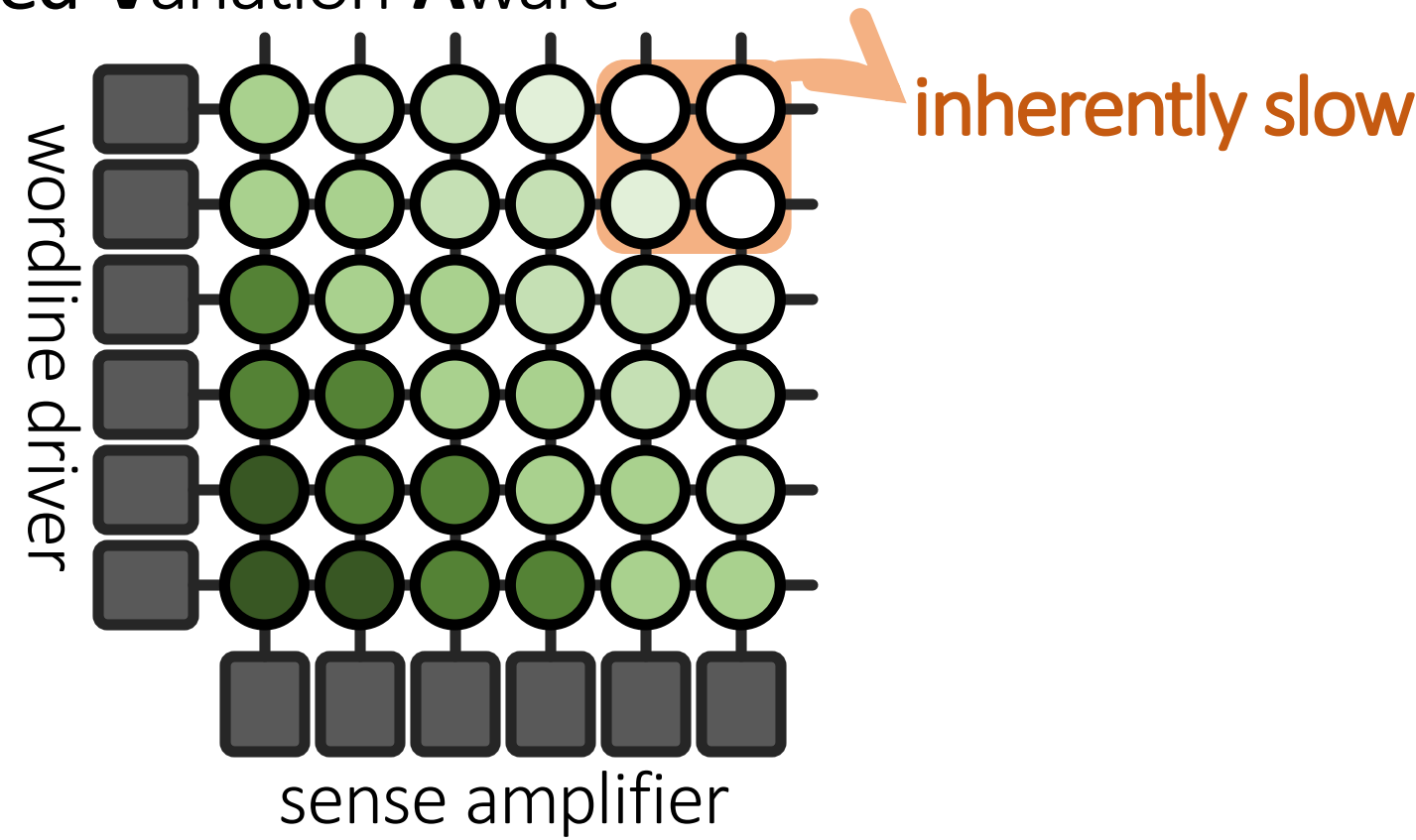
What Is Design-Induced Variation?



Systematic variation in cell access times caused by the ***physical organization*** of DRAM

DIVA Online **Profiling**

Design-**I**nduced-**V**ariation-**A**ware

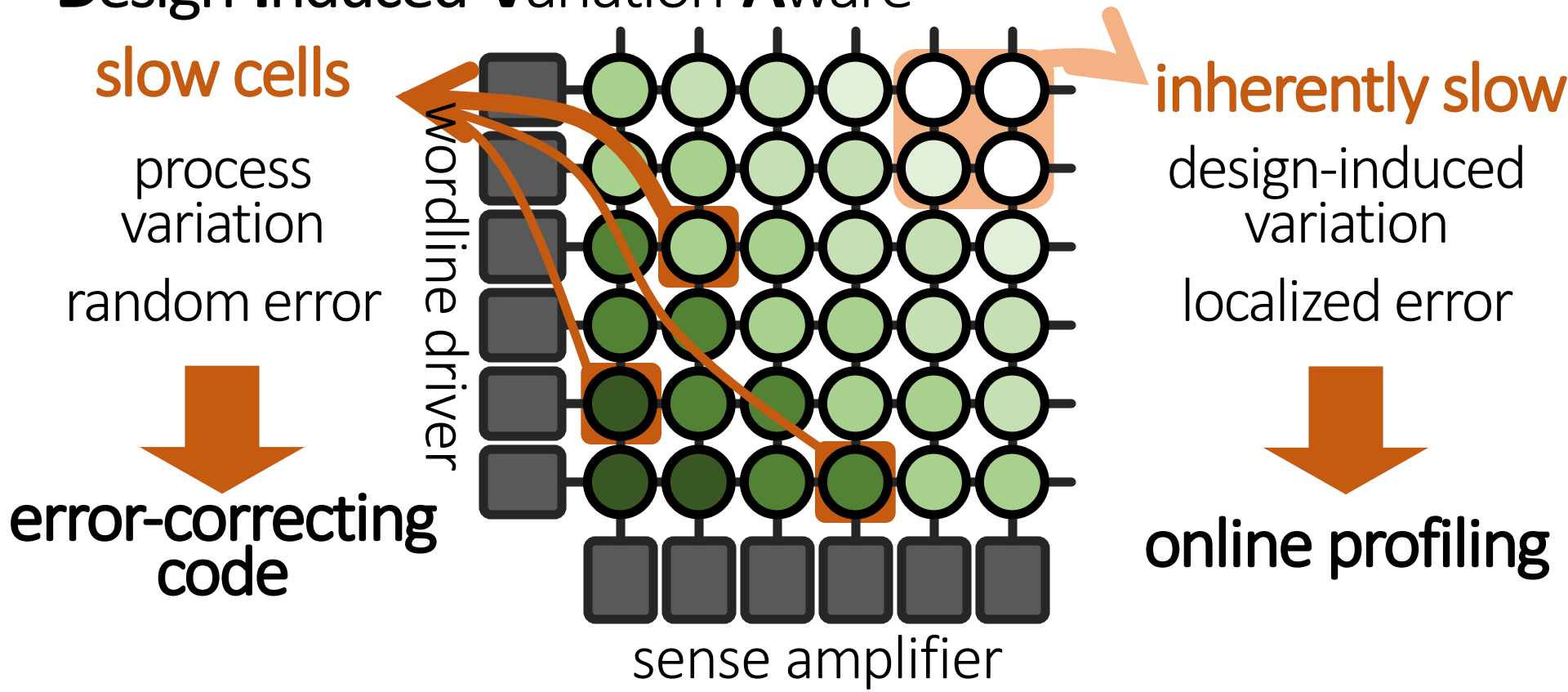


Profile *only slow regions* to determine min. latency

→ *Dynamic* & *low cost* latency optimization

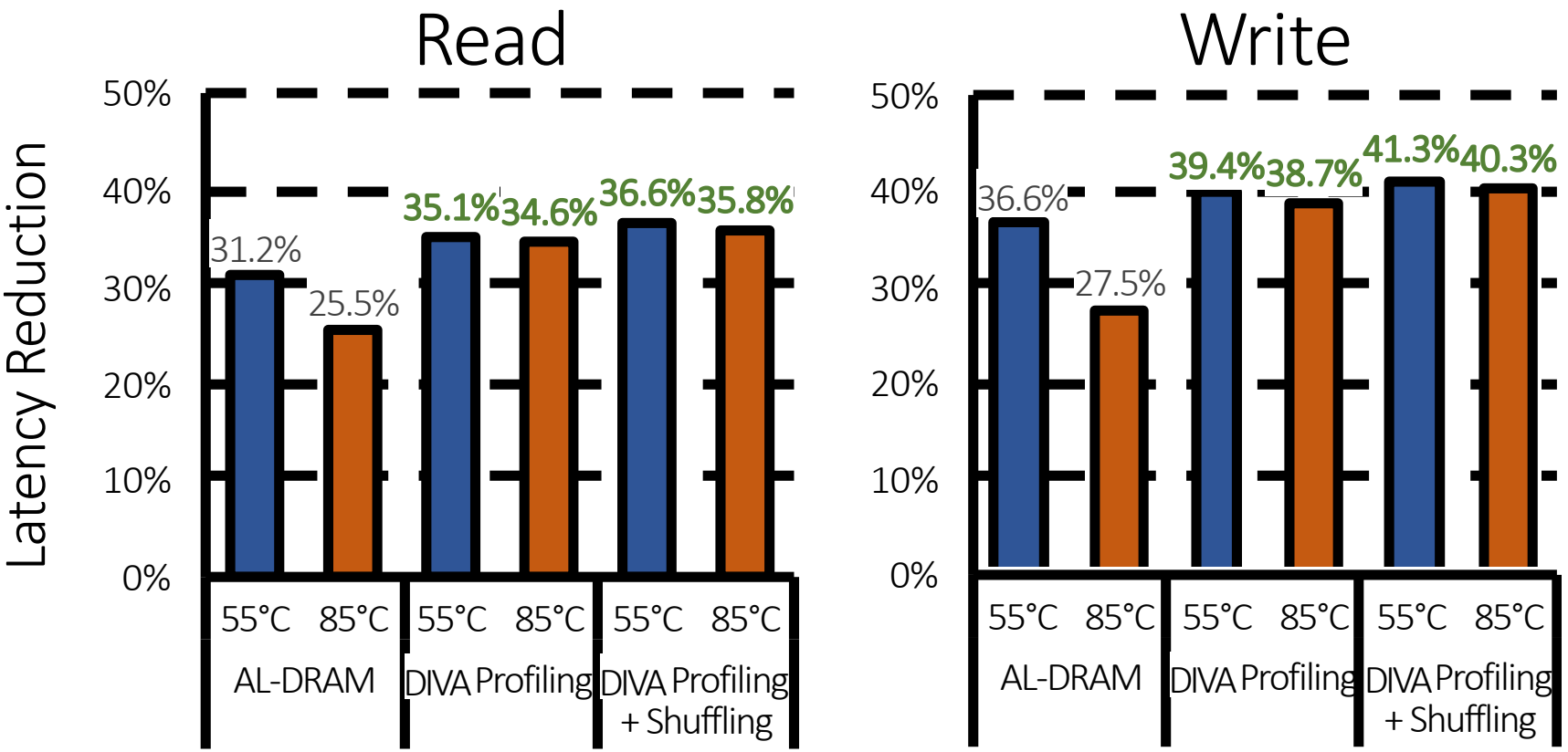
DIVA Online **Profiling**

Design-**I**nduced-**V**ariation-**A**ware



Combine **error-correcting codes** & **online profiling**
→ **Reliably** reduce DRAM latency

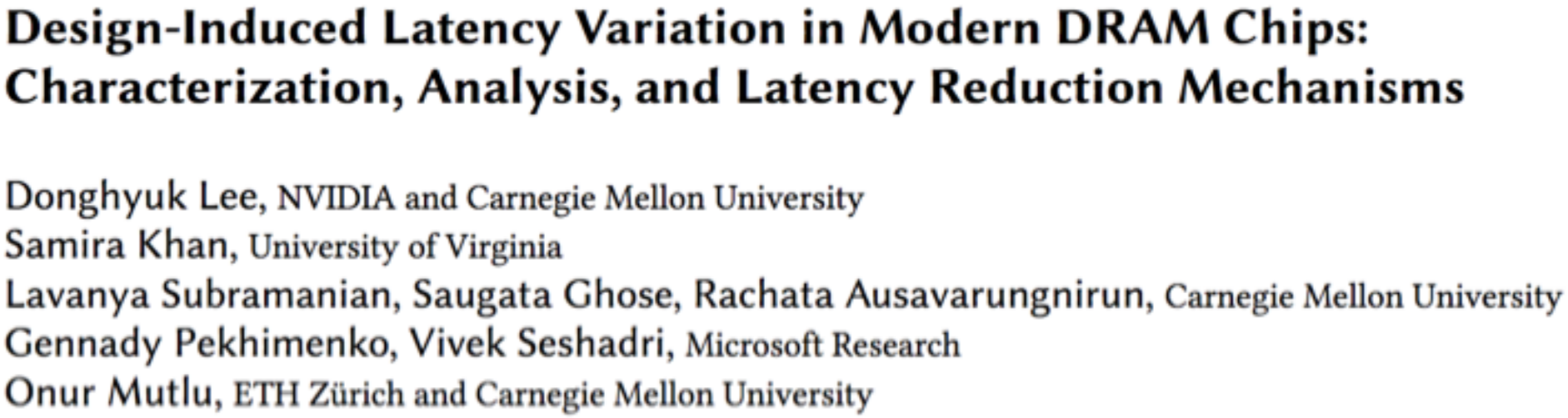
DIVA-DRAM Reduces Latency



DIVA-DRAM ***reduces latency more aggressively*** and uses ECC to correct random slow cells

Design-Induced Latency Variation in DRAM

- Donghyuk Lee, Samira Khan, Lavanya Subramanian, Saugata Ghose, Rachata Ausavarungnirun, Gennady Pekhimenko, Vivek Seshadri, and Onur Mutlu,
  "Design-Induced Latency Variation in Modern DRAM Chips: Characterization, Analysis, and Latency Reduction Mechanisms"
  *Proceedings of the ACM International Conference on Measurement and Modeling of Computer Systems (**SIGMETRICS**)*, Urbana-Champaign, IL, USA, June 2017.



Design-Induced Latency Variation in Modern DRAM Chips: Characterization, Analysis, and Latency Reduction Mechanisms

Donghyuk Lee, NVIDIA and Carnegie Mellon University
Samira Khan, University of Virginia
Lavanya Subramanian, Saugata Ghose, Rachata Ausavarungnirun, Carnegie Mellon University
Gennady Pekhimenko, Vivek Seshadri, Microsoft Research
Onur Mutlu, ETH Zürich and Carnegie Mellon University

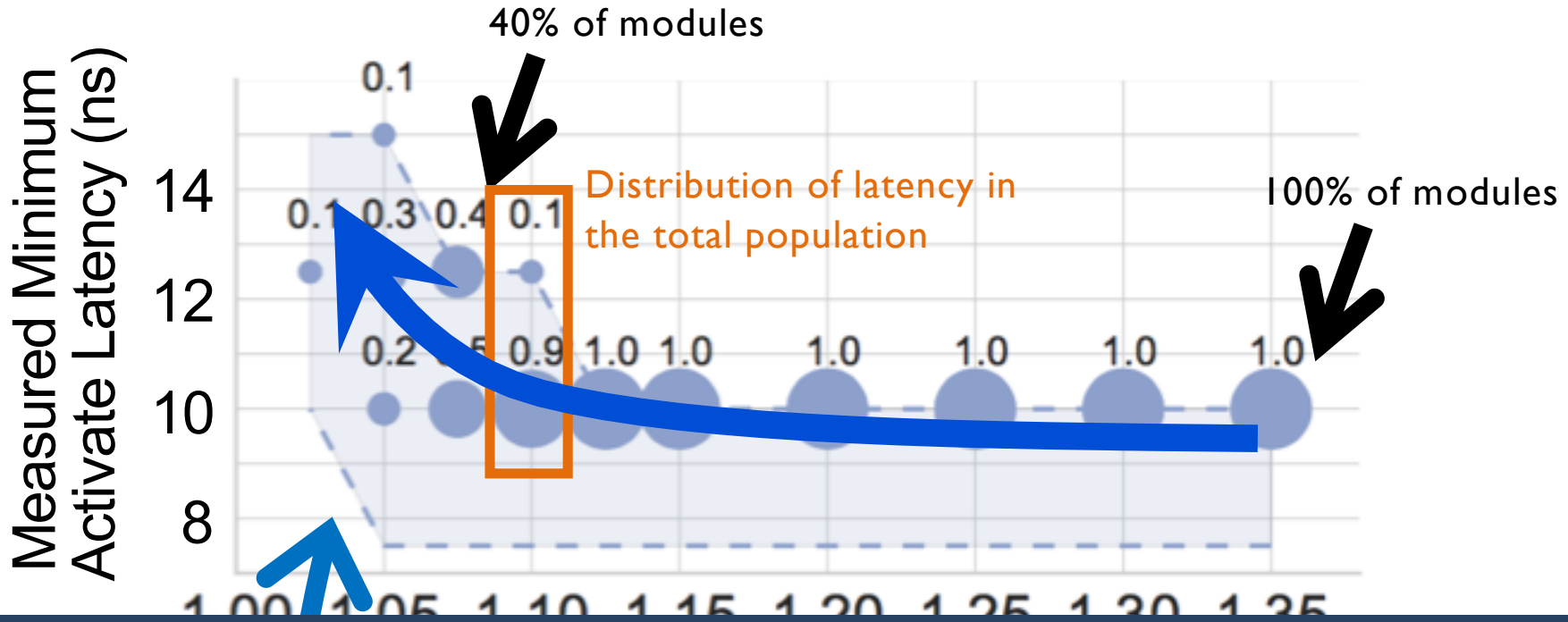
Voltron: Exploiting the Voltage-Latency-Reliability Relationship

Executive Summary

- DRAM (memory) power is significant in today's systems
  - Existing low-voltage DRAM reduces voltage **conservatively**
- Goal: Understand and exploit the reliability and latency behavior of real DRAM chips under ***aggressive reduced-voltage operation***
- Key experimental observations:
  - Huge voltage margin -- Errors occur beyond some voltage
  - Errors exhibit spatial locality
  - Higher operation latency mitigates voltage-induced errors
- **Voltron**: A new DRAM energy reduction mechanism
  - Reduce DRAM voltage **without introducing errors**
  - Use a **regression model** to select voltage that does not degrade performance beyond a chosen target → 7.3% system energy reduction

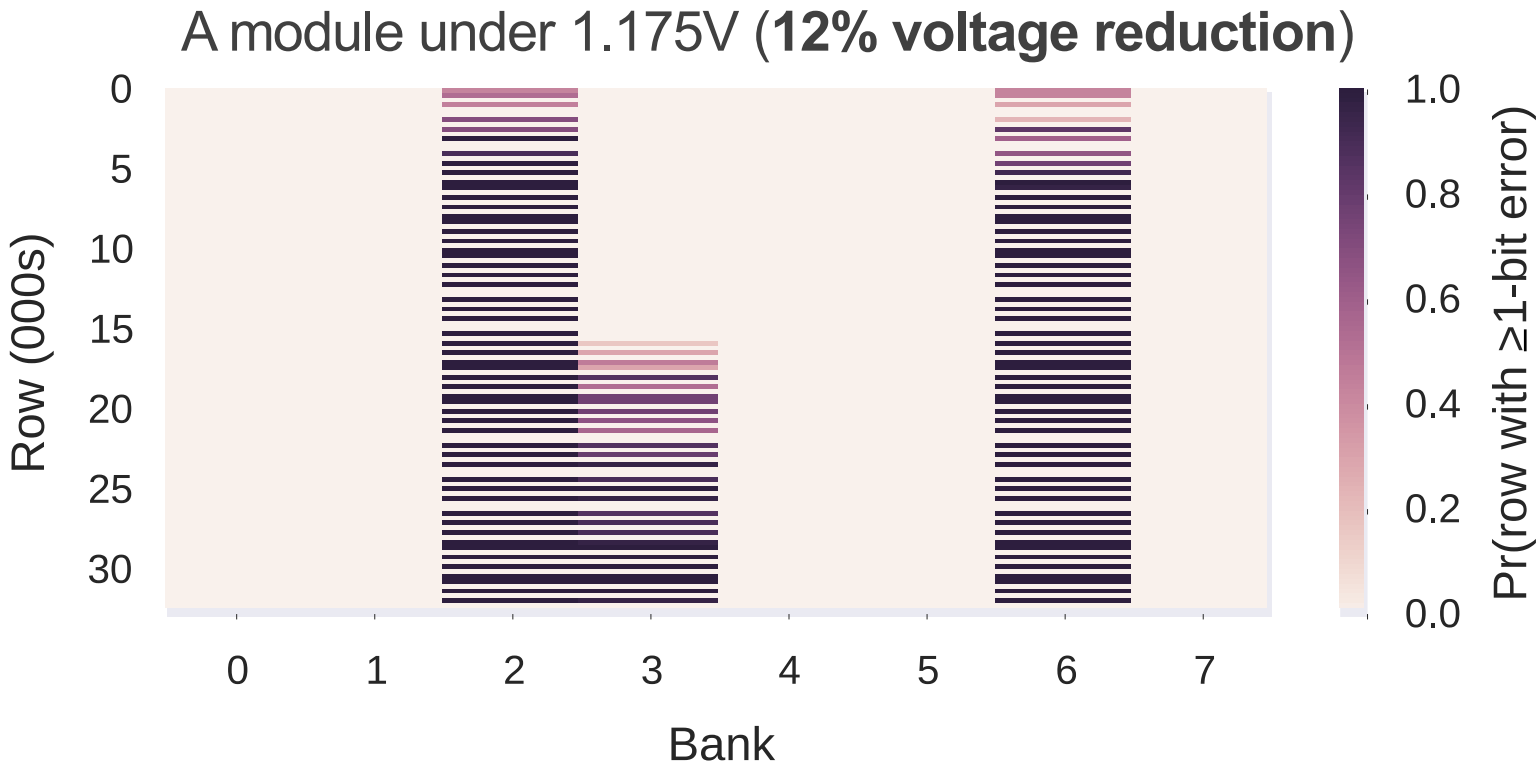
DIMMs Operating at Higher Latency

Measured minimum latency that *does* ***not*** *cause errors* in DRAM modules



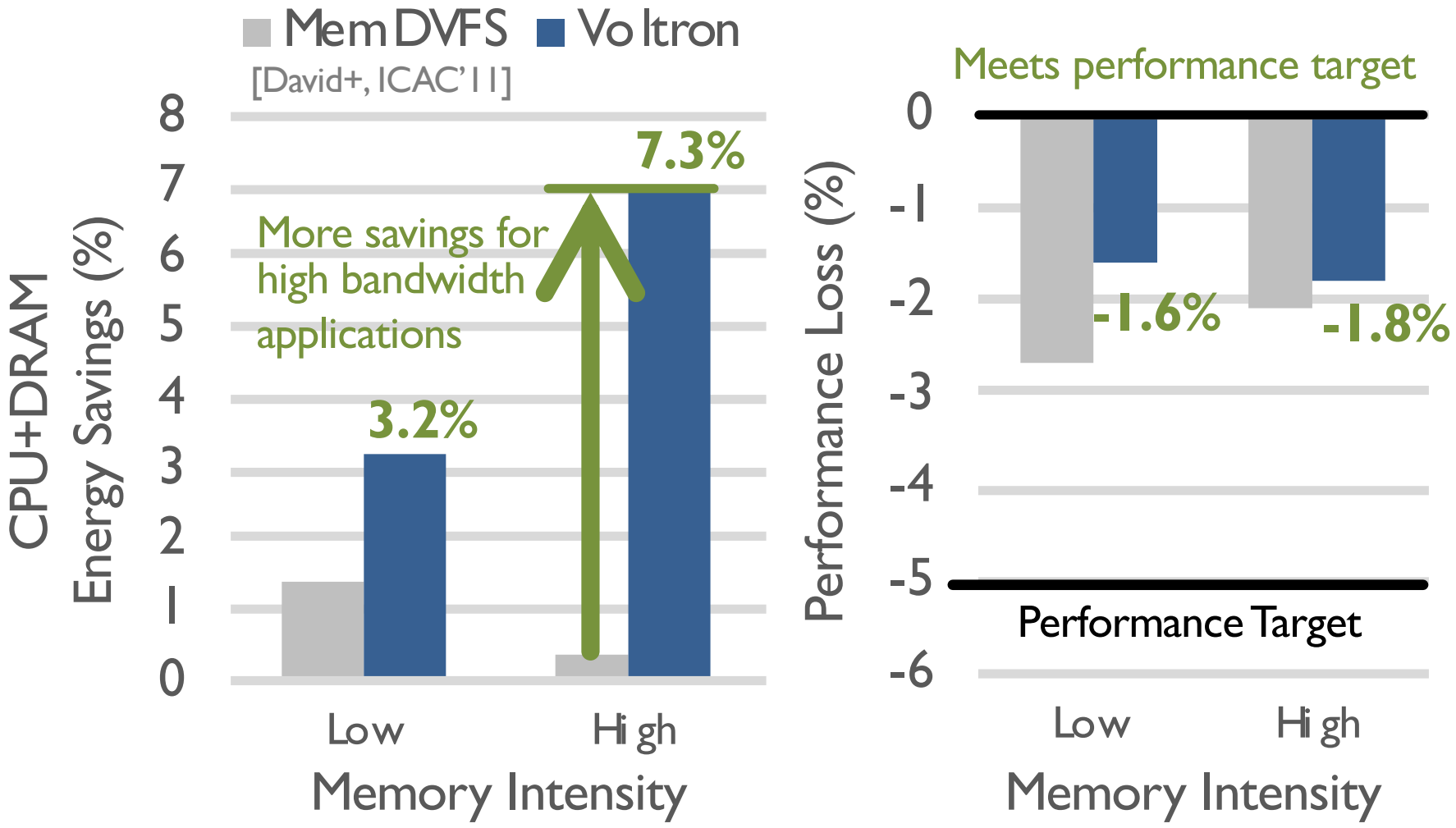
DRAM requires longer latency to access data without errors at lower voltage

Spatial Locality of Errors



Errors concentrate in certain regions

Energy Savings with Bounded Performance



Analysis of Latency-Voltage in DRAM Chips

- Kevin Chang, A. Giray Yaglikci, Saugata Ghose, Aditya Agrawal, Niladrish Chatterjee, Abhijith Kashyap, Donghyuk Lee, Mike O'Connor, Hasan Hassan, and Onur Mutlu,
  "Understanding Reduced-Voltage Operation in Modern DRAM Devices: Experimental Characterization, Analysis, and Mechanisms"
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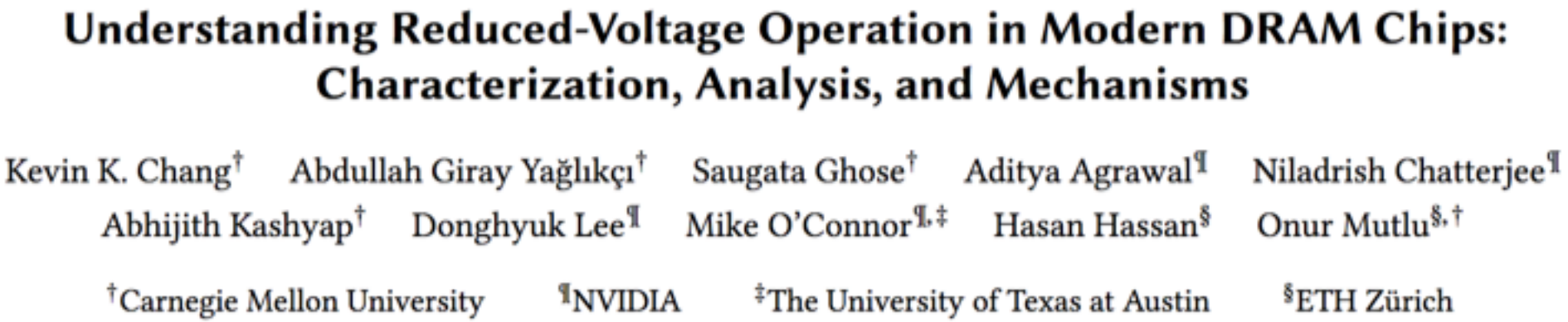


Understanding Reduced-Voltage Operation in Modern DRAM Chips: Characterization, Analysis, and Mechanisms

Kevin K. Chang[†] Abdullah Giray Yağlıkçı[†] Saugata Ghose[†] Aditya Agrawal[¶] Niladrish Chatterjee[¶]
Abhijith Kashyap[†] Donghyuk Lee[¶] Mike O'Connor[¶,‡] Hasan Hassan[§] Onur Mutlu[§,†]

[†]Carnegie Mellon University [¶]NVIDIA [‡]The University of Texas at Austin [§]ETH Zürich

And, What If …

- … we can sacrifice reliability of some data to access it with even lower latency?

The DRAM Latency PUF:

Quickly Evaluating Physical Unclonable Functions by Exploiting the Latency-Reliability Tradeoff in Modern Commodity DRAM Devices

Jeremie S. Kim **Minesh Patel**

Hasan Hassan **Onur Mutlu**

SAFARI

ETH Zürich

Carnegie Mellon

Motivation

- A **PUF** is function that generates a signature **unique** to a given device

- Used in a **Challenge-Response Protocol**
  - Each device generates a unique **PUF response** depending the inputs
  - A trusted server **authenticates** a device if it generates the expected PUF response

DRAM Latency Characterization of 223 LPDDR4 DRAM Devices

- Latency failures come from accessing DRAM with **reduced** timing parameters.

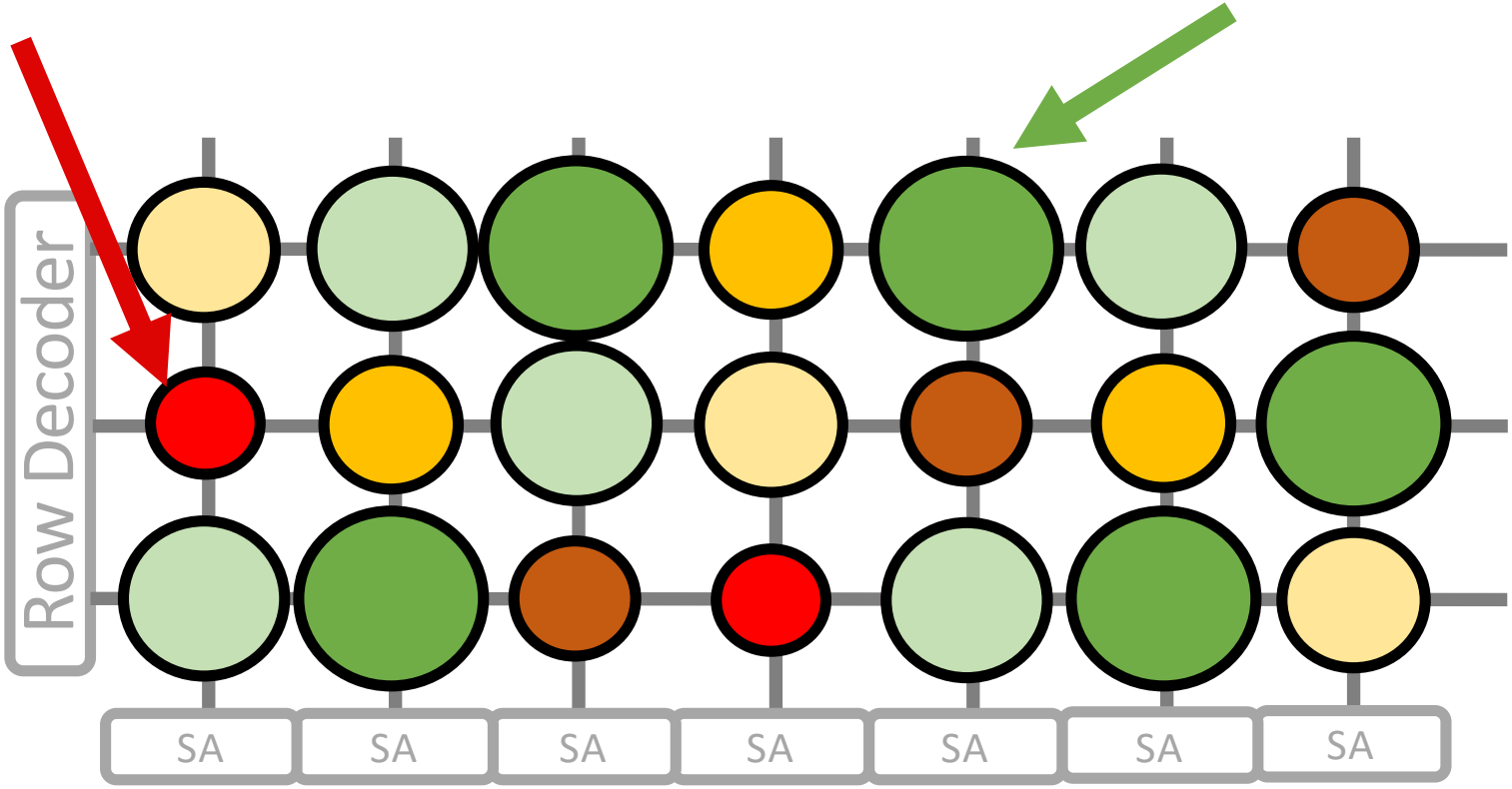
- **Key Observations:**
  1. A cell's **latency failure** probability is determined by **random process variation**

  2. Latency failure patterns are **repeatable and unique to a device**

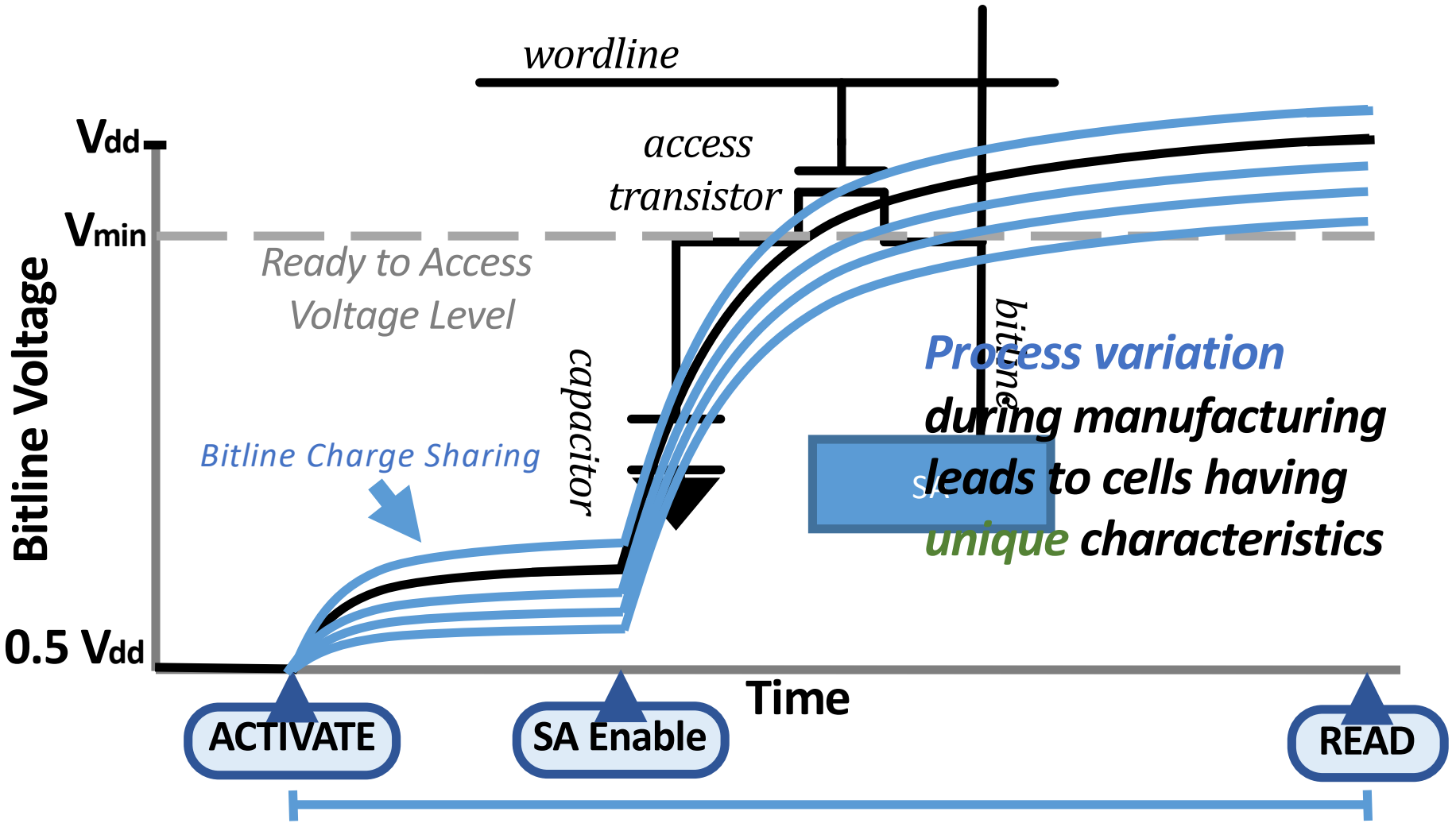
DRAM Latency PUF Key Idea

High % chance to fail with reduced t_{RCD}

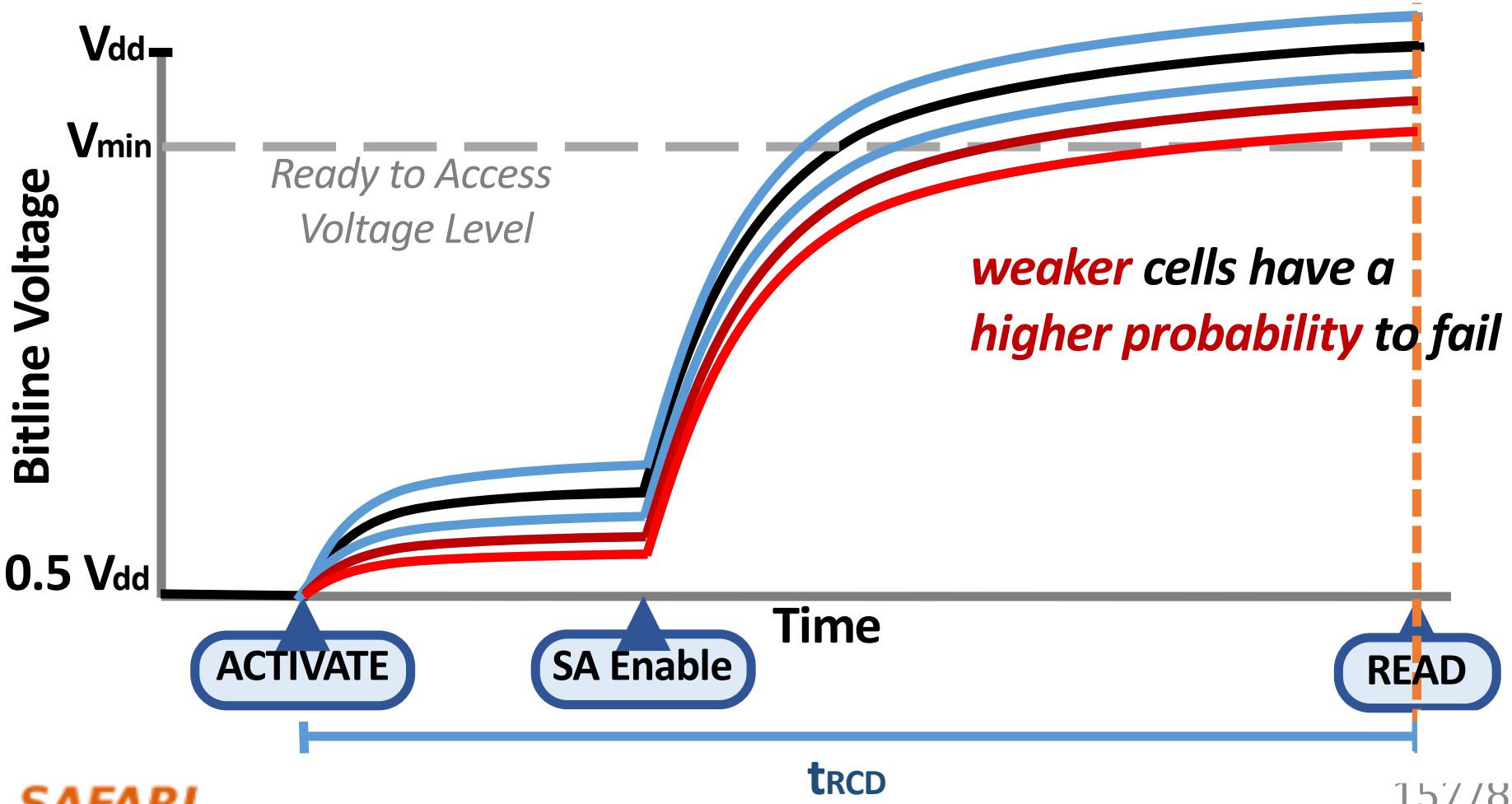
Low % chance to fail with reduced t_{RCD}



DRAM Accesses and Failures



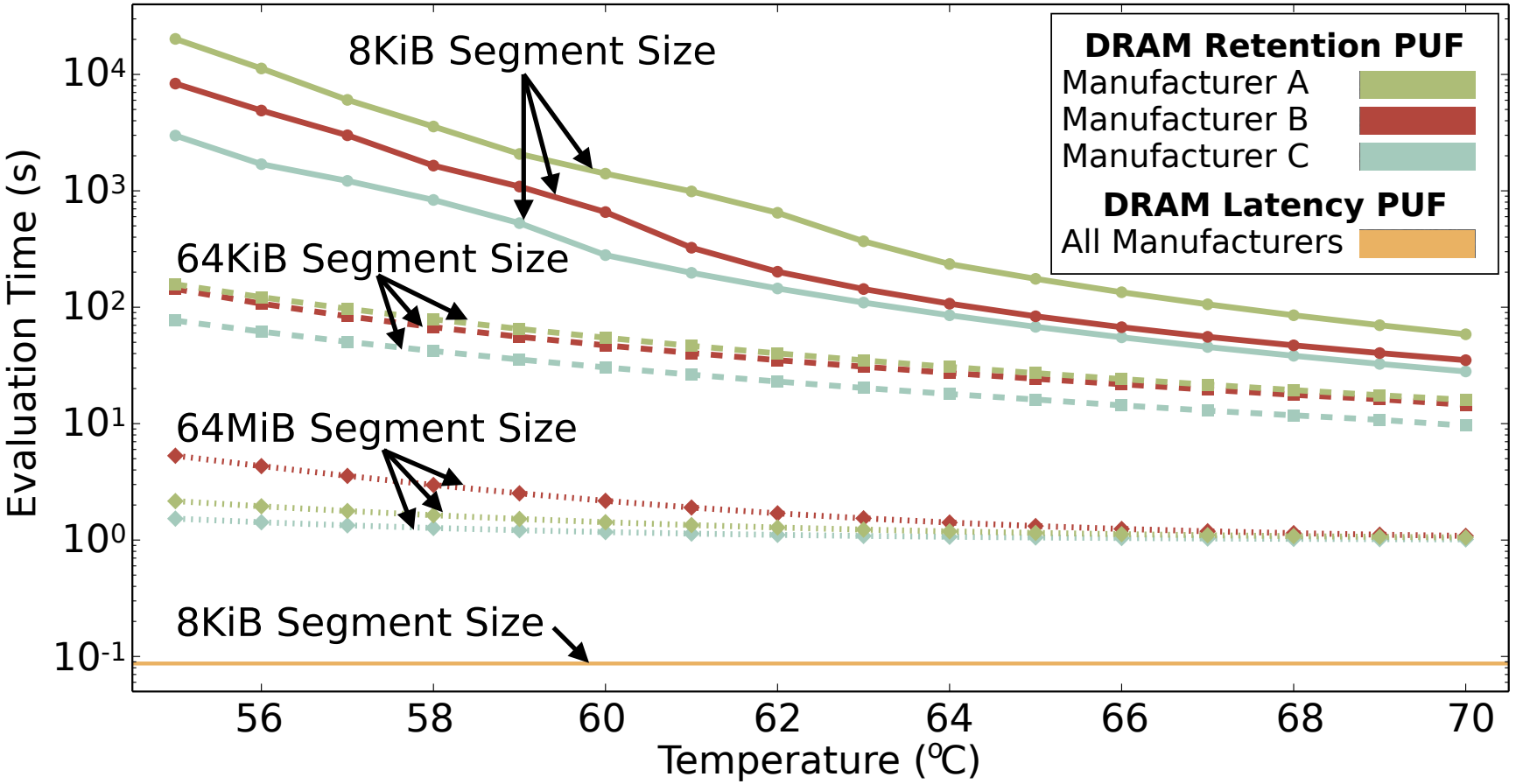
DRAM Accesses and Failures



The DRAM Latency PUF Evaluation

- We generate PUF responses using **latency errors** in a region of DRAM
- The latency error patterns **satisfy PUF requirements**
- The DRAM Latency PUF **generates PUF responses in 88.2ms**

Results



- DL-PUF is **orders of magnitude faster** than prior DRAM PUFs & temperature independent

The DRAM Latency PUF:

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Hasan Hassan **Onur Mutlu**

QR Code for the paper

https://people.inf.ethz.ch/omutlu/pub/dram-latency-puf_hpca18.pdf

HPCA 2018

Systems@ETH Zürich

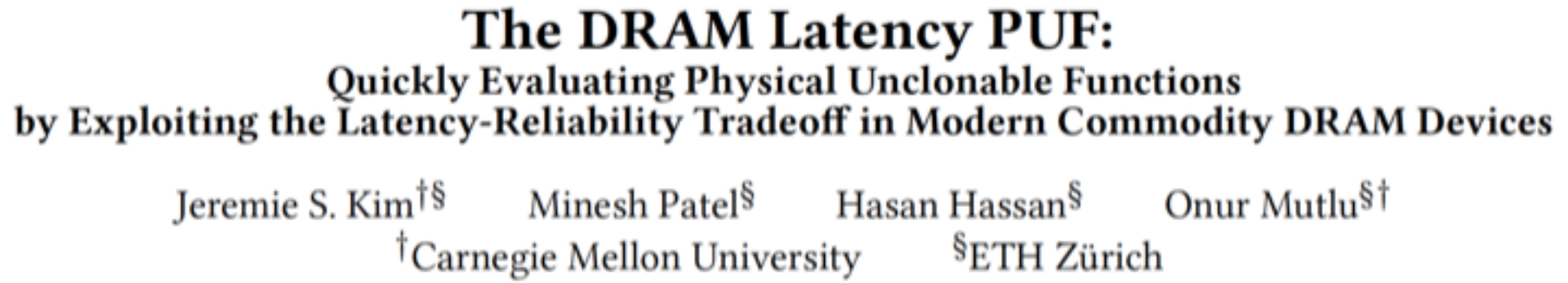
SAFARI

ETH Zürich

Carnegie Mellon

DRAM Latency PUFs

- Jeremie S. Kim, Minesh Patel, Hasan Hassan, and Onur Mutlu,
  "The DRAM Latency PUF: Quickly Evaluating Physical Unclonable Functions by Exploiting the Latency-Reliability Tradeoff in Modern DRAM Devices"
  *Proceedings of the 24th International Symposium on High-Performance Computer Architecture (**HPCA**)*, Vienna, Austria, February 2018.
  [Lightning Talk Video]
  [Slides (pptx) (pdf)] [Lightning Session Slides (pptx) (pdf)]



The DRAM Latency PUF:
Quickly Evaluating Physical Unclonable Functions by Exploiting the Latency-Reliability Tradeoff in Modern Commodity DRAM Devices

Jeremie S. Kim[†§] Minesh Patel[§] Hasan Hassan[§] Onur Mutlu[§†]
[†]Carnegie Mellon University [§]ETH Zürich

Challenge and Opportunity for Future

Fundamentally Low-Latency Computing Architectures

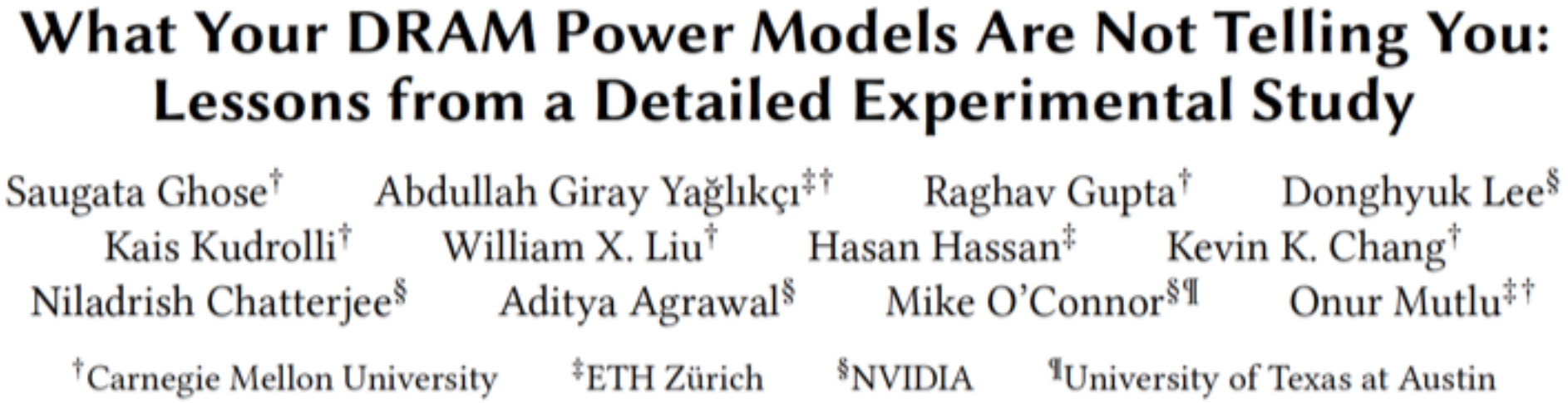
One Important Takeaway

Main Memory Needs Intelligent Controllers

On DRAM Power Consumption

VAMPIRE DRAM Power Model

- Saugata Ghose, A. Giray Yaglikci, Raghav Gupta, Donghyuk Lee, Kais Kudrolli, William X. Liu, Hasan Hassan, Kevin K. Chang, Niladrish Chatterjee, Aditya Agrawal, Mike O'Connor, and Onur Mutlu,
  "What Your DRAM Power Models Are Not Telling You: Lessons from a Detailed Experimental Study"
  Proceedings of the ACM International Conference on Measurement and Modeling of Computer Systems (***SIGMETRICS***), Irvine, CA, USA, June 2018.
  [Abstract]



What Your DRAM Power Models Are Not Telling You: Lessons from a Detailed Experimental Study

Saugata Ghose[†] Abdullah Giray Yağlıkçı[‡†] Raghav Gupta[†] Donghyuk Lee[§]
Kais Kudrolli[†] William X. Liu[†] Hasan Hassan[‡] Kevin K. Chang[†]
Niladrish Chatterjee[§] Aditya Agrawal[§] Mike O'Connor[§¶] Onur Mutlu[‡†]

[†]Carnegie Mellon University [‡]ETH Zürich [§]NVIDIA [¶]University of Texas at Austin

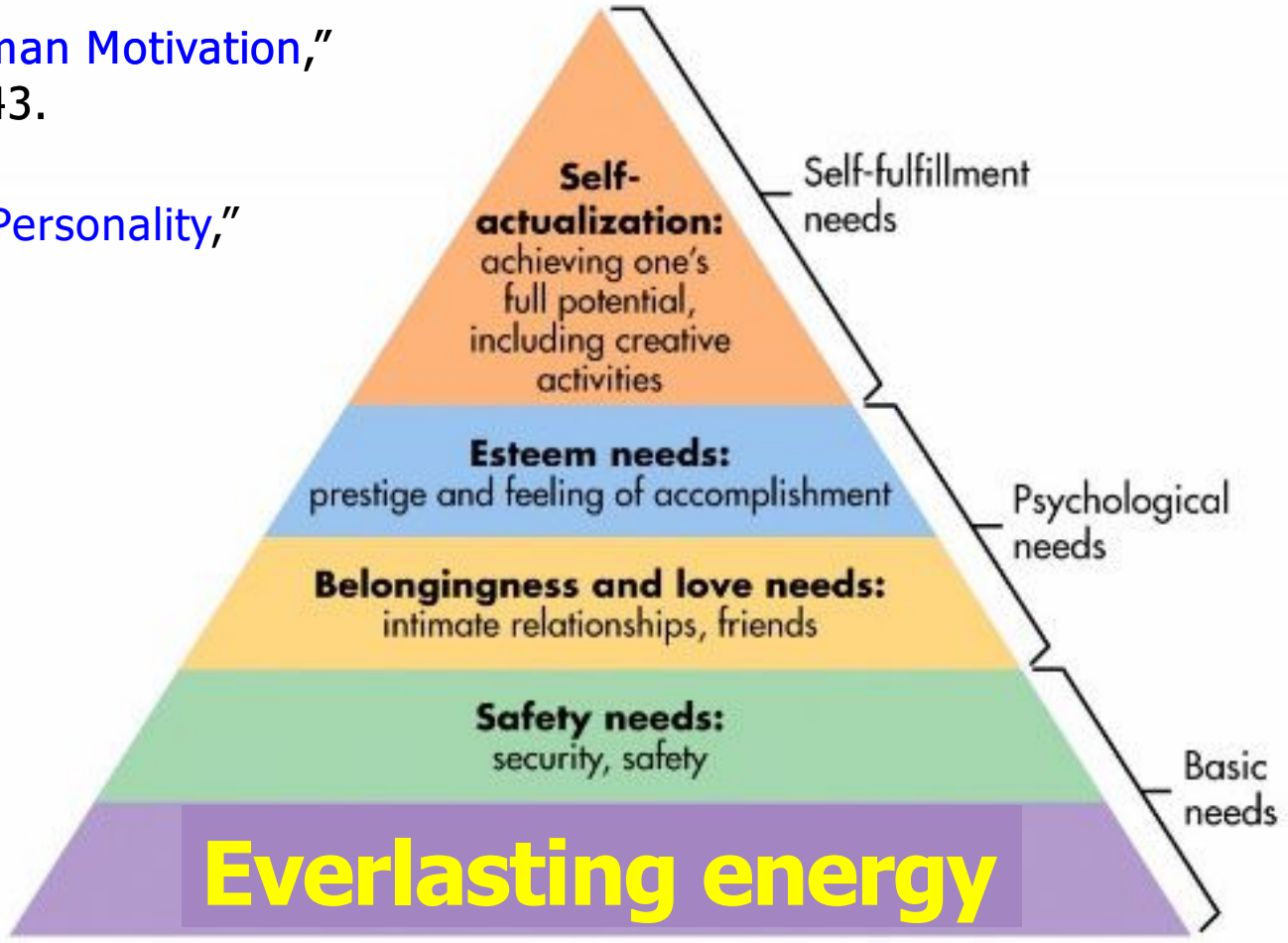
Four Key Issues in Future Platforms

- Fundamentally Secure/Reliable/Safe Architectures
- Fundamentally Energy-Efficient Architectures
  - Memory-centric (Data-centric) Architectures
- Fundamentally Low-Latency Architectures
- Architectures for Genomics, Medicine, Health

Maslow's (Human) Hierarchy of Needs, Revisited

Maslow, "A Theory of Human Motivation," Psychological Review, 1943.

Maslow, "Motivation and Personality," Book, 1954-1970.

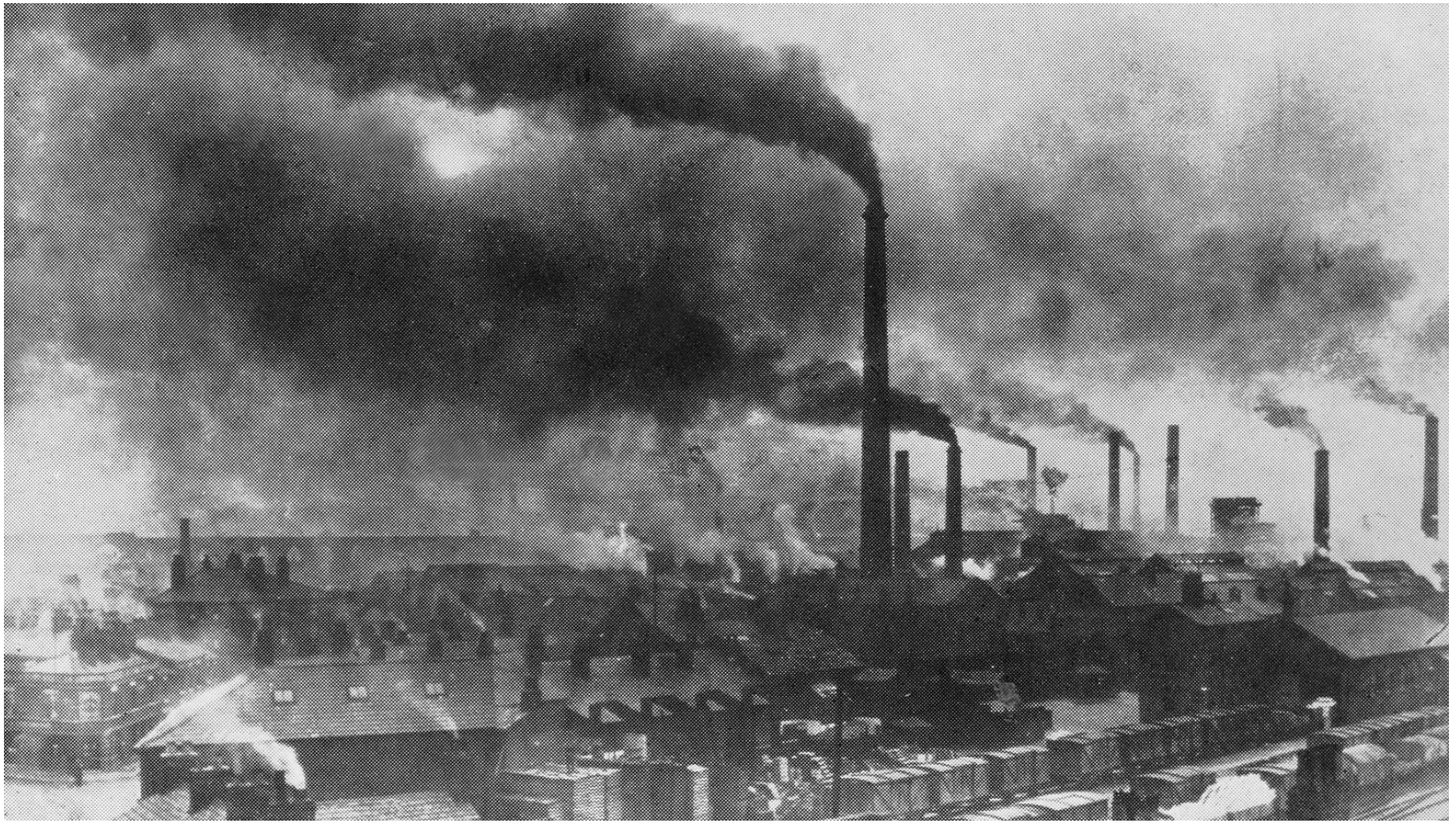


Source: https://www.simplypsychology.org/maslow.html

Do We Want This?

Source: V. Milutinovic

Or This?



Source: V. Milutinovic

Challenge and Opportunity for Future

Sustainable

and

Energy Efficient

The Problem

Data access is the major performance and energy bottleneck

Our current

design principles

cause great energy waste

(and great performance loss)

The Problem

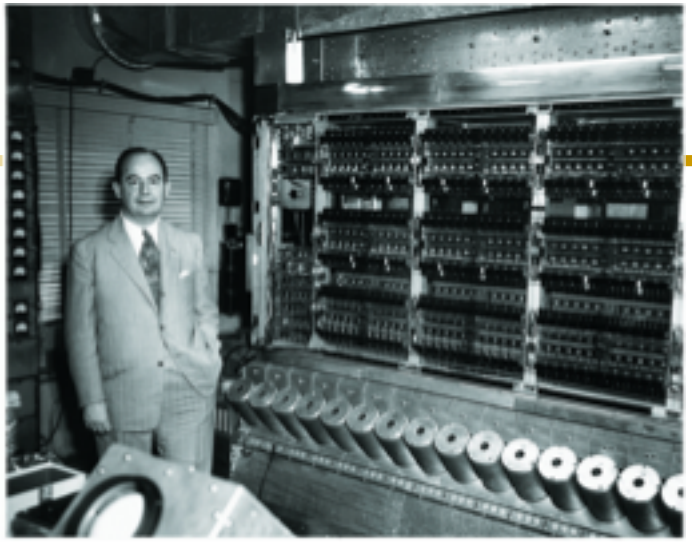
Processing of data

is performed

far away from the data

A Computing System

- Three key components
- Computation
- Communication
- Storage/memory



Burks, Goldstein, von Neumann, "Preliminary discussion of the logical design of an electronic computing instrument," 1946.

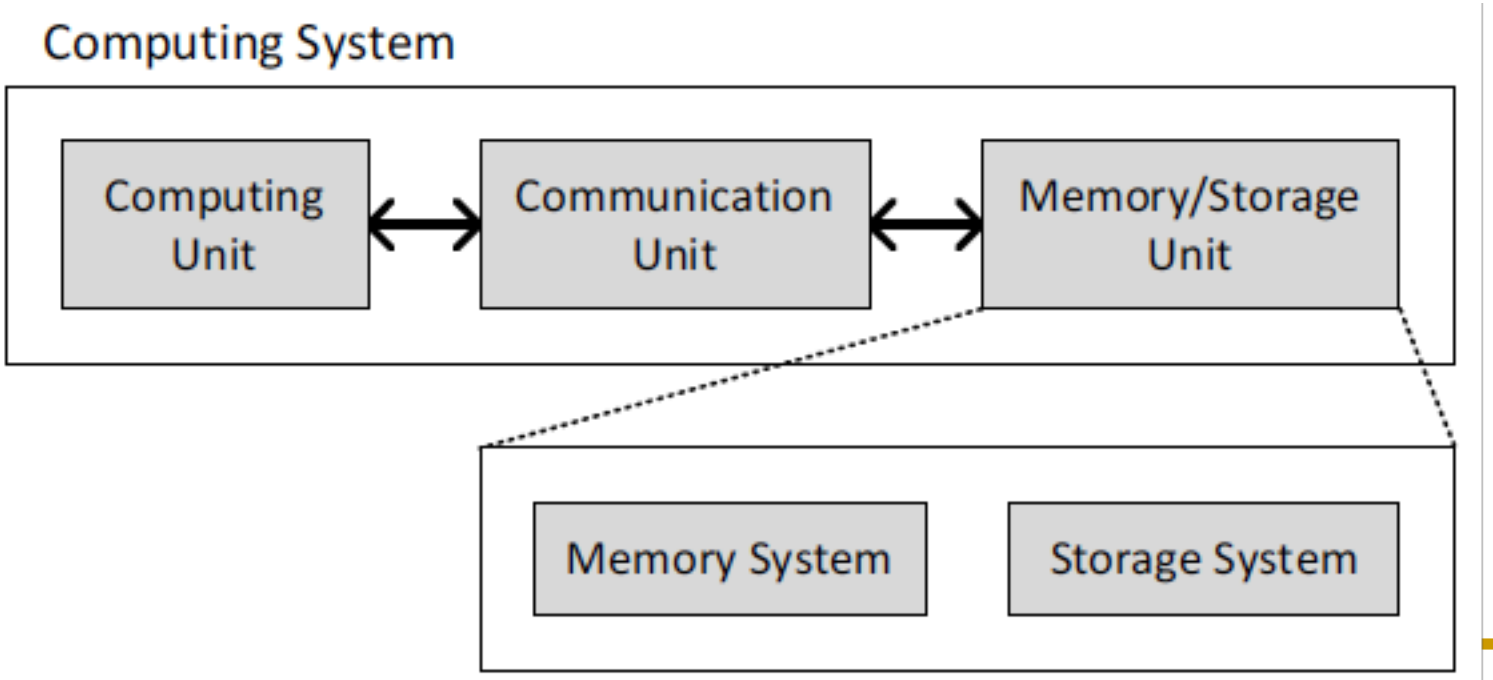


Image source: https://lbsitbytes2010.wordpress.com/2013/03/29/john-von-neumann-roll-no-15/

A Computing System

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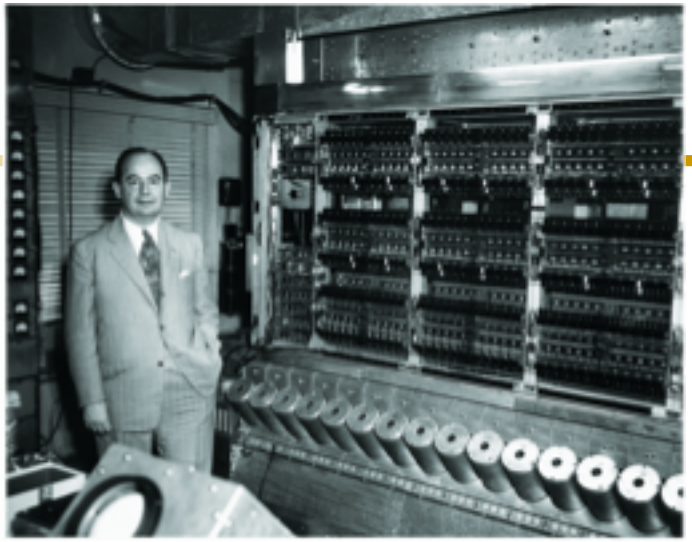

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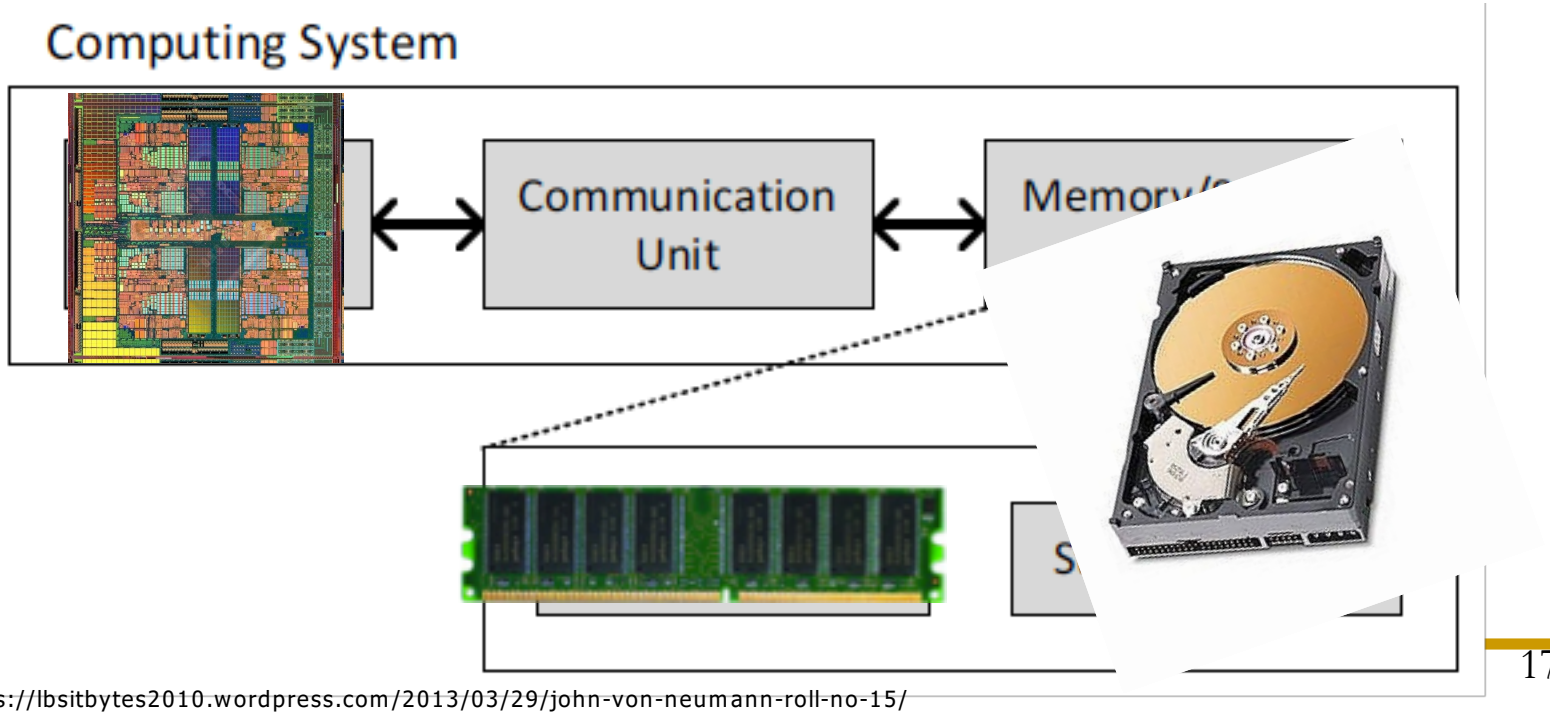
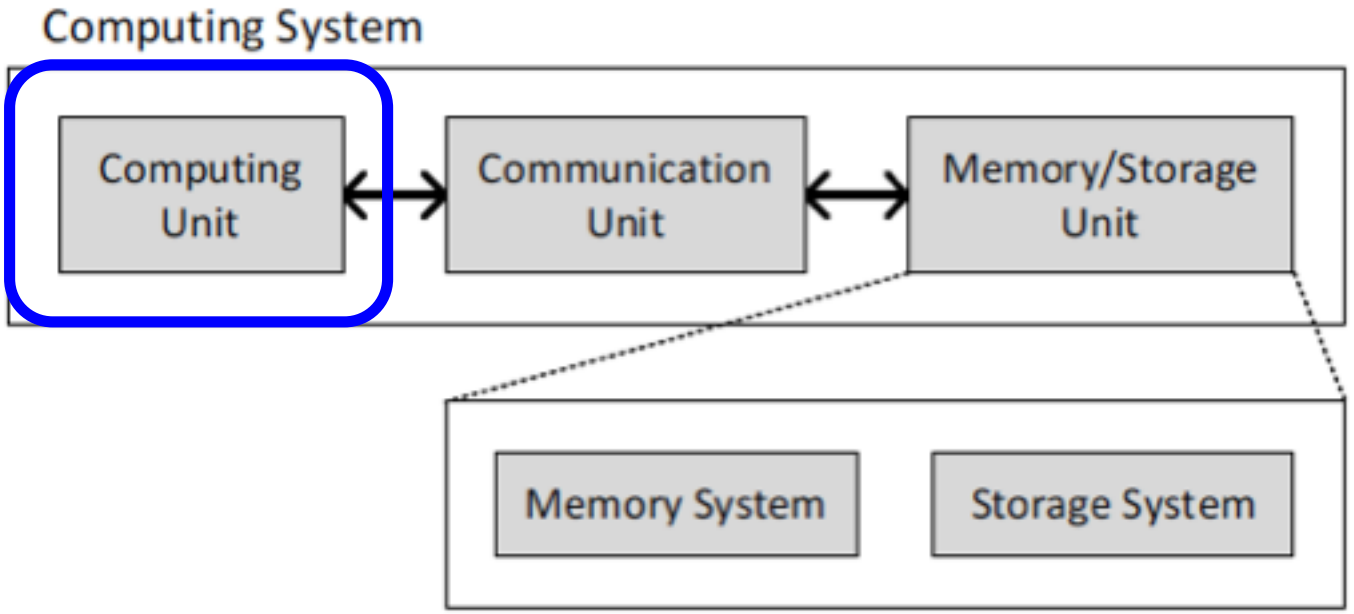


Image source: https://lbsitbytes2010.wordpress.com/2013/03/29/john-von-neumann-roll-no-15/

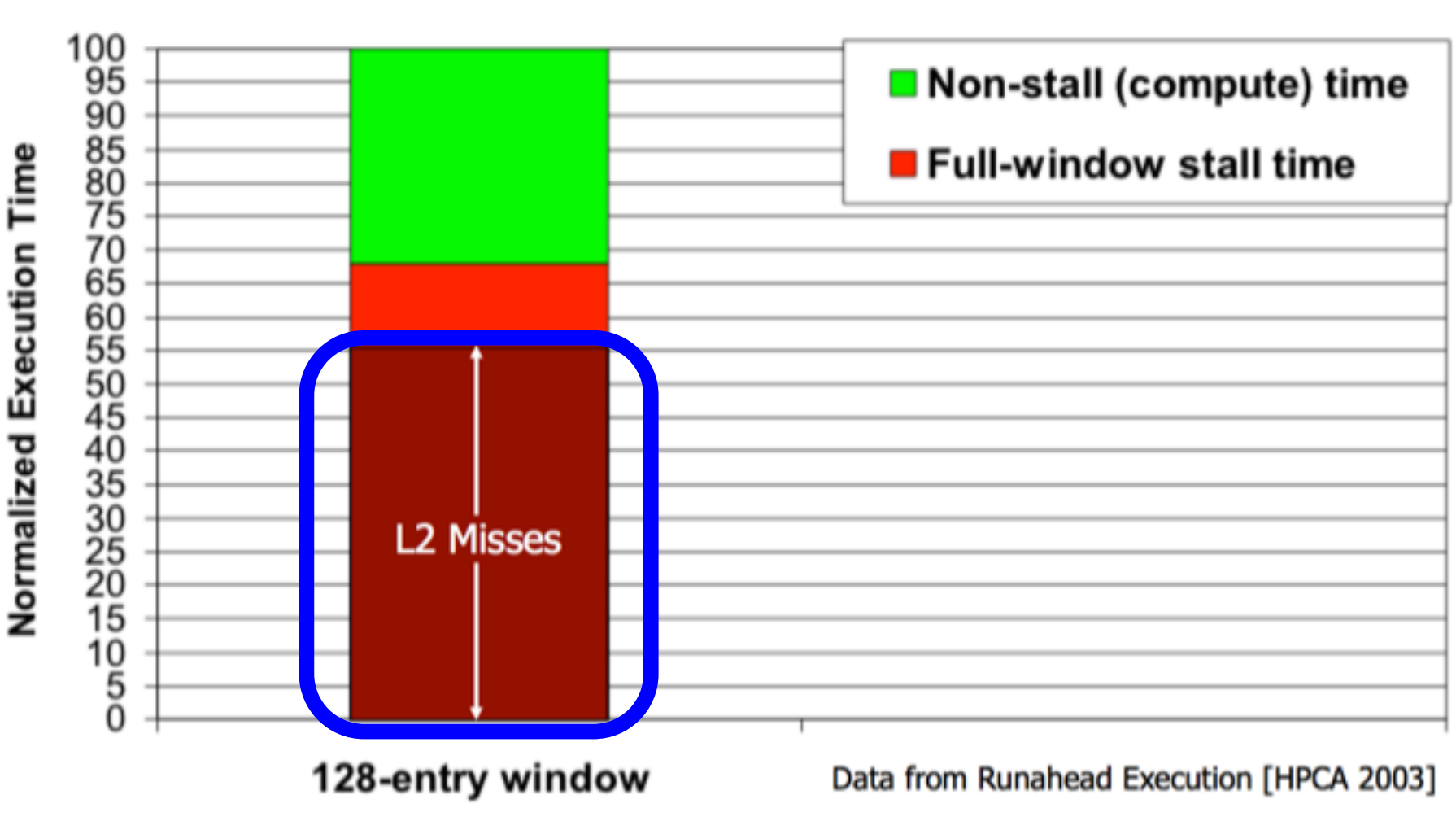
Today's Computing Systems

- Are overwhelmingly processor centric
- All data processed in the processor → at great system cost
- Processor is heavily optimized and is considered the master
- Data storage units are dumb and are largely unoptimized (except for some that are on the processor die)



Yet …

- "**It's the Memory, Stupid!**" (Richard Sites, MPR, 1996)



Mutlu+, "Runahead Execution: An Alternative to Very Large Instruction Windows for Out-of-Order Processors," HPCA 2003.

The Performance Perspective

- Onur Mutlu, Jared Stark, Chris Wilkerson, and Yale N. Patt, **"Runahead Execution: An Alternative to Very Large Instruction Windows for Out-of-order Processors"** *Proceedings of the 9th International Symposium on High-Performance Computer Architecture* (***HPCA***), pages 129-140, Anaheim, CA, February 2003. Slides (pdf)

Runahead Execution: An Alternative to Very Large Instruction Windows for Out-of-order Processors

Onur Mutlu § Jared Stark † Chris Wilkerson ‡ Yale N. Patt §

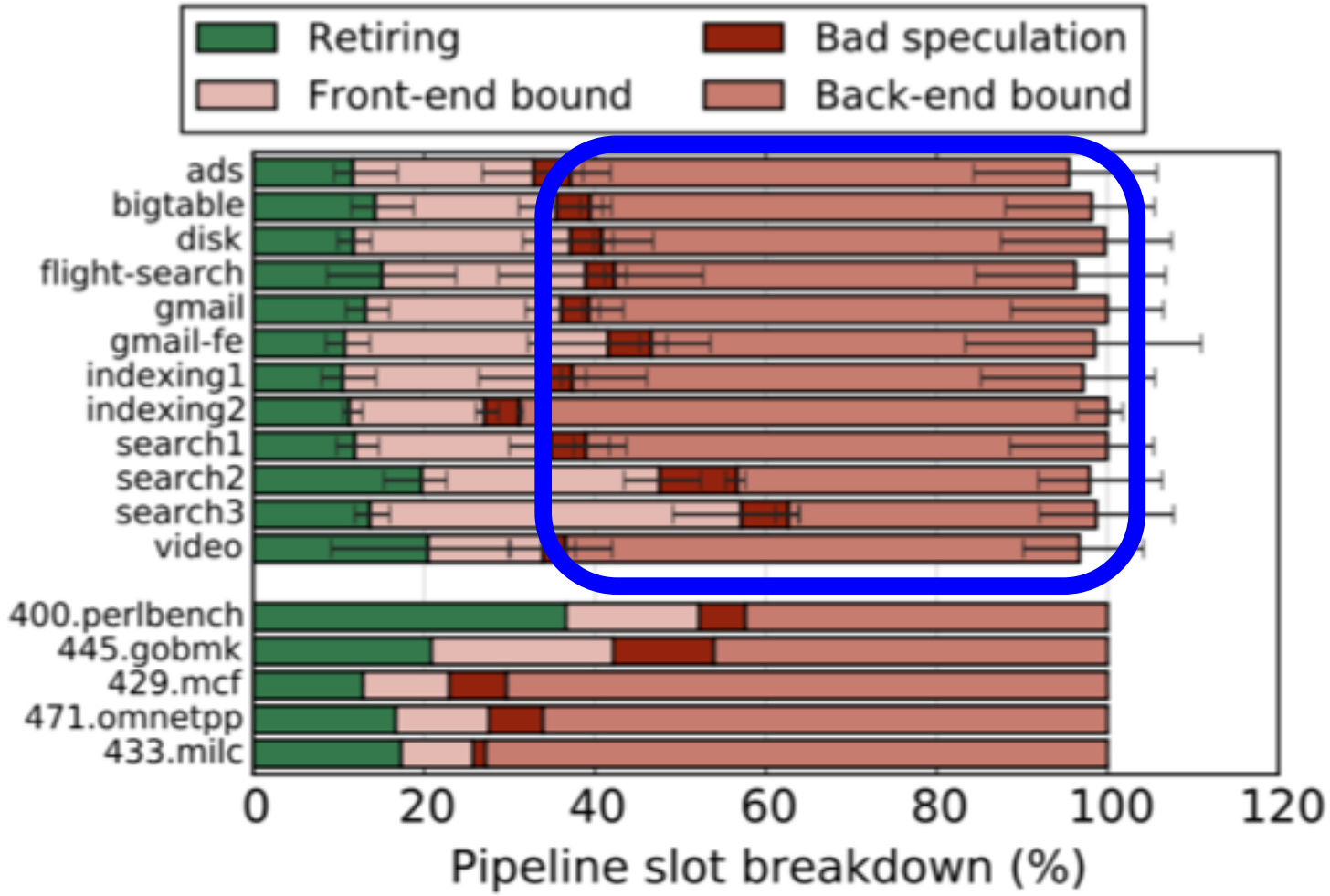
§ECE Department
The University of Texas at Austin
{onur,patt}@ece.utexas.edu

†Microprocessor Research
Intel Labs
jared.w.stark@intel.com

‡Desktop Platforms Group
Intel Corporation
chris.wilkerson@intel.com

The Performance Perspective (Today)

- All of Google's Data Center Workloads (2015):



Kanev+, "Profiling a Warehouse-Scale Computer," ISCA 2015.

The Performance Perspective (Today)

- All of Google's Data Center Workloads (2015):

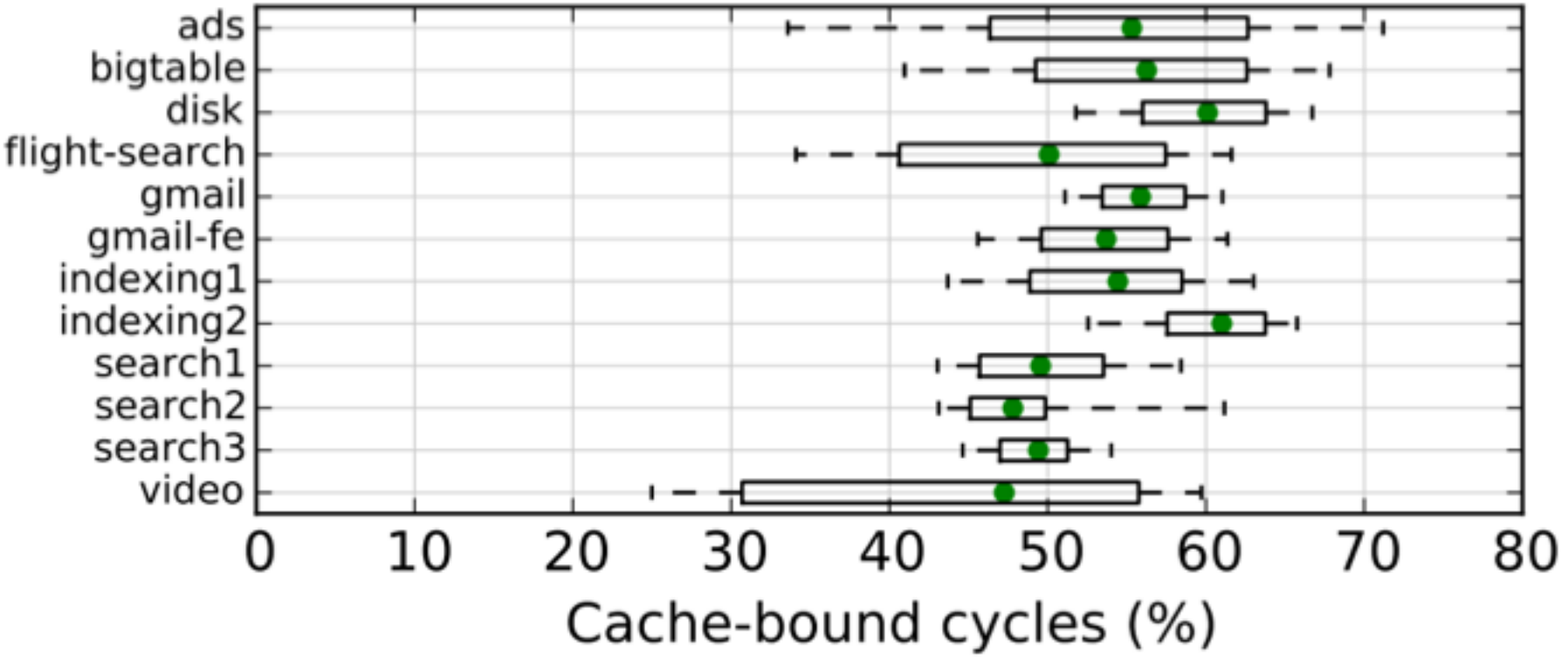


Figure 11: Half of cycles are spent stalled on caches.

Kanev+, "Profiling a Warehouse-Scale Computer," ISCA 2015.

Perils of Processor-Centric Design

- Grossly-imbalanced systems
  - Processing done only in **one place**
  - Everything else just stores and moves data: **data moves a lot**

  → Energy inefficient

  → Low performance

  → Complex

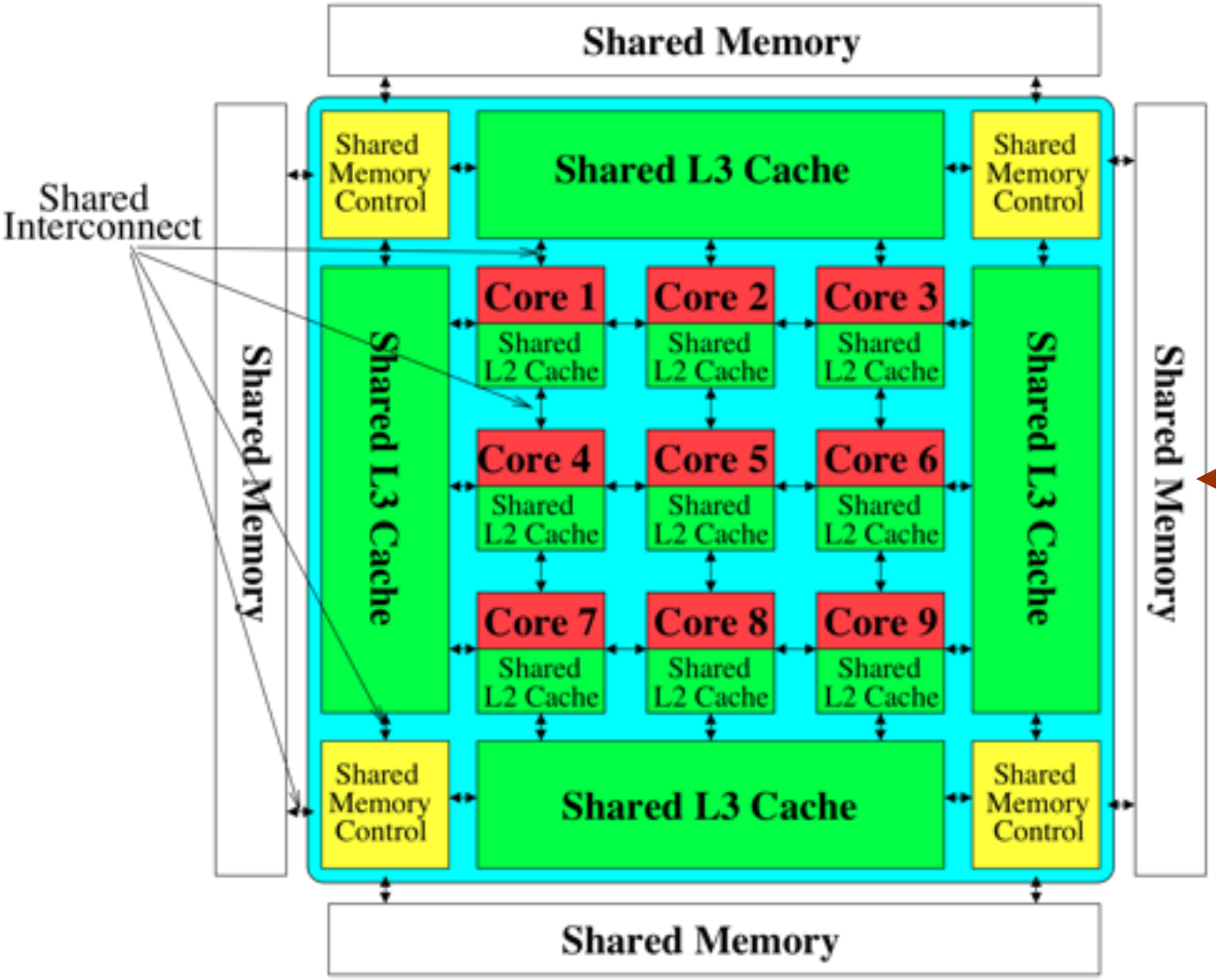
- Overly complex and bloated processor (and accelerators)
  - To tolerate data access from memory
  - Complex hierarchies and mechanisms

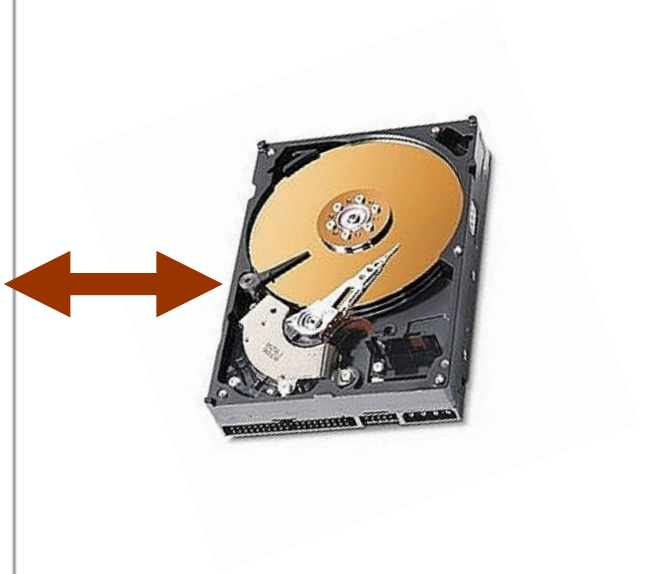
  → Energy inefficient

  → Low performance

  → Complex

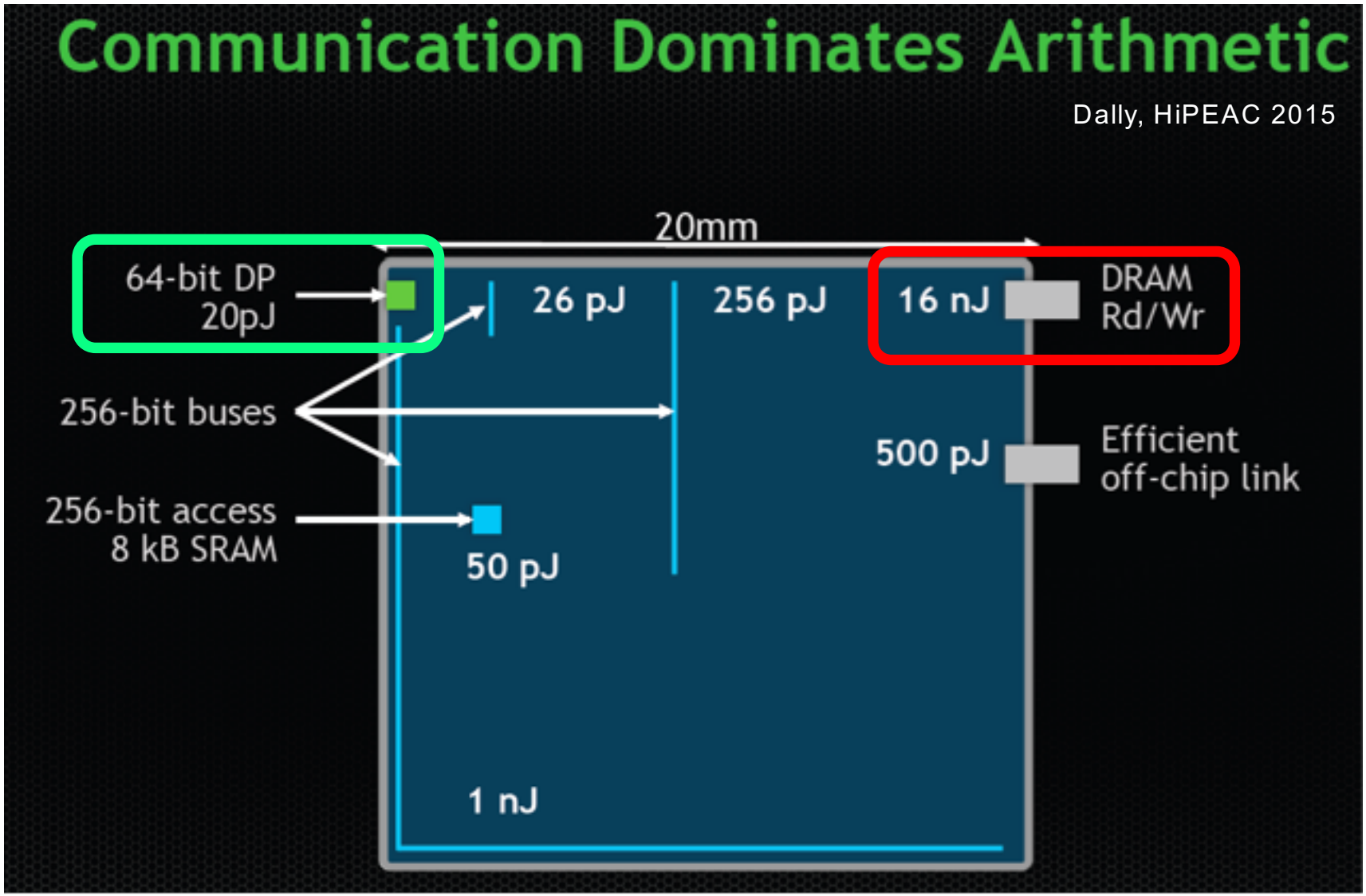
Perils of Processor-Centric Design



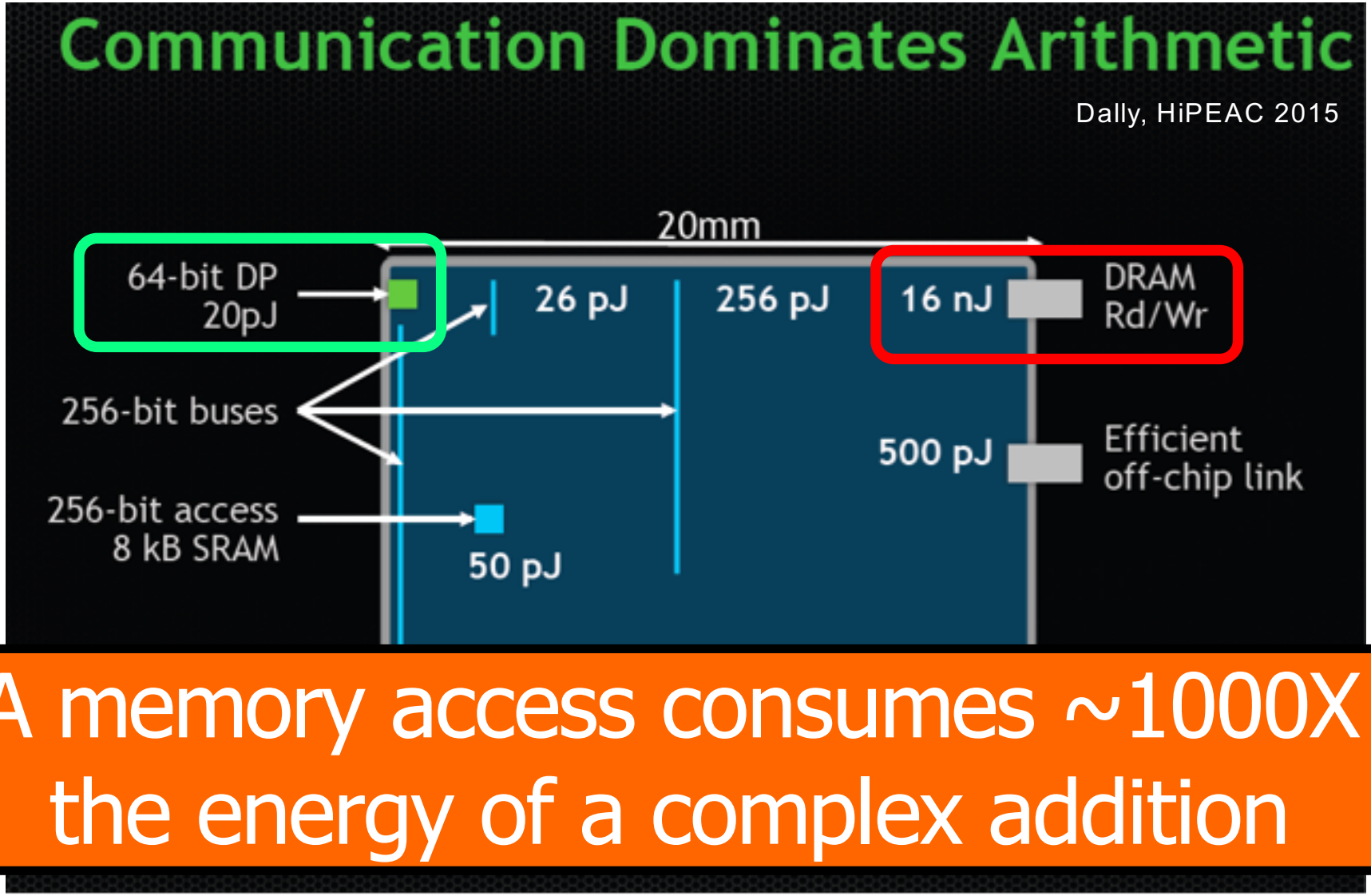


Most of the system is dedicated to storing and moving data

The Energy Perspective



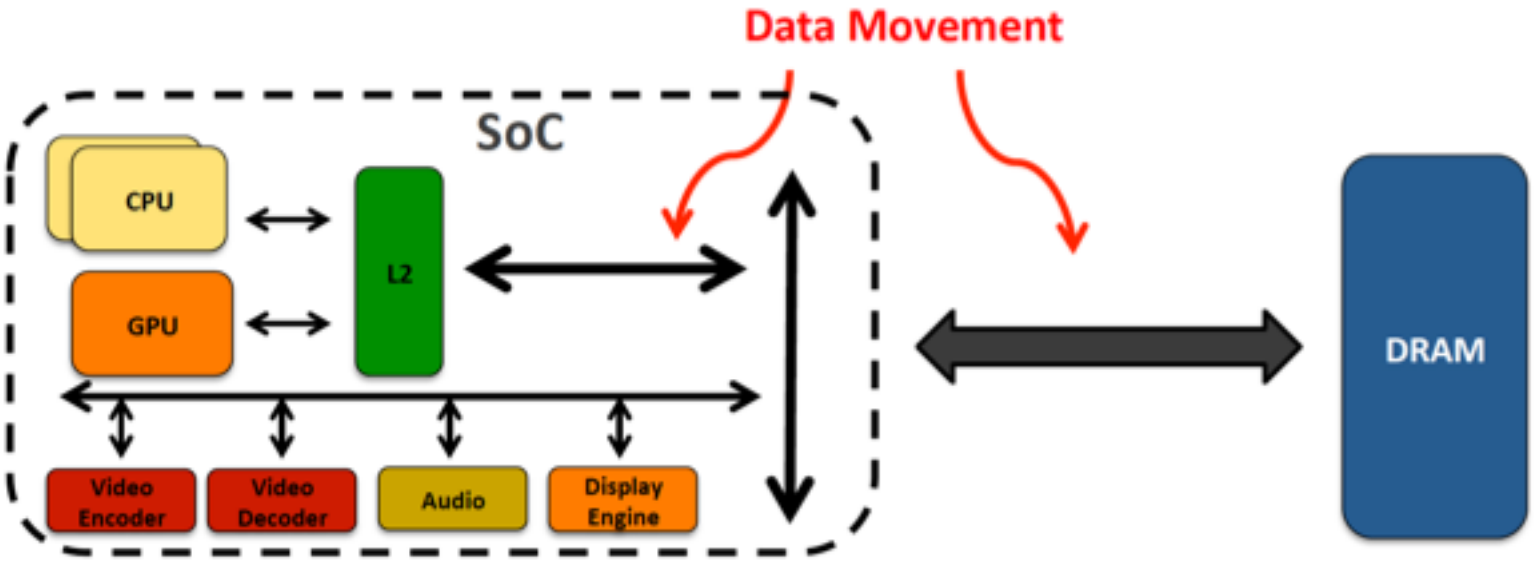
Data Movement vs. Computation Energy



A memory access consumes ~1000X the energy of a complex addition

Data Movement vs. Computation Energy

- Data movement is a major system energy bottleneck
  - Comprises 41% of mobile system energy during web browsing [2]
  - Costs ~115 times as much energy as an ADD operation [1, 2]



[1]: Reducing data Movement Energy via Online Data Clustering and Encoding (MICRO'16)

[2]: Quantifying the energy cost of data movement for emerging smart phone workloads on mobile platforms (IISWC'14)

Energy Waste in Mobile Devices

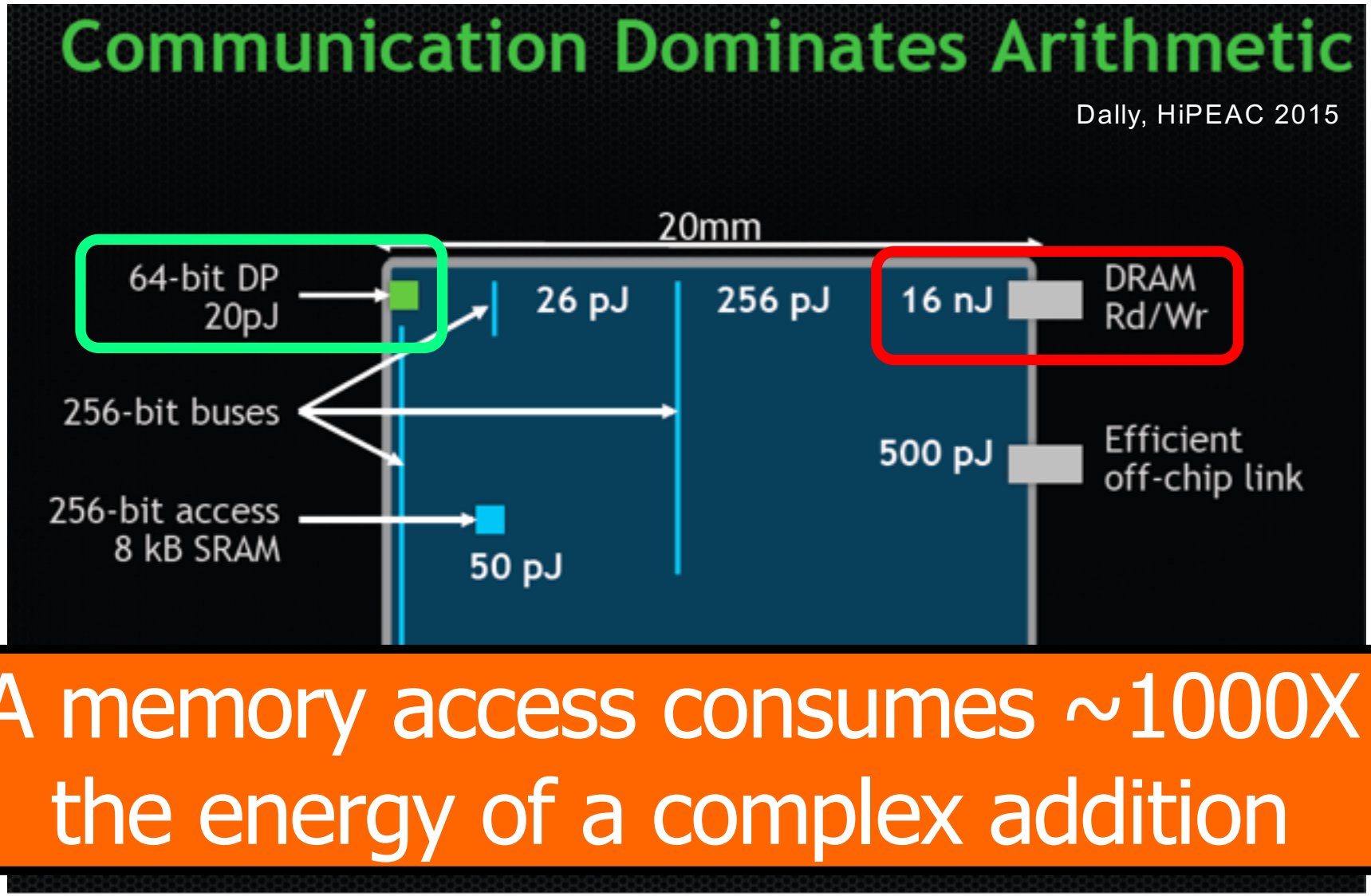
- Amirali Boroumand, Saugata Ghose, Youngsok Kim, Rachata Ausavarungnirun, Eric Shiu, Rahul Thakur, Daehyun Kim, Aki Kuusela, Allan Knies, Parthasarathy Ranganathan, and Onur Mutlu, **"Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks"** *Proceedings of the 23rd International Conference on Architectural Support for Programming Languages and Operating Systems (**ASPLOS**)*, Williamsburg, VA, USA, March 2018.

62.7% of the total system energy is spent on data movement

Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks

Amirali Boroumand[1] Saugata Ghose[1] Youngsok Kim[2]
Rachata Ausavarungnirun[1] Eric Shiu[3] Rahul Thakur[3] Daehyun Kim[4,3]
Aki Kuusela[3] Allan Knies[3] Parthasarathy Ranganathan[3] Onur Mutlu[5,1]

We Do Not Want to Move Data!

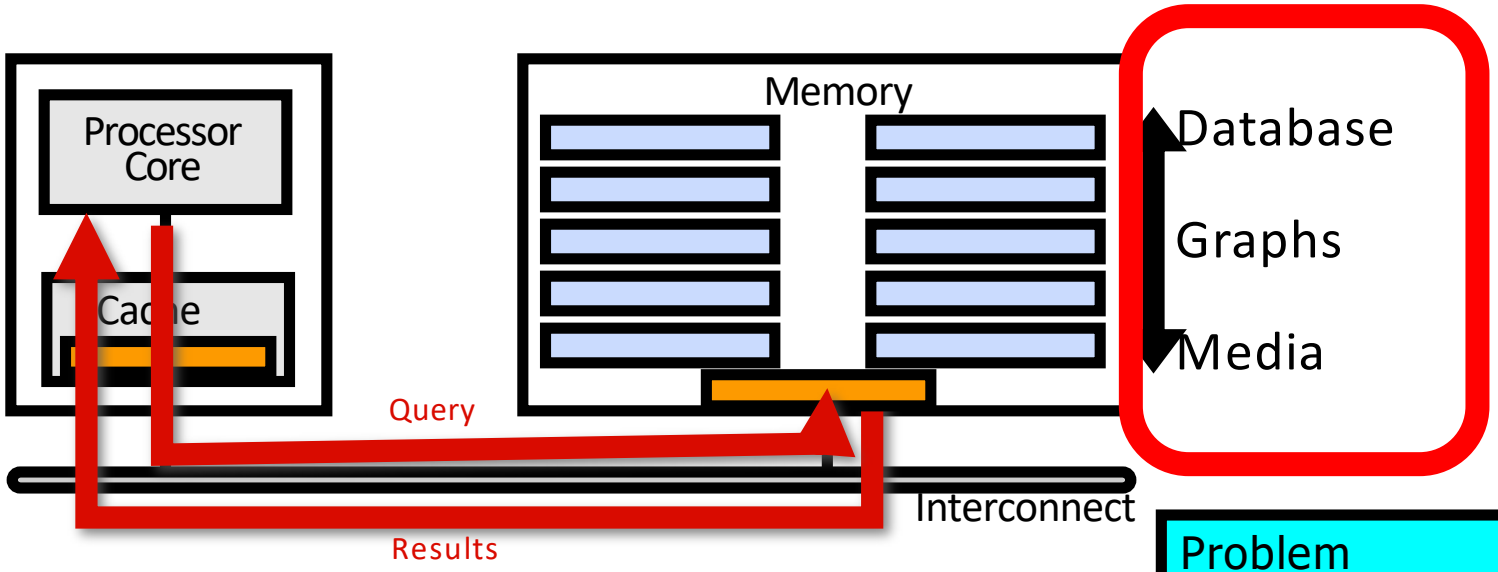


A memory access consumes ~1000X the energy of a complex addition

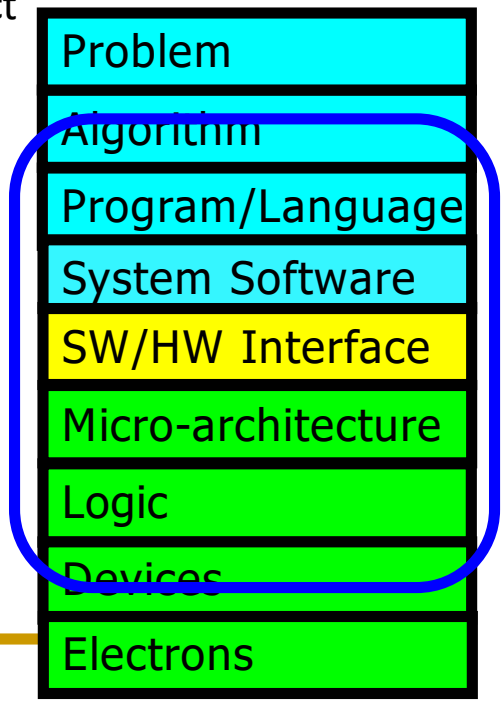
We Need A Paradigm Shift To …

- Enable computation with minimal data movement
- Compute where it makes sense (where data resides)
- Make computing architectures more data-centric

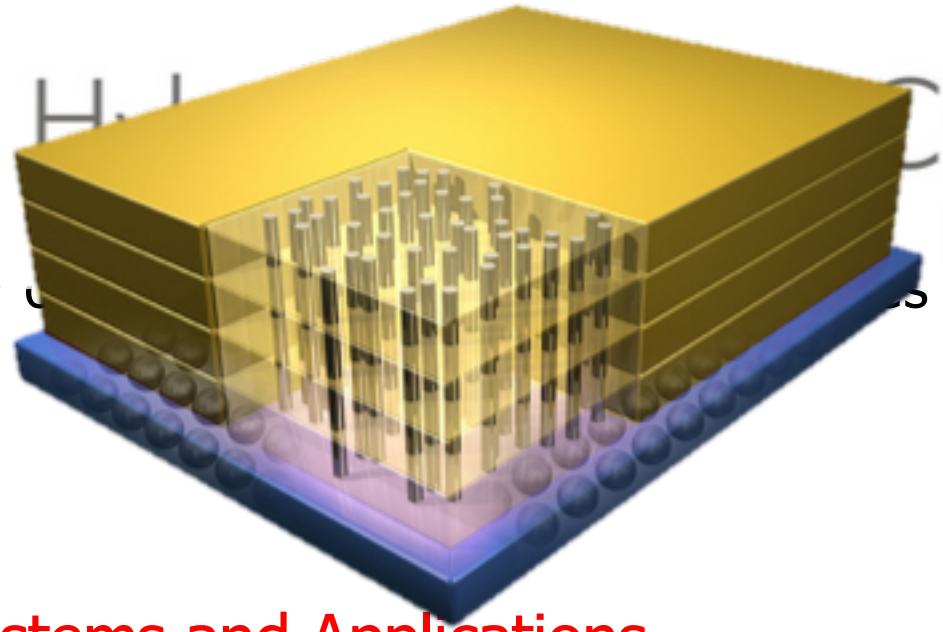
Goal: Processing Inside Memory



- Many questions … How do we design the:
  - compute-capable memory & controllers?
  - processor chip?
  - software and hardware interfaces?
  - system software and languages?
  - algorithms?



Why In-Memory Computation Today?



Dally, HiPEAC 2

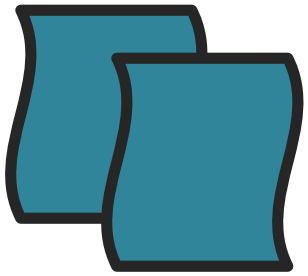
- Pull from Systems and Applications
  - Data access is a major system and application bottleneck
  - Systems are energy limited
  - Data movement much more energy-hungry than computation

Processing in Memory: Two Approaches

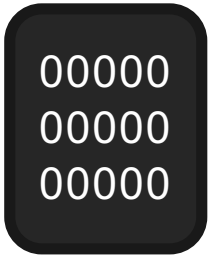
1. Minimally changing memory chips
2. Exploiting 3D-stacked memory

Starting Simple: Data Copy and Initialization

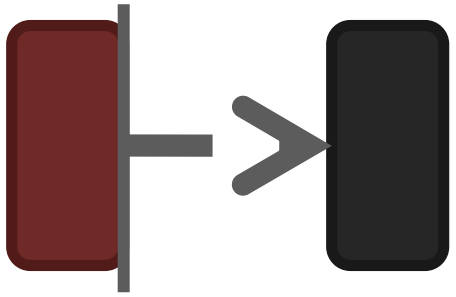
memmove & memcpy: 5% cycles in Google's datacenter [Kanev+ ISCA'15]



Forking

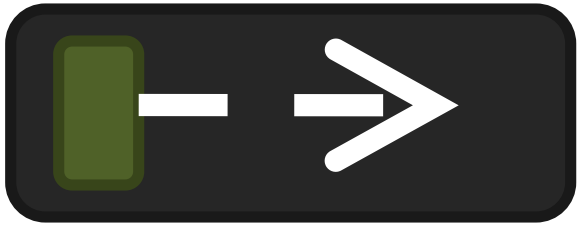


Zero initialization (e.g., security)



Checkpointing

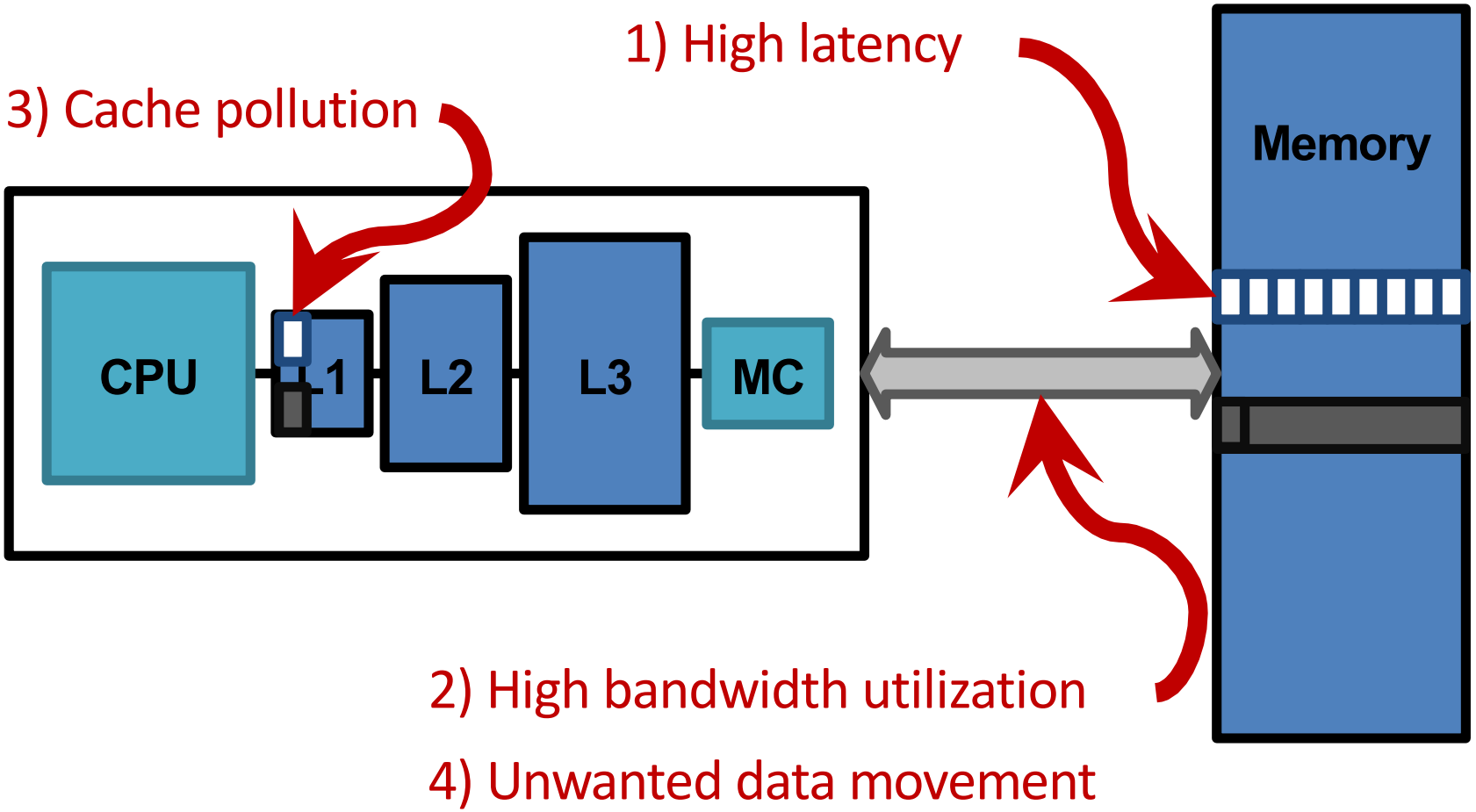
VM Cloning
Deduplication



Page Migration

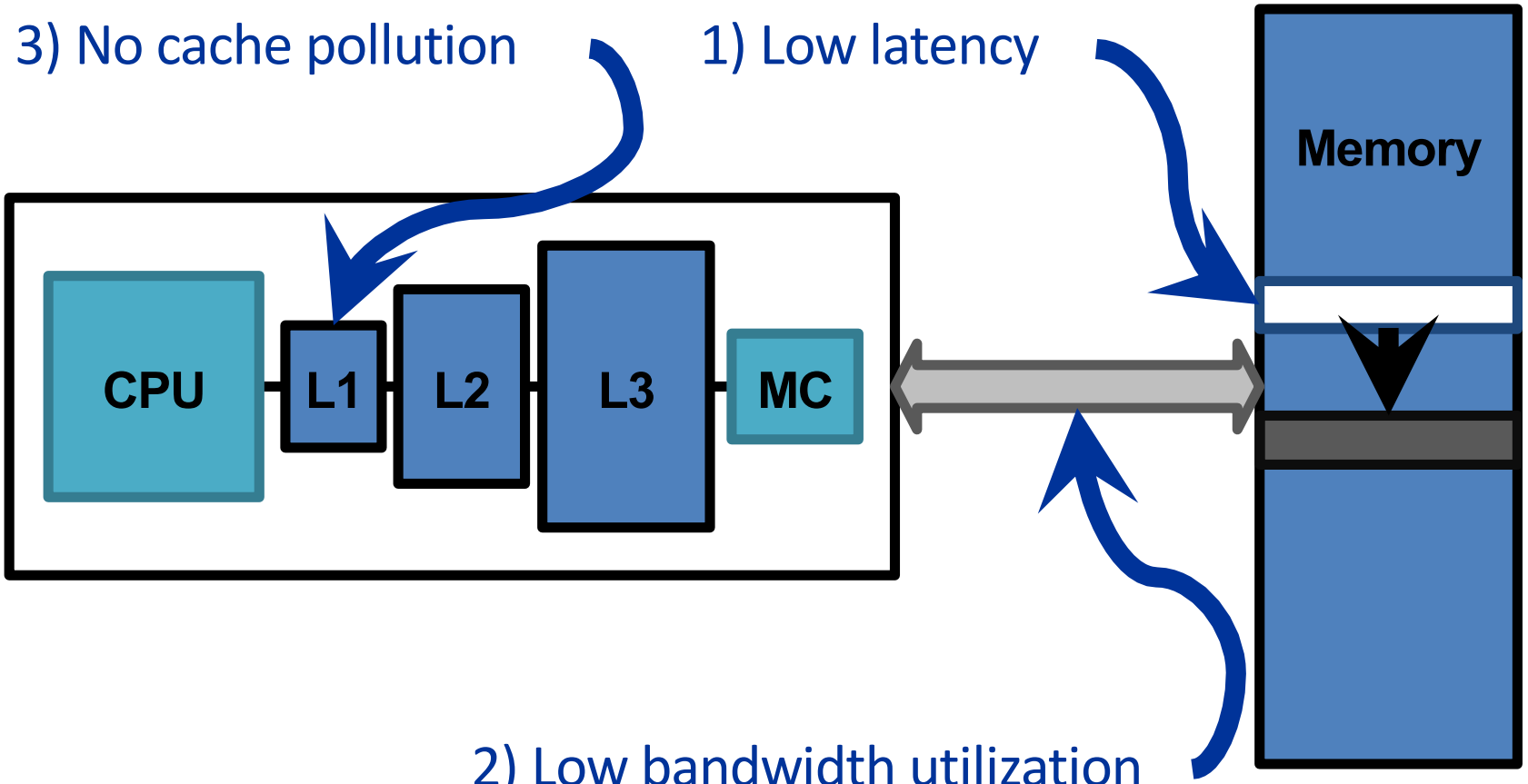
• • •
Many more

Today's Systems: Bulk Data Copy



1046ns, 3.6uJ (for 4KB page copy via DMA)

Future Systems: In-Memory Copy

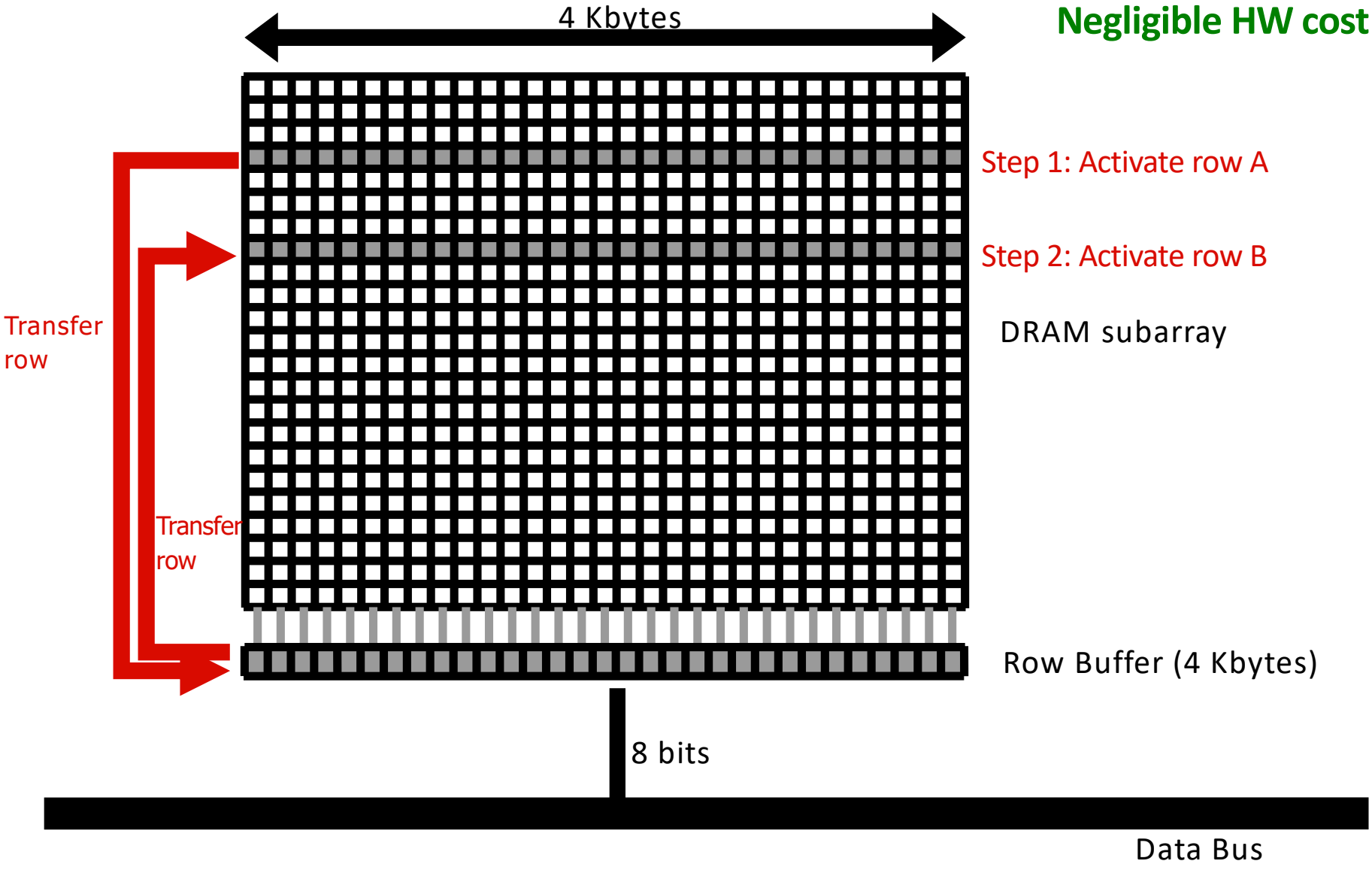


1046ns, 3.6uJ → 90ns, 0.04uJ

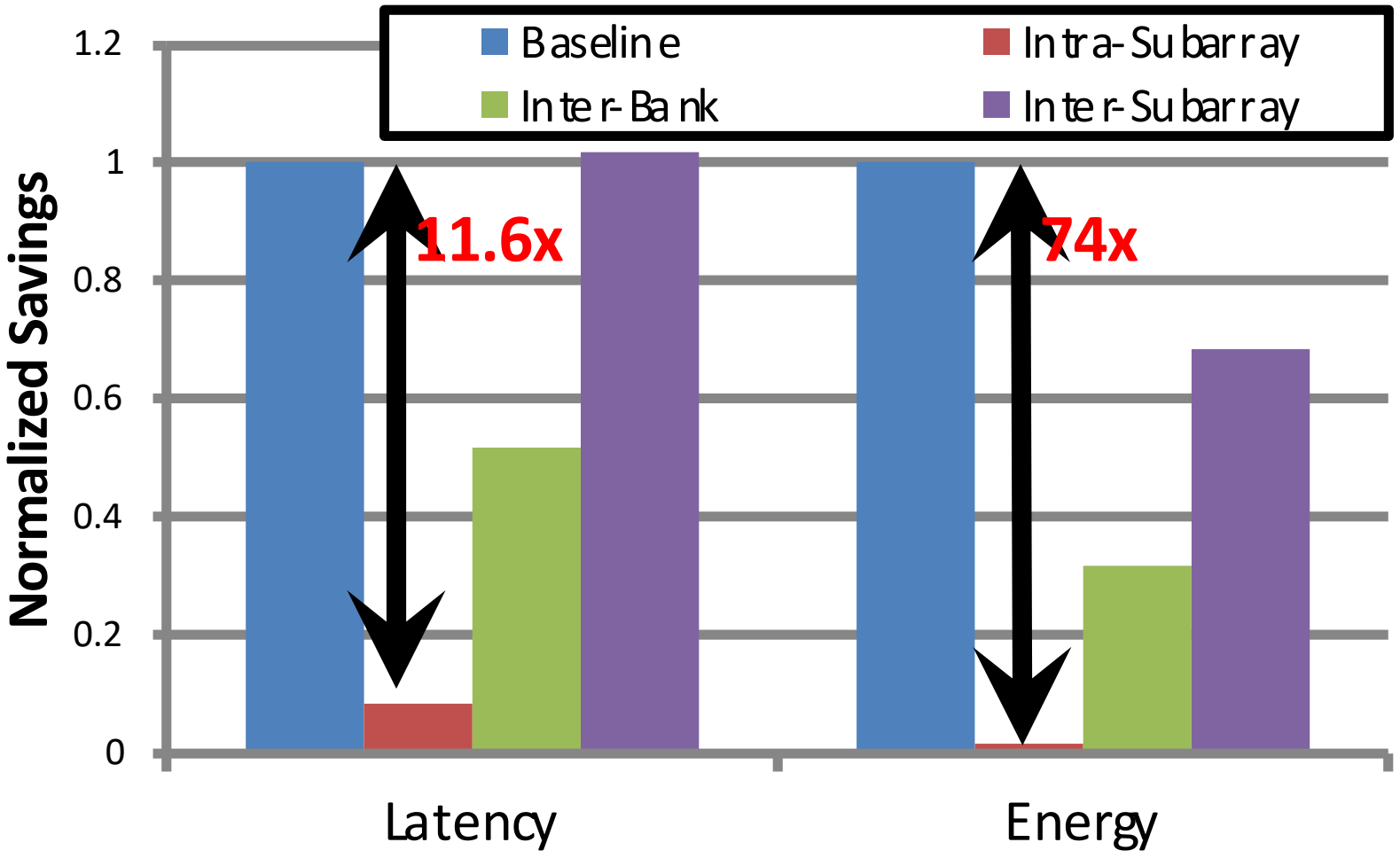
RowClone: In-DRAM Row Copy

Idea: Two consecutive ACTivates

Negligible HW cost



RowClone: Latency and Energy Savings



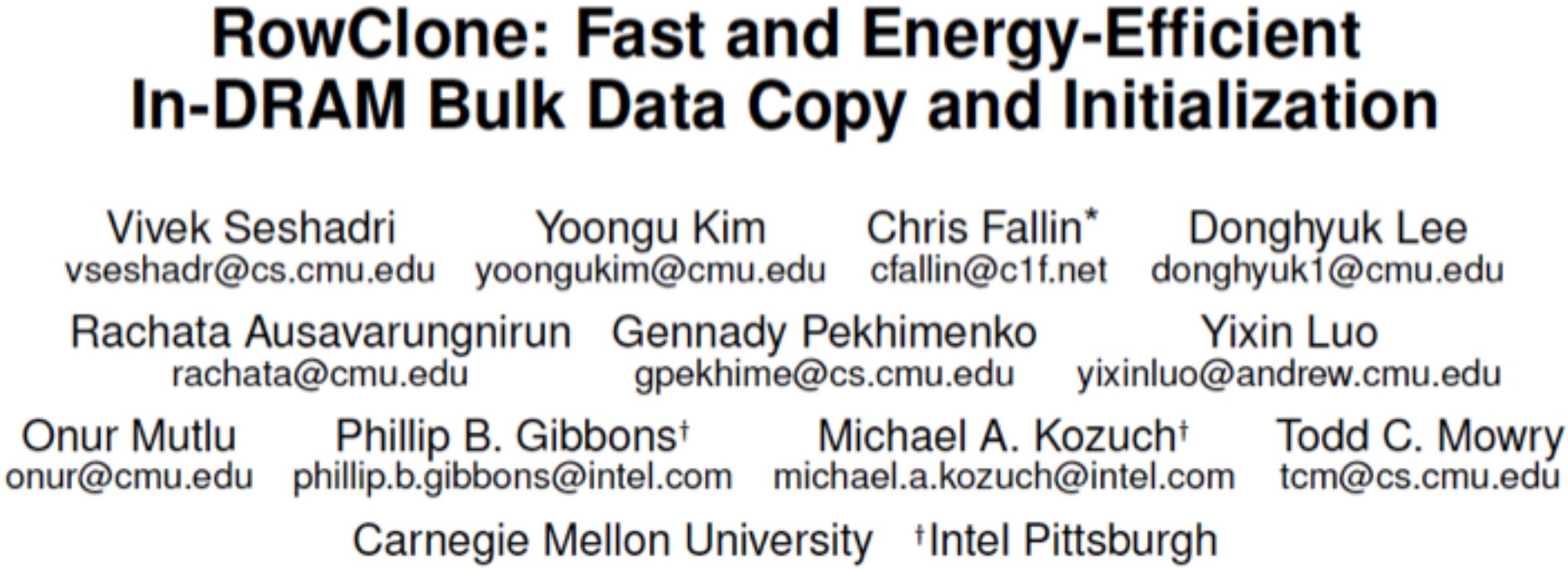
Seshadri et al., "RowClone: Fast and Efficient In-DRAM Copy and Initialization of Bulk Data," MICRO 2013.

More on RowClone

- Vivek Seshadri, Yoongu Kim, Chris Fallin, Donghyuk Lee, Rachata Ausavarungnirun, Gennady Pekhimenko, Yixin Luo, Onur Mutlu, Michael A. Kozuch, Phillip B. Gibbons, and Todd C. Mowry,

  "RowClone: Fast and Energy-Efficient In-DRAM Bulk Data Copy and Initialization"

  *Proceedings of the 46th International Symposium on Microarchitecture (**MICRO**)*, Davis, CA, December 2013. [Slides (pptx) (pdf)] [Lightning Session Slides (pptx) (pdf)] [Poster (pptx) (pdf)]



RowClone: Fast and Energy-Efficient In-DRAM Bulk Data Copy and Initialization

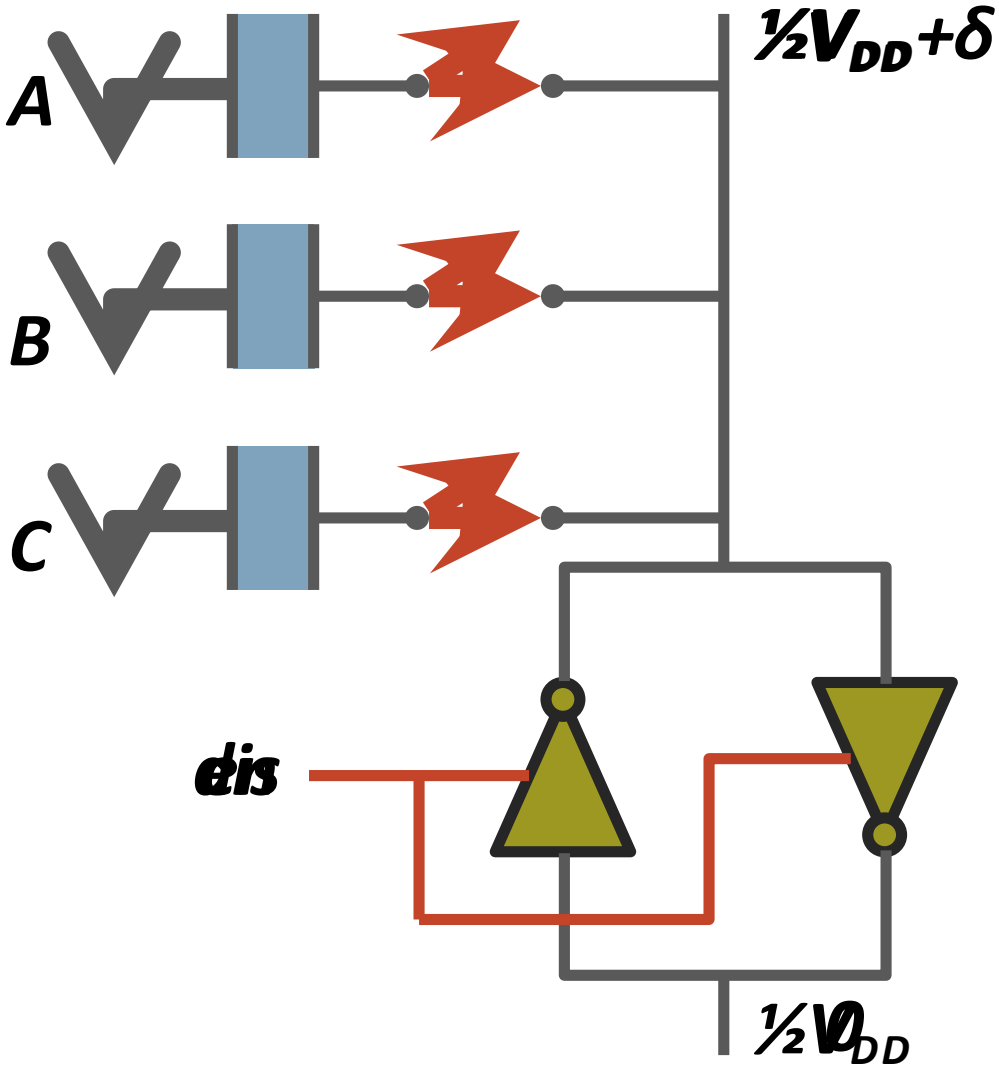
Vivek Seshadri vseshadr@cs.cmu.edu
Yoongu Kim yoongukim@cmu.edu
Chris Fallin* cfallin@c1f.net
Donghyuk Lee donghyuk1@cmu.edu
Rachata Ausavarungnirun rachata@cmu.edu
Gennady Pekhimenko gpekhime@cs.cmu.edu
Yixin Luo yixinluo@andrew.cmu.edu
Onur Mutlu onur@cmu.edu
Phillip B. Gibbons† phillip.b.gibbons@intel.com
Michael A. Kozuch† michael.a.kozuch@intel.com
Todd C. Mowry tcm@cs.cmu.edu
Carnegie Mellon University †Intel Pittsburgh

In-Memory Bulk Bitwise Operations

- We can support in-DRAM COPY, ZERO, AND, OR, NOT, MAJ
- At low cost
- Using analog computation capability of DRAM
  - Idea: activating multiple rows performs computation
- 30-60X performance and energy improvement
  - Seshadri+, "Ambit: In-Memory Accelerator for Bulk Bitwise Operations Using Commodity DRAM Technology," MICRO 2017.

- New memory technologies enable even more opportunities
  - Memristors, resistive RAM, phase change mem, STT-MRAM, …
  - Can operate on data with minimal movement

In-DRAM AND/OR: Triple Row Activation



Final State
AB + BC + AC

C(A + B) + ~C(AB)

Seshadri+, "Fast Bulk Bitwise AND and OR in DRAM", IEEE CAL 2015.

In-DRAM NOT: Dual Contact Cell

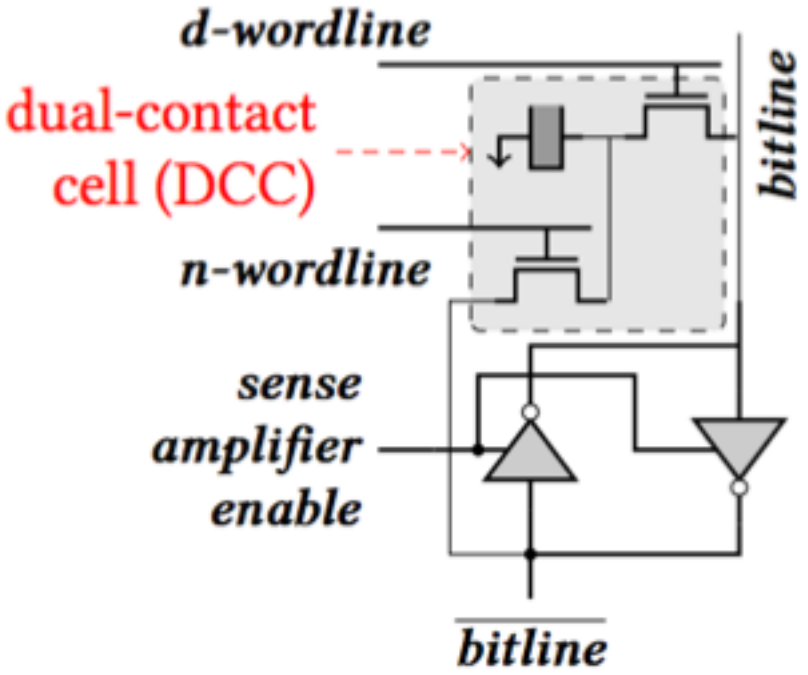


Figure 5: A dual-contact cell connected to both ends of a sense amplifier

Idea:

Feed the negated value in the sense amplifier into a special row

Seshadri+, "Ambit: In-Memory Accelerator for Bulk Bitwise Operations using Commodity DRAM Technology," MICRO 2017.

Performance: In-DRAM Bitwise Operations

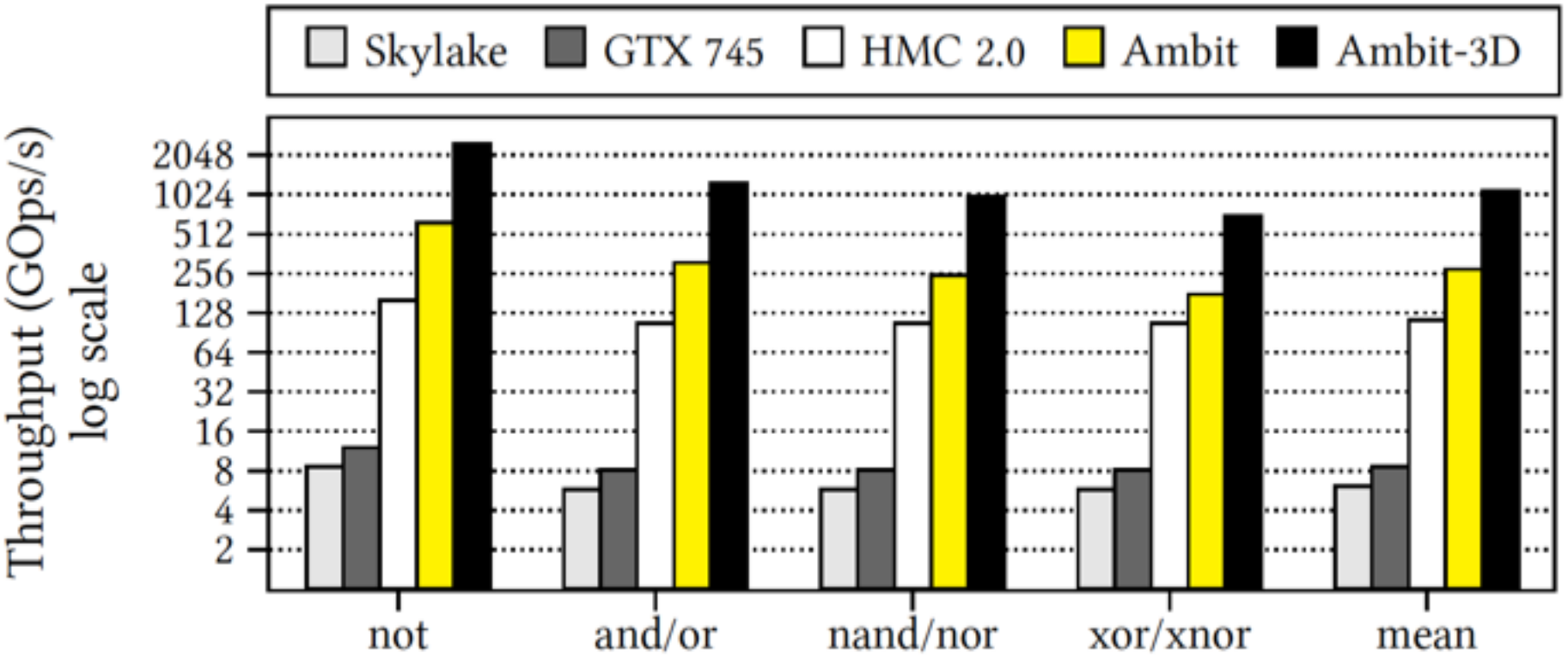


Figure 9: Throughput of bitwise operations on various systems.

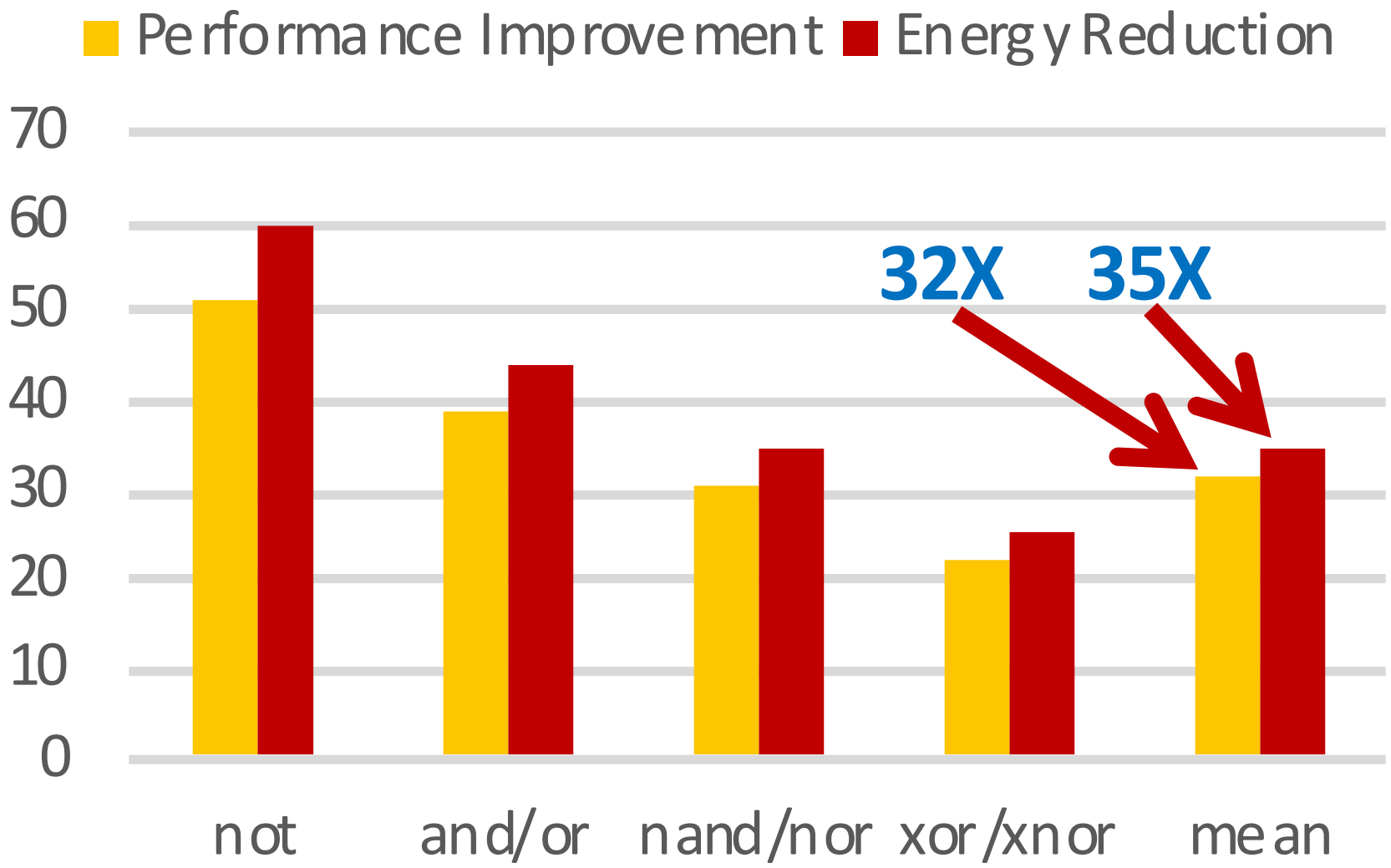
Energy of In-DRAM Bitwise Operations

	Design	not	and/or	nand/nor	xor/xnor
DRAM &	**DDR3**	93.7	137.9	137.9	137.9
Channel Energy	**Ambit**	1.6	3.2	4.0	5.5
(nJ/KB)	(↓)	59.5X	43.9X	35.1X	25.1X

Table 3: Energy of bitwise operations. (↓) indicates energy reduction of Ambit over the traditional DDR3-based design.

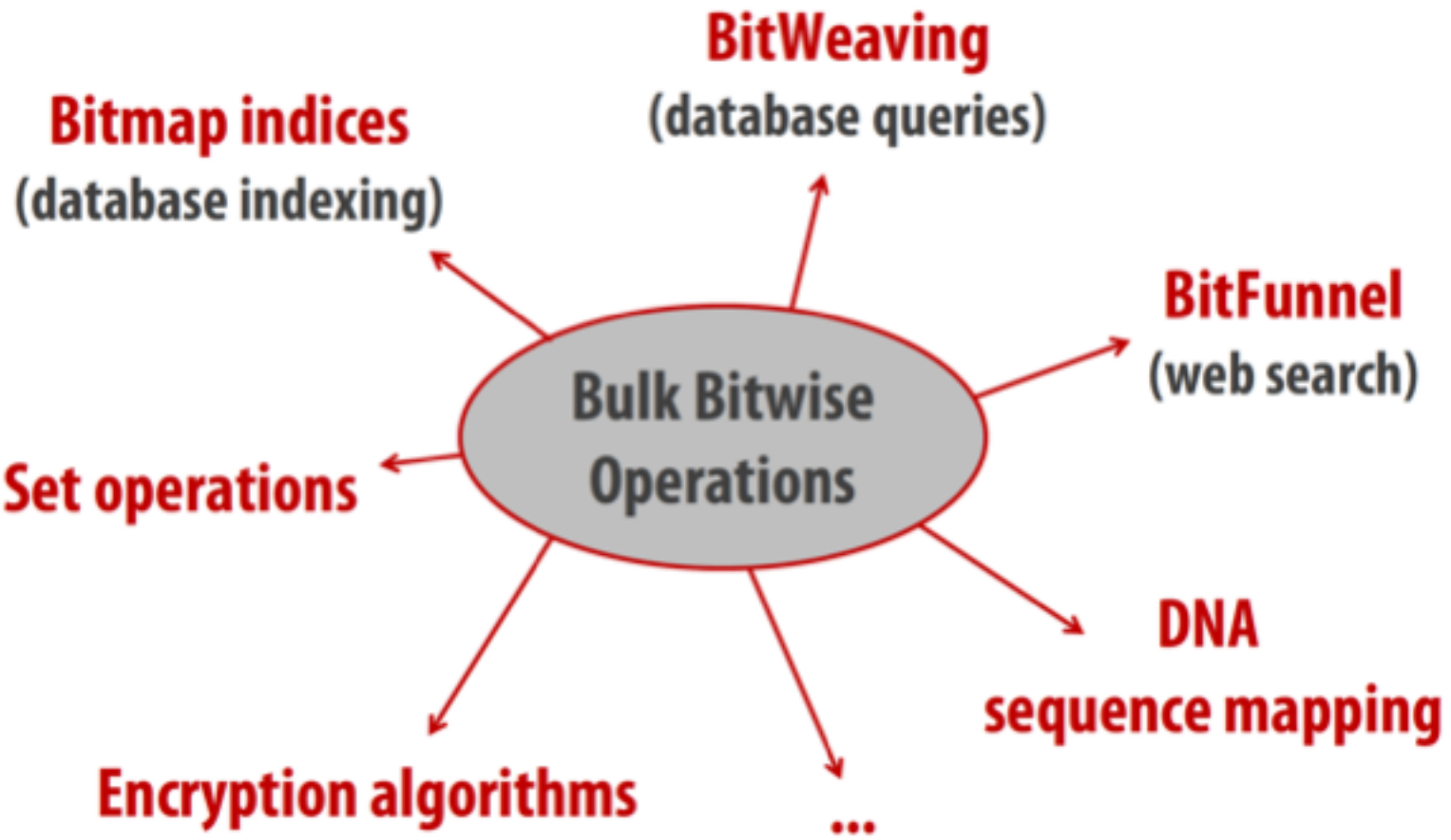
Seshadri+, "Ambit: In-Memory Accelerator for Bulk Bitwise Operations using Commodity DRAM Technology," MICRO 2017.

Ambit vs. DDR3: Performance and Energy



Seshadri+, "Ambit: In-Memory Accelerator for Bulk Bitwise Operations using Commodity DRAM Technology," MICRO 2017.

Bulk Bitwise Operations in Workloads



[1] Li and Patel, BitWeaving, SIGMOD 2013
[2] Goodwin+, BitFunnel, SIGIR 2017

Performance: Bitmap Index on Ambit

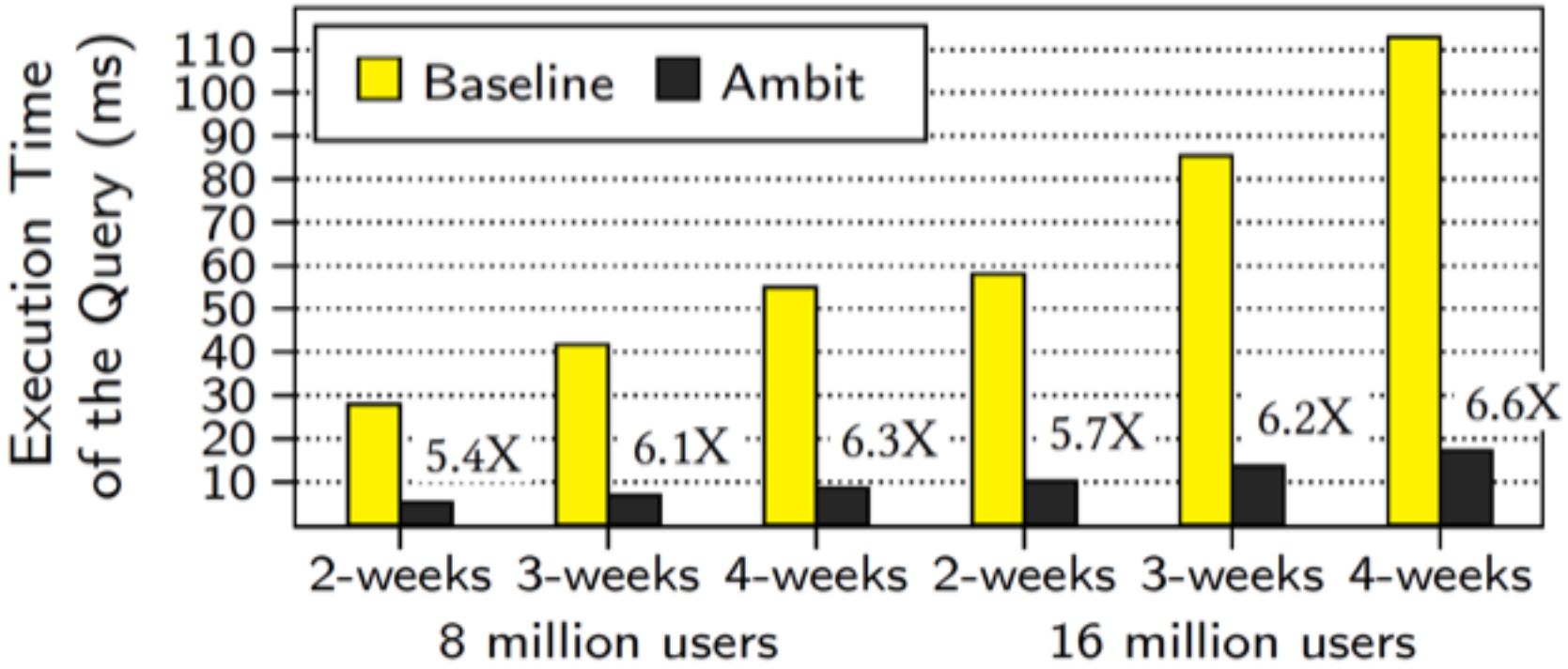


Figure 10: Bitmap index performance. The value above each bar indicates the reduction in execution time due to Ambit.

Seshadri+, "Ambit: In-Memory Accelerator for Bulk Bitwise Operations using Commodity DRAM Technology," MICRO 2017.

Performance: BitWeaving on Ambit

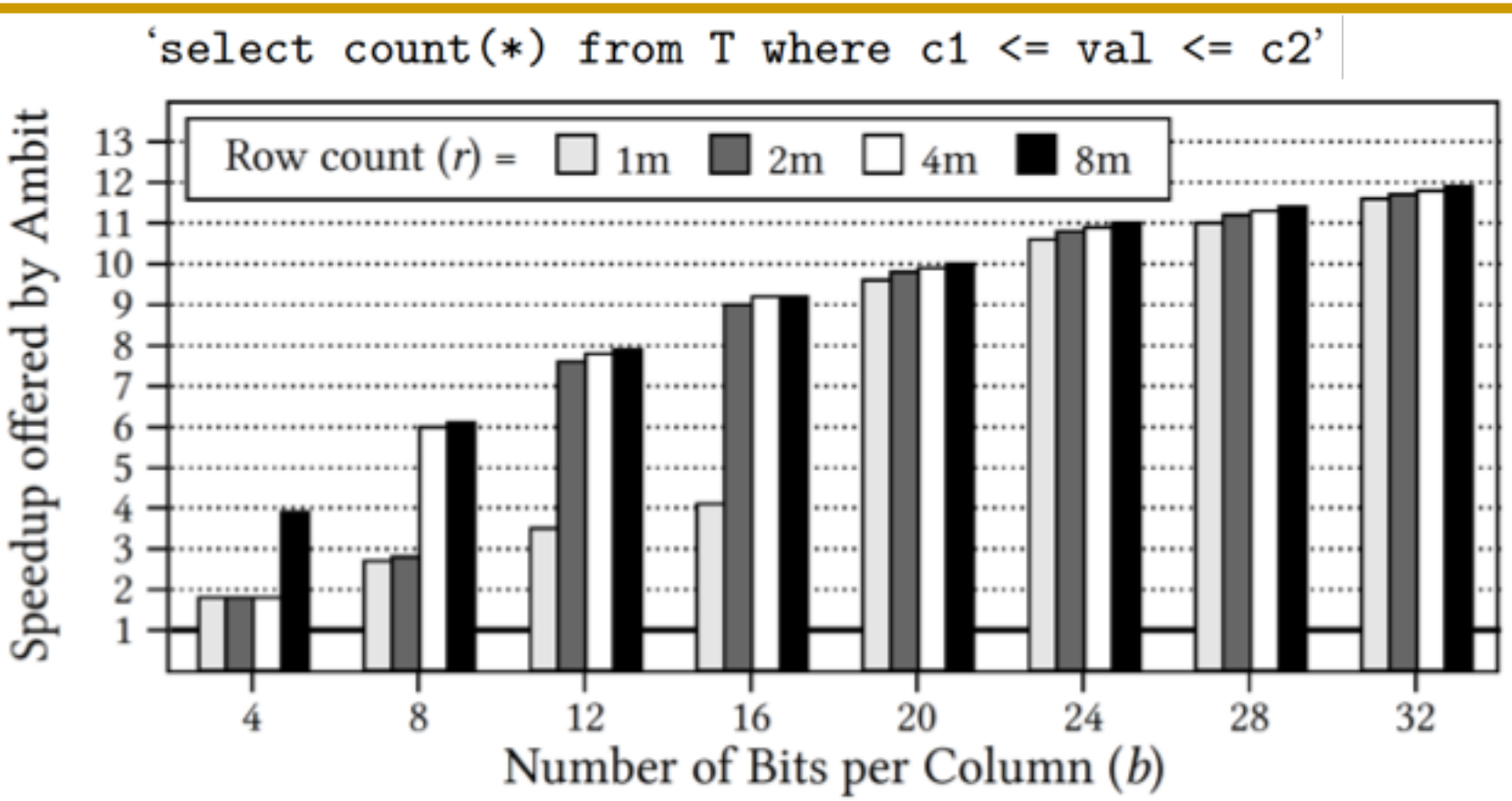


Figure 11: Speedup offered by Ambit over baseline CPU with SIMD for BitWeaving

Seshadri+, "Ambit: In-Memory Accelerator for Bulk Bitwise Operations using Commodity DRAM Technology," MICRO 2017.

More on In-DRAM Bulk AND/OR

- Vivek Seshadri, Kevin Hsieh, Amirali Boroumand, Donghyuk Lee, Michael A. Kozuch, Onur Mutlu, Phillip B. Gibbons, and Todd C. Mowry,
  "Fast Bulk Bitwise AND and OR in DRAM"
  IEEE Computer Architecture Letters (***CAL***), April 2015.

Fast Bulk Bitwise AND and OR in DRAM

Vivek Seshadri*, Kevin Hsieh*, Amirali Boroumand*, Donghyuk Lee*,
Michael A. Kozuch†, Onur Mutlu*, Phillip B. Gibbons†, Todd C. Mowry*
*Carnegie Mellon University †Intel Pittsburgh

More on In-DRAM Bitwise Operations

- Vivek Seshadri et al., "**Ambit: In-Memory Accelerator for Bulk Bitwise Operations Using Commodity DRAM Technology**," MICRO 2017.

Ambit: In-Memory Accelerator for Bulk Bitwise Operations Using Commodity DRAM Technology

Vivek Seshadri[1,5] Donghyuk Lee[2,5] Thomas Mullins[3,5] Hasan Hassan[4] Amirali Boroumand[5]
Jeremie Kim[4,5] Michael A. Kozuch[3] Onur Mutlu[4,5] Phillip B. Gibbons[5] Todd C. Mowry[5]

[1]Microsoft Research India [2]NVIDIA Research [3]Intel [4]ETH Zürich [5]Carnegie Mellon University

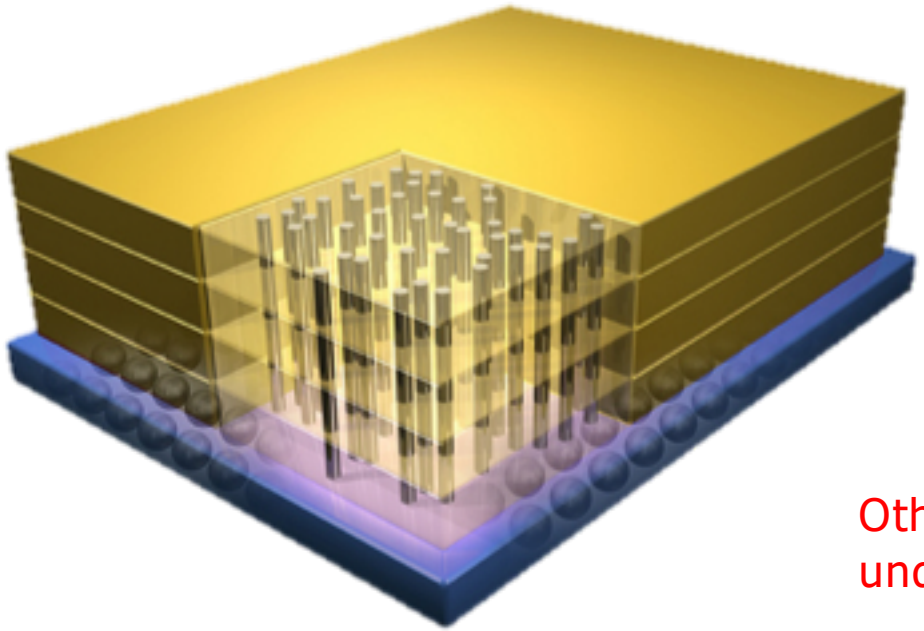
Computing Architectures with Minimal Data Movement

Processing in Memory: Two Approaches

1. Minimally changing memory chips
2. Exploiting 3D-stacked memory

Opportunity: 3D-Stacked Logic+Memory

Hybrid Memory Cube
CONSORTIUM



Other "True 3D" technologies under development

DRAM Landscape (circa 2015)

Segment	*DRAM Standards & Architectures*
Commodity	DDR3 (2007) [14]; DDR4 (2012) [18]
Low-Power	LPDDR3 (2012) [17]; LPDDR4 (2014) [20]
Graphics	GDDR5 (2009) [15]
Performance	eDRAM [28], [32]; RLDRAM3 (2011) [29]
3D-Stacked	WIO (2011) [16]; WIO2 (2014) [21]; MCDRAM (2015) [13]; HBM (2013) [19]; HMC1.0 (2013) [10]; HMC1.1 (2014) [11]
Academic	SBA/SSA (2010) [38]; Staged Reads (2012) [8]; RAIDR (2012) [27]; SALP (2012) [24]; TL-DRAM (2013) [26]; RowClone (2013) [37]; Half-DRAM (2014) [39]; Row-Buffer Decoupling (2014) [33]; SARP (2014) [6]; AL-DRAM (2015) [25]

Table 1. Landscape of DRAM-based memory

Kim+, "Ramulator: A Flexible and Extensible DRAM Simulator", IEEE CAL 2015.

Two Key Questions in 3D-Stacked PIM

- How can we accelerate important applications if we use 3D-stacked memory as a coarse-grained accelerator?
  - what is the architecture and programming model?
  - what are the mechanisms for acceleration?

- What is the minimal processing-in-memory support we can provide?
  - without changing the system significantly
  - while achieving significant benefits

Another Example: In-Memory Graph Processing

- Large graphs are everywhere (circa 2015)

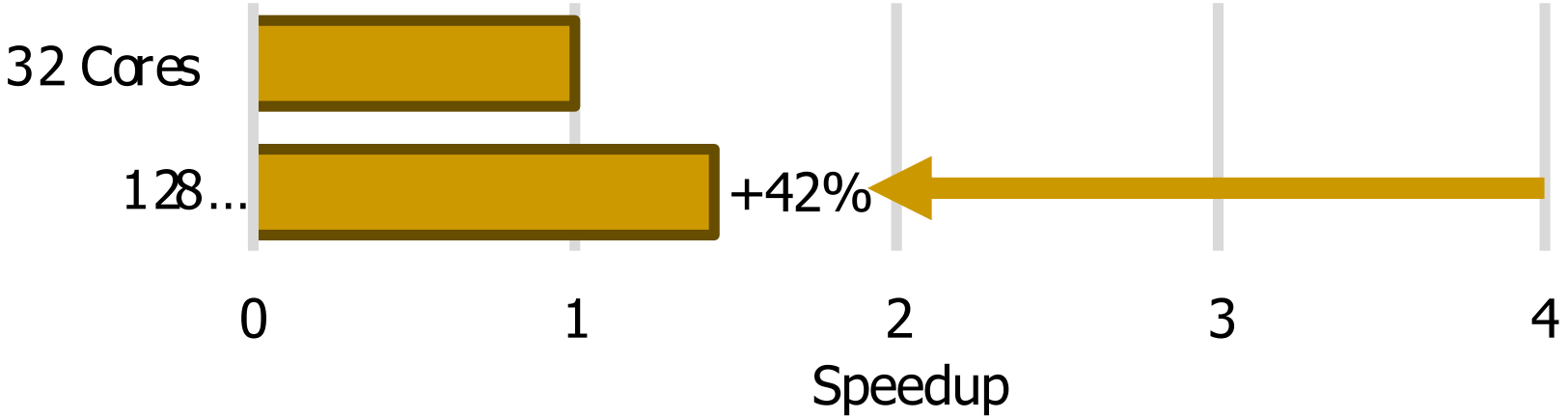
36 Million
Wikipedia Pages

1.4 Billion
Facebook Users

300 Million
Twitter Users

30 Billion
Instagram Photos

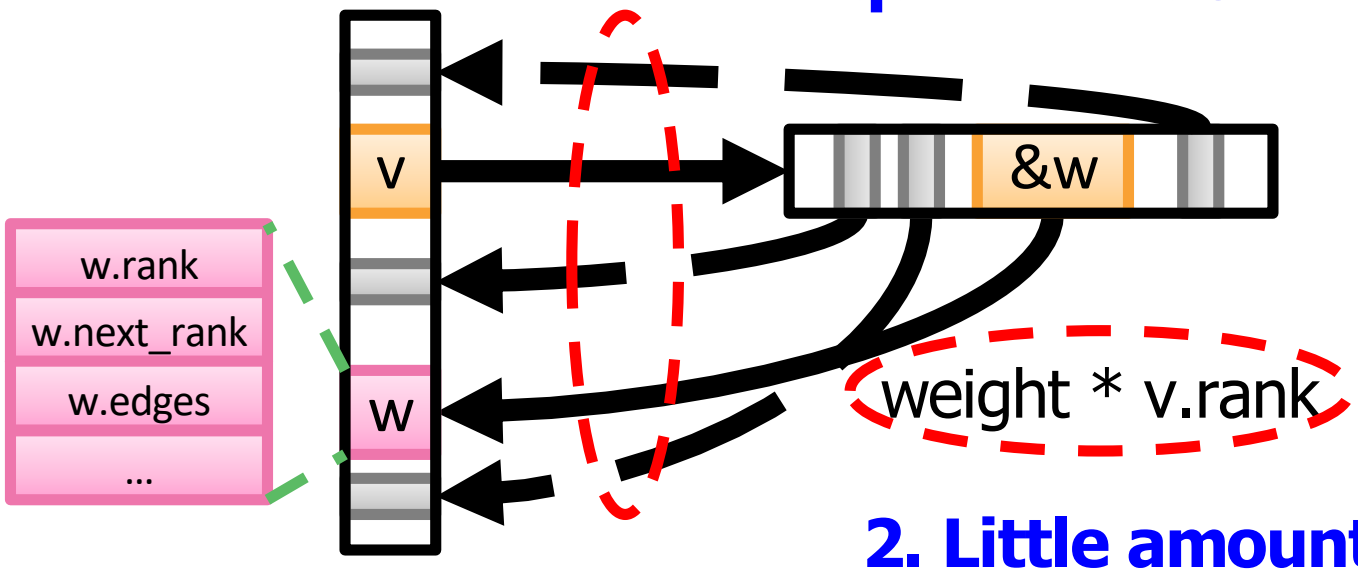
- Scalable large-scale graph processing is challenging



Key Bottlenecks in Graph Processing

```
for (v: graph.vertices) {
    for (w: v.successors) {
        w.next_rank += weight * v.rank;
    }
}
```

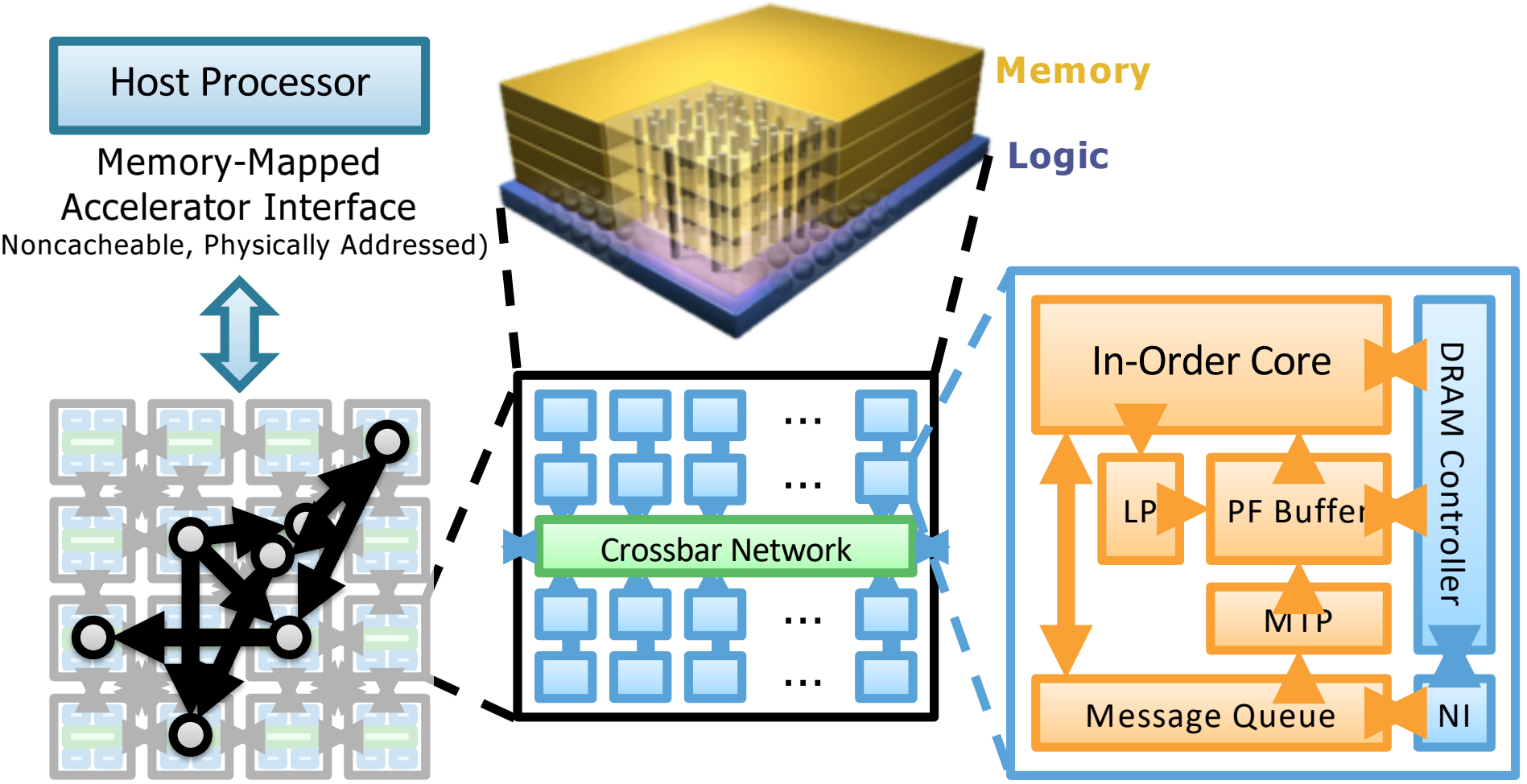
1. Frequent random memory accesses



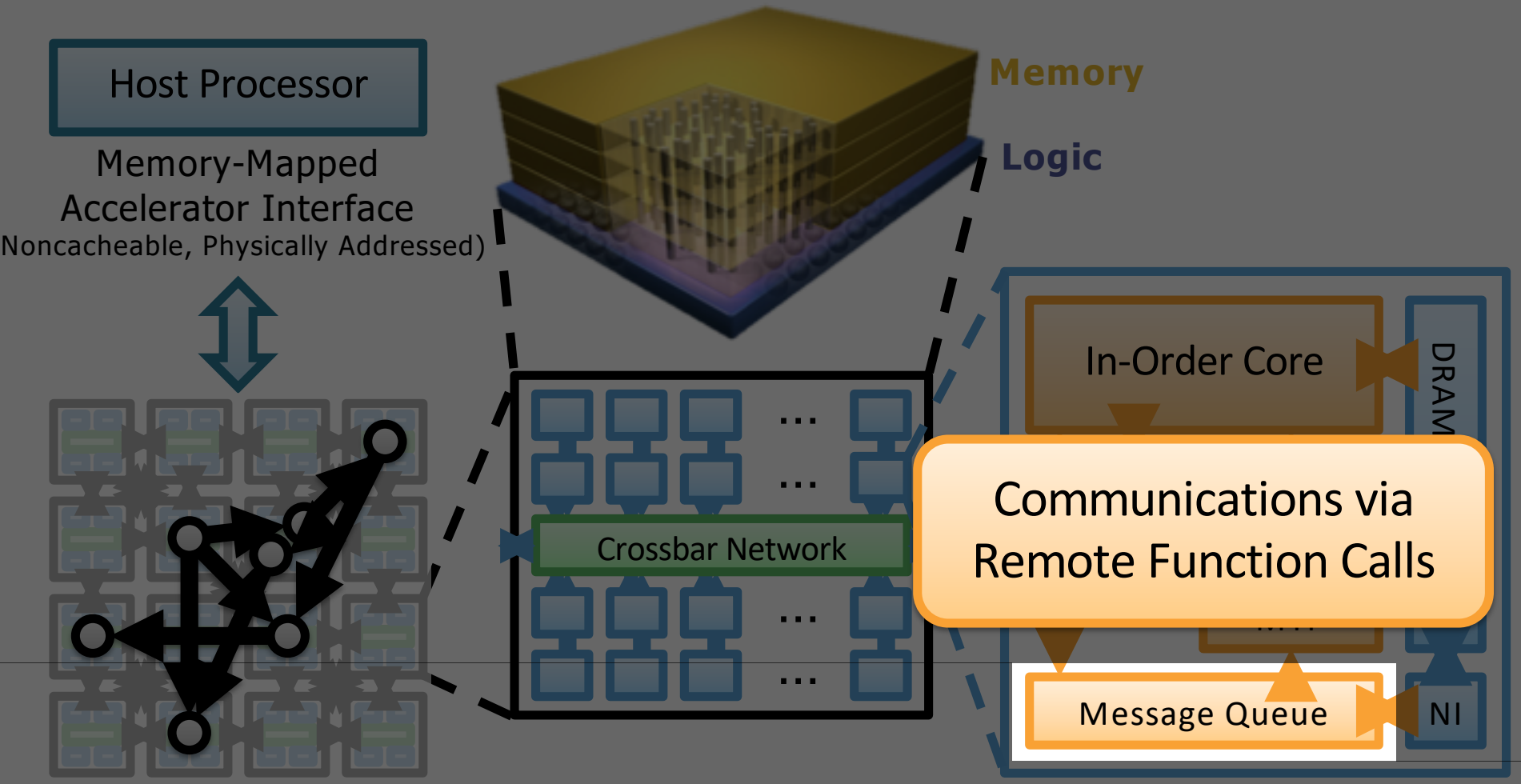
2. Little amount of computation

Tesseract System for Graph Processing

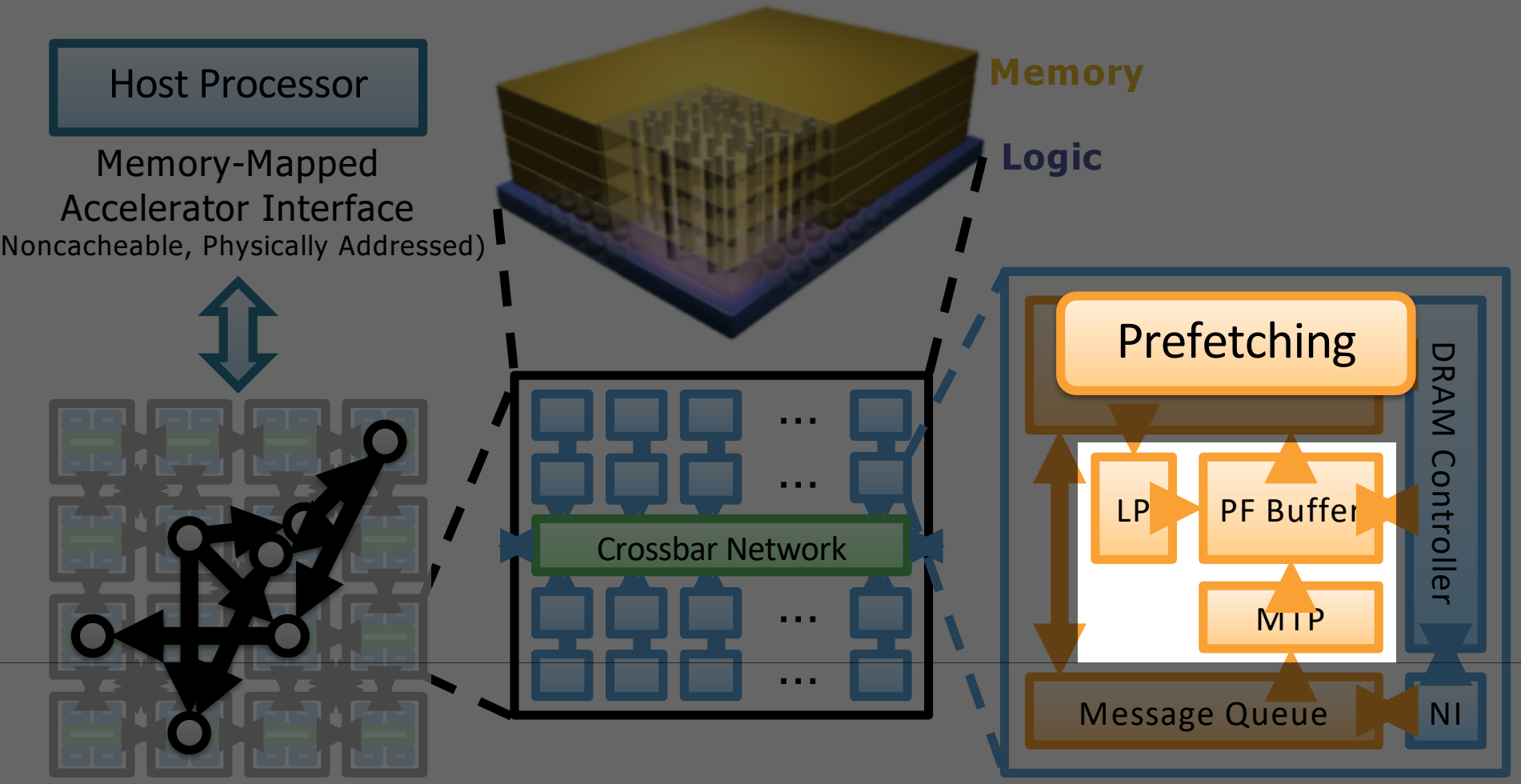
Interconnected set of 3D-stacked memory+logic chips with simple cores



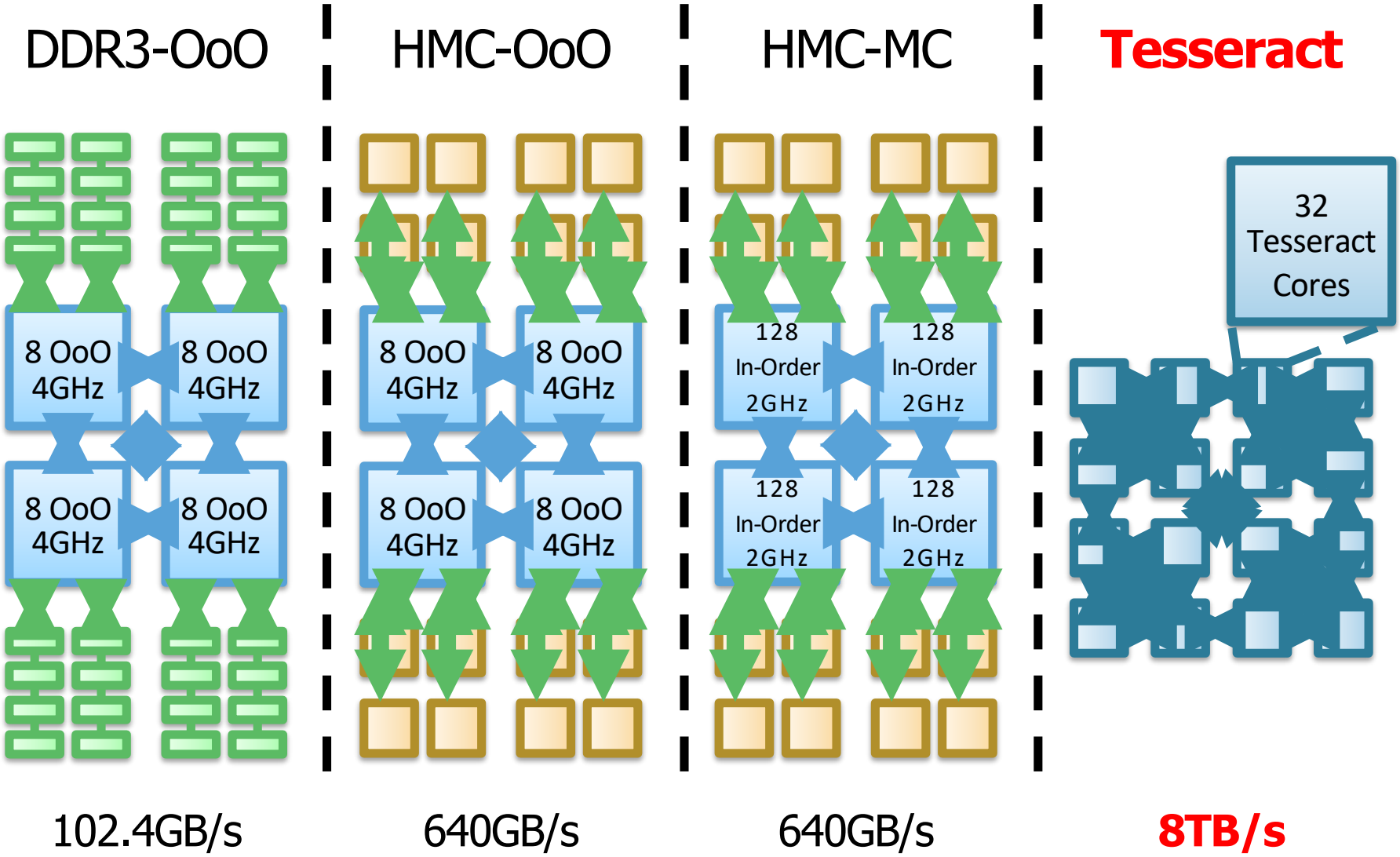
Tesseract System for Graph Processing



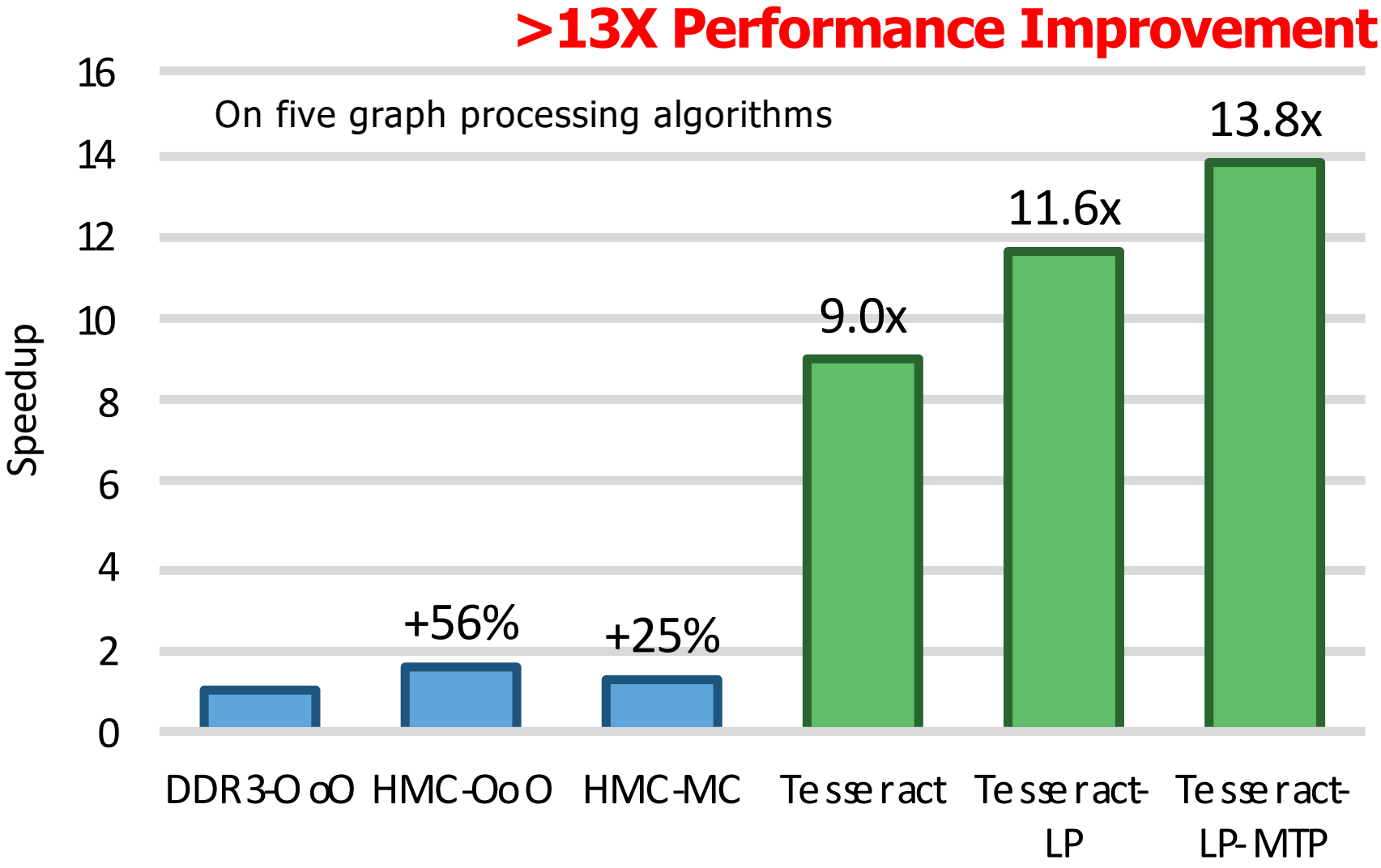
Tesseract System for Graph Processing



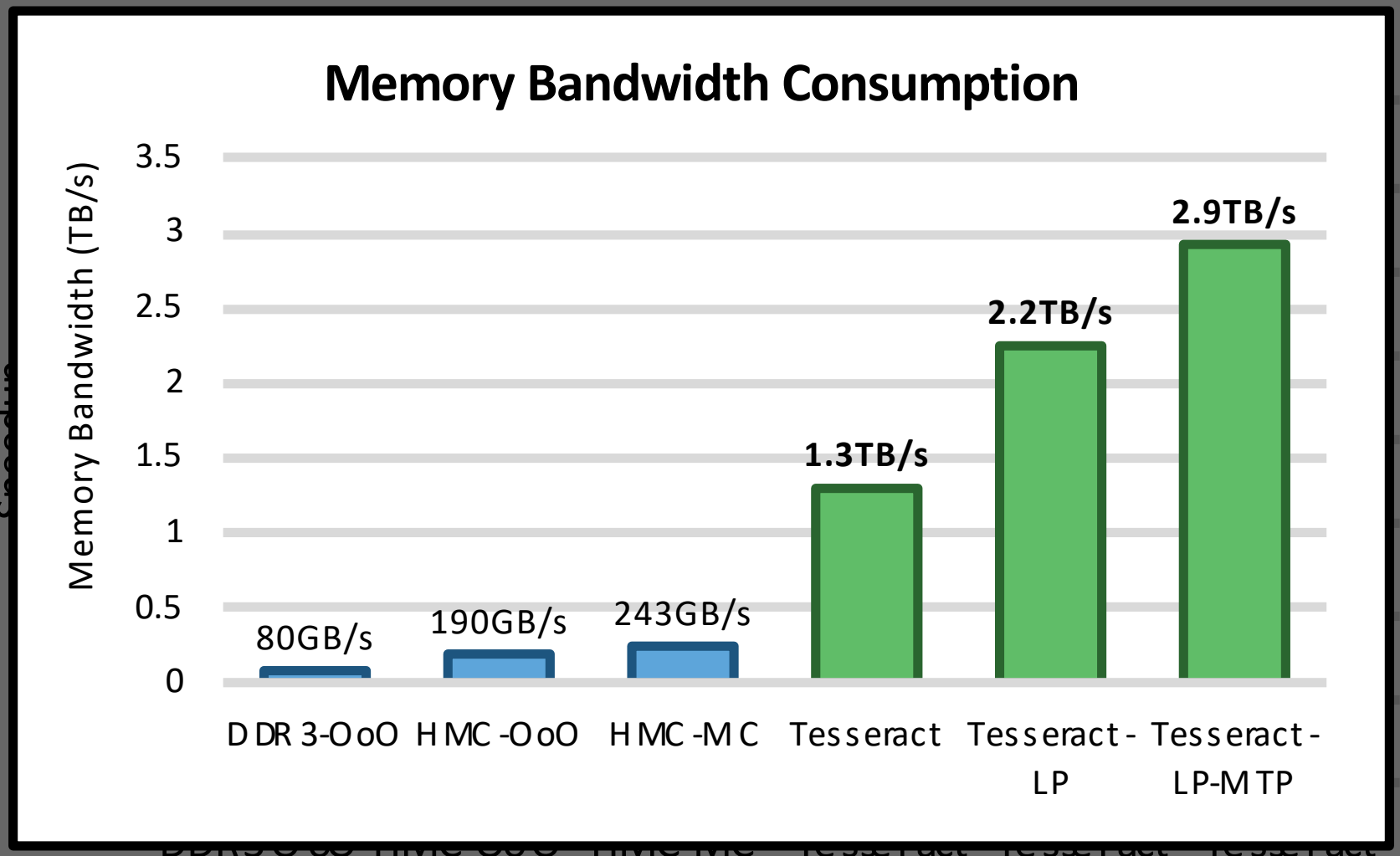
Evaluated Systems



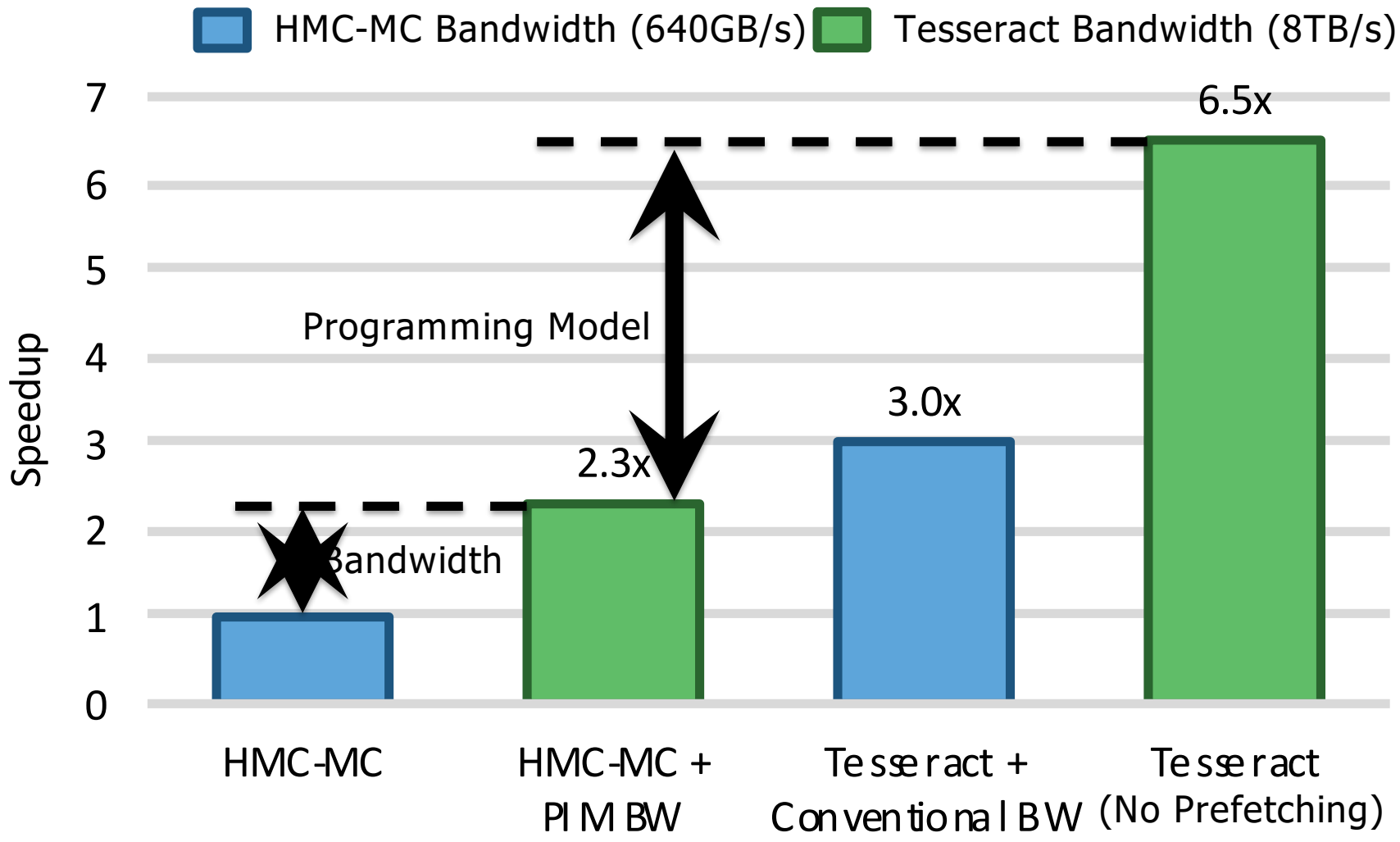
Tesseract Graph Processing Performance



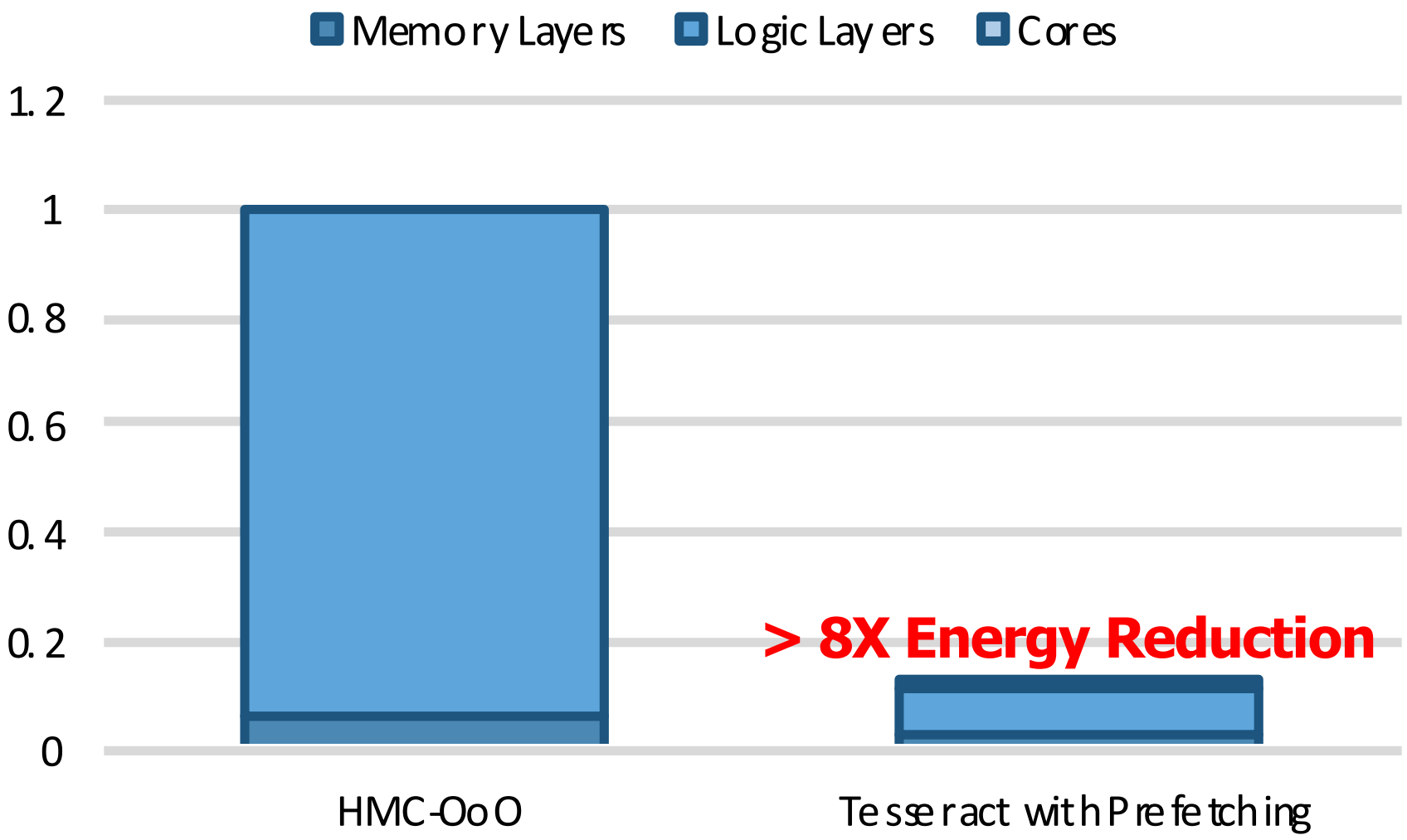
Tesseract Graph Processing Performance



Effect of Bandwidth & Programming Model



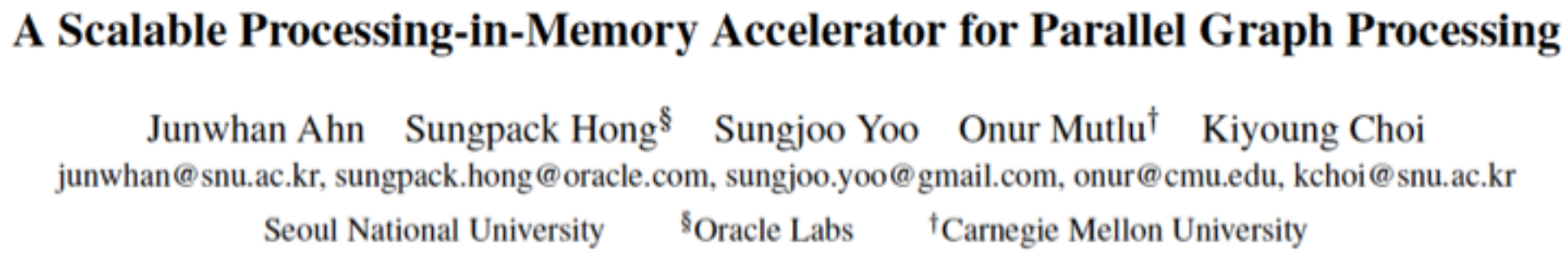
Tesseract Graph Processing System Energy



 Ahn+, "A Scalable Processing-in-Memory Accelerator for Parallel Graph Processing" ISCA 2015.

More on Tesseract

- Junwhan Ahn, Sungpack Hong, Sungjoo Yoo, Onur Mutlu, and Kiyoung Choi,
  "A Scalable Processing-in-Memory Accelerator for Parallel Graph Processing"
  *Proceedings of the 42nd International Symposium on Computer Architecture (**ISCA**)*, Portland, OR, June 2015.
  [Slides (pdf)] [Lightning Session Slides (pdf)]



A Scalable Processing-in-Memory Accelerator for Parallel Graph Processing

Junwhan Ahn Sungpack Hong[§] Sungjoo Yoo Onur Mutlu[†] Kiyoung Choi
junwhan@snu.ac.kr, sungpack.hong@oracle.com, sungjoo.yoo@gmail.com, onur@cmu.edu, kchoi@snu.ac.kr
Seoul National University [§]Oracle Labs [†]Carnegie Mellon University

3D-Stacked PIM on Mobile Devices

- Amirali Boroumand, Saugata Ghose, Youngsok Kim, Rachata Ausavarungnirun, Eric Shiu, Rahul Thakur, Daehyun Kim, Aki Kuusela, Allan Knies, Parthasarathy Ranganathan, and Onur Mutlu, **"Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks"**
  *Proceedings of the 23rd International Conference on Architectural Support for Programming Languages and Operating Systems (**ASPLOS**)*, Williamsburg, VA, USA, March 2018.

Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks

Amirali Boroumand

Saugata Ghose, Youngsok Kim, Rachata Ausavarungnirun, Eric Shiu, Rahul Thakur, Daehyun Kim, Aki Kuusela, Allan Knies, Parthasarathy Ranganathan, Onur Mutlu

SAFARI Carnegie Mellon Google

SAMSUNG SEOUL NATIONAL UNIVERSITY ETH Zürich

Consumer Devices

Consumer devices are everywhere!

Energy consumption is a first-class concern in consumer devices

Popular Google Consumer Workloads

Chrome

Google's web browser

TensorFlow Mobile

Google's machine learning framework

Video Playback

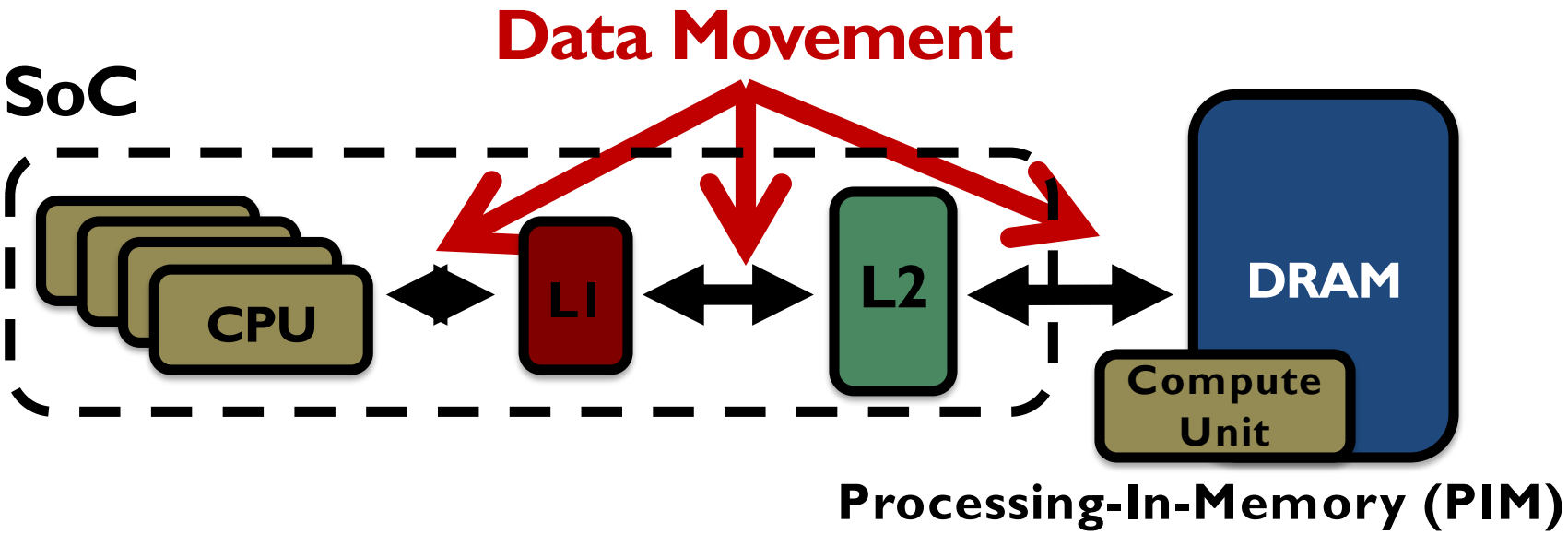
Google's video codec

Video Capture

Google's video codec

Energy Cost of Data Movement

1st key observation: 62.7% of the total system energy is spent on data movement



Potential solution: move computation close to data

Challenge: limited area and energy budget

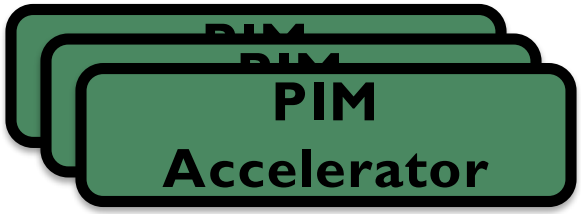
Using PIM to Reduce Data Movement

2nd key observation: a significant fraction of the data movement often comes from simple functions

We can design lightweight logic to implement these *simple functions* in memory

Small embedded low-power core

Small fixed-function accelerators



Offloading to PIM logic reduces energy and improves performance, on average, by 55.4% and 54.2%

Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks

Amirali Boroumand

Saugata Ghose, Youngsok Kim, Rachata Ausavarungnirun, Eric Shiu, Rahul Thakur, Daehyun Kim, Aki Kuusela, Allan Knies, Parthasarathy Ranganathan, Onur Mutlu

ASPLOS 2018

SAFARI

Carnegie Mellon

Google

SAMSUNG

SEOUL NATIONAL UNIVERSITY

ETH zürich

More on PIM for Mobile Devices

- Amirali Boroumand, Saugata Ghose, Youngsok Kim, Rachata Ausavarungnirun, Eric Shiu, Rahul Thakur, Daehyun Kim, Aki Kuusela, Allan Knies, Parthasarathy Ranganathan, and Onur Mutlu, **"Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks"** *Proceedings of the 23rd International Conference on Architectural Support for Programming Languages and Operating Systems (**ASPLOS**)*, Williamsburg, VA, USA, March 2018.

62.7% of the total system energy is spent on data movement

Google Workloads for Consumer Devices: Mitigating Data Movement Bottlenecks

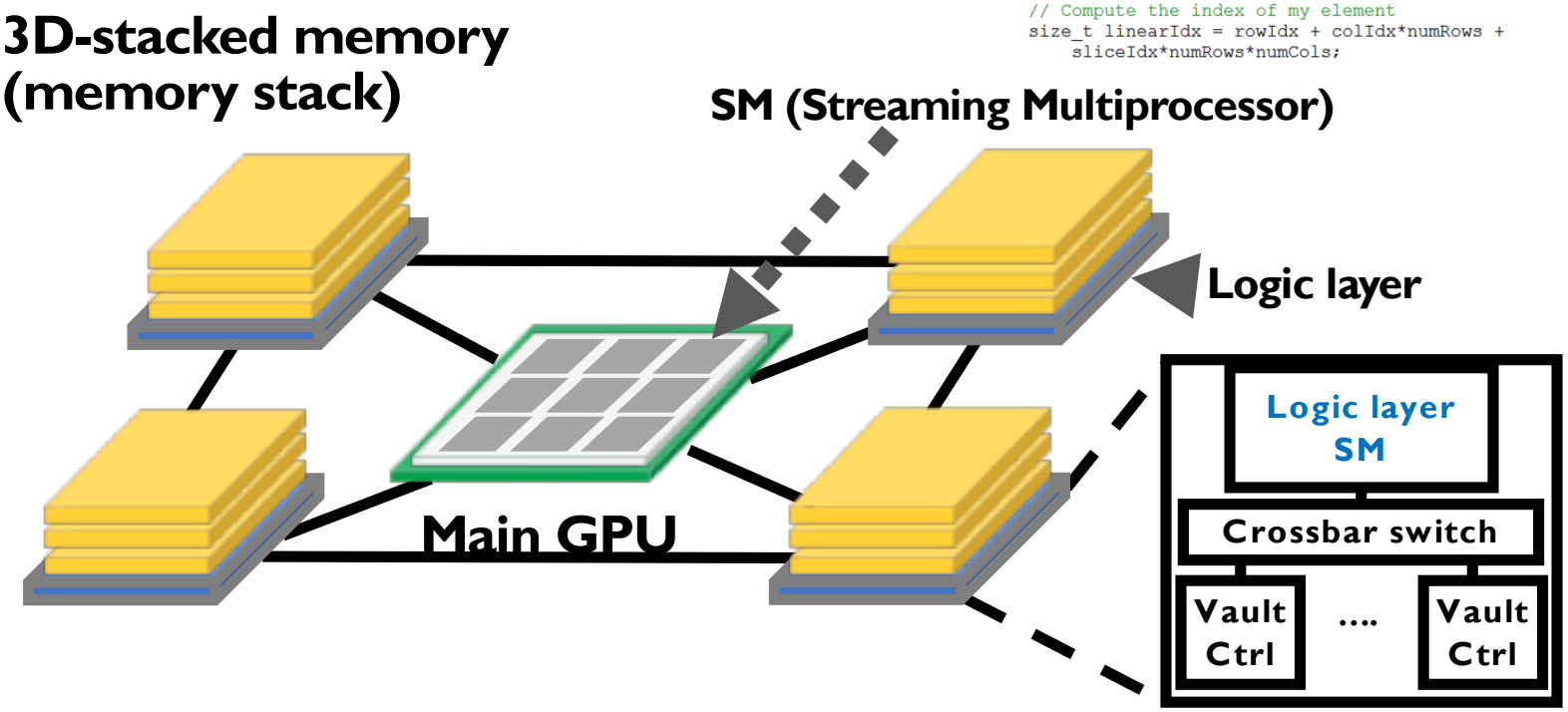
Amirali Boroumand[1] Saugata Ghose[1] Youngsok Kim[2]
Rachata Ausavarungnirun[1] Eric Shiu[3] Rahul Thakur[3] Daehyun Kim[4,3]
Aki Kuusela[3] Allan Knies[3] Parthasarathy Ranganathan[3] Onur Mutlu[5,1]

Truly Distributed GPU Processing with PIM?

```
__global__
void applyScaleFactorsKernel( uint8_T * const out,
    uint8_T const * const in, const double *factor,
    size_t const numRows, size_t const numCols )
{
    // Work out which pixel we are working on.
    const int rowIdx = blockIdx.x * blockDim.x + threadIdx.x;
    const int colIdx = blockIdx.y;
    const int sliceIdx = threadIdx.z;

    // Check this thread isn't off the image
    if( rowIdx >= numRows ) return;

    // Compute the index of my element
    size_t linearIdx = rowIdx + colIdx*numRows +
        sliceIdx*numRows*numCols;
```



Accelerating GPU Execution with PIM (I)

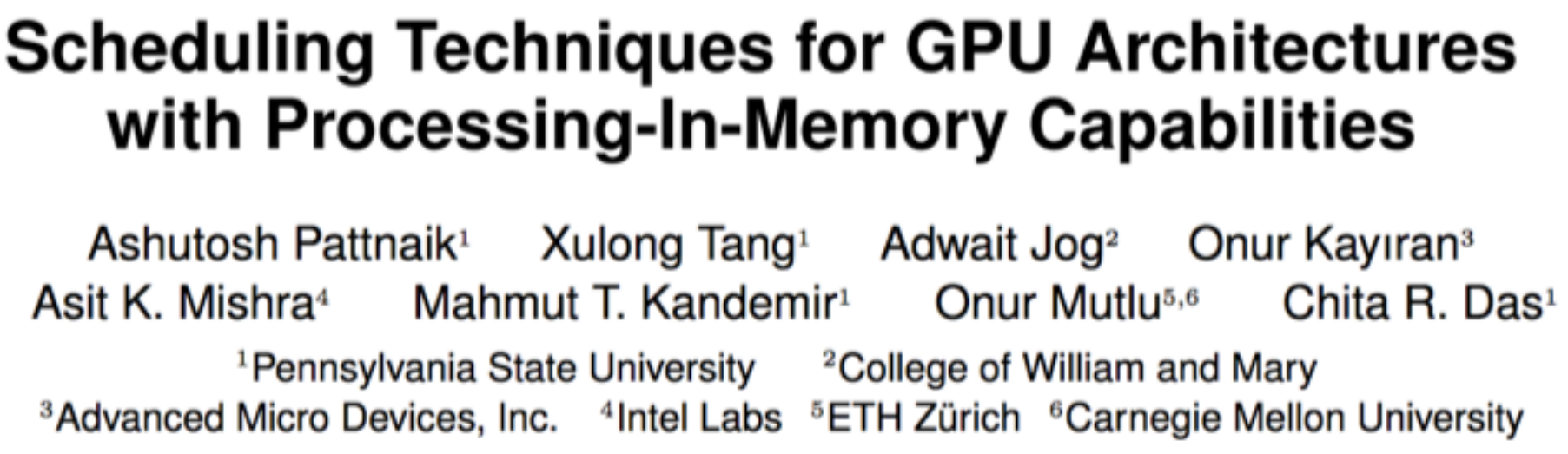
- Kevin Hsieh, Eiman Ebrahimi, Gwangsun Kim, Niladrish Chatterjee, Mike O'Connor, Nandita Vijaykumar, Onur Mutlu, and Stephen W. Keckler, **"Transparent Offloading and Mapping (TOM): Enabling Programmer-Transparent Near-Data Processing in GPU Systems"**
  *Proceedings of the 43rd International Symposium on Computer Architecture (**ISCA**)*, Seoul, South Korea, June 2016.
  [Slides (pptx) (pdf)]
  [Lightning Session Slides (pptx) (pdf)]

Transparent Offloading and Mapping (TOM):
Enabling Programmer-Transparent Near-Data Processing in GPU Systems

Kevin Hsieh[‡] Eiman Ebrahimi[†] Gwangsun Kim[*] Niladrish Chatterjee[†] Mike O'Connor[†]
Nandita Vijaykumar[‡] Onur Mutlu[§‡] Stephen W. Keckler[†]
[‡]Carnegie Mellon University [†]NVIDIA [*]KAIST [§]ETH Zürich

Accelerating GPU Execution with PIM (II)

- Ashutosh Pattnaik, Xulong Tang, Adwait Jog, Onur Kayiran, Asit K. Mishra, Mahmut T. Kandemir, Onur Mutlu, and Chita R. Das, **"Scheduling Techniques for GPU Architectures with Processing-In-Memory Capabilities"**
  Proceedings of the 25th International Conference on Parallel Architectures and Compilation Techniques (***PACT***), Haifa, Israel, September 2016.



Scheduling Techniques for GPU Architectures with Processing-In-Memory Capabilities

Ashutosh Pattnaik[1] Xulong Tang[1] Adwait Jog[2] Onur Kayıran[3]
Asit K. Mishra[4] Mahmut T. Kandemir[1] Onur Mutlu[5,6] Chita R. Das[1]

[1]Pennsylvania State University [2]College of William and Mary
[3]Advanced Micro Devices, Inc. [4]Intel Labs [5]ETH Zürich [6]Carnegie Mellon University

Accelerating Linked Data Structures

- Kevin Hsieh, Samira Khan, Nandita Vijaykumar, Kevin K. Chang, Amirali Boroumand, Saugata Ghose, and Onur Mutlu,
  "Accelerating Pointer Chasing in 3D-Stacked Memory: Challenges, Mechanisms, Evaluation"
  *Proceedings of the 34th IEEE International Conference on Computer Design (**ICCD**)*, Phoenix, AZ, USA, October 2016.


Accelerating Pointer Chasing in 3D-Stacked Memory: Challenges, Mechanisms, Evaluation

Kevin Hsieh[†] Samira Khan[‡] Nandita Vijaykumar[†]
Kevin K. Chang[†] Amirali Boroumand[†] Saugata Ghose[†] Onur Mutlu[§†]
[†]*Carnegie Mellon University* [‡]*University of Virginia* [§]*ETH Zürich*

Accelerating Dependent Cache Misses

- Milad Hashemi, Khubaib, Eiman Ebrahimi, Onur Mutlu, and Yale N. Patt, **"Accelerating Dependent Cache Misses with an Enhanced Memory Controller"**
  *Proceedings of the 43rd International Symposium on Computer Architecture (**ISCA**)*, Seoul, South Korea, June 2016.
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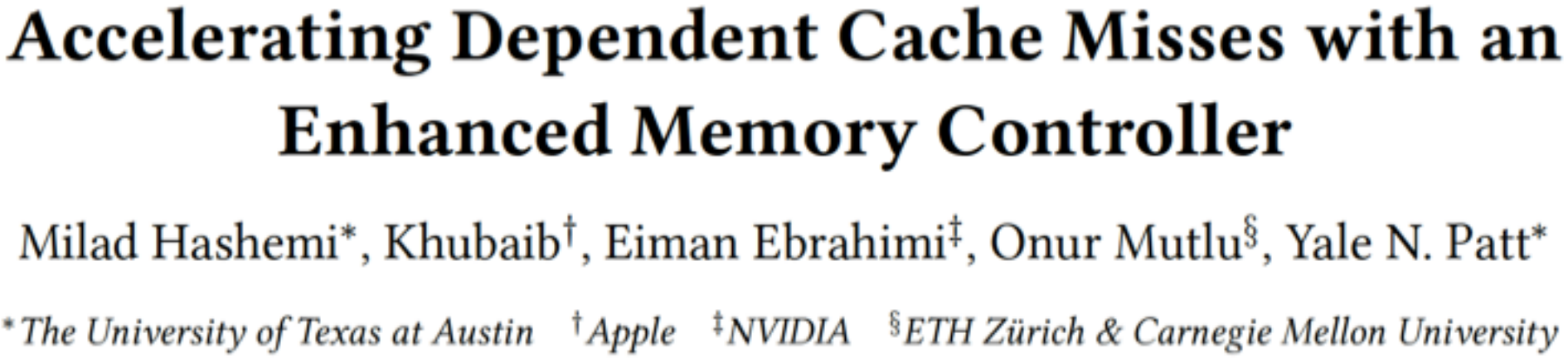

Accelerating Dependent Cache Misses with an Enhanced Memory Controller

Milad Hashemi*, Khubaib†, Eiman Ebrahimi‡, Onur Mutlu§, Yale N. Patt*

*The University of Texas at Austin †Apple ‡NVIDIA §ETH Zürich & Carnegie Mellon University

Two Key Questions in 3D-Stacked PIM

- How can we accelerate important applications if we use 3D-stacked memory as a coarse-grained accelerator?
  - what is the architecture and programming model?
  - what are the mechanisms for acceleration?

- What is the minimal processing-in-memory support we can provide?
  - without changing the system significantly
  - while achieving significant benefits

PIM-Enabled Instructions

- Junwhan Ahn, Sungjoo Yoo, Onur Mutlu, and Kiyoung Choi, **"PIM-Enabled Instructions: A Low-Overhead, Locality-Aware Processing-in-Memory Architecture"** *Proceedings of the 42nd International Symposium on Computer Architecture (**ISCA**)*, Portland, OR, June 2015. [Slides (pdf)] [Lightning Session Slides (pdf)]

PIM-Enabled Instructions: A Low-Overhead, Locality-Aware Processing-in-Memory Architecture

Junwhan Ahn Sungjoo Yoo Onur Mutlu† Kiyoung Choi
junwhan@snu.ac.kr, sungjoo.yoo@gmail.com, onur@cmu.edu, kchoi@snu.ac.kr
Seoul National University †Carnegie Mellon University

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Automatic Code and Data Mapping

- Kevin Hsieh, Eiman Ebrahimi, Gwangsun Kim, Niladrish Chatterjee, Mike O'Connor, Nandita Vijaykumar, Onur Mutlu, and Stephen W. Keckler, **"Transparent Offloading and Mapping (TOM): Enabling Programmer-Transparent Near-Data Processing in GPU Systems"**
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Transparent Offloading and Mapping (TOM):
Enabling Programmer-Transparent Near-Data Processing in GPU Systems

Kevin Hsieh[‡] Eiman Ebrahimi[†] Gwangsun Kim[*] Niladrish Chatterjee[†] Mike O'Connor[†]
Nandita Vijaykumar[‡] Onur Mutlu[§‡] Stephen W. Keckler[†]
[‡]Carnegie Mellon University [†]NVIDIA [*]KAIST [§]ETH Zürich

Automatic Offloading of Critical Code

- Milad Hashemi, Khubaib, Eiman Ebrahimi, Onur Mutlu, and Yale N. Patt, **"Accelerating Dependent Cache Misses with an Enhanced Memory Controller"**
  *Proceedings of the 43rd International Symposium on Computer Architecture (**ISCA**)*, Seoul, South Korea, June 2016.
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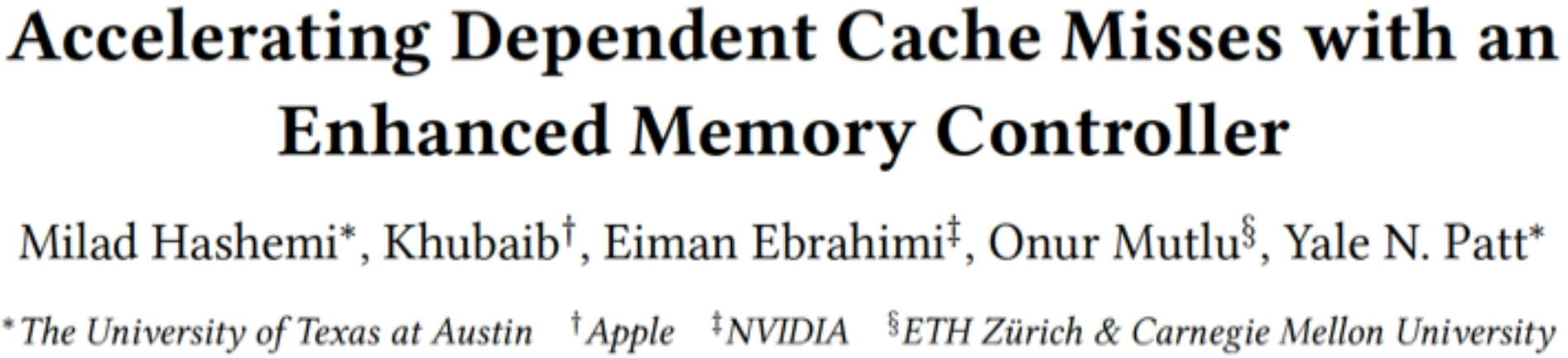


Accelerating Dependent Cache Misses with an Enhanced Memory Controller

Milad Hashemi*, Khubaib†, Eiman Ebrahimi‡, Onur Mutlu§, Yale N. Patt*

*The University of Texas at Austin †Apple ‡NVIDIA §ETH Zürich & Carnegie Mellon University

Automatic Offloading of Prefetch Mechanisms

- Milad Hashemi, Onur Mutlu, and Yale N. Patt,
  "Continuous Runahead: Transparent Hardware Acceleration for Memory Intensive Workloads"
  *Proceedings of the 49th International Symposium on Microarchitecture (**MICRO**)*, Taipei, Taiwan, October 2016.
  [Slides (pptx) (pdf)] [Lightning Session Slides (pdf)] [Poster (pptx) (pdf)]

Efficient Automatic Data Coherence Support

- Amirali Boroumand, Saugata Ghose, Minesh Patel, Hasan Hassan, Brandon Lucia, Kevin Hsieh, Krishna T. Malladi, Hongzhong Zheng, and Onur Mutlu,
  "LazyPIM: An Efficient Cache Coherence Mechanism for Processing-in-Memory"
  IEEE Computer Architecture Letters (***CAL***), June 2016.

LazyPIM: An Efficient Cache Coherence Mechanism for Processing-in-Memory

Amirali Boroumand[†], Saugata Ghose[†], Minesh Patel[†], Hasan Hassan[†§], Brandon Lucia[†],
Kevin Hsieh[†], Krishna T. Malladi[*], Hongzhong Zheng[*], and Onur Mutlu[‡†]
[†]*Carnegie Mellon University* [*]*Samsung Semiconductor, Inc.* [§]*TOBB ETÜ* [‡]*ETH Zürich*

Challenge and Opportunity for Future

Fundamentally Energy-Efficient (Data-Centric) Computing Architectures

Computing Architectures with Minimal Data Movement

Eliminating the Adoption Barriers

How to Enable Adoption of Processing in Memory

Barriers to Adoption of PIM

1. Functionality of and applications for PIM

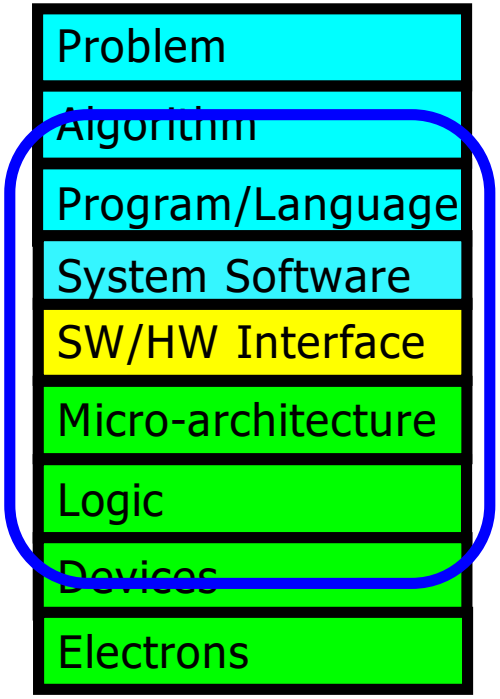
2. Ease of programming (interfaces and compiler/HW support)

3. System support: coherence & virtual memory

4. Runtime systems for adaptive scheduling, data mapping, access/sharing control

5. Infrastructures to assess benefits and feasibility

We Need to Revisit the Entire Stack



Open Problems: PIM Adoption

Enabling the Adoption of Processing-in-Memory: Challenges, Mechanisms, Future Research Directions

SAUGATA GHOSE, KEVIN HSIEH, AMIRALI BOROUMAND,
RACHATA AUSAVARUNGNIRUN
Carnegie Mellon University

ONUR MUTLU
ETH Zürich and Carnegie Mellon University

https://arxiv.org/pdf/1802.00320.pdf

Key Challenge 1: Code Mapping

- **Challenge 1:** Which operations should be executed in memory vs. in CPU?

```
__global__
void applyScaleFactorsKernel( uint8_T * const out,
    uint8_T const * const in, const double *factor,
    size_t const numRows, size_t const numCols )
{
    // Work out which pixel we are working on.
    const int rowIdx = blockIdx.x * blockDim.x + threadIdx.x;
    const int colIdx = blockIdx.y;
    const int sliceIdx = threadIdx.z;

    // Check this thread isn't off the image
    if( rowIdx >= numRows ) return;

    // Compute the index of my element
    size_t linearIdx = rowIdx + colIdx*numRows +
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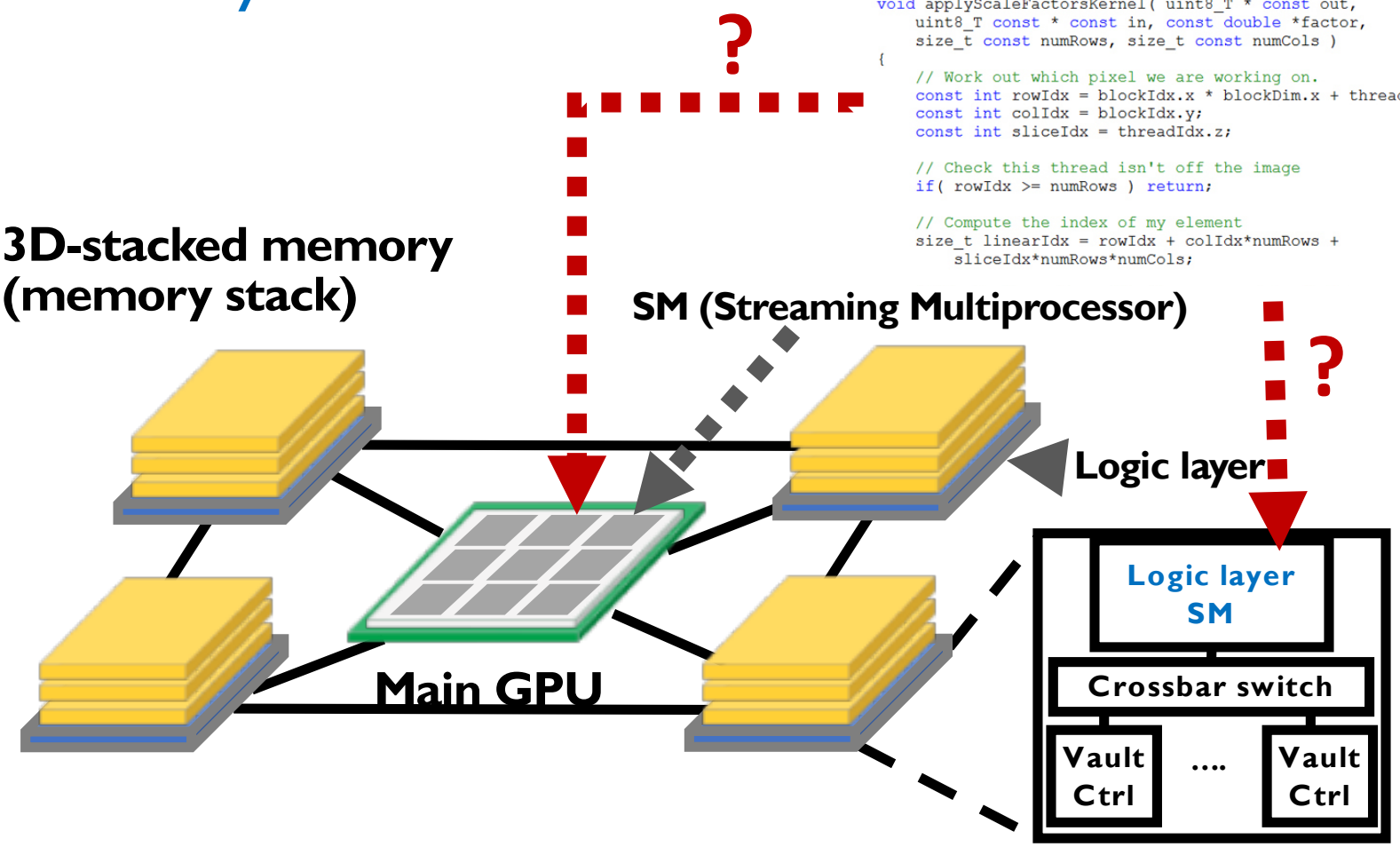
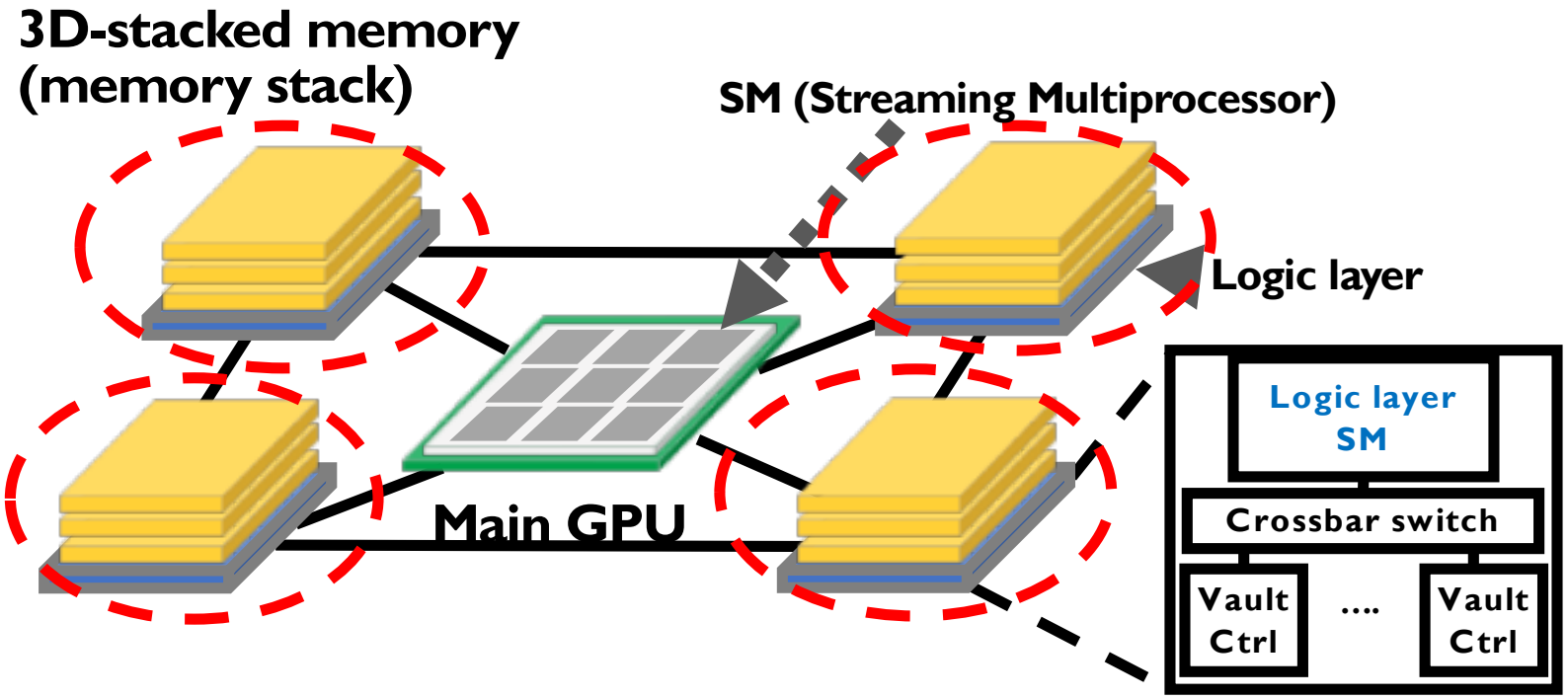
```



Key Challenge 2: Data Mapping

- **Challenge 2:** How should data be mapped to different 3D memory stacks?



How to Do the Code and Data Mapping?

- Kevin Hsieh, Eiman Ebrahimi, Gwangsun Kim, Niladrish Chatterjee, Mike O'Connor, Nandita Vijaykumar, Onur Mutlu, and Stephen W. Keckler, **"Transparent Offloading and Mapping (TOM): Enabling Programmer-Transparent Near-Data Processing in GPU Systems"**
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Nandita Vijaykumar[‡] Onur Mutlu[§‡] Stephen W. Keckler[†]
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How to Schedule Code?

- Ashutosh Pattnaik, Xulong Tang, Adwait Jog, Onur Kayiran, Asit K. Mishra, Mahmut T. Kandemir, Onur Mutlu, and Chita R. Das, **"Scheduling Techniques for GPU Architectures with Processing-In-Memory Capabilities"**
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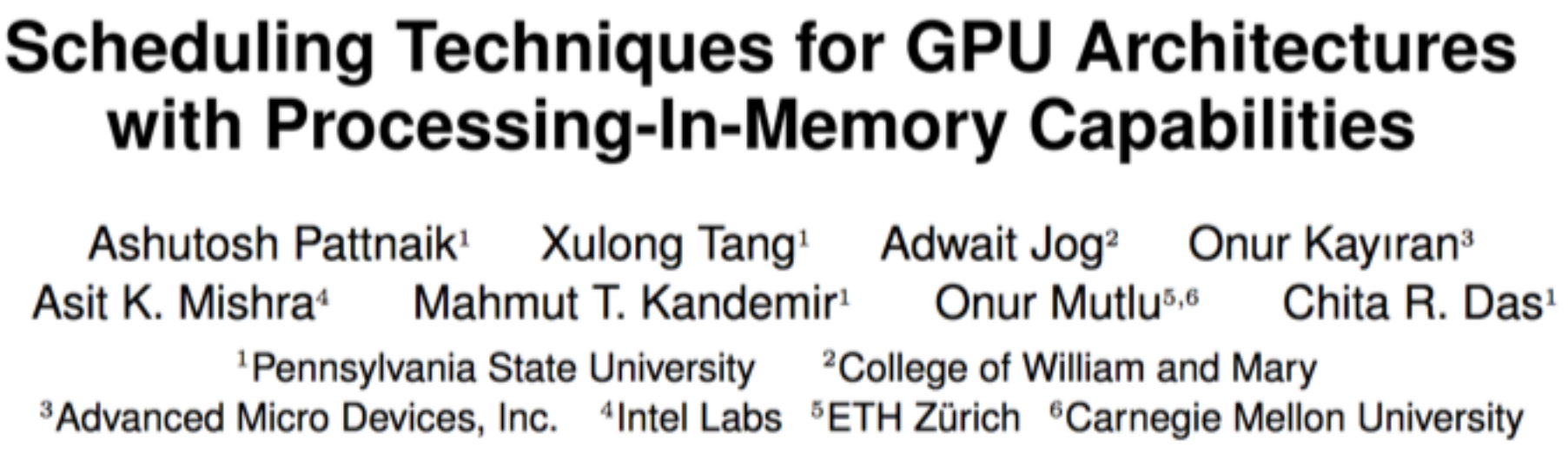
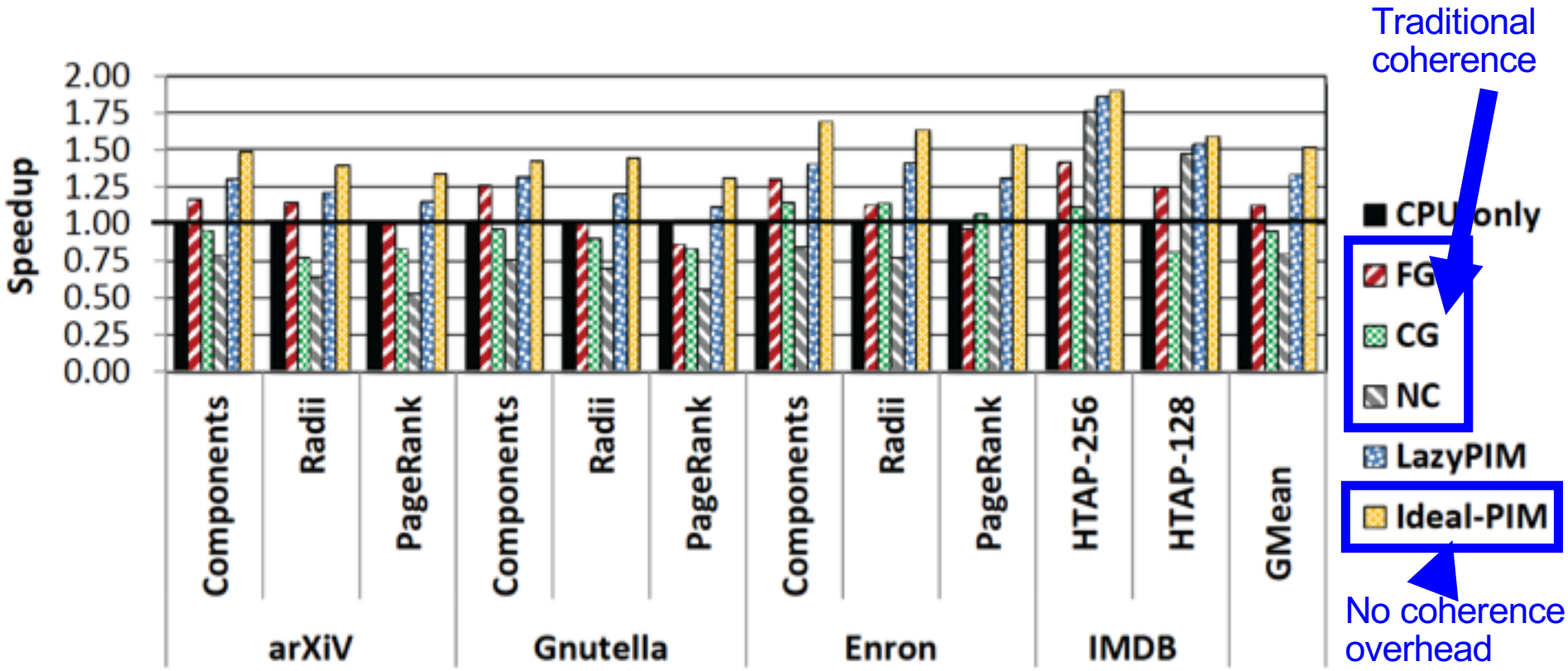


Scheduling Techniques for GPU Architectures with Processing-In-Memory Capabilities

Ashutosh Pattnaik[1] Xulong Tang[1] Adwait Jog[2] Onur Kayıran[3]
Asit K. Mishra[4] Mahmut T. Kandemir[1] Onur Mutlu[5,6] Chita R. Das[1]

[1]Pennsylvania State University [2]College of William and Mary
[3]Advanced Micro Devices, Inc. [4]Intel Labs [5]ETH Zürich [6]Carnegie Mellon University

Challenge: Coherence for Hybrid CPU-PIM Apps



How to Maintain Coherence?

- Amirali Boroumand, Saugata Ghose, Minesh Patel, Hasan Hassan, Brandon Lucia, Kevin Hsieh, Krishna T. Malladi, Hongzhong Zheng, and Onur Mutlu,
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How to Support Virtual Memory?

- Kevin Hsieh, Samira Khan, Nandita Vijaykumar, Kevin K. Chang, Amirali Boroumand, Saugata Ghose, and Onur Mutlu,
  "Accelerating Pointer Chasing in 3D-Stacked Memory: Challenges, Mechanisms, Evaluation"
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[†]*Carnegie Mellon University* [‡]*University of Virginia* [§]*ETH Zürich*

How to Design Data Structures for PIM?

- Zhiyu Liu, Irina Calciu, Maurice Herlihy, and Onur Mutlu, **"Concurrent Data Structures for Near-Memory Computing"** *Proceedings of the 29th ACM Symposium on Parallelism in Algorithms and Architectures (**SPAA**)*, Washington, DC, USA, July 2017. [Slides (pptx) (pdf)]

Concurrent Data Structures for Near-Memory Computing

Zhiyu Liu
Computer Science Department
Brown University
zhiyu_liu@brown.edu

Irina Calciu
VMware Research Group
icalciu@vmware.com

Maurice Herlihy
Computer Science Department
Brown University
mph@cs.brown.edu

Onur Mutlu
Computer Science Department
ETH Zürich
onur.mutlu@inf.ethz.ch

Simulation Infrastructures for PIM

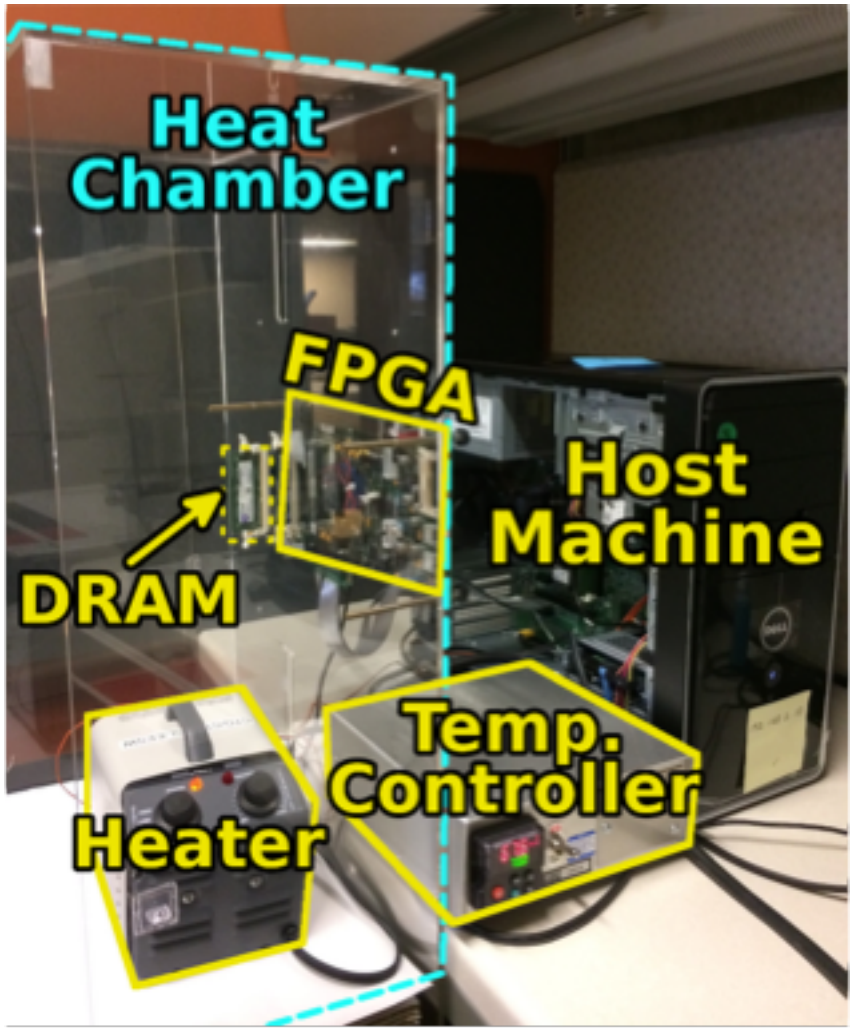
- Ramulator extended for PIM
  - Flexible and extensible DRAM simulator
  - Can model many different memory standards and proposals
  - Kim+, "**Ramulator: A Flexible and Extensible DRAM Simulator**", IEEE CAL 2015.
  - https://github.com/CMU-SAFARI/ramulator

Ramulator: A Fast and Extensible DRAM Simulator

Yoongu Kim[1] Weikun Yang[1,2] Onur Mutlu[1]
[1]Carnegie Mellon University [2]Peking University

An FPGA-based Test-bed for PIM?

- Hasan Hassan et al., **SoftMC: A Flexible and Practical Open-Source Infrastructure for Enabling Experimental DRAM Studies** HPCA 2017.

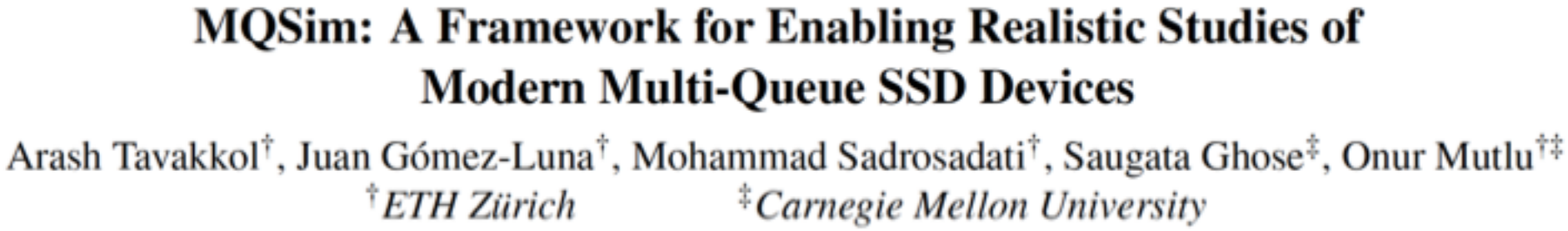


- **Flexible**
- **Easy to Use (C++ API)**
- **Open-source**

  github.com/CMU-SAFARI/SoftMC

Simulation Infrastructures for PIM (in SSDs)

- Arash Tavakkol, Juan Gomez-Luna, Mohammad Sadrosadati, Saugata Ghose, and Onur Mutlu,
  "MQSim: A Framework for Enabling Realistic Studies of Modern Multi-Queue SSD Devices"
  *Proceedings of the 16th USENIX Conference on File and Storage Technologies (**FAST**)*, Oakland, CA, USA, February 2018.
  [Slides (pptx) (pdf)]
  [Source Code]



MQSim: A Framework for Enabling Realistic Studies of Modern Multi-Queue SSD Devices

Arash Tavakkol[†], Juan Gómez-Luna[†], Mohammad Sadrosadati[†], Saugata Ghose[‡], Onur Mutlu[†‡]

[†]*ETH Zürich* [‡]*Carnegie Mellon University*

Concluding Remarks

A Quote from A Famous Architect

- "architecture [...] based upon principle, and not upon precedent"

Precedent-Based Design?

- "architecture [...] based upon principle, and not upon precedent"

Principled Design

- "architecture [...] based upon principle, and not upon precedent"


www.GreatBuildings.com

The Overarching Principle

Organic architecture

From Wikipedia, the free encyclopedia

Organic architecture is a philosophy of architecture which promotes harmony between human habitation and the natural world through design approaches so sympathetic and well integrated with its site, that buildings, furnishings, and surroundings become part of a unified, interrelated composition.

A well-known example of organic architecture is Fallingwater, the residence Frank Lloyd Wright designed for the Kaufmann family in rural Pennsylvania. Wright had many choices to locate a home on this large site, but chose to place the home directly over the waterfall and creek creating a close, yet noisy dialog with the rushing water and the steep site. The horizontal striations of stone masonry with daring cantilevers of colored beige concrete blend with native rock outcroppings and the wooded environment.

Another Example: Precedent-Based Design

Source: http://cookiemagik.deviantart.com/art/Train-station-207266944

Principled Design

Source: By Toni_V, CC BY-SA 2.0, https://commons.wikimedia.org/w/index.php?curid=4087256

Another Principled Design

Source: By Martín Gómez Tagle - Lisbon, Portugal, CC BY-SA 3.0, https://commons.wikimedia.org/w/index.php?curid=13764903

Source: http://www.arcspace.com/exhibitions/unsorted/santiago-calatrava/

Principle Applied to Another Structure

Source: By 準建築人手札網站 Forgemind ArchiMedia - Flickr: IMG_2489.JPG, CC BY 2.0, https://commons.wikimedia.org/w/index.php?curid=31495390, https://en.wikipedia.org/wiki/Santiago_Calatrava

https://commons.wikimedia.org/w/index.php?curid=31495390, https://en.wikipedia.org/wiki/Santiago_Calatrava

The Overarching Principle

Zoomorphic architecture

From Wikipedia, the free encyclopedia

Zoomorphic architecture is the practice of using animal forms as the inspirational basis and blueprint for architectural design. "While animal forms have always played a role adding some of the deepest layers of meaning in architecture, it is now becoming evident that a new strand of biomorphism is emerging where the meaning derives not from any specific representation but from a more general allusion to biological processes."[1]

Some well-known examples of Zoomorphic architecture can be found in the TWA Flight Center building in New York City, by Eero Saarinen, or the Milwaukee Art Museum by Santiago Calatrava, both inspired by the form of a bird's wings.[3]

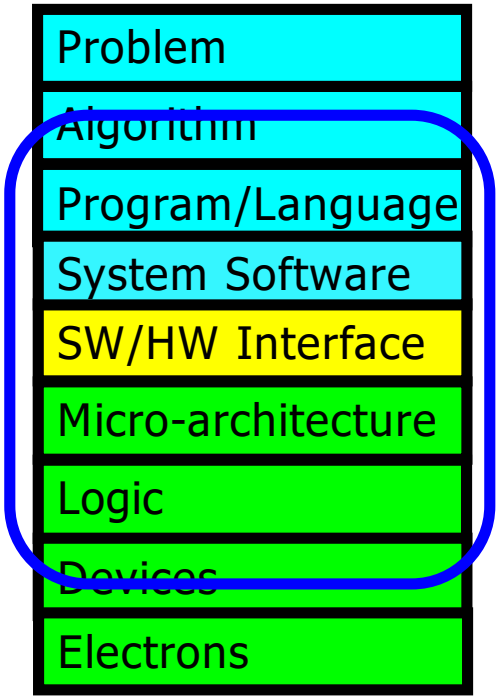
Overarching Principles for Computing?

Source: http://spectrum.ieee.org/image/MjYzMzAyMg.jpeg

Concluding Remarks

- It is time to design principled system architectures to solve the memory problem
- Discover design principles for fundamentally secure and reliable computer architectures
- Design complete systems to be balanced and energy-efficient, i.e., low latency and data-centric (or memory-centric)
- Enable new and emerging memory architectures
- This can
  - Lead to **orders-of-magnitude** improvements
  - **Enable new applications & computing platforms**
  - **…**

We Need to Think Across the Stack



If In Doubt, See Other Doubtful Technologies

- A very "doubtful" emerging technology
  - for at least two decades

Proceedings of the IEEE, Sept. 2017

Error Characterization, Mitigation, and Recovery in Flash-Memory-Based Solid-State Drives

This paper reviews the most recent advances in solid-state drive (SSD) error characterization, mitigation, and data recovery techniques to improve both SSD's reliability and lifetime.

By Yu Cai, Saugata Ghose, Erich F. Haratsch, Yixin Luo, and Onur Mutlu

https://arxiv.org/pdf/1706.08642

Rethinking Memory System Design
Robustness, Energy, Performance

Onur Mutlu

omutlu@gmail.com

https://people.inf.ethz.ch/omutlu

July 3, 2018

IOLTS Keynote Talk

SAFARI

ETH zürich

Carnegie Mellon

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- My current and past students and postdocs
  - Rachata Ausavarungnirun, Abhishek Bhowmick, Amirali Boroumand, Rui Cai, Yu Cai, Kevin Chang, Saugata Ghose, Kevin Hsieh, Tyler Huberty, Ben Jaiyen, Samira Khan, Jeremie Kim, Yoongu Kim, Yang Li, Jamie Liu, Lavanya Subramanian, Donghyuk Lee, Yixin Luo, Justin Meza, Gennady Pekhimenko, Vivek Seshadri, Lavanya Subramanian, Nandita Vijaykumar, HanBin Yoon, Jishen Zhao, …
- My collaborators
  - Can Alkan, Chita Das, Phil Gibbons, Sriram Govindan, Norm Jouppi, Mahmut Kandemir, Mike Kozuch, Konrad Lai, Ken Mai, Todd Mowry, Yale Patt, Moinuddin Qureshi, Partha Ranganathan, Bikash Sharma, Kushagra Vaid, Chris Wilkerson, …

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Slides Not Covered But Could Be Useful

Open Problems and References

Reference Overview Paper I

Enabling the Adoption of Processing-in-Memory: Challenges, Mechanisms, Future Research Directions

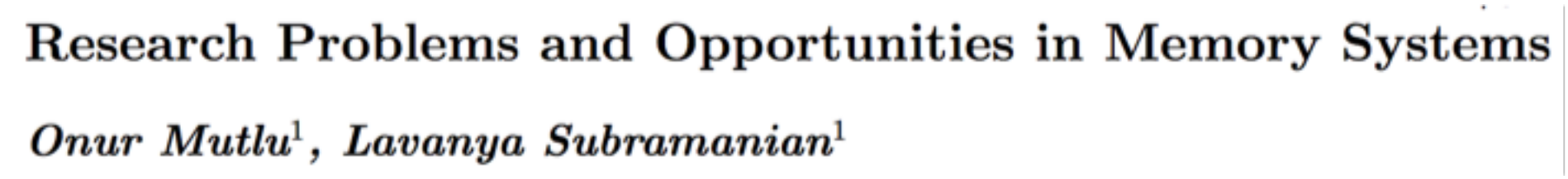
SAUGATA GHOSE, KEVIN HSIEH, AMIRALI BOROUMAND,
RACHATA AUSAVARUNGNIRUN
Carnegie Mellon University

ONUR MUTLU
ETH Zürich and Carnegie Mellon University

https://arxiv.org/pdf/1802.00320.pdf

Reference Overview Paper II

- Onur Mutlu and Lavanya Subramanian,
  "Research Problems and Opportunities in Memory Systems"
  *Invited Article in Supercomputing Frontiers and Innovations (**SUPERFRI**)*, 2014/2015.

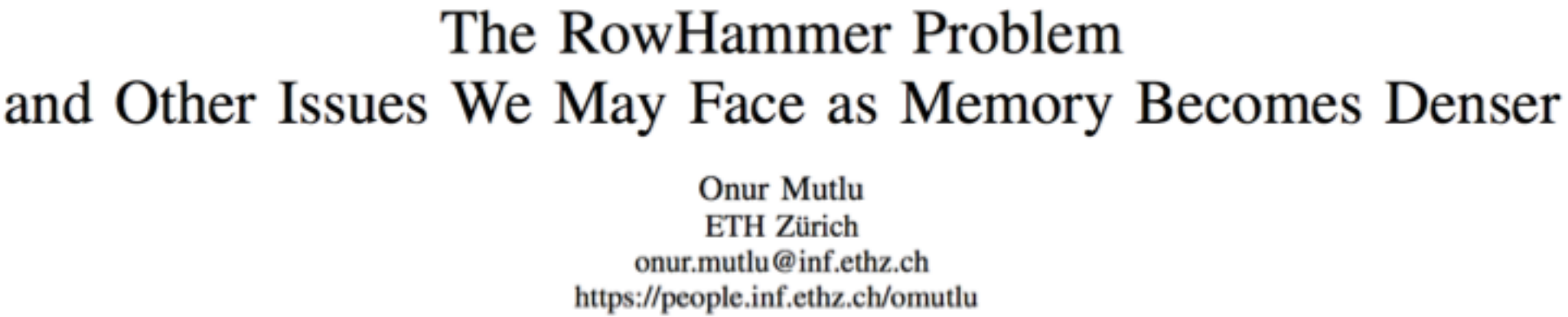

Research Problems and Opportunities in Memory Systems

Onur Mutlu[1], *Lavanya Subramanian*[1]

https://people.inf.ethz.ch/omutlu/pub/memory-systems-research_superfri14.pdf

Reference Overview Paper III

- Onur Mutlu,
  "The RowHammer Problem and Other Issues We May Face as Memory Becomes Denser"
  *Invited Paper in Proceedings of the Design, Automation, and Test in Europe Conference (**DATE**)*, Lausanne, Switzerland, March 2017.
  [Slides (pptx) (pdf)]

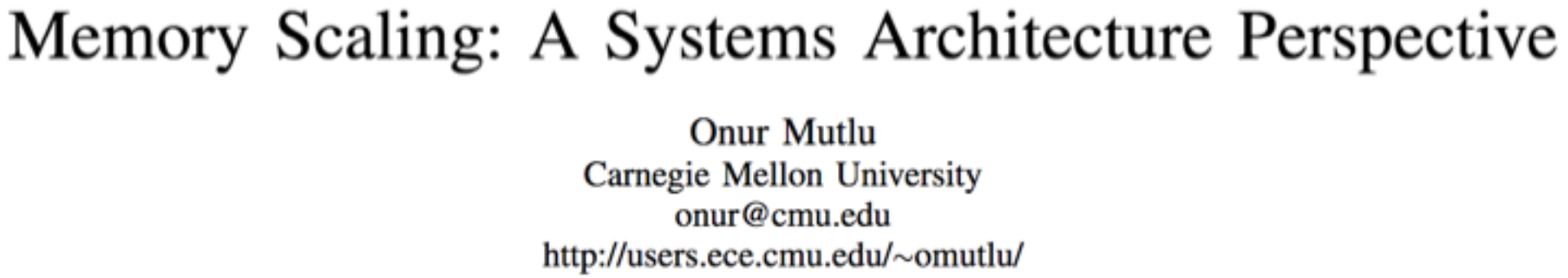

The RowHammer Problem
and Other Issues We May Face as Memory Becomes Denser

Onur Mutlu
ETH Zürich
onur.mutlu@inf.ethz.ch
https://people.inf.ethz.ch/omutlu

https://people.inf.ethz.ch/omutlu/pub/rowhammer-and-other-memory-issues_date17.pdf

Reference Overview Paper IV

- Onur Mutlu,
  "Memory Scaling: A Systems Architecture Perspective"
  *Technical talk at MemCon 2013 (**MEMCON**)*, Santa Clara, CA, August 2013. [Slides (pptx) (pdf)]
  [Video] [Coverage on StorageSearch]



Memory Scaling: A Systems Architecture Perspective

Onur Mutlu
Carnegie Mellon University
onur@cmu.edu
http://users.ece.cmu.edu/~omutlu/

https://people.inf.ethz.ch/omutlu/pub/memory-scaling_memcon13.pdf

Reference Overview Paper V

Proceedings of the IEEE, Sept. 2017

Error Characterization, Mitigation, and Recovery in Flash-Memory-Based Solid-State Drives

This paper reviews the most recent advances in solid-state drive (SSD) error characterization, mitigation, and data recovery techniques to improve both SSD's reliability and lifetime.

By Yu Cai, Saugata Ghose, Erich F. Haratsch, Yixin Luo, and Onur Mutlu

https://arxiv.org/pdf/1706.08642

Related Videos and Course Materials (I)

- Undergraduate Computer Architecture Course Lecture Videos (2015, 2014, 2013)
- Undergraduate Computer Architecture Course Materials (2015, 2014, 2013)

- Graduate Computer Architecture Course Lecture Videos (2017, 2015, 2013)
- Graduate Computer Architecture Course Materials (2017, 2015, 2013)

- Parallel Computer Architecture Course Materials (Lecture Videos)

Related Videos and Course Materials (II)

- Freshman Digital Circuits and Computer Architecture Course Lecture Videos (2018, 2017)
- Freshman Digital Circuits and Computer Architecture Course Materials (2018)

- Memory Systems Short Course Materials

  (Lecture Video on Main Memory and DRAM Basics)

Some Open Source Tools (I)

- Rowhammer – Program to Induce RowHammer Errors
  - https://github.com/CMU-SAFARI/rowhammer
- Ramulator – Fast and Extensible DRAM Simulator
  - https://github.com/CMU-SAFARI/ramulator
- MemSim – Simple Memory Simulator
  - https://github.com/CMU-SAFARI/memsim
- NOCulator – Flexible Network-on-Chip Simulator
  - https://github.com/CMU-SAFARI/NOCulator
- SoftMC – FPGA-Based DRAM Testing Infrastructure
  - https://github.com/CMU-SAFARI/SoftMC
- Other open-source software from my group
  - **https://github.com/CMU-SAFARI/**
  - **http://www.ece.cmu.edu/~safari/tools.html**

Some Open Source Tools (II)

- MQSim – A Fast Modern SSD Simulator
  - https://github.com/CMU-SAFARI/MQSim
- Mosaic – GPU Simulator Supporting Concurrent Applications
  - https://github.com/CMU-SAFARI/Mosaic
- IMPICA – Processing in 3D-Stacked Memory Simulator
  - https://github.com/CMU-SAFARI/IMPICA
- SMLA – Detailed 3D-Stacked Memory Simulator
  - https://github.com/CMU-SAFARI/SMLA
- HWASim – Simulator for Heterogeneous CPU-HWA Systems
  - https://github.com/CMU-SAFARI/HWASim
- Other open-source software from my group
  - **https://github.com/CMU-SAFARI/**
  - **http://www.ece.cmu.edu/~safari/tools.html**

More Open Source Tools (III)

- A lot more open-source software from my group
  - **https://github.com/CMU-SAFARI/**
  - **http://www.ece.cmu.edu/~safari/tools.html**

Referenced Papers

- All are available at

  https://people.inf.ethz.ch/omutlu/projects.htm

  http://scholar.google.com/citations?user=7XyGUGkAAAAJ&hl=en

Key Principles and Results

- Two key principles:
  - Exploit the structure of the genome to minimize computation
  - Morph and exploit the structure of the underlying hardware to maximize performance and efficiency

- **Algorithm-architecture co-design** for DNA read mapping
  - **Speeds up** read mapping by **~200X (sometimes more)**
  - **Improves accuracy** of read mapping in the presence of errors

Xin et al., "Accelerating Read Mapping with FastHASH," BMC Genomics 2013.

Xin et al., "Shifted Hamming Distance: A Fast and Accurate SIMD-friendly Filter to Accelerate Alignment Verification in Read Mapping," Bioinformatics 2015.

Alser et al., "GateKeeper: A New Hardware Architecture for Accelerating Pre-Alignment in DNA Short Read Mapping," Bioinformatics 2017.

Kim et al., "Genome Read In-Memory (GRIM) Filter," BMC Genomics 2018.

End of Backup Slides

Brief Self Introduction

- Onur Mutlu
  - Full Professor @ ETH Zurich CS, since September 2015 (officially May 2016)
  - Strecker Professor @ Carnegie Mellon University ECE/CS, 2009-2016, 2016-…
  - PhD from UT-Austin, worked at Google, VMware, Microsoft Research, Intel, AMD
  - https://people.inf.ethz.ch/omutlu/
  - omutlu@gmail.com (Best way to reach me)
  - https://people.inf.ethz.ch/omutlu/projects.htm

- Research and Teaching in:
  - Computer architecture, computer systems, hardware security, bioinformatics
  - Memory and storage systems
  - Hardware security, safety, predictability
  - Fault tolerance
  - Hardware/software cooperation
  - Architectures for bioinformatics, health, medicine
  - …